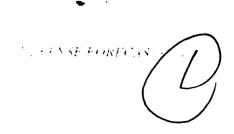
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DUAL-USE APPLICATIONS OF INFRARED SENSITIVE MATERIALS

BARRY M. BLECHMAN AND SCOTT C. LUSH

JUNE 1993

APPENDICES



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Appendix A

Current Military Programs to Develop Sensitive Infrared Detector Technologies

With Dual-Use Potential

As table A-1 illustrates below, there are nearly 20 DoD funded programs to either develop second generation MCT-based focal plane arrays or their components, or to integrate such sensors into operational systems. Although some programs address essential producibility issues such as PACE II and SHIELD, others are nearing initial production runs, including the Thermal Weapon Sight and AN/AAS-42. All together, total military demand for IR arrays in the 1990s could reach 300,000 units or more, resulting in a market worth about \$6 billion, at today's prices. In response to this rising demand, manufacturers have developed more than 65 types of IR focal plane arrays (see tables A-2 and A-3).

Amongst this broad range of development programs, four have particular potential to advance the potential of IR sensitive detectors for dual-use applications: Javelin missile, Thermal Weapon Sight (TWS), Standard Advanced Dewar Assembly (SADA), and the Infrared Materials Producibility Program. Each can make a unique contribution to the commercialization of IRFPAs. We describe each program below, and report the opinions of program officers, contractors, and outside commentators on its commercial potential. Most importantly, we analyze both the advantages which each program could offer in the development of detectors with dual-use potential, and the commercial limitations of each.

Javelin Missile Program

The US Army and Marine Corps plan to procure about 67,000 second generation FPAs for the Javelin missile program, at affordable prices. If any military program can bring down the costs of IRFPAs through economies of scale, automation, batch production, and other volume related manufacturing gains, it is the Javelin. Although the eventual cost of the IRFPAs being used in the Javelin missile is highly uncertain, most estimators believe that the total cost will exceed one-half billion dollars over the next ten years.

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Table A.1. Development Programs for Second Generation IRIPAs

		<u> </u>	<u> </u>	<u> </u>	l .	T ==		
Nots	To be placed in ground based launchers, Tiger/Tigre helicopter, and as aircraft's piloting aid.							
Material Used	MCT	MCT	MCT.	MCT	ЖСТ	LDW	MCT	MCT
Size of Array Bandwidth	288x4 LWIR (thermal sight for long range version)	48x4 LWIR (thermal sight for medium range version)	32x1 LWIR (for seeker for long range version)	64x1 MWIR (for seeker)	ė	j	64x64 LWIR (for sæker)	240X1 LWIR (for C'L'U)
Supplier of IRFPA	EURODIR (jont venture of SOFRADIR and AEG)	EURODIR	EURODIR	SOFRADIR	SBRC	SBRC	SBRC	П
Prime Contractor	SAT	ŧ	•	MATRA	Lockheed Missiles and Space	W.H.	MWIL	ī
Weapon System	TRJGAT anti-tank missile			MCA air-to-air missile	Follow-on Early Warning System (FEWS)	Bulliant Eyes Dem/Val	Javelin anti-tank missile	

Weapon System	Prime Contractor	Supplier of IRFPA	Size of Array Bandwidth	Material Used	Notes
Second Generation Tank Sight (SGTS)	Hughes Electro- Optical Systems	SBRC	460X4 LWIR	MC.I.	
Thermal Weapon Sight	Hughes Electro- Optical Systems	SBRC	40x 16 MWIR	MCT	TEC cooled. First second generation device to be off the blocks.
FEWS Bid	TRW/Grumma n	Loral Infrared Imaging Systems (LJRIS)		MCI	
Ground Based Interceptor	MM/Lockheed	LIRIS	480x380 PrSi CCD 128X128 (for sight) LWIR (for seeker)	MC.I.	
Electro-Optic Sensor System for RAH-66 Comanche	MM	LIRIS	480X4 LWIR LWIR for Electro-Optical Target Acquisition/Designation System for Night Vision Pilotage System	MCT.	
Multi-Sensor Target Recognition System	ЖЖ	רואוצ	480X4 LWIR	MCT	
Advanced IRST	N. X.	LIRIS	480x4 1.WIR	MCT	A candidate to equip Lockheed's F-22 fighter and other arcraft under a US \$50 m contract from US Air Force's Wright Lahoratory
FLIR and Automatic Cuer Technology Insertion into the LANTIRN	W.W.	LIRIS	480x4	MC.T.	Under test by US Air Force, to replace the standard first gen FLIR in the LANTIRN Largeting pod with an FPA-based imager.
AN/AAS-42	WDW	GE Aerospace (purchased recently by MM)	256x1	MCT	For US Navy F-14Ds. The first production application of second-generation long-wave arrays.

Weapon System	Prime Contractor	Supplier of IRFPA	Size of Array Bandwidth	Material Used	Notes
FEWS bid	Grumman Space & Electronics Group	Rockwell International Electro-Optical Center	MWIR LWIR	MCT	
Helicopter Extended Range Laser Illuminating Sight	Rock well International Tactical Systems Division and SFIM (France)	Rockwell International Electro-Optical Center (EOC)	MWIR 2564256	MCT.	
SDI Miniature Secker Technology Integration	Rockwell	i	Ĺ	MCT	
Infrared Materials Producibility Program	Johnson Matthey Electronics-led Consortium	N/A	Various	MCT	
Standard Advanced Dewar Asemblies		11.	240x4 480x4	MCT.	Potentially used in Improved TOW Acquisition Sight, TI's own Combat Behicle Tank Thermal Sight, and an ungrade to the Commander's Independent Thermal Viewer for M1A2
Silicon Hybrids with Infrared Extrinsic Long-Wavelength Detectors (SHIELD)		Rock well EOC	128x128 256x256	Extrinsic silicon	From USAF Phillips Laboratory. Will use blocked impurity band technology developed under the HYWAYS producibility effort to provide arrays for several SDIO programs, including Brilliant Eyes and GBI.

Weapon System	Prime Contractor	Supplier of IRFPA	Size of Array Bandwidth	Material Used	Notes
Producible Alternative to Cadmium Telluride for Epitaxy (PACE I)	Rockwell EOC	Rockwell EOC			Uses MCT deposited on a sapphire substrate to produce circular wafers. Rock well says that this approach, with which it has made dramatic strides in the past year, allows it to produce the highest-quality detectors available and to achieve a yield significantly above norm
PACE II	Rockwell	Rockwell	LWIR staring and scanning	MCT on GaAs	lfas not progressed as fast as had been hoped and has been returned to laboratory status for further research. The next approach to reach production is expected to be PACE III, using MCT on silicon

Table A-2. MCT-based IRFPAs for Military Applications

Company	Infra	Infrared Focal Plane Array		
	Array Format	Bandwidth	Material	Known Uses
GEC-Marconi Infrared (formerly Phillips Components)	Formats up to 1,024x1	ć.	МСТ	Development for Marconi Radar and Control Systems, funding from UK Defense Research Agency (DRA).
e .	128x128	?	MCT	1
Loral Infrared and Imaging Systems	240x1	LWIR	MCT	CLU's for Javelin second source.
	ı		MCT	For the TRW/Grumman FEWS candidate.
•	480x380	Visible	CCD, PISi	Sight for the MM/Lockheed team for the Ground Based Interceptor bid.
*	128×128	LWIR	MCT	Seeker for GBI bid.
	480x4	LWIR	MCT.	For MM's Electro-Optic Sensor System (EOSS) to equip the US Army's RAII-66 Comanche helicopter. This includes two Flirs: the Eletro-Optical Target Acquisition/Designation System (EOTADS) and the Night Vision Pilotage System (NVPS). Also for ARPA's Multi-Sensor Target Recognition System to develop technology for the autonomous attack of high-value mobile targets such as tactical ballistic missile launchers. Also for Advanced IRST under development by MM as candidate for Lockheed F-22 and other aircraft. Also for FRACTII. (FILR and Automatic Cuer Technology).
Martin Marietta (formerly GE Aerospace Electronics Laboratory	256x1	I.WIR	МСТ	AN/AAs-42 IRST being supplied for US Navy F-14Ds, the first production program for LWIR IR-PAs.
*	512x1	I.WIR	MCT	Prototype.
ı	1,024x1	I.WIR	MC.I.	Prototype.

Company	lnfra	Infrared Focal Plane Array		
	Array Format	Bandwidth	Material	Known Cses
t	480x4 TD!	LWIR	мст	Part of sensor suites successfully demonstrated by MM for the RAH-66 Comanche that can discriminate between targets 50-60 percent better than its predecessor on the AII-64 Apache. Two second-gen FLIRs are to work in conjunction with the Comanche's "Two Bar Scan" target acquisition system, and aid in navigation.
liughes' Santa Barbara Research Center	÷	LWIR	MCT	For Lockheed Missiles and Space Company for its FEWS (Follow-On Early Warning System) bid.
-	i	LWIR	MCT	For TRW on Brilliant Eyes Dem/Val Program.
*	64164	LWIR	MCT	Seeker for TIMM Javelin missile.
•	128x128	LWIR	MCT	Hughes Aircraft Co.'s Missile Systems Group is planning to propose use of an imaging infrared seeker on the possible successor to the Sidewinder air-to-air missile, currently known as the AIM-9X, which we ald use this IREPA.
•	480x640	LWIR	мст	Believed to be largest MCT array. Possible applications are as sensors on the future Navy AX aircraft and the next generation M-1 tank, and a number of low-cost commercial security systems.
	480x4	LWIR	мст	To Ilughes EOS for Second Generation Tank Sight (SGTS) technical demonstrator for NVEOD.
E	40x16 TDI	MWIR	MCT	To flughes EOS for ANPAS-13 Thermal Weapons Sight (TWS).
e.	960x4	LWIR	мст	Developed under DARPA's Infrared Focal Plane Array program, and recently delivered to TI for implementation in a forthcoming helicopter electro-optic system.

Company	Infra	Infrared Focal Plane Array		
	Array Format	Bandwidth	Material	Known Uses
SOFRADIR (France)	288x4	LWIR	MCT	Adopted for the British/French/German TRIGAT. Will form heart of SAT thermal sight for the long-range version of TRIGAT, both in ground-based launchers and aboard Tiger/Figre helicopier, and will be used as an aircraft's piloting aid. Also chosen by nine manufacturers in seven countries for basis of FLIRs and IRSTs. SAGE:M doing the most with them for submarine periscopes. Also purchased by Kolsman and Texas Instruments.
Ŧ	32x1	LWIR	MCT	Seeker for long-range TRIGAT. Seeker for Norwegian missile undergoing flight trials.
	288x1	LWIR	MCT	
	1,152x1	LWIR	MCT	
*	480x4	I.WIR	MCT	
÷	48x4	I.WIR	LDW	Thermal sight for medium range version of TRIGAT. Also sold to 11 for FLIR in Loral Vought System's LOSAT hypervelocity anti-tank weapon.
	288x4	MWIR	:WC.L	
:	64x1	MWIR	мст	Prototype. For seeker that SAT is developing for the Matra MICA air-to-air missile.
	64x64	LWIR	NCT	Ргоцогурс.
	128x128	MWIR	MC.I.	Ргомурс.
Texas Instruments	TIM family of 240x2 480x4 960x4		МСТ	Designed to fit into SADAs. Potential applications include the Improved TOW Acquisition Sight (FLAS), 11's own Combat Vehicle Tank Thermal Sight (CVTTS), and an upgrade to the COmmander's Independent Thermal Viewer (CTIV) installed in the M1A2 tank. If has bought TDI arrays from SOI-RADIR as an interim measure.
	240x1	LWIR	MCT	For CLUS for Javelin

Table A-3. Non MCT-based IRFPAs for Military Applications

Company	Infr	Infrared Focal Plane Array		
	Array Format	Wavelength Band	Material	Known Lyts
Amber Engineering (A Raytheon company)	128x128	LWIR	пЅь	For insertion into Amber's Series 4000 and 5000 cameras.
	\$12x512	LWIR	InSb	Advanced Large-area Infrared Transducer (ALIRT) program sposored by SDIO. Builds on success with 128x128 and 256x256 arrays.
	256x256	LWIR	InSb	Put into prototype imager by Marconi Radar and Control Systems for UK Defence Research Agency for FARSIGHT demonstrator progam. The imager will be installed in a high-performance aircraft to evaluate its usefulness for applications including piloting aids and detection of airborne and ground-based targets. Also for DRA's program on autonomous seekers for air-to-surface weapons. Existing array should be replaced with another Amber 512x512 later on. Marconi also considering offering a new system using the same array for retrofitting in tank sights.
Cincinnati Electronics	160×120	LWIR	InSb	
	256x256	LWIR	InSb	Prototype:
David Samolf Research Center	640x480	MWIR	P.Si	May be upgrade using indium silicide detectors manufactured under contract to the Rome Laboratory.
	i	LWTR	Germanium Silicide	In collaboration with Jet Propulsion Laboratory and Princeton University.
Eastman Kodak	640x480		PtSi	Kodak is sellings its PLSi camera business to companies in Europe and the US, but is continuin with development and manufacture of the arrays themselves for their industrial camera business.
Honeywell/ Alliant Techsystems		LWR	Microbolometers	For Army's Low-Cost Uncooled Sensor Prototype (LOCUSP) program.
Hughes Technology Center	640x480		PrSi	Potential use in the NLOS-CA missile program.
Laser Aeronutronic	256x256	MWIR	PtSi	For possible use in missile seekers, airbome surveillance pods, and themal weapon sights.

Company	lnfr	Infrared Focal Plane Array		
	Array Format	Wavelength Band	Material	Known Uses
Loral Fairchild Systems	640x480	MWIR	isu	For B-52 retrofit program to replace the standard AN/AAQ-6 FLIR in the navigation and targeting system aboard the B-52G/H planes. May also be used for Loral Thermal Sight System (LTSS), intended to replace the image-intesification elbows in M32, M35 and M36 periscopes abaord armored vehicles such as the LAV-25. Also may be in Loral Gunner's Sight (LGS).
Loral IRIS and Fairchild	ė	MWIR	PASi	Seeker to perform acquisition, tracking, and aim-point selection for the Theater High Altitude Area Defense (THAAD) missile system. System incorporates a Loral Fairchild system two-axis gimballed camera (using PSi array), integrated with an intential measurement unit employing ring laser gyros.
Misubishi Electric	1,040χ1,040	MWIR	P.S.	Uses proprietary charge-sweep device (CSD) technology which provides a greater amount of detector material in a given area than those using conventional CCD multiplexers. This array has demonstrated a 53 percent fill factor, compared with 38-50 percent for competitors' arrays. Has pixels that are 17 microns rather than usual 25 in diameter. Has licensed technology to Tillomson-CSF in France.
	256x256	MWIR	PtSi	Used in M300 thermal camera.
	512x512	MWIR	P.S.i	Used in IR-M500 camera.
Rockwell Electro-Optics Center	128x128 256x256	I.WIR	Extrinsic Silicon	Award from USAF's Phillips Laboratory for the Silicon Hybrids with Infrared Extrnsic Long-Wavelength Detectors (SHIELD) program. Will use blocked impunity band technology developed under the HYWAYS producibility effort. For potential use in several SDIO programs, including Brilliants Eyes and GBI.
Santa Barbara Focalplane	128x128	LWIR	чSи	Put into ImagIR thermal camera system, with multiplexers supplied by partner company Westinghouse.
	320x256	LWR	qSul	
	256x256	LWR	qSuI	

Company	Infra	Infrared Focal Plane Array		V.
	Array Format	Wavelength Band	Material	Allowii Oska
Semi-Conductor Devices (Israel)	128x1	LWIR	InSb	Company jointly owned by Tadiran and Rafael. Array for use in the seekers of air-to-air missiles and ni thermal imagers. SDC has also developed LWIR MCT arrays with very smaller detector elements.
Texas Instruments			Ferroclectric	For Army's Low-Cost Uncooled Sensor Prototype (LOCUSP) program.

The Javelin is a hand-held, man-portable "fire-and-forget" anti-tank weapon intended by the Army to replace the M-47 Dragon. each of its two main components requires a second generation focal plane array. The first, called the Command Launch Unit (CLU), is an infrared telescope weapon sight used by the operator to spot a potential target. The second component is the actual missile round. The missile cone contains an IR focal plane array which can lock on to a potential target chosen by the operator in under ten seconds, and continue to track the target until impact. During flight, the missile is connected to the CLU on the operator's shoulder by an electrical umbilical cord. As soon as the missile's IRFPA locks on to a target, however, the missile's image is transmitted back to the CLU, at which point the operator can disengage and take cover. The CLU is reusable, while the missiles are not, so the current plan is to procure twelve times more missiles than CLUs.

The Command Launch Unit and missile round each use a second generation forward looking IR detector. The CLU uses a LWIR, MCT-based, 240x1 scanning array, cryocooled to 77 °C. The CLU scans an image bi-directionally, with 120 pixels reading in one direction while the other 120 scan in the opposite direction. The unit operates at a rate of 30 Hz, and produces a 240x480 display. Although the image is viewed through an eyepiece, it also can be read out digitally to other display units or video equipment through a port on the unit's side.

The IR detector in the CLU operates in the LWIR for two reasons. First, the high energy of photons in the 8-12 micron window make detection easier at longer distances. In fact, any detector with ranges greater than about a kilometer needs to operate generally in the LWIR to achieve the sensitivity necessary to image objects at those distances. Second, the LWIR is not attenuated or filtered as much as the MWIR by moisture, fog, dirt, or rain. Any ground-based IR system intended to operate under battlefield conditions can make better use of the LWIR than the MWIR.²

Texas Instruments is the primary source of the CLU scanning array. TI's novel architecture makes use of the company's Vertically Integrated Photodiode (VIP) approach. The sensor incorporates a front-side illuminated n-on-p doped MCT wafer which is essentially glued on to a silicon read-out circuit. TI claims the VIP technique can be cheaper than conventional IR detectors which are indium bump-bonded. But TI only turned to the VIP technique after failing the manufacture cheaper and better IR arrays by another innovative technique called

¹ Programs to develop space based infrared sensors have used doped silicon as the excitor material, to achieve even longer-wave detection, up to about 100 microns.

² The Navy, by contrast, has preferred infrared sensors which operate generally in the MWIR because they are said to perform better in maritime environments. This is discussed further below.

Appendix B

Uncooled Pyroelectric Detectors Are a Formidable Competing Technology

Uncooled infrared detectors, also called pyroelectric detectors, differ fundamentally from advanced infrared detectors based on MCT, InSb, or PtSi. Uncooled focal planes are two-dimensional arrays of infrared pixels that are thermally isolated from their surroundings by insulating material. Rather than detecting photons directly, as MCT-, InSb- and PtSi- based systems do, uncooled detectors respond to incoming radiation by changing their temperature. Read-outs of signals from up to 80,000 pixels are then multiplexed and sent for processing, just as in sensitive, cooled IR detectors.

Two-dimensional staring arrays of uncooled infrared materials, such as barium strontium titanate (BST) and silicon-based microbolometers, operate at room temperature, in the long-wave infrared (LWIR) at 8-12 microns. They require no more than a single-stage, low-power thermoelectric cooler to smooth temperature fluctuations in surrounding ambient air. By comparison, the MCT-based IR system with the least cooling requirement is the MWIR staring array being developed for the Thermal Weapon Sight (TWS), which requires six-stage

thermoelectric cooling.

Texas Instruments and Honeywell are the leading developers of pyroelectric devices.

Texas Instrument's approach uses ferroelectric, BST-based arrays. The detectors are fabricated from a ceramic material, barium strontium titanate. The polarization and dielectric constant of BST pixels change with temperature, resulting in a change in charge on a capacitor as the target scene varies. The pixels are diced by the same process as MCT-based arrays. The read-out circuit chip is hybridized onto the read-out chip, just as with MCT-based arrays, using indium bump bonds. The detector looks alternately at the target scene and a background reference temperature to sense change. The incoming infrared scene is AC-coupled by a rotating mechanical chopper. Without a chopper in the system, the surface charge would dissipate and cause the scene contrast to decrease to zero, resulting in fade-out of the scene, except for any moving objects. Rows and columns of the array are read out in sequence by sending voltages along a two-dimensional switch matrix. The signals are then sent through an amplifier, a multiplexer, and an analog/digital converter prior to further signal processing. Gain and offset correction are applied to remove the fixed-pattern noise due to the non-uniformity of response of up to 80,000 detectors. Dead pixels are corrected by substituting information from adjacent pixels.

By comparison, Honeywell's approach uses two-dimensional arrays of bolometers. The

resistance of each pixel changes about two percent per degree change in temperature. Vanadium Oxide is the temperature-sensitive resistor material, suspended on a bridge of silicon nitride that is thermally isolated from the substrate containing the read-out electronics. As with TI's BST-based arrays, Honeywell's bolometers use a single-stage thermoelectric cooler. As a voltage is applied to each row of gates in sequence, a bias current flows through all of the detectors in the row, and they are read out in parallel via the column leads to a high-speed multiplexer at the base of the columns. This row of information is then multiplexed before the next row is read. Since there is no AC coupling of the incoming thermal radiation, no mechanical chopper is used. The only moving part is a shutter that is periodically closed momentarily for the system to recalibrate. As with BST-based arrays, the signals are conditioned with gain- and offset-correction to remove non-uniformities, and dead-cell correction is applied.

Military Development of Uncooled Detector Technology

US Army and DARPA funds helped develop pyroelectric detector technology to the point where commercial spin-offs are within grasp. Specifically, the Night Vision and Electro-Optics Directorate (NVEOD) and Balanced Technology Initiative (BTI) division of DARPA have funded basic research in uncooled infrared detectors mostly for night vision systems, and helped TI and Honeywell move a long way toward commercializing their pyroelectric technologies. TI, in particular, is venturing into commercial applications for its BST-

based system as defense funding for BST declines. It is aggressively developing a high volume production facility, fielding prototypes, and developing close relationships with potential endusers. TI executives reason that, at worst, the commercial market will tide their BST-based detector line over until other military programs using BST-based detectors come on-line. At best, Texas Instruments expects large sales in the commercial sector within the next decade.

Four military programs fostered uncooled detector technology over the last 15 years. TI began to develop BST-detector technology in the mid-1970s, whereas Honeywell only began to develop resistance bolometers in 1985.

The Short Range Thermal Sight (SRTS) was the first military system to use BST-based detectors, and demonstrated the potential of BST-based detectors for moderately demanding applications. Texas Instruments' rough prototypes integrated a two-dimensional, 100 X 100 pixel array. Although the mosaic array offered good sensitivity, the resolution was extremely poor, and each pixel measured four millimeters square, much larger than competing infrared systems.

The Army then followed-up with the Small Pixel Program (SPP), also awarded to Texas Instruments. That program doubled the resolution of the BST arrays to 100 X 200 pixels, and halved the pixel size to two square millimeters. Resolution therefore doubled while the array remained on a chip of the same size as the SRT. This demonstrated that BST-based arrays were on the road to reaching the staring potential of more expensive and more sensitive infrared

materials. From this program forward, military development efforts stressed two goals for BST-based detectors: To increase the pixel density to approach television resolution and smaller pixel sizes so entire chips could be less than one inch square.

A third Army and BTI/DARPA funded technology development program, the High Density Array Development (HIDAD), is the major reason for the current capabilities of both BST- and microbolometer-based detectors. The program was active from 1987-91, with awards to both Texas Instruments for BST technology and to Honeywell for its bolometer arrays. The goal was to procure "breadboards," table-top assemblies with accompanying racks and power supplies, designed to demonstrate the technology rather than produce fieldable prototypes. The BST-based array grew to 240 X 328, which met the goal of TV-compatible RS-170 video output. Sensitivity on those units reached about 0.2°C, from 0.3°C at the start of the HIDAD program. This is still far from the .02°C sensitivity of advanced MCT-based systems, but is acceptable in less demanding military applications and sufficient for many commercial applications. Honeywell's bolometer technology, however, did not fare as well and produced brassboards which never performed to spec and were unreliable. Hone, well took until December 1989 to demonstrate a reliable brassboard with a 240 X 336 array for HIDAD.

The most recent program to foster BST-based detector research is the Low Cost Uncooled Sensor Prototypes (LOCUSP), which is a two-phase program to deliver fieldable prototypes of four different systems for a variety of military applications. These prototypes incorporating the

uncooled HIDAD arrays described above, would meet varying performance specifications. Texas Instruments and Alliant Techsystems (with Honeywell as a subcontractor to provide microbolometer arrays) were awarded contracts for BST- and bolometer-based technologies.

Phase I of LOCUSP, which ended in early 1993, developed a medium-range thermal imaging weapon sight and a thermal sensor for surveillance applications. TI manufactured 23 fieldable prototypes for that phase. They included six for the Air Force for security surveillance of airstrips containing the B-2 Bomber, one to the Naval Research Lab for reconfiguration into a fire fighter's helmet for vision through smoke, and six to the Immigration and Naturalization Service (INS) as a surveillance aid atop police vans. TI was able to increase the average sensitivity to .08°C, with a distinction of .065°C possible at a higher cost. The systems cost \$100,000 each to manufacture, which of course is far more than they would cost in volume production. Alliant Techsystems, however, has not yet developed a working prototype that achieves all the milestones. Most officials we contacted attributed this to Alliant/Honeywell's late entry into the uncooled market. Their technology is still immature, and will take two to three years to catch up to Texas Instruments'.

Phase Two of the LOCUSP program would procure fieldable prototypes of sub-munition seekers and missile seekers, and require detectors which meet more stringent parameters. Sensitivity would need to be better than 0.1 ° C. The sub-munition environment would challenge system design because of the jolt and stress on electronics during launch from a howitzer.

Although both contractors met the performance requirement of 0.1 °C, which was the required NETD (sensitivity) for the modified HIDAD program, funding cut-backs have prevented NVEOD from authorizing the contractors to begin Phase II of the LOCUSP program. The hold-up appears to be more due to realignments within DARPA itself as it takes the BTI office under its fold than wholesale loss of interest in uncooled technology.

Representatives from the Army, Marines, Air Force, Navy, INS, Sandia National Laboratories, and other government agencies have been following progress on the LOCUSP program closely, because system prototypes have many potential applications outside of submunitions and surveillance cameras. The Air Force and Navy, in particular, were not part of the original review sessions but have joined and purchased prototypes because of their interest in LOCUSP. The small size, light weight, low power requirement, and availability of video output from the weapon sight of Phase I prototypes make them particularly useful for portable applications, and for commercial spin-offs.

The development of uncooled detector technologies has not been funded by Army and DARPA decision-makers since fiscal year 1991, however, and these technologies are beginning to lose their footing in the infrared market. According to industry and military officials, the next logical step in development would be a program to design a monolithic architecture for the BST-based detector. The Army's Thermal Weapon Sight (TWS) program, for example, could have further honed BST-detector technology, but performance requirements all but ruled out uncooled

technology. For example, the TWS program intends to acquire at low cost about 20,000 rifle sights operating in three standard ranges: 550 meters, 1,100 meters, and 2,000 meters. BST-based detectors could currently meet the short and medium, but not the longest range requirement for the TWS. BST-based systems also require about one watt more of electricity, and weigh about a half pound more, than is specified for the TWS. For these reasons, Texas Instruments was not awarded a TWS development contract, losing out to Santa Barbara Research Center (SBRC) for MCT-based detectors using thermo-electric coolers (TECs).

Advantages and Disadvantages of Uncooled IR Detectors

Uncooled detectors offer substantial advantages which make them attractive in night vision equipment, thermal weapon sights, sub-munitions and missile seekers, and surveillance equipment, and also give them strong commercial potential. Most importantly, the absence of a cryocooler and dewar saves up to \$10,000 per unit. Uncooled detectors also have very modest power needs at about three watts, and can run for long periods without recharge, about 24 hours with standard military batteries. Since they do not need frequent topping off with liquid nitrogen, uncooled detectors are more portable, as well. Even a closed-cycle cryocooler needs to have its hydrogen recharged every 800 hours, reducing portability. Uncooled staring detectors also do not have the optics used in scanning infrared detectors, and are therefore an additional several thousand dollars cheaper and easier to maintain. They have virtually no moving parts, which

increases reliability, reduces maintenance, and system costs. TI's BST-based detectors have one moving part, which is a simple mechanical chopper. Honeywell's bolometers have no moving parts at all.

These advantages of uncooled infrared detectors are tempered by several disadvantages.

- The largest drawback is that uncooled detectors are an order of magnitude weaker than MCTor InSb- based systems in resolution, fill factor, and quantum efficiency. Pyroelectric materials offer only moderate performance, a weakness inherent in their physical properties.
- Second, TI's BST-based detectors in particular have a degree of signal crossover which causes bright spots in an image to spill over into adjoining pixels. This is inherent in BST-based detector architecture, and can not be overcome. TI's detectors use diced and thermally isolated BST cubes, covered by a silicon signal processor which is both a ground for the common electrodes and a thermal pass. As a result, though, electrons leak to read-outs from neighboring pixels, producing an image which is less crisp. This problem is not found in Honeywell's bolometers, which have a bridge structure that supports the sensor and is thermally well isolated from adjacent detectors, preventing any thermal cross-talk.
- Third, uncooled detector arrays cannot measure absolute temperatures in each pixel of view because they do not have advanced gain and offset correction as MCT-based systems do.

However, advocates of pyroelectric detectors note that uncooled detectors could make absolute temperature measurements if simple signal conditioning technologies were developed (or adapted from MCT-based detector technology). That capacity has not been developed in the past because thermal weapon sights and night vision equipment, the devices for which uncooled detectors were developed, do not require radiometric measurements.

In summary, uncooled IR detectors offer cost advantages that are offset by performance drawbacks. The potential markets for pyroelectric detectors, therefore, are applications for which neither sensitivity nor absolute temperature measurement are paramount issues. These areas of application require infrared detectors which are easy to maintain, operate at moderate scan rates (about 30 Hz), maintain sensitivities of about 0.1 °C, and do not require radiometric readings. If uncooled IR detectors can be manufactured for less than \$3,000, as producers claim can be achieved, they could likely overtake competing IR materials for such less sophisticated applications as non-destructive evaluation of buildings and structures, food inspection, underground remote sensing, pipeline and gas leak detection, driver's vision enhancers, and IVHS components.

Texas Instruments Considers Commercialization

Officials at Texas Instruments state that BST-based detectors now meet two criteria for entry into the commercial detector market: 0.1 °C sensitivity, and resolution fine enough for a

program, and refined for Phase I of the LOCUSP program. Texas Instruments has turned its efforts, therefore, toward meeting a final criterion for entry into the commercial market: drastic cost reductions.

TI fabricated BST-based detectors in a laboratory-style environment for the HIDAD program. Production was in low volume with a high fraction of the cost attributable to manual labor. BST wafer yields were as low as five percent for the early HIDAD detectors. TI's first priority, therefore, was to construct a new facility which integrated automated processes in a high volume production line. That facility is still being put together, having cost \$10 million over the last two years and still in need of \$5 million to \$10 million over the next year before completion. The center has been designed to produce 1,000 uncooled detector units a month.

TI took several innovative steps to design this facility to produce cheap BST-based IR detectors for the commercial market. The facility was designed to be about ten times cleaner than TI's other infrared production facilities, because impurities are a leading problem in bringing up the yields of BST-based arrays. A statistical process control system has also been set up to increase yields. Also, although the silicon wafer industry has advanced to about 8-inch square wafers, TI utilizes in its new facility some older, silicon processing equipment which makes cheaper 4-inch square wafers. Those wafers are used for signal processing and hybridized with the BST wafers to make the detector. That silicon processing equipment had become obsolete

to TI's integrated circuit board business, but produces wafers which are cheaper and satisfactory for hybridization with BST wafers bound for the commercial market. Without the need to make silicon wafers for hybridization to military specs, one executive at TI estimates that the new boards could be made at one-hundredth their military cost. Slice processing also reduces recurring labor cost, because forty to fifty detectors are processed simultaneously, instead of one-by-one.

TI has embarked on a sophisticated marketing effort for its BST-based system. Early-on, the company decided to focus on four prospective commercial market segments: surveillance, all-weather and night vehicle vision, predictive maintenance, and remote sensing. About ten people at TI work full-time researching these potential segments, talking with prospective customers, taking market surveys, and discussing needs with prospective end-users. This market-oriented approach is much different from the classical technology-directed commercial attempts being made by several other US military contractors. Test units have been sent out to users in key industries, and feedback is sought on how well the BST-based pilot installations meet customer needs. For instance, a TI uncooled specialist explained that the commercial trucking business could use infrared detectors to aid in night vision and collision avoidance. When a trucking company executive saw TI's prototype unit, according to an official at TI, he suggested they create a model to test the brake pads of trucks. Truck drivers are sued for millions of dollars each year for accidents caused by brakes which overheat and fail, and there are no quick and reliable non-destructive testing techniques short of dismantling brakes. So TI is now developing

a thermal vision system to meet that application also. By working closely with end-users, TI is developing systems which meet customer needs and helping design altogether new applications. No one else in the military infrared business appears to have tried these pilot installations, or solicited so much feedback from prospective customers.

Executives at TI claim that BST-based detectors will fall in price to about \$5,000 each when their facility begins operation in 1994, and that many commercial applications can be met at that price. The eventual goal is to reach about \$500 a unit, which would enable very large scale production in the tens of thousands of units per year. The foremost high-volume application which TI is reportedly seeking is placement of BST-based detector in cars as a nightvision aid. Development of the truck prototypes is expected to help reach economies of scale. There are reports from executives outside of TI that BST-based arrays will be purchased in great numbers by Hughes and General Motors for placement in Cadillac-model cars as early as 1995, but more likely by 1997. Amid industry reports that both the Japanese car manufacturers and BMW are interested in placing similar head-up displays in their cars after 1995, the transportation market could be extremely profitable. Placement of BST-based detectors in the Cadillac would Hughes is widely certainly be a breakthrough for TI and the commercial infrared market. acknowledged by outsiders as the unspecified "large defense contractor" with which TI is teamed in the BST-detector business, but executives at TI have not gone public with the name of its teaming partner.

Executives at TI stressed that their extensive development of BST for the commercial market will feed back positively into their ability to compete in the military infrared market as well. If the Army and DARPA have confidence in TI's extensive BST-based detector experience, according to TI executives, they will be more likely to give the go-ahead for Phase II of LOCUSP and design all together new programs around BST-based detectors. They even contend that TI will be able to compete for lower-end infrared applications which could use MCT, PtSi, and InSb-based detectors in three particular military programs.

First, the Driver's Vision Enhancer (DVE) program plans to procure 19,225 infrared detector units beginning in 1998 for Army wheeled vehicles. Operation Desert Storm highlighted the need for night vision equipment on all Army vehicles; tanks outfitted with night vision equipment advanced during the night but had to leave support vehicles behind with supplies, equipment, and food. BST-based detectors could reportedly meet the DVE's specifications, but would have to compete directly with more sensitive and more expensive cooled detectors. A request for procurement is expected to be released during the first half of 1993.

Second, DARPA's Flexible Manufacturing Program may have about ten percent of its funds fenced off for uncooled detector technology, but TI executives believe they could meet the specs for cooled IR detectors as well. Third, TI believes it could be an attractive recipient for DARPA's dual-use funds because it is cultivating a technology with clear military and civilian uses.

In summary, Texas Instruments is keeping its BST-based detector unit in "fighting shape" for military programs which may potentially use ferroelectric detectors. Without its sustaining commercial effort, TI contends that its BST production facilities and expertise would be idle. The synergies between Defense and commercial applications are apparent.

Appendix C

Annotated Bibliography Database

(i) Basic Scientific Primers

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- Cenn, G.K.T. and D.G. Avery, Infrared Radiation (Boston: Van Nostrand, 1966)
- Dereniak, E.L. and D. Crowe, Optical Radiation Detectors (New York: Wiley, 1984)
- Ghys, R., <u>Thermaographic Medicale</u> (NY:Somabec Ltee, 1973). On the clinical aspects of infrared thermography.
- Hadni, A., L'Infrarouge lointain (Paris: Presses Universitaires de France, 1969).
- Holter, M.R., S. Nudelman, G.H. Suits, W.L. Wolfe and G.J. Zisses, <u>Fundamentals of Infrared Technology</u> (New York: Macmillian, 1962).
- Hudson, R.D., Infrared System Engineering (New York: Wiley, 1969).

 Probably the best of the group for a general introduction. It comes from a collection of design experience at Hughes. It has been around for a while, as is evident by the date, but the fundamentals do not change. It is also distinguished by a very fine literature search, including much material that appeared in patents. The last part has a nice collection of discussions of various infrared applications.
- Hudson, R.D. and J.W. Hudson, <u>Infrared Detectors</u> (New York: Dowden, Hutchinson and Ross, 1975). A collection of reprints.
- Jamieson, J.A., R.H. McFee, G.N. Plass, R.H. Grube and R.G. Richards, <u>Infrared Physics and Engineering</u> (New York: McGraw-Hill, 1963).
 This was a very early book in the field. It is similar to Kruse and Seyrafi, with a slightly different emphasis. Jamieson is strong on statistics and detection theory.
- Johnson, R.B. and W.L. Wolfe, <u>Selected Papers on Infrared Design</u> (Bellingham, WA: SPIE, 1985).

 A two-volume collection of papers devoted to various aspects of infrared design.
- Kemp, B., Infrarcd (City: Sams, year unknown)
- Keyes, R.J. Optical and Infrared Detectors, <u>Topics in Applied Physic</u> (New York: Springer Verlag, 1980).

 A collection of chapters, written by authorities, just like the two Willardson books.
- Kingston, R., <u>Detection of Optical and Infrared Radiation</u> (Springer Verlag, 1978).

 A well organized and minimalist book (read: short and small) which leaves much of the derivation development to the reader. It is a good book for those who are already technically prepared.

- Kroger, F.A. The Chemistry of Imperfect Crystals, 2nd rev. ed. (Elsevier, New York, 1974).

 A classic on semiconductor crystal growth which explains techniques, types of defects, and epitaxial growth. "Essential reading" on crystal science.
- Kruse, P.W., L.D. McGlauchlin and R.B. McQuistan, <u>Elements of Infrared Technology</u> (New York: John Wiley and Sons, 1962).

 Best of the older books on detectors, and the "purple peril" is the best introduction
- Lloyd, J.M. Thermal Imaging Systems (New York: Plenum Press, 1975).

 The best of the lot on the design of thermal imaging devices, and comes from the collected wisdom of Honeywell and the Night Vision Lab. It includes excellent discussions of the use of modulation transfer functions, when they were still new to the infrared field. It is also a fine treatise on the properties of the eye as it relates to the sensitivity of real-time infrared systems.
- Morten, F.D., T.J. Jarratt, P.R.D. Coleby, R.A. Lockett, M.H. Jervis, R.J. Hutchinson, <u>Applications of Infrared Detectors</u> (City: Mullard, 1971).
- Rhines, F.N., Phase Diagrams in Metallurgy: Their Development and Application (McGraw Hill, New York, 1956)

 A classic on wafer and epitaxial growth which explains the fundamentals on MCT and semiconductors which still apply today.
- Seyrafi, K., <u>Electro-optical Systems Analysis</u> (Electro-Optical Research Company, Phoenixville, PA, 1973).

 Although published by his own company (and therefore not receiving the benefit of outside review), a thorough treatment of the details of system design in the visible and the infrared.
- Simon, I., Infrared Radiation (New York: Van Nostrand, 1966)
- Spiro, I.J. and M. Schlessinger, <u>Infrared Technology Fundamentals</u> (Toronto: Marcel Dekker, 1989)

 The newest addition to the seminal pieces; the authors have spent much time at Aerospace. It has a spacey flavor, and it incorporates modern considerations of staring systems.
- Vanzetti, I, <u>Practical Applications of Infrared Techniques</u> (New York: Wiley, 1972).

 as good insights into present (in 1972) and future applications for infrared technology at the back of the book in which it lists and discusses applications.
- Wallace, J.D. and C.M. Cade, <u>Clinical Thermography</u> (Boston: CRC Press, 1975).

 Largely on the medical use of thermal imaging, which is a burgeoning field using infrared scanners.
- Willardson, R and R. Beer, Semiconductors and Semimetals Volume 5 (1970) and Volume 12 (1977), Infrared Detectors (New York: Academic Press, 1970).

 Detailed treatmen's of the physical properties of detector materials.
- Wolfe, W.L. and G.J. Zissis, <u>The Infrared Handbook</u> (Ann Arbor, MI: Environmental Research Center, 1985). Not meant to be tutorial, but has much data. Will serve as a dependable reference piece.
- (ii) Overviews of Technological Trends

- Ballingall, R.A. "Review of Infrared Focal Plane Arrays," (SPIE Paper 1320-11) 1990.

 General technological discussion and introduction into varieties of arrays, technologies and concepts.
- Balcerak, Raymond and Lynette Brown, "Mercury Cadmium Telluride Material Requirements for Infrared Systems,"

 J. Vac. Sci. Technol. B (Jul/Aug 1992), 1353-1358.

Discusses primarily how the choice of infrared detecting material in second generation photovoltaic IRFPAs and its quality affect nearly all the other design requirements in an IRFPA, from signal processing, to cooling requirements, to processing electronics. It stresses that by boosting uniformity, reliability, and size of wafers, primarily MCT, will cut the overall system cost. There is a discussion of ways to improve on MCT epitaxial quality.

Botts, S.E., "New Horizons for IR FPA," Photonics Spectra (July 1988), pp. 125-28.

A bit dated, but explains that infrared systems utilize light-sensitive devices for the conversion of thermally generated photons into electronic signals that are amplified and processed to perform a variety of functions including targeting, tracking and imaging. As the technology matures, so do the integrated circuits that read out the infrared signals from the detectors and the parallel processors that operate on the signals. This article is an overview of second-generation detectors, integrated readout circuits, focal plane configurations and parallel processing.

Cross, E.F., and T. Reese, "Figures of Merit to Characterize Integrating Image Sensors: A Ten-Year Update," (DTIC: Sept 1989), 34p.

A ten-year update is presented on performance criteria and measurement techniques to evaluate integrating image sensors. The integrating image continuously monitors the field of view and an electronic mechanism that sequentially reads out the integrated signal on each resolution element. Ten years ago, camera tubes were the integrating imager of interest; today, staring focal plane arrays have supplanted camera tubes as integrating imagers. The adaptability of the 1978 figures of merit to the new staring devices is reviewed and, when indicated, modified.

Director of Defense Research and Engineering, <u>DoD Key Technologies Plan</u>, (Department of Defense, Washington: DC) July 1992.

A yearly document on key technologies which DoD considers critical to the national defense. Printed to fulfill the requirement of the National Defense Authorization Act of FY 1990 and 1991. Extensive discussion of passive sensors, trends, technologies, producers.

Elliot, C.T., "Future Infrared Detector Technologies," <u>Fourth International Conference on Advanced IR Detectors and Systems</u> (London June 5-7 1990), pp. 61-68.

Trends in infrared detectors are toward larger, electronically addressed arrays and higher operating

temperatures. This will lead both to higher performance and to smaller, lighter, more affordable systems. Three detector technologies are discussed: electronically addressed thermal detector arrays, Schoutky barrier devices, and CMT FPAs. IR detectors based on low dimensional solids are considered briefly.

Gillham, J.P., "Materials and Technology Research in Uncooled Ferroelectric IR Detector Arrays," Fourth

International Conference on Advanced IR Detectors and Systems (London June 5-7 1990), pp. 6977.

A technical piece on the key areas of technological advancement in ferroelectric IRFPAs which may render them very useful in industrial applications. The emphasis is decidedly on technical research rather than applications. This is a good piece on emerging IRFPA materials.

Hartung, C., Mueller, J. "Sensitive Detection of Infrared Radiation, the Optothermal Detector and its Application," Infrared Physics (May 1989), pp. 279-284.

The development of thermal detectors has reached a high technological level. The main characteristics such as detectivity, sensitivity and noise equivalent power are near the theoretical limits. The way to future development of detectors will be their specialization, especially their combination with other physical effects. Recent developments of room temperature infrared detectors, especially considering the coupling of the detectors with absorption in gaseous media, ic. optothermal detection, is discussed.

Hoelter, Ted. "Testing Second-Generation IR Focal Planes," Photonics Spectra (July 1992), pp. 105-108. Modern 128X128 and 256X256 FPAs are constructed by indium-bump-bonding a Si readout device to the InSb detector array. Testing must be done on both the individual components and the completed, bonded device. McCoy, Joseph R., "FPA Packaging: A Second Generation," Photonics Spectra (January 1992), pp. 99-100.

The second generation of FPAs, called integrated detector/cooler assemblies, offers higher performance, less weight, and less expensive infrared systems for sale on both the military and commercial markets. Improvements were made possible by databanks on expansion of key materials under varying temperature, as well as analyses of predicted stress areas on the FPAs. Although the U.S. military is committed to an effort to make this second generation of FPAs commercially available and standardized, several key parameters vary on the market, making standardization difficult.

- Jamison, J.A., "Infrared Technology: Advances 1975-1984," (SPIE Vol. 510, 1984) pp. 56-68.

 Extremely informative historical piece on the major technological issues which were overcome in that period! Jamiesen is a strong believer in the ability of MCT to overcome producibility issues which have plagued it since the PC scanning arrays first entered into R&D.
- Leech, D.P., et. al., "Industrial Base Analysis of Infrared Detector Industry," <u>Air Force Task Command</u> February 1991.

 Systematic analysis of every facet of the military IRFPA market, with an accent on MCT-based IRFPAs. Including market structure, market size, production techniques, materials issues, and areas where technology
- Leech, D.P., "The US Infrared Detector Industry: Prospects for Commercial Diversification," (SPIE Vol. 1683, 1992) 11pgs.

is still in need of research.

Industry appears to be groping to identify solid commercial applications for its more advanced technologies. Government representatives are no doubt anxious about potential erosion of the industrial base. The author suggests that some serious thought be given to innovative intra-industry or government-industry activities focused on lowering cost and providing useful information about dual-use applications.

- Marchee, P.P., "New Generation Infrared Camera," (SPIE Paper 1320-18) 1990.

 Work done at Thomson-TRT Defense, France on advanced IRFPA based cameras. Discussion of applications and novel technologies used to produce the camera.
- Mundie, L.G. and K. J. Hofmayer, Infrared Focal Plane Array Cost Considerations in the SDI Environment (Rand National Defense Institute, August 1990), 52 pgs.

 Begins with a brief background on focal-plane theory and manufacturing technology which may be very useful. It then proposes a new manner of evolving cost-estimating relationships for IRFPAs. Cost estimates have hitherto been a large problem due to the uncertainty of many cost factors (especially the array and dewar cooler)

- Silverman, Jerry, et al., "Infrared Video Cameras," Scientific American (March 1992), pp. 78-83.

 This is the renaissance man's introduction to IR cameras. Similar to home video cameras, these devices can "see" thermal radiation. This emerging technology offers a host of applications, including night vision, visualization of heat flow and medical analysis. There is a discussion of architecture and applications which is at the common-man's level, but little on the materials aspect.
- Scribner, Dean A. et al., "Infrared Focal Plane Array Technology," Proceedings of the IEEE (January 1991), pp. 66-85. In 20 pages, the authors give a detailed discussion, from the layman's to arch-technical level, of all major design considerations in IRFPAs. Requirements for IRFPAs are discussed and an overview is given of different IRFPA architectures. Applications are hardly discussed.
- Stahl, K.J., "IR- Detectors: State-of-the-Art, Future Trends," Photonics Spectra (September 1989), pp. 95-98. Infrared detectors are key components for systems that are used for such things as radiometry, guidance, thermal imaging, telemetry, and communication. Starting with WWII, developments were concentrated on detectors for military applications, e.g. weapon guidance, reconnaissance and thermal imaging devices. In the past ten years, however, IR detectors have become more and more important in earth-bound, air and spaceborn systems for spectral earth mapping, environmental contamination control, meteorology, volcanism study, agricultural research, resources exploration, planetary and space research and star mapping. For military applications, the spectral band form 0.9 to 14 microns is sufficient, whereas for the other mentioned applications the spectrum between 0.9 and 300 microns (and beyond) is of interest. Detecting mechanisms and future trends are considered.
- Tebo, Albert, "Infrared Imaging: Detector Arrays," <u>OE Reports</u> (May 1992), pp. 1,13.

 This is a short survey article on what technological advances are emerging in second generation IRFPAs.

 It discusses new architectures, matrices, materials, and the leading companies. It does not discuss applications.
- Tennant, William, et. al, "Key Issues in HgCdTe- Based Focal Plane Arrays: An Industry Perspective," <u>Unpublished Paper</u>, 27pgs.

Technological limits rather than fundamental issues are the only barrier keeping MCT from completely dominating almost all IR applications. The paper highlights some of the more vexing and as yet unsolved A thorough review of MCT's advantages, product source purity, lattice mismatch due to nonuniformity, MIS devices, alternative substrates, nucleation, thermal expansion differential mismatch, longevity, comparisons of different production techniques, etc. The theme is that several problems once considered limited, have either been dismissed because the problem was circumnavigated, or hitherto unimportant obstacles have become major sticking points (ie. purity)MCT materials science and engineering problems that the authors see as being important.

Wanstall, Brian and Doug Richardson, "Towards Lower-Cost Focal Plane Arrays," <u>Interavia Acrospace Review</u> (November 1989), pp. 1123-1126.

A thorough, albeit dated, article on the factors contributing to the expense of FPAs and research being conducted to overcome those hurdles to lowering cost. It talks about IRFPAs for military use, but the concern is cutting cost, which applies to any IRFPAs. Discusses the different military powerhouses' ideas on what IR wavelength to use, which material and substrate, and architecture.

(iii) Trends in IR Materials

- Ackerman, Robert K., "Quantum Well Designs Shed Light on Infrared Sensors," Signal (January 1992), pp. 55-58. An extremely important article which discusses the advantages GaAs detectors built by quantum well techniques have over conventional, MCT ones. Quantum well design incorporates a detector on the surface of a microchip, decreasing size and weight while raising efficiency. A molecular beam epitaxy technique is used to deposit materials on the surface of the GaAs virtually one atom at a time to yield extremely thin, sensitive, and uniform detector layers. The tradeoff in quantum well GaAs technology is between uniformity (quantum well's strength) and sensitivity (which is MCT's strength). The technology is fairly mature and will soon be available at prices competitive with, if not cheaper than, MCT arrays.
- Ashley, Steven, "New Life for Solar: Photovoltaic Power Systems," <u>Popular Science</u> (May 1989), p. 117.

 Reports on how a hybrid solar cell of one layer of gallium-arsenide and one crystalline-silicon has reached a thirty-one-percent efficiency level.
- Bailey, Robert B., et. al., "256 X 256 Hybrid HgCdTe Infrared Focal Plane Arrays," <u>IEEE Transactions on Electron Devices</u> (May 1991), pp. 1104-1109.

 Hybrid 256 X 256 MCT IRFPAs have been developed using either sapphire or silicon for the detector substrate to meet the sensitivity, resolution, and field-of-view requirements of high-performance medium-wavelength infrared imaging systems. The special substrate climinates the thermal expansion mismatch to the silicon readout circuit which had been a major cost factor due to cracked rejections. This may be considered a major breakthrough.
- Beck, W.A. and G.D. Davis, "Overlayer Growth on HgCdTe," Journal of Vacuum Science and Technology A (May-June 1988), 9p.

 The interactions between both cleaved and ion-sputtered MCT and deposited overlays are reviewed. The overlayers are classified into four groups: ultrareactive, reactive, intermediate reactive, and unreactive-based on the relative heats of formation of the overlayer telluride and HgTe and CdTe. Ultrareactive overlayers react with both HgTe and CdTe to form an interfacial metallic telluride and elemental Hg and Cd (which are lost from the interface), while reactive overlayers react only with HgTe components. Once the HgTe is depleted from the surface region, further deposition results in growth of a metallic film. Unreactive metals, on the other hand, do not react with the surface, but form a stoichiometric interface. Finally, the extent of interactions between intermediate overlayers and MCT depend on other factors, substrate material, the heat of cation alloying and the propensity of the overlayer element to diffuse into MCT.
- Bicknell-Tassius, "Growth of CdTe- CdMnTe heterostructures by Molecular Beam Epitaxy," (SPIE paper 1484-(12)
- Brau, Maurice J. "Ultra-high-Purity Starting Materials for Infrared Detector Crystal Growth," Colorado Research Lab, December 1991, 38p.
- Bubulac, L.O. "Ion Implantation and Diffusion for Electrical Junction Formation in MCT," (SPIE Paper 1848-10).

 Description of work going on at Rockwell Science Ctr in this area.
- Cabanski, W.A. "Electronic and Optical Properties of Silicide/ Silicon IR Detectors," (SPIE Paper 1848-12).

 Description of work at the university of Erlangen in Germany on silicon/ silicide arrays.
- Childs, A. etc. al. "Manufacturing Technology for Mid-Wavelength HgCdTe," Rockwell International Electrical Optical Center, May 1991, 317p.

 Final Report

Chow, K., et. at., "Source-Coupled HgCdTe Staring Hybrid Focal Planes for Tactical Applications," SPIE (Vol. 267 1981) 6p.

Staring infrared IRFPA with epitaxial MCT epitaxial MCT photovoltaic detectors coupled to surface channel CCD multiplexers have been fabricated and characterized. A source-coupled input circuit with background suppression is utilized. The MCT backside-illuminated detector arrays have bandgaps suitable for operation in either the 3-5 or 8-12 microns region. Performance characterization of the multiplexer will be given at cryogenic temperatures. Charge transfer efficiency, subthreshold transconductance, threshold voltage, etc. will be presented. These measurements will be compared with ideal models. Characteristics of the hybrid IRFPA have been measured in a wide variety of background.

Cockrun, C.A. et. al., "Development of LPE HgCdTe for Common Modules, Interim Report" November 1982, Santa Barbara Research Center, 109p

A 24-month research and development contract between the SBRC and US Army Night Vision and Electro-Optics Laboratory to develop LPE growth techniques for 0.1ev MCT to the point where standard photoconductive arrays can be produced with high yield.

Conner, A.D., et. al., "Manufacturing Technology, Interim Report," January 1990, Hughes, Santa Barbara Research Center

Extensive producibility and yield data under MANTECH contract. A major article on cost cutting measures on IRFPAs.

Cooper, D.E. et. al., "Spectroscopic Techniques for the Analysis of CdTe Substrates Used for the Growth of MCT," (DTIC Report #AD-A214-545, September 1989) 27p.

Photoluminescence and electron paramagnetic resonance are powerful techniques for both fundamental studies and potential materials screening of CdTe substrates for MCT growth. Certain extended defects that are common in epitaxial CdTe have distinctive PL signature that correlates with X-ray measurements of crystallinity. Bulk samples with prominent subgrain structure also have this PL feature, and cathodoluminescence images show that the defect is localized to the subgrain boundary regions. PL and EPR are very sensitive techniques, and specific impurities such as Fe or Ag have been observed in some nominally pure samples. PL and EPR spectroscopy can also detect changes associated with thermal annealing treatments, which alter the stoichiometry of CdTe by varying the number of Cd vacancies and interstitials. These findings illustrate the versatility of PL and EPR as nondestructive techniques to assess the quality of substrates for IR detector materials.

Crarcy, P.E. and Cathleen M. Farley, "Modeling the Cost and Producibility of INFRA Operability," (BDM International, Inc., 1991) 10pgs.

Extensive mathematical modeling of how IRFPA specifications can drive IRFPA cost and yield. Specifically, IRFPA operability affects IRFPA producibility in two ways, each having an opposite impact. Operability improvements resulting from purer, more perfect materials (fewer defects) become increasingly difficult to achieve as the operability reaches 100 percent. On the other hand, IRFPAs with higher operability have a greater probability of meeting system specifications for defective pixels, and thus final test yields are better. This paper reports on efforts to quantify the latter effect.

Dereniak, E. and Robert E. Sampson, <u>Infrared Detectors and Focal Plane Arrays II</u>, (SPIE: WA) APril 1992. The proceedings include discussions on topics ranging from basic device physics to novel applications. Papers report recent advances and developments in the field, with an emphasis on new concepts. Infrared detector materials such as InSb, MCT, PtSI, GaAs are discussed. Other topics include superlattices, strained superlattices, superconductors, planar hybrid array, z-plane array technology, hybrid input circuits, infrared sensor systems, FPA data processing, cryogenic electronics, and on-FPA signal processing.

- Faurie, Jean-Pierre, "Evaluation of the Feasibility and the Cost of HgCdTc Epitaxial Layers Grown by MBE on CdTe, CZT, and GaAs substrates," (DTIC report #AD-A238-602, Jan. 1991) 19p.

 In this contract which has been awarded to EPIR Ltd, two tasks were assigned. The first one was related to the evaluation of the cost MCT epitaxial layers grown by MVE on various substrates. The substrates which were supposed to be considered were CdTe, CZT, and GaAs. In addition, EPIR has also analyzed the cost on silicon substrates since Si is currently considered to be the most important substrates for IR photodiode technology. The second task was related to the feasibility of growing a few MCT epilayers by MDE with at least one exhibiting standard specifications.
- Faurie, Jean-Pierre, "MBE Growth, Characterization and Electronic Device Processing of MCT, HgZnTc, Related Heterojunctions and MCT-CdTe Superlattices," (DTIC Report #AD-A197-752, December 1987) 42p. A report is made on growth at the University of Chicago and characterization of high quality MCT epilayers, MBE growth and characterization of two-inch diameter p- and n- type MCT films on GaAs 100 substrate. The n-type intrinsic and extrinsic doping is discussed. The incorporation of As has been photo assisted using a Nd-YAG pulsed laser. X-Ray photoemission of Hg clusters on MCT surfaces has been studies. Direct measurement by XPS and electrical determination of MCT valence band discontinuity give values of 300-400 meV at 300K. Silicon has been used as a n-type dopant to grow a homojunction which electrical characteristics are presented in the paper.
- Felix, P. et al., "CCD Readout of Infrared Hybrid Focal Plane Arrays," <u>IEEE Trans. On Electron Devices</u>, (Vol. SC-13, NO. 1, February 1980)

 Excellent discussion of a now-mature technology at the outset, namely CCD processing.
- Freedman, A. "Patterned Etching of Infrared Detector Arrays," (DTIC Rpt #Ad-A236-124. March 1991) 25p. The authors attempted to develop a patterned etching technique for infrared detector arrays based on photo-induced processes. The technique is based on the efficacy of methyl radical etching of II-Vi compounds such as MCT and CT. Methyl radicals were produced in a pattern above a MCT substrate for photodissociation a radical precursor such as acctone or nitromethane using an excimer laser operating at 193 nm. Neither optical nor scanning electron microscopy could confirm the presence of any etching action. The failure of the proposed technique is ascribed to surface scavenging and/or reaction quenching mechanisms.
- "Gallium Arsenide Comes of Age," Financial Times (May 14, 1991), p. 29.

 Silicon continues to rein supreme in the market for computer chips, although GaAs offers inherent speed and power advantages, while GaAs transistors consume less energy than silicon transistors. However, working with GaAs has been more difficult and expensive than expected. The DARPA funds for GAAS research may allow breakthroughs in working with the materials (not discusses) and several major manufacturers, including Motorola, are jumping into the market.
- Ghandi, S.K. "Research on Mercury Cadmium Telluride," (DTIC Report #AD-A197-238, June 1988), 127p.

 This report summarizes work done during the third year of a program entitled Research on MCT. CdTe studies were extended to the DLTS of both n- and p- material. The wide gap materials effort was expanded with the growth of Zine Selenides, which is lattice matched to GaAs. Significant (200-300 times) improvement in the photoluminescence of GaAs was demonstrated by the use of a pseudomorphic ZnSe layer. The new reactor is fully operational, and is capable of growing HgCdTe with a Cd composition control of +- 0.002 across a 1cm X 1cm slice. In addition, significant improvement in MCT quality was obtained by the use of CdTeSe substrates. Work with CdTeZn substrates was also carried out during this year.

- Gurary, A., et. al., "Vapor Transport Epitaxy (VTE), A Novel Technique for Compound Semiconductors," <u>Journal of Vacuum Science and Technology A</u> (July/August 1992) p.1453-1457.

 Report from EMCORE Corporation and Rutgers University. An advanced VPE technique for depositing compound semiconductors is described. The technique operates using elemental, gas, or metalorganic sources. The resolving of several problems common to MBE, Chemical-beam epitaxy, and MOCVD systems has been the motivation for investigation of this technique.
- Kosnocky, W.F. "State of the Art in Schottky-Barrier IR Image Sensors," (SPIE Paper #1685-01), 19pgs.

 Reviews the progwerss in the development of infrared image sensors with Schottky-barrier detectors. At the present, they represent the most advanced technology for large-area high-density focal plane arrays for many SWIR and MWIR applications. The article is an updated and abbreviated version of recent reviews by the author on progress in the development of infrared image sensors with Schottky-bvarrier detectors.
- Jindal, Bal K. "High Quality Large Area Wasers of Mercury Cadmium Telluride," Xacton Corporation, March 1992, 180p.
- Kozlowski, L.J., et. al., "640 X 480 PACE MCT FPA Development for High performance FLIRs," (ROckwell International Science Center, February 1991) 11pgs.

 A hybrid 640 X 480 PACE MCT FPA is being developed to meet the needs of many applications including missile seekers and FLIRS. The device will offer full TV resolution with sensitivity much superior to PtSi, having over one-quarter million pixels. The hybrid is comprised of a PACE MCT detector array having nominal 5 micron cut-off wavelength, mated to a high speed CMOS readout having high charge-handling capacity.
- Kozlowski, L.J. et. al., "MWIR 256 X 256 PACE-1 MCT FPA: Performance Assessment," <u>Proceedings of the IRIS Specialty Group on Detectors</u> (Naval Postgraduate School, Monterey CA) 14-18 August 1989.
- Kozlowski, L.J. et. al., "Large Staring IRFPAs of HgCdTe on Alternative Substrates," SPIE International Symposium on Optical Applied Science and Engineering" (San Diego: July 1991). 12pgs.

 A report on hybrid MCT 256 X 256 IRFPAs developed at Rockwell International Science Center to meet the sensitivity, resolution, and field-of-view requirements of high-performance medium wavelength infrared imaging systems. The hybrid, also used in a 640 X 480 array still in research, has a MCT detector array mated to silicon-based multiplexers.
- Kozlowski, L.J. et. al., "Reproducible High Performance LWIR MCT Staring Focal Plane Arrays," <u>Proceedings of the National IRIS</u> (Johns Hopkins University, Laurel, MD) 12-14 June 1990.
- Linden, K.J., "MOCVD: Expanding the Range of Photonic Materials," <u>Photonics Spectra</u> (February 1991) 4pgs. Recent research in the semiconductor area has yielded major improvements in device performance as well as new structures based on electron confinement mechanisms resulting in quantum effects. Two methods discussed of epitaxial growth generally used to synthesize such structure are MOCVD and OMVPA, and molecular MBE. More recently developed methods discussed that incorporate elements of both of these

technologies is Chemical Beam Epitaxy (CBE), or Metallorganic Molecular Beam Epitaxy (MOMBE). Reviews significant advances in photonic devices structure achieved by MOCVD.

Lockwood, A.H., et al., "Photovoltaic HgCdTe Hybrid Performance," SPIE (Vol. 267, 1981) 4p.

At the Santa Barbara Research Center, second generation infrared imaging systems require high density focal plane arrays for staring applications. To meet this need, a focal plane structure using MCT photodiodes for detectors and Si CCds for signal processing has been developed. Although conventional ion-implanted hybrid arrays have successfully been interfaced to CCD multiplexers, hybrid arrays fabricated on LPE layers offer some inherent advantages with respect to performance, processing, and yields. It has been determined that heterostructure diodes fabricated by a Hg infinite melt LPE technique give superior performance relative to conventional ion-implanted devices. Data is presented on devices fabricated for both 8 to 12 microns and 3 to 5 microns applications.

Marciniac, J.W., "Hybrid PV HgCdTe Detectors: Technology Reliability and Failure Physics Program," (DTIC Rpt #AD-A226-675, 1988) 29p.

MCT IRFPAs are finding greater application in systems designed to operate in the MWIR and LWIR. Prior to those IRFPA being deployed in the field, it is important to understand the potential failure mechanisms to permit high reliability units to be built. Indium bump is a widespread method for providing electrical interconnect and mechanical support to these focal planes to circuit boards or silicon multiplexers. This program was designed to evaluate the effect of the hybridization process on MWIR focal planes, as well as assess their long term stability.

- McArthur, S.B., "Low-Cost Cooled CCDs Open Doors," <u>Photonics Spectra</u> (January 1992) pp. 92-93. Discusses how these new CCDs have applications in a broad range of fields for scientists, researchers and engineers.
- Moazed, K.L., "MBE Growth of HgCdTc," (DTIC Report #AD-A207-218, June 1980) 21p.

 The II-VI compound MCT is a material of considerable interest as a semi-conductor, for optical devices, particularly in the infrared spectral regions. Solid solutions appear to exist for all values of x, and for values of x between about 0.2 and 1.0 the material behaves as a semiconductor with a variable bandgap between 0.05 ev and 1.53 ev at room temperature.
- Myers, T.H. "Advanced Infrared Focal Plane Concepts," GE Aerospace, March 1992, 180p.

 This report describes the results of research carried out under the US Air Force contract "Advanced INFRA Concepts." The overall ogjective of the program was to advance the state-of-the-art of IRFPA technology through the development of molecular beam epitaxial growth of MCT alloys and HgTe-CdTe superlattices for novel multilayer detector structures for LWIR applications.
- National Materials Advisory Board, "Process Challenges in Compound Semiconductors," (DTIC Report #AD-A204-868, August 1988) 154p.

Compound semiconductors, such as GaAs, InP, and MCT, are essential components in future photonics and microelectronics technologies. If the US is to be competitive in these technologies, attention must be directed to the reproducible and affordable processing of these materials. This report assesses the current status of compound semiconductor processing technology and identifies factors that limit the ability to fabricate advanced electronic and optoelectronic devices. Emphasis is placed on current and near-term devices, but the process technology discussed are generic to future components and systems based on these materials.

Niedziela, T. and J. Piotrowski, "Ultimate Performance of CdHgTe Photoelectromagnetic Detectors of Middle and Far Infrared," <u>Journal of Technical Physics</u> (no. 3, 1987), pp. 289-296.

Photoelectromagnetics effect (PEM) finds important applications for ambient temperature IR detectors due to its advantages including no need of electrical supply, the wide response frequency band, absence of low frequency noise and the weak sensitivity on ambient temperature. An attempt was made to evaluate the ultimate performance of the middle and far IR PEM detectors, made of homogenous (Cd, Hg) Te assuming Auger 7 as the dominant recombination mechanisms.

Razeghi, Manijech, Optoelectronic Materials and Device Concepts (SPIE: WA) November 1990.

The past decade of research and development in optoelectronics has been a continuous interplay between materials improvements and advances in devices, circuits, and system technology. There has been much creative activity in new materials that has led to substantial improvements in devices and systems, and at the same time, the need for newer and better materials having specific properties has been recognized. Contents: Compound semiconductors, strained layer epitaxy, impact of semiconductors on optoelectronic technology, device applications, quantum phenomena, organic materials for optoelectronics, 1990 optoelectronics semiconductors issues, better materials.

- Reynolds, R.A., "The II-VI Compounds: 30 Years of Acceptor Dopants in MCT Alloys," <u>Journal of Vacuum Sciand Tech A</u> (Vol. 269, 1989)
- Reynolds, R.A., "The II-VI Compounds: 30 Years of History and the Potential for the Next 30 Years," <u>Journal of Vacuum Science and Technology A</u> (March/April 1989) p.269-270.

 The past thirty years of progress in II-VI compounds is briefly summarized. Existing problems with both the materials and methods for their production are noted. The probable future uses of the II-VI compound is in infrared sensors and photonics. Possible applications are discussed.
- Roberts, C.G. and S.R. Borrello. "Monolithic MCT Focal Plane Array Structures," SPIE (Vol. 217, 1980) 8p. Sophisticated infrared imaging systems require complex focal plane device structures to perform the basic functions of detection, time delay and integration (TDI), multiplexing, and possible scanning in large array formats with minimal on-focal plane power dissipation. Monolithic MCT charge transfer device structures are promising candidates for many focal plane requirements. CCDs are the natural structure for scanning system IRFPAs which utilize TDI. Charge injection devices (CIDs) are directly applicable to staring system focal plane requirements. This paper discusses the applicability and design considerations of various devices which have been developed using this technology.
- Santa Barbara Research Center, "NRL Hybrid Reliability: Physics of Failure Initial Study," (DTIC Report #AD-A217-986, Jan 1990) 71p.

The objective of this program was to identify the failure mechanisms associated with the thermal cycling of MCT hybrid IRFPAs from room temperatures to cryogenic temperature (typically 77K). There is a concern in the IR community that the long-term reliability of IRFPAs may be in question due to defects being formed as a result of the hybridization process and/or thermal cycling of the arrays from room to cryogenic temperatures.

Schetzina, J.F., <u>Device Processing of II-VI Semiconductor Films and Quantum Well Structure</u> (DTIC: March 1991), 4p.

The objective of this program was to develop a device processing technology necessary for proper utilization of Hg-based heterostructures and superlattices in device applications. The specific focus or long term goal guiding the direction of the program was to develop the devices and processing technology required for an

IR focal plane integrated with on-board signal processing electronics.

- Schorrocks, N.M., et. al., "Uncooled Infrared Thermal Detector Arrays," (SPIE paper 1320-12).

 Excellent review of uncooled IRFPAs, raises issue of strong commercial potential for uncooled arrays because they save money on the cryocooler, a significant cost component.
- Scribner, D.A. and Ray Balcerak, <u>Infrared Focal Plane Array Producibility and Related Materials</u> (SPIE: WA) April 1992.

The increasing demand for infrared focal plane arrays for advanced imaging systems has led to several major producibility programs. The proceedings discusses solutions to producibility problems with an emphasis on new concepts and techniques for manufacturing improvements. Production planning and integration are the topics of several papers, including computer integrated manufacturing systems, in-situ process monitoring, and analysis of criteria selection for production. Other topics include packaging and cooling, 'ligh throughput testing for improved producibility, and related new materials and their potential with respect to the production of advanced IRFPAs.

Sher, A. Tsigelman, A Eger, D., "Growth of HgZnTe Layers by LPE Technique," (DTIC Report #AD-A198-368, March 1988) 47p.

Report on work at Israel Atomic Energy Commission Yavne Soreq Nuclear Research Center. Solid solution mixtures of a wide band gap II-VI compound with one constituent being the semimetal HgTe may be tuned to yield narrow gap semiconductors, suitable for the fabrication of infrared photon detectors. Among this groups of solid solutions, MCT is at present the most commonly used material for photon detectors. In spite of the scientific and technological achievements difficulties still exist, generally attributed to the instability of these alloys. Thus, theoretical prediction about the relative stability of HgZnTe, reported recently, stimulated experimental research into the narrow band gap range of this solid solution. In the present work the LPE of HgCdTe was studied, focusing on the evaluation of this technique as a tool for achieving epitaxial layers of the "new material" the solid solution HgZnTe, with morphological, crystalline, and electrical properties comparable with those of MCT epilayers.

- Smith, L.M., et. al, <u>Integrated Technology in MCT/ GaAs and MCT/ Si for Medium and Long Wavelength Infrared</u> (DTIC: May 1990), 54p.

 MCT layers gave been grown by MOCVD on CdTe, GaAs, and GaAs/Si for device processing. Both 111
 - MCT layers gave been grown by MOCVD on CdTe, GaAs, and GaAs/Si for device processing. Both 111 and 100 MCT have been grown on GaAs and the relative merits of the two orientations are discussed.
- Stringfellow, G.B. <u>Oragnometallic Vapor-Phase Epitaxy: Theory and Practice</u> (Academic Press San Diego, 1989). Excellent review of VPE, and a full discussion of the problems with LPE that pushed VPE to be developed.
- Tennant, W.E. "HgCdTe Mid-Wavelength Infrared (MWIR) Epitaxial Mosaics for Tactical Applications," SPIE (Vol. 267, 1981) 5p.

Epitaxial MCT/CdTe, combined with ion implantation technology, has proven ideally suited for proposed photodiode focal plane array applications. State of the Art performance planar photodiodes have been fabricated in epitaxial materials of all wavelengths. Important applications of these arrays are in tactical defense missions employing MWIR arrays operated at 77K and near 195K. A critical issue for these devices is stability through the bakeout required for the sealing off of dewar packaging. This report presents measurements of ion-implanted MCT/CdTe device and arrays which have broadband spectral response and high RoA values.

Tennant, W.E., et. al., "Key Issues in MCT-Based IRFPAs: An Industry Perspective," (Unpublished article transmitted by author).

The best survey article available on the materials issues confronting the IRFPA industry. Discusses all facets of materials technology which need to be addressed by government funding and proposes innovative ideas for reshaping government spending to spur second generation IRFPA development.

Tong, F.M., Yuan Haoxin and Yang Xiuzhen, "HgCdTe Photovoltaic Detectors and Some Related Aspects," (SPIE Paper #1685-21) April 1992, 11pgs.

Recent developments in HgCdTe photovoltaic detector technology are reviewed. The status of related area in China are introduced. Some aspects of research work on device physics and technology conducted in authors' laboratories are discussed. These include the performance of HgCdTe photodiodes for IR fiber communications, the effects of field-enhanced generation-recombination and imperfections of the pn junction on HgCdTe photodiode I-V characteristics; an analysis of the dependence of energy gap of MCT on temperature compositions.

Tower, John R., "Silicon-Based Imaging: Extending Performance on All Fronts." <u>Photonics Spectra</u> (April 1992), pp. 165-167.

This article discusses how silicon-based sensors are penetrating the market in all sectors from visible wavelength, to UV, to infrared. In the platinum silicide Schottky-barrier market, thermography is a growing business area for industrial process control, energy management, and medical diagnostics (no specifics mentioned). Since John Tower is a manager at the David Sarnoff Research Center, this is mostly an ad for Sarnoff's ability to produce sensors for all IR wavelengths.

Tower, John R., "Staring PtSi IR Cameras: More Diversity, More Applications," <u>Photonics Spectra</u> (February 1991), pp. 103-106.

A thorough review of the technological diversity and applications of PtSi IR cameras which employ PtSi Schottky-Barrier IRFPAs. There is no comparison with MCT or other materials. Discusses the major architectural approaches at the David Sarnoff Research Center for: high frame rate cameras (to aid in understanding failure modes in power semiconductors), multispectral cameras (still in prototype stage), thermography, and infrared acquisition and tracking systems (military)

Tsaur, Bor-Yeu, et. al., "PtSi Schottky-Barrier Focal Plane Arrays for Multispectral Imaging in Ultraviolet, Visible, and Infrared Spectral Bands," <u>IEEE Electron Device Letters</u> (April 1990), p162-164.

PtSi Schottky-barrier detectors, which are conventionally used in the back-illumination mode for thermal imaging in the 3-5 micron infrared spectral band, are shown to exhibit excellent photoresponse in the near-ultraviolet and visible regions when operated in the front-illuminated mode. For devices without antireflection coatings, external quantum efficiency in excess of 60% has been obtained for wavelengths between 400 and 800 microns. The efficiency decreases below 400 microns but is still about 35% at 290 microns.

Vociker, Jeffrey, "Dual-Band Focal Plane Array Trade Studies," General Electric Company Electronics Lab, January 1992, 23p.

Details results of a study that examined the current state-of-the-art of two IRFPA technologies: InSb 3-5um, and PV HgCdTe 8-12. Advanced techniques, such as MBE, MOCVD, and to a lesser extent LPE offer the promise of greater uniformity, operability, and detectivity, but wide-spread use of devices fabricated in these ways are currently cost prohibitive. The principal focus of this effort centerd on characterizing the ilmitations imposed by current growth and process techniques on the ability of devices to function radiometrically.

Vu, TT et al., "Integrated GaAs Readout Multiplexer and Preprocessing Electronics for Infrared Sensors," <u>IEEE International Symposium on Circuits and Systems</u> (New Orleans, LA May 1-3 1990), pp. 3093-3096.

A thorough, technical report on the use of gallium arsenide technology for IRFPA sensors. GaAs's characteristics, circuits, and architectures for readout multiplexer and preprocessing electronics are described for the first time in open literature for both scanning and staring arrays.

Vural, Cadri, "Mercury Cadmium Telluride Hybrid Focal Plane Array Technology," <u>Proceedings of the SPIE Conference on Lasers and Electro-Optics</u> (April 25-29 1988), pp. 28-29.

The MCT hybrid FPA, microelectronics chip architecture that emulates in the IR the function of Si visible imagers is discussed. As MCT is an alloy semiconductor whose bandgap can be varied from greater than 1 eV to less than 0.1eV, a hybrid FPA can be made with an IR long-wavelength cutoff from 1 to less than 10 microns. The development is reported of large arrays in two spectral bands: 1-2.5 microns (SWIR) and 3-5 microns (MWIR). The SWIR FPA has its principal application in earth resources and astronomy, while the MWIR FPA is useful in passive thermal imaging. The architecture and performance of the arrays are reported.

- Vural, Cadri and L.J. Kozlowski, "256 X 256 MCT IRFPAs for the Hubble Space Telescope," (SPIE Paper 1320-14) 1990.
 Excellent article on specifications and technological techniques for the most advanced and reliable MCT IRFPAs produced.
- Watton, R., M.A. Todd, and J.P. Gillham, "Materials and Technology Research in Uncooled Ferroelectric IR Detector Arrays," IEEE Transaction Papers (Date Unknown), pp. 69-77.

 An extremely technical piece which proposes an altogether new material for IRFPAs, using iron based material. The technology for the fabrication of large hybrid pyroelectric (thermasense) arrays has been established using the lead compound perovskite ceramics. These IRFPAs would operate at ambient temperature, and the absence of cryogenic requirements eases the operation, particularly in remote situations. The major drawback of the technology, expense, is not explained because the ferroelectric proposal is still in the prototype stage.
- West, S.A., et. al., "Producible MWIR MCT Detector Array Program Intermediate Production Performance," August 1989, Rockwell International.

 Interim report on Rockwell's MANTECH program. An essential document on yield and producibility technologies.
- Williams, G.M., "Development of LPE HgCdTe for 305 Micron by PV Diode Arrays," Rockewell International Science Center, August 1988, 134p.
 Final Report
- Williams, T.L. and B. Newton "In Situ Testing of FLIRs and other Thermal Images," (SPIE Paper 1320-50) 1990, 9 pgs.

 Discusses work at Sira, Ltd, in United Kingdom on reducing costs of FLIR testing by using in situ testing to determine faults as they occur so that material can be modified in situ instead of being discarded. This is a technology to watch closely.
- Woolaway, James T, "New Sensor Technology for the 3- to-5 Micron Imaging Band," Photonics Spectra (February 1991), pp. 113-119.

 The author discusses tradeoffs in IRFPAs operating in the 3-5 micron or the 8-12 micron band. He explains that sensors in the 3-5 micron range offer higher contrast, but receives more solar noise, and has lower radiance, particularly at low background temperatures. By contrast, the 8-12 micron range has a higher radiance, and higher thermal derivative (ie. it reacts faster to light). Since the 3-5 micron band offers

potentially better resolution, technological efforts are focused on imaging systems which can better filter the background noise, and elucidate the image better.

Yasuta, Brian, "Tower Video Signal-To-Noise Ratios of TICM II and Mitsubishi 512X512 PtSi Sensors," Wright Lab, Wright Patterson AFB, March 1992, 198p.

The PtSi Sensor Program reports on comparisons of these PtSi detectors with MCT and InSb detectors. PtSi sensors are evaluated for their potential as a low cost alternative to HgCdTe and InSb detectors for imaging applications. To accomplish this goal, these sensors are compared in the laboratory and under a variety of weather conditions in the field (tower) to determine the capabilities of the PtSi sensors for Air Force missions in all environments.

Zanio, K.R., "Hs to street on Si for Hybrid and Monolithic FPAs," (SPIE Paper 1308-14), 1990, 15pgs.

Discussion of work underway at Ford Aerospace on MCT using silicon as an alternative substrate.

(iv) Applications of IR Sensitive Materials in Biomedical Thermography

Afromowitz, et. al., Multispectral Imaging of Burn Wounds: A New Clinical Instrument for Evaluating Burn Depth," IEEE Trans Biomed Eng (1988:10) 842-849.

Predecessor to Hejazi study. Found that multispectral imaging could help determine absolute temperatures of skin, independent of emissivity.

Alfano, R., Ping P.Ho and K.M. Yoo, "Optical Imaging vs. X-rays for Breast Cancer Screening," <u>Photonics Spectra</u> (October 1992), p.109-13.

A professor at City College of the City University of New York discusses the novel technique of using infrared scanning as an alternative, safer, and higher resolution technique than x-rays (the conventional technique) for breast cancer screening.

- Allen, R.C., et. al., "Localized Scleroderma: Treatment Response Measure by Infrared Thermography," <u>Thermology</u> (1987:2) pp. 550-553.
- Amalric, R., et. al., "Prognostic Use of Thermography in Breast Cancer," <u>International Congress of Thermology</u> (August 1992).

Found that breast cancer with temperature increases of more than 3°C had a high failure risk, and "deserves systematic additional medical treatment."

American Medical Association, "Thermography in Neurological and Musculoskeletal Conditions," Reprinted in Thermology (1987:2) pp. 600-607.

Very conservative study which approved positively of thermography but concluded that thermography was not useful in directly measuring pain, and that more studies were needed to support its use.

Anbar, M. "Objective Assessment of Clinical Computerized Thermal Images," Processings of SPIE Medical Society V: Image Processing SPIE Proceedings (1991; 1445) pp. 845-847.

Echoes Anbar's main theme, that quantitative thermography will overtake biomedical thermography applications. Also notable because is written in public forum, rather than the "trade journal," Thermology.

- Anbar, M., "Recent Technological Developments in Thermology and their Impace on Clinical Applications," (Unpublished), 13 pgs,
 - Reviews three new major technological developments in thermology: quantitative thermology, dynamic thermology, and absolute temperature thermology. Concludes absolute temperature thermology will prevail becase it provides quantitative thermological info fre from artifacts associated with the measurement of infrared flux at a single wavelength band. It also measure the emissivity of the skin, which may have independent diagnostic applications, especially in the field of dermatology.
- Anbar, M. D'Arcy, S.J. "Localized Regulatory Frequencies of Human Skin Temperature Derived from the Analysis of Series of INfrared Images" <u>Proc. of the 4th Annual IEEE Symposium on COmputer Based Medical Systems (CBMS '91)</u> (1991) 184-191
- "A New Method for Detecting Cervical Cancer," Photonics Spectra (February 1992) p.106

 A promising new method for detecting cervical cancer is currently being developed and tested at the NeW York Hospital-Comell Meical Center and Canada's National Research Council. The method, which employs infrared spectroscopic analysis of human cervical cells, may eventually lead to a new, rapid diagnostic test for the disease.
- Clark, R.P., "Medical Thermography: Current Status," (SPIE Paper 1320-27) 1990.

 Although the discussion revolves around thermography, almost all of these applications are suffering without IRFPAs, and this article highlights areas where IRFPAs would be extremely helpful because of their window of IR imaging, and resolution quality.
- Clark, R.P., Goff, M.R., and Culley, J.E., "High Resolution Thermography in Medicine," <u>The Journal of Photogaphic Science</u> (Vol. 37, 1989), pp. 168-171.

 Explains advancements in biomedical diagnosis made possible by a high resolution medical thermal imaging sytem using an 8 element SPRITE detector.
- Clark, R.P., et. al., "Thermography and Pedobarography in the Assessment of Tissue Damage in Neuropathic and Atherosclerotic Feet," Thermology (3: 1988), pp. 15-20.

 Discusses application of thermography in these two disciplines.
- Croissant, P.D., et. al., "Neurological Clinical Procedure Review," <u>Joint Council of State Neurosurgical Societies of</u>
 <u>the American Association of Neurological Surgeons and the Congress of Neurological Surgeons</u> (June 1988)

 4 pgs.
 - This is the lukewarm endorsement of thermography by the technology assessment committee of the American Assoc of Neurological Surgeons. It concluded thermography was safe and effective, but is to be considered an adjunctive test and not solely diagnostic except in cases of reflex sympathetic dustrophy.
- DeMey, F., and R. Vermeir, "A Turtorial of Infrared Thermography," Meeting of International Congress of Thermology (August 1992).

 Offers general overview of IR thermography, starting from basic physical principles, the mechanics of IR equipment, and emissivity correction.
- Fujimasa, I., "Current Status of Medical Thermography in Japan," <u>International Congress of Thermology</u> (August 1992).

 Discusses evolution of machines used and diseases diagnosed with thermography since 1968 in Japan.
- Goodman, P.H., "Cost-Effective Analysis of Thermography and Venography in the Diagnosis of Deep Vein Thrombosis," Thermology (1989:3), pp. 113-120.

- Argues that thermography should be used before taking expensive chemical or surgical procedures to remove deep vein thrombosis, because it could possibly save patients thousands of dollars by corroborating or sometimes contradicting diagnoses made by other, more prevalent equipment.
- Handelsman, H., "Thermography for Indications Other Than Breast Lesions," Office of Health Technology

 Assessment, US Department of Health and Human Services (1989).

 A negative review which argued that thermology is not effective in medical diagnoses.
- Hejazi, S., Wobschall, D.C., Spangler, R.A., and Anbar, M. "Scope and Limitations of Thermal IMaging Using Multi-wavelength Infrared Detection," Optical Engineering (November 1992), pp. 2383-2393.

 Reports on a single experiment which successfully determined absolute temperatures of surfaces by their blackbody emissions, by simulteneous acquisition of infrared emissions at different wavelengths.
- Hubbard, J.E., "Neuromuscular Thermography: An Analysis of Criticisms," Thermology (1990:3) pp. 160-165.

 Examines the critical points and issues raised by the criticisms of the AMA, Joint Council of State Neurosurgical Societies, the Office of Health Technology Assessment, the the American Academy of Neurology.
- Hubbard, J.E., "Pain Evaluation in 805 Studies by Infrared Imaging," Thermology (1986:1) pp. 161-66.

 Compares diagnostic precision of IR thermography with CT scans, EMG, and myelography for evaluation of pain in lumbar, cervical, thoracic, and facial areas. Found that IR thermography is clinically useful in pain evaluation as an indicator of peripheral nerve patho-physiology.
- Jankel, W.R., Ucmatsu, S., "Thermography in Neurological Evaluation," <u>Curr Ther Neurolog Surg</u> (1989:2) pp. 331-34.
 Very positive, objective review of usefullness of thermography in these diagnoses.
- Jones, C.H., Ring, E.F.J., and R.P. Clark, "Biomedical Thermography," in Burney, S.G., Williams, T.L., Jones, C.H.N., <u>Applications of Thermal Imaging</u> (Adam Hilger: Philadelphia) 1988.

 Discusses both technical aspects of biomedical IR, and all major areas in which their use has been proposed.
- LeRoy, P. and R. Filasky, "Thermography," in J.J. Bonica, J.D. Loeser, C.R. Chapman (eds.), <u>The Management of Pain, 2nd edition</u>. (Lea & Febiger: Philadelphia) 1990, Volume 1, pp. 610-621.
- Mohr, F.W., et. al., "Thermal Coronary Angiography: A Method for Assessing Graft Patency and Coronary Anatomy to Coronary Bypass Surgery," Ann THorac Surg (1989:47) pp.441-449.
- Montoro, J.C., Anbar, M. "Visualization and Analysis of Dynamic Thermographic Changes," Proc. of the First Conference on Visualization in Biomedical Computing. (1990) pp.486-489. Discusses reading and understanding clinical information embedded in absolute temperature thermal scans of bodies.
- Montoro, J.C., Hershey, LA and Anbar, M., "Enhancement of Interpretation of Thermograms Through On-Line Software" Thermology (1989;3) pp. 121-124

 Explains how radiometric readings and dynamic diagnoses can be made through the softwre available currently.
- Nyirjesy, N., et. al., "Clinical Evaluation, Mammography and Thermography in the Diagnosis of Breast Carcinoma,"

Thermology (1986:1) pp. 170-173.

Concludes that the three major techniques used to evaluate the state of health of the mammary gland, namely clinical evaluation, mammography, and thermography, have inherent inaccuracies and cannot be used alone, either in screening or in diagnostic examinations. Recommends using IR thermography in conjunction with other these other methods.

- Ohashi, Y., ctl. al., "Significance of Dynamic Thermography in the Diagnosis of Breast Cancer, "International Congress of Thermology (August 1992).
- Pavot, A.P., Ignacio, D., and Gargour, G, "Use of Thermography in the Diagnosis and Management of Reflex Sympathetic Dystrophy," <u>International Congress of Thermology</u> (August 1992).

 Authors found that IR imaging, with its characteristic abnormal temperature pattern, is very useful in confirming the diagnosis of RSD. Technique also found useful in monitoring symmathetic nerve blocks and determining the adequacy of sympathettomy, both of which are used commonly in treatment of the disease.
- Pochaczevsky, R., "Status of Thermography: 1989," <u>Thermology</u> (1989:2) pp. 97-100.

 Good overview of potential applications. Emphasizes that thermology images the heat produced by body processes, rather than the imaging the processes directly; author contends this misunderstanding has led to low confidence of medical public in thermography.
- Pochaczevsky, R., "The Value of Thermography as a Clinical Imaging Diagnostic Test: A Review of and Response to the 1989 Office of Health Technology Assessment Report of Thermography for Indications Other than Breast Lesions," Thermology (1991:4), pp. 227-233.
- Pochaczevsky, R., "Thermography in Posttraumatic Pain," <u>Am J of Sports Medicine</u> (1987:15) p.243-250

 A how-to article targeted at physicians interested in thermography and its applications to sympathetically maintained pain, resulting from sports injuries.
- Ring, E.F., "Thermography in Rheumatology," <u>Thermology</u> (1986:1) pp. 149-153.

 Pioneering experiment, using late-model IR machines, to diagnose and follow treatment of rheumatology through the temperature given off by peripheral joints, which varies in accordance to the synovial blood flow and inflammation.
- Sterns, E.E., Zee, B., "Thermography as a Predictor of Prognosis in Cancer of the Breast," <u>Cancer</u> (1991:67) pp. 1678-1680.

 Although recognizing the significance of biomedical thermography equipment, remains skeptical about reaching close to 100 percent confidence in thermography as a prognostic technique.
- Stoner, H.B., Taylor. L., Marcuson, R.W. "The Value of Skin Temperature Measurements in Forecasting the Healing of a Below-Knee Amputation for End-Stage Ischemia of the Leg in Peripheral Vascular Disease," <u>Eur J Vasc Surg</u> (1989:3) pp. 255-261.
- Suave, C., Hand, D., Thomassin, L., Amalric, R. "The Diagnosis and Prognosis of Thermography in Breast Cancers,"

 International Congress of Thermology (August 1992).

 Found direct correlation between temperatures of cancerous breast tumors, and mortality. Recommends use of IR thermography in making prognoses for patients found to have breast cancer.
- Thomassin, L., Giraud, D., Sauve, C., Amalric, R., "The Value of Thermography in Small Size Breast Cancer"

 International Congress of Thermology (August 1992).

- Found thermography to be modestly effectively in the diagnosis of small breast cancer tumors. Recommends that thermography be an integral diagnostic technique for breast cancer diagnosis, coupled with other techniques.
- Torres, J.H., Springer, T.A., Welch, A.J., Pearce, J.A., "Limitations of a Thermal Camera in Measuring Surface Temperature of Laser-irradiated Tissues," <u>Lasers Sur Med</u> (1990:10) pp. 510-23.
- Ucmatsu, G. "Thermographic Imaging of Cutaneous Sensory Segment in Patienst with Peripheral Nerve Injury: SKin Temperature Stability Between Sides of the Body," <u>J of Neurosurgery</u> (1985;62) pp. 716-720.
- Ulmer, H.U., Brinkmann, M. Frischbier, H.J. "Thermography in the Follow-up of Breast Cancer Patients After Breast Conserving Treament by Tumorectomy and Radiation Therapy," <u>Cancer</u> (1990; 65) pp.276-80. Concludes that thermography does serve a valuable role in follow-up procedures.
- Wagter, C. De, Martens, L. "Hyperthermia State of the Art: Physical and Technological Aspects," <u>International Congress of Thermology</u> (August 1992).

 Proposes use of biomedical thermography to ensure that the heat differential and heat dynamics in the body do not thwart attempts to heat cancerous tumors to very specific temperatures, in order to kill the tumor.
- Yoo, K.M., Das, B.B., and Alfano, R.R., "Imaging of a Translucent Object Hidden in a Highly Scattering Medium from the Early Portion of the Diffuse Compnoent of a Transmitted Ultrafast Laser Pulse," Optics Letter (July 1, 1992) pp. 958-60.

 Presents scientific basis for use of thermography in breast cancer diagnosis.

(v) Applications of IR Sensitive Materials in Non-Destructive Evaluation

- Blazquez, C.H., "Detection of Citrus Freeze Damage with Natural Color and Color Infrared Video Systems," SPIE Thermosense XIII Conference (April 1991) pp. 394-401.

 Infrared videography was used, but wavelength is in SWIR, making the application probably unavailable to MCT-based detectors.
- Brecher, V.H., "Recent Advances in Inspecting Integrated Circuits for Pattern Defects," (SPIE Paper #1661-296) 1992, 16pgs.

 Use of infrared detectors is discussed for inspection of IC boards; technical description of how the closed-loop inspection regime is arranged and run.
- Bruno, Robert P., "Thermography in Nondestructive Industrial Testing." Photonics Spectra (July 1989), pp. 123-24.

 Thermal imaging, or thermography, is now being used effectively as a tool for inspecting the integrity of composite materials and the adhesion of bonded protective overcoatings. The thermographic inspection of metals for stress-induced cracking now showing promise. Applications in metals are discussed.
- Bruno, Robert P., "Tracking Gas Leaks with Active IR Scanning," Photonics Spectra, (February 1992) pp. 94-98. Discusses how an IR laser can shine on an area and visually reveal where gas is leaking. This is because various gases have a different light absorption band than ordinary air. This is an interesting breakthrough because it shows how spectroscopy (usually without IRFPAs) begins to work more like focal plane arrays. FPAs in fact would make this process much more efficient and simpler if only the technology became

cheaper.

- Cantella, M.J. et al., "Application of IR Staring Arrays to Space Surveillane," (SPIE Paper #1540-75) 1991, 20pgs.

 Best overview in the bibliography of the technologies, applications, and techniques for space-based second generation photovoltaic IRFPAs.
- Cawley, P. and R.D. Adams, "Defect Types and Non-Destructive Testing Techniques for Composites and Bonded Joints," Materials Science and Technology (May 1989), pp. 413-25.

 In this paper, an introduction to the aspects of composites and adhesive joints relevant to non-destructive testing is provided. The first part consists of a brief introduction to composites and adhesive joints, together with a description of the types of defects that may occur. In the second part, the main relevant non-destructive techniques used to identify these defects are described and the sensitivity of each method to the different types of defect is indicated. Thermographic inspection is described and discussed.
- Cramer, K.E., P.A. Howell, W.P. Winfree, "Quantitative Thermal Depth Imaging of Subsurface Damage in Insulating Materials," SPIE Thermosense XV Conference (April 1993) Paper 1933-24.

 Another application for Langley Research Center's pulse-echo thermal-wave imagnig.
- Cramer, K.E., P.A. Howell, W.P. Winfree, "Wuantitative Thermal Depth Imaging of Subsurface Damage in Insulating Materials," <u>Unpublished</u> 10 pgs.

 A thermal technique is presented for imaging subsurface admage and computing the depth of defects. This technique has been used in the detection of defects in aging aircraft skins.
- Davis, Roy C., A Robotic Workcell for Linear Welding/Thermovision Scanning of Thermoplastic Bumpers (SME: 1984), 9 pgs.
 This article is old but pertinent. The Ford Motor Company's Milan plastics plant utilized infrared scanning of a linear welded plastic bumper utilizing the robotic workcell concept. Buchanan, R.A., P.E. Condon, L.M. Klynn, "Recent Advances in Digital Thermography for Nondestructive Evaluation," SPIE Thermosense XII Conference (April 1990) pp. 134-142.
- Ellingson, W.A., "Defect Detection in Multilayers Plasma-Sprayed ZrO2 by Time-Resolved Infrared Radiometry:

 A Comparison Between Analytical and Experimental Methods," SPIE Thermosense XV Conference (April 1993) Paper 1933-17.

 Discusses a high-end NDE application of IRFPAs. More down-to-earth, common inspections may derive their techniques from the one explained in this article.
- Favro, L.D., "Inversion of Pulse-Echo Thermal-Wave Images," SPIE Thermose XV Conference (April 1993) Paper 1933-15.

 Advocates a new data processing technique for improving thermal-wave images, which is a technique being improved for the assessment of aging-aircraft and advanced composite metals.
- Favro, L.D., et. al., "Infrared Thermal-Wave Studies of Coatings and Composites," SPIE Thermosense XIII

 Conference (April 1991) pp. 290-294.

 Although focuses on high-tech coatings and composites, explains system which will likely become model for later, mass-produced machines for more down-to-earth applications.
- Favro, L.D., P.K. Kuo, R.L. Thomas, "Real-Time Thermal Wave Imaging," <u>Unpublished</u> 27 pgs. Extremely technical piece on this technique originally used by the researchers for detection of delaminations

and defects in aging aircraft skins.

- Favro, L.D., et. al., "Real-Time Thermal Wave Tomography," in D. Bicanic (ed) <u>Photoacoustic and Photothermal Phenomena III</u> (Springer Verlag: 1992) pp. 519-45.

 Images from thermal wave tomography have often been blurred because heat from the strobe lights diffuses out in the material. The authors contend that the diffusion can be easily removed from images if the data is correctly processed.
- Favro, L.D., ct. al., "Thermal Wave Detection and Analysis of Adhesion Disbonds and Corrosion in Aircraft Panels," in D.O. Thompson, D> CHimenti, Review of Progress in Quantitative Nondestructive Evaluation (Plenum Press: 1993) 5 pgs.
- Feit, Edward, "Infrared Thermography for Acrospace NDT," Advanced Imaging (March 1991), 2 pgs.

 The author outlines how the Physical Properties Laboratory at General Dynames's Space Systems Division (San Diego) is using thermography for nondestructive testing, rocket plume studies, to observe materials under simulated re-entry conditions, to visualize gaseous leaks, and to find defects in circuit boards. A good overview.
- Finney, P., "Use Thermography to Pinpoint Faults," <u>Test & Measurement World</u> (November 1992) pp. 43-44.

 No other test equipment can detect printed circuit board faults as well as infrared thermography. This article explains the usage, application, and different levels of integration of the testing equipment.
- Gartenberg, E., A.S. Roberts, Jr., "Twenty-Five Years of Aerodynamic Research with Infrared Imaging," SPIE

 Thermosense XIII Conference (April 1991) pp.338-356.

 Used as a reference piece; this is a pure research application with no wide-spread use.
- Hadjifotiou, A., "Coherent Optical Systems: Current Status and Future Prospects." SPIE Sponsored Conference on Fiber Optics '90 (April 24-26 1990), pp. 14-24.

 A case history is presented in which infrared imaging is used to locate shorts in a complex printed wiring board. Passing current through the short heats the conductor trace, and the current path is delineated on the IR image. This method is shown to be useful for a variety of current-carrying structures, both for failure analysis and reverse engineering. It can often be used with very limited knowledge of the detailed function of the device.
- Hamilton, A., Childs E., and Marcia Kunz, Infrared Thermographic Evaluation of Fiber-Reinforced Composite

 Structures with Honeycomb and Closed-Cell Cores (SME: 1989), 26 pgs.

 The planned utilization of closed-cell core in aircraft applications where honeycomb had been used previously and the fabrication of more complex shaped honeycomb parts, has necessitated the development of advanced NDE techniques for the purpose of assessing the quality of these structures. Infrared thermography has been identified as a viable candidate for evaluating bonded structures that are difficult or impossible to evaluate using conventional ultrasonics. Infrared thermographic inspection can be applied to these structures after an extensive qualification effort has been successfully concluded. The selective implementation of infrared thermography can reap both technical and economic benefits. The results of two distinct qualification projects, one involving sandwich structures having closed-cell core and the other, honeycomb core, are described.
- Hamrelius, T., "Accurate Termpature Measurement in Thermography: An Overview of Relevant Features, Parameters, and Definitions," SPIE Thermosense XIII Conference (April 1991) pp. 448-457.

 This piece applied to all areas of application, not just NDE.

- Howell, P.A., W.P. Winfree, B.S. Crews, "Numerical Simulations of Thermal Detection of Disbonds in Lap Joints, in <u>Review of Progress in Quantitative NonDestructive Evaluation</u>, Thompson, D.O., D.E. Chimenti, (eds.) Vol. 10B, 1991, pp. 1367-73.
- Howell. P.A., W.P. Winfree, B. X. Crews, E. Cramer, "Parametric Studies of Thermographic Detection of Disbonds in Laminated Structures Using Computational Simulations," in <u>Review of Progress in Quantitative NDE</u>, Thompson, D.O., D.E. Chimenti (eds.) Vol. 9, 1990, pp. 1263-69
- "IR Method Identifies Surface Contaminants," <u>Chemical and Engineering News</u> (Date Unknown in 1990), p.56.

 A new form of microscopy developed by the Sandia National Labs, called IR microprofiling, uses a precise scanning movement of the microscopic stage to profile an entire region, pixel by pixel. (note: This sounds very much like the role IRFPAs now play, and it shows an area in which IRFPAs may make a good contribution if prices come down.)
- Jones, T.S., H. Berger, and E. Weaver, "Large-Area Thermographic Inspection of CRP Composite Marine Vessel Hulls," <u>SPIE Thermosense XV Conference</u> (April 1993) Paper 1933-25.

 Another application of IR systems designed for inspection of aging aircraft skins.
- Luong, M.P., "Infrared Thermographic Characterization of Engineering Materials," Proceedings of the SPIE v. 1341 (July 11-13, 1990), pp. 327-338.

 This paper illustrates the use of infrared thermography as a nondestructive and noncontact technique (a) to observe the physical processes of unstable crack propagation or flaw coalescence of engineering materials subject to various loadings, (b) to detect material defects or leakage phenomena and (c) to aid tribology experiments.
- Lutovinov, V.M. et. al., "Some ways of using Thermal Imaging in Acromechanics," Fluid Mechanics, Soviet Research (March-April 1990) pp. 82-91.

 There are four main possible uses of thermal imaging systems in aeromechanics: measurement of temperature distributions on the bodies, experimental determination of points of extreme temperature on a given surface, measurement of the rate of heating of a surface, the motion of isotherms (e.g. for determing the heat flows to the surface), and monitoring changs in surface temperature in order to maintain it in a given range with the help of some other means (e.g. by cooling). Many applications in aeromechanics do not require temperature calculations, but instead qualitative analyses of the distribution of extreme heat transfer values and methods of controlling it. Thermal imaging systems are very effective in such cases. There is no doubt that most of the information thus derived requires computer processing.
- Mackay, C.D., "Cooled CCDs in Lab Spectroscopy: The System of Choice," Photonics Spectra (February 1992) pp. 113-116

 Cooled CCD systems are now the detector of choice, according to this article, in a wide range of imaging applications, and in recent years they have become the fastest-growing detector system for laboratory spectroscopy. Explains how CCDs are suited well to spectroscopy and what developments one can expect in the next few years.
- Madrid, Angel, "Using IR Thermography for Detecting and Diagnosing Cracking in Concrete Dams," Conference on Infrared Technology XVI; Proceedings of the SPIE (July 11-13 1990), pp. 110-126.

 Analytical and experimental research has been concluded to assess the feasibility of detecting and diagnosing deep crack in concrete dams by means of IR thermography measurements. A simplified, scale-down model of the nonoverflow section in a conventional concrete gravity dam and its reservoir has been designed with the capability of simulating both air-filled and water-filled deep cracks. A high-resolution

CMT thermal imager (BSI 7000 equipment) has been utilized for mapping the temperatures at the downstream face of the latter mode, under realistic quasi-static thermal conditions, in similar situations both with and without deep cracks present in the concrete body. The results obtained form these measurements compare reasonably well with calculations based on an ad hoc one-dimensional heat-transfer model of the simulated dam-reservoir complex.

- Maldague, X., et. al., "Transient Thermogarphic NDE of Turbine Blades," SPIE Conference on Thermosense XII (1991) pp. 161-171.
- McLaughlin, P.V., Jr., "Defect Detection and Quantification in Laminated Composites by EATF (Passive)

 Thermography," Review of Progress in Quantitative Nondestructive Evaluation (v7B, 1988), pp. 11251132.

The capabilities and limitations of externally applied thermal field (EATF) thermography are presented along with applications for which it seems best suited. Heating methods are reviewed for both parallel and normal EATF thermography. Liquid crystal and video radiometers are assessed for their temperature measurement sensitivities and ranges and techniques for the analysis of EATF thermographic phenomena are given. Detection and quantification of debonds and surface cracks are discussed along with ambient surface condition and support structure effects. Directors for future development of the technique are highlighted.

- McLaughlin, P.V. Jr., "Using EATF Thermography for Nondestructive Evaluation," <u>Plastics Engineering</u> (July 1988), pp. 47-50.
 - The externally applied thermal field (EATF) thermographic technique for nondestructive evaluation (NDE) is capable of detecting surface and subsurface flaws, such as surface cracks and delaminations, in laminated composites during routine inspections. EATF thermography can also be used to quantify delaminations and impact damage.
- Ramamurthy, A.C., et. al., "Stone Impact Damage to Automotive Paint Finishes: Post Impact Damage Analysis,"

 International Congress and Exposition of the Engineering SOciety for Advanced Mobility Land Sea Air and

 Space (March 1993) 19 pgs.

 Discusses several technique to assess paint chips and dents in automotive bodies after the impact of stones, such as Electrochemical Impedance Spectroscopy, Themal Wave Imaging, and Acoustic Microscopy. The
- Reizman, F., "Fault Location in Printed Wiring Boards Using Thermal Imaging," <u>SPIE Thermosense XII</u> (April 1990) pp. 172-177.

 Early article on a very popular application.

authors do not unfortunately discuss the market potential (which appears very limited).

- Sciman, J.J., "Evaluation of a Prototype Thermal Wave Imaging System for NDE of Composite and Aluminum Aerospace Structures," SPIE Thermosense XV Conference (April 1993) Paper 1933-22.
- Shephard, S.M., et. al., "Comparison of Scanning and PtSi Focal Plane Array Cameras for IR Thermal Wave Imaging," SPIE Thermosense XV (April 1993) Paper 1933-16.

 Concludes that although scanning systems are more predictable and calibrated better, staring PtSi cameras should offer improved resolution, sensitivity, and faster frame rates, which should be a boon for thermal wave imaging.
- Snell, J.R., "A High-Tech Tool Meets Low-Income Weatherization, 'Home Energy (May/June 1989) 6 pgs.
 Infrared thermography equipment has come down in price to the point where weatherization programs can fully utilize them. This article describes how weatherization programs use this equipment, and what they

specifically look for.

- Snell, J.R., "A Survey of the Use of Infrared Thermography in the Department of Energy's Weatherization Assistance Program," SPIE Thermosense XI 1989 (August 1989).

 The Low Income Weatherization Assistance program, administered by the Department of Energy, aims to reduce the energy consumptions of homes owned by lower income families. In the past four years, infrared thermography has become a central tool used by energy assessors to locate air leaks around windows, holes in walls, faulty heating or cooling ducts, etc.
- Snell, J.R., "Moisture in Roofs: What to do About it," <u>Roofer Magazine</u> (October 1990) 6 pgs.

 Infrared detectors can be instrumental in the location of moisture deposits in roof, which can spread and eventually require roof replacement.
- Spicer, J.W., W.D. Kerns, L.C. Aamodt, J.C. Murphy, "Time-Resolved Infrared Radiometry Using Focal Plane Arrays for Characterization of Hidden Corrosion," <u>SPIE Thermosense XV Conference</u> (April 1993) Paper 1933-18.

 More garden-variety corrosion detection techniques using IR would probably be derived from the technique explained here.
- Syed, H.I., and K.E. Cramer, "Corrosion Detection in Aircraft Skin," SPIE Thermosense XV Conference (April 1993) Paper 1933-19.

 Explains the major effort, being conducted at Langley Air Force Base under NASA's auspices, to use IR pulse-echo thermal-wave imagery to detect flaws in aging aircraft skin.
- Tenek, L.H., E.G. Henneke, "Flaw Dynamics and Vibrothermographic-Thermoelastic NonDestructive Evaluation of Advanced Composite Materials," SPIE Thermosense XIII Conference (April 1991) pp.252-263. Earlier article on testing metal construction materials for stress, using "stress photonics," techniques, such as IR.
- Thiclen, D.A., "Infrared Thermographic Inspection of Superclastically Formed/ Diffusion Bonded Titanium Structures," <u>SPIE Thermosense XV Conference</u> (April 1993) Paper 1933-21. Discusses a specific, high-end application of IRFPAs in composite inspection.
- Thomas, R.L., L.D. Fabro, P.K. Kuo, R. Bruno, "Using Thermal Wave Imaging to See Below the Surface," <u>Photonics Spectra</u> (January 1993) pp. 147-150.
- Thun, R.L., "Thermographic Inspection of Composite Aerostructures," SPIE Thermosense XV Conference (April 1993) Paper 1933-23.

 Describes use of infrared imaging techniques, contrasting it with ultrasonic techniques, the traditional method.
- Titman, D.J., "Some Applications of Infra-Red Thermography to Civil Engineering Problems," British Journal of Non-Destructive Testing (December 1990), pp. 627-630.

 Thermography is totally non-destructive and under suitable conditions can provide a rapid hands off approach to an investigation. However, as with other non-destructive tests, it may be necessary to correlate results with other forms of inspection, utilizing other non-destructive techniques. This paper concentrates on applications of the technique to the investigation of structural details and defects. Subject covered included conditions under which the technique may be useful, applications involving a heat source within a structure, thermal gradients, and induced heating, and practical considerations.

- Traub, A.C., "Parts Inspection by Laser Beam Heat Injection," NDT International (April 1988), pp. 63-69. When a pulse of laser radiation falls on a material surface, a certain amount of warming will occur which depends upon the surface properties of the material, particularly upon its absorptivity. The amount of warming will also depend upon what is underneath the surface and especially upon the amount of mass which is available for the thermal energy to expand into. If the warming process is monitored by an infrared detection system, one has a ready means of determining whether or not two parts are alike in their surface properties or in their international features. An automatic, non-contact system is described which uses this principle for the inspection of solder joints on printed wiring boards at rates of up to 10 joints per second. With minor changes, the inspection system an be used to repair defective joints and to manufacture new ones by the reflow of solder paste of preforms. Extensions of the inspection method are described with regard to the testing of bonds in metal sheets and to the measurement of paint thicknesses on metals.
- Vogel, C., "The Art Market: When the Crowds Go Home, Museum Officials Peek Behind the Scenes, Literally,"

 New York Times (February 5, 1993), pp. C24.

 The use of infrared video cameras to closely examine great artworks on loan to museums is discussed. The Museum of Modern Art in New York City recently learned a great deal about Matisse works usnig the cameras.
- Warren, L. and J.R. Paterson, "The Development of Elastomeric Insulating Materials For Use Under Extreme Service Conditions," Fifth International Conference on Dielectric Materials, Measurements and Applications (Canterbury, UK June 27-30 1988), pp. 143-146.

 This technical piece discusses how to use a thermal imager to conduct predictive maintenance on insulation systems in high temperature environments. After testing insulating material in a severe heat environment, imagers and spectrometers were used to monitor the composition and gases given off from the insulation to test for toxic materials could harm users of the company's insulating equipment. The authors mention that much proprietary information has been withheld by manufacturers.
- Warren, L. and J.R. Paterson, "The Use of Thermal Imaging for the Development of Materials to Withstand Extreme Service Conditions," Fifth International Conference on Dielectric Materials, Measurements, and Applications (Canterbury, UK June 27-30 1988), pp. 1290-1292.

 This piece is very similar to the other from Warren and Peterson. The authors propose exposing polymeric materials to extreme testing conditions of heat, then analyzing them by thermal imaging to test for hot, weak spots which will lead to degradation and breakdown of the materials.
- Watanabe, T. et. al., "Radiation Thermometry of Silicon Wafers in a Diffusion Furnace for Fabrication of LSI,"

 IEEE Transactions on Semiconductor Manufacturing (February 1991), pp. 59-63.

 Discusses a novel technique in which thermal imagers are used to measure the temperature of silicon wafers in a diffusion furnace in production. This experimental technique is very important because as annealing (cooling) time decreases in silicon wafer production (a desirable trait to increase productivity), monitoring sensitive temperature variations becomes very important.
- Welch, C.S., "Material Property Measurements with Post-Processed Thermal Image Data," SPIE Conference on Thermosense XII (April 1990) pp. 124-132.

 Proposes method for data processing to find defects in materials.
- Yonushonis, T.M., et. al., "Infrared Thermal Wave Imaging of Thermal Barrier Coatings for Diesel Applications,"

 American Ceramic Society Bulletin (August 1992) 9 pgs.

 A rapid non-destructive evaluation technique has been developed for rapid inspection of coatings.

 Processing parameters can be improved without requiring expensive, time-consuming engine tests, thereby

significantly improving productivity and performance.

Zuech, N., "Improve Product Reliability with Thermal Imaging," <u>Test & Measurement World</u> (October 1990) pp.
 73-81.
 Infrared detectors can be used to assess electronics, and most significantly integrated circuit boards, at

Infrared detectors can be used to assess electronics, and most significantly integrated circuit boards, at several stages of production: bare-printed circuit boards, damaged circuit cards, or prototypes.

(vi) Applications of IR Sensitive Materials in Preventive Maintenance

- Ayers, W.A., "Nonintrusive Infrared Testing of High-Voltage Switchgear," <u>Materials Evaluation</u> (May 1991) 3 pgs. Contends that IR thermography could be used to inspect far more electrical components in plants, and therefore be even more valuable, but quality control engineers are afraid of getting closer to high-voltage components which should be inspected. IR inspection, of course, is the most remote way to inspect those components.
- Baird, G.S., and R.T. Mack, "ASNT Thermographic Certification Update," <u>SPIE Thermosense XIV Conference</u> (April 1992) pp.98-99.
- Black, J.E., Jr., "Utility Gain Through Infrared Predictive Maintenance," SPIE13 pp. 34-40. A case study of Toledo Edison Co.
- Bryson, F.G., "Rational Approach to Nuclear Power Station IR Surveys," <u>SPIE Thermosense XII</u> (April 1990) pp. 64-71.
- Dickey, J.W. and B.R. Schulthorpe, "Predictive Maintenance Practices at FPL," <u>Nuclear News</u> (December 1992), pp. 64-67.

 The Florida Power & Light Co. has made significant improvements in its ability to identify existing or potential problem areas using predictive maintenance methodologies. These methods allow the utility to

potential problem areas using predictive maintenance methodologies. These methods allow the utility to determine not only what work has to be scheduled, but also what work does not have to be performed, during plant outages. Thermography has been used to identify such things as high-resistance electrical connections, overloaded distribution circuits, boiler insulation degradation, blocked cooling passages, overheating bearing, shorted motor windings, etc. The article emphasizes the money savings from investing in thermography maintenance.

- Edgley, Kip, "Infrared Scanning Improves Preventive Mainetnance on Equipment Used for Water and Wastewater Treatment," P/PM Technology (1991) p.21.

 Infrared thermogaphy is particularly important in electrical preventive maintenance. Loose, diorty, corroded, or oxidized electrical contacts and connections produce heath proportional to the power dissipation. Thermographic scans identify and measure the termpature gain of heat related anomalies in electrical equipment. Because it surveys from a distance, it makes possible the innspection of otherqise inaccessible components.
- Edgley, K. "Infrared Scanning Improves Preventive Maintenance," Water: Engineering & Management (March 1991) pp. 38-41.

 Explains to utility and economic sense of periodic scheduled thermographic inspections, and applies it directly to wastewater facility machinery and electrical equipment.
- Fallon, Mary D. and Andrew C. Teich., "Role of Infrared in Plant PDM." Plant Services (October 1991), 3 pgs.

Discusses how infrared thermography is emerging as one of the most diversely applicable and effective predictive maintenance diagnostic tools available today. The reason for imaging the heat distribution in moving parts is that mechanical or rotating equipment produces excessive heat when corrosion build-up occurs or when it is not properly lubricated or aligned. Abnormal heat in electrical equipment is often the result of loose connections and overloaded circuits. This is a very important article which discusses the widespread applications of thermography to maintenance.

- Feit, E., "Infrared Inspection Saves Time & Money," <u>Forest Industries</u> (February 1986) pp. 10-11.

 Describes how wood industry could benefit from thermographic inspections. Case studies. The earliest article we found on thermographic PM.
- Garner, J.M., "Infrared Research Services vs. SSS: The Bottom Line," <u>SPIE Thermosense XIV Conference</u> (April 1992), pp. 23-29.

 Case studies of how thermographic inspection as part of a preventive maintenance regime has saved companies money. Article investigates the positive savings when recommendations were implemented and the cost attributed to recommendations ignored.
- Graf, R.J. and G.J. Weil, "Steel Plant Predictive Maintenance Programs Utilizing IR NDT," SPIE Thermosense XII (April 1990) pp. 47-52.

 Another case study of IR used in PM.
- Green, T.R., "Preventive Maintenance Program Ensures System Reliability," <u>Transmissions & Distribution</u> (April 1991) pp. 52-54.

 Case study of Balitmore Gas & Electric, which uses thermography to inspect all its overhead power lines.
- Grover, P., "Applying ANSI/IEEE/NEMA Temperature Standards to Infrared Inspections," SPIE Thermosense XIV Conference (April 1992) pp.101-107.

 Discusses the temperature standards which are fundamental to thermographic inspection. Proposes an alternated method for prioritizing potential problems with overheating equipment, which is referenced to nationally-recognized electical equipment temp standards which are adjusted to account for ambient temperature and load differences.
- Hurley, T.L., "Infrared Qualitative and Quantitatitive Inspections for Electric Utilities," <u>SPIE Thermosense XII</u> (April 1990) pp. 6-24.
- <u>Infraspection Institute Newsletter</u>, Published quarterly by Infraspection Institute.
- Johnson, P.F., "Is It Worth It? -- Statistics of Corporate-based IR Program Results," SPIE Thermosense XIII

 Conference (April 1991) pp. 47-50.

 Using statistics, authors at American Risk Management Corp. persuade industry that substantial savings can be found to companies that implement IR regimes.
- Kaplan, H. "IR Monitoring Makes Nuclear Plants Safer," <u>Photonics Spectra</u> (December 1990) pp.74-76. Describes how nuclear power industry has grown, by necessity, to utilize thermographic inspection more thoroughly than any other one.
- Kaplan, Herbert, "Photonics at Work," Photonics Spectra (September 1988), pp. 70-72.

 Infrared nondestructive testing (IRNDT) of laminar materials is based on the facts that a good thermal bond is a good structural bond, and that voids, unbonds and foreign matter affect the flow of thermal energy

across (normal to) the laminar layer. The thermal injection approach requires the generation of a controlled flow of thermal energy across the laminar structure of the sample material under test, thermographic monitoring of one of the surfaces (or sometimes both) of the sample, and the search for anomalies in the thermal patterns so produced that will indicate a defect in accordance with established accept-reject criteria. The author reviews the mechanisms used for generation and injection of thermal energy into test samples, and the typical failure modes.

- Kaplan, Herbert, "What's New in IR Thermal Imagers," Photonics Spectra (February 1991), pp. 86-88.

 A short article describing several new thermal imaging models on the market, and the trends which make them more "user friendly" and therefore more likely to gain a wide audience among manufacturing engineers and non-destructive testing managers. The trends are: portability, uncooled FPA's (vastly reducing cost), and better liquid-crystal displays.
- Leftwich, R., "Multi-Detector Thermal Imagers," (Magnavox Government and Industrial Electronics Company: 1989), 10 pgs.

 An overview and comparison was given of the most commonly used TV- compatible systems employing

An overview and comparison was given of the most commonly used TV- compatible systems employing parallel and serial scanners. Also described were a variety of image processing techniques for image enhancement and operator aids.

Lucier, Ronald D., "Using Infrared Thermography in Nuclear Power Generating Stations" <u>Nuclear Plant Journal</u> (May-June 1989), pp. 1-4.

Infrared scanning, as part of a preventive maintenance program, can isolate and or detect problems before costly failures occur. The article considers infrared as a thermal performance tool, in particular: image recording, temperature resolution, image interpretation, some infrared applications in nuclear facilities, are discussed, e.g. checking of electrical systems safety equipment, and insulation. Some new application examples are described. Computerization of infrared thermography and differential thermography are cited among new developments. Kittson, J.E., "Department of National Defence's Use of Thermography for Facilities Maintenance," SPIE

Thermosense XII Conference (April 1990) pp. 2-5

- Lucier, R.D., "Essential Elements and Goals for an Infrared Predictive Maintenance Expert System," SPIE

 Thermosense XV Conference (April 1993) Paper 1933-05.

 Discusses how to implement a thermographic PM regime.
- Lucier, R.D., "Predictive Maintenance for the 90's: An Overview," <u>SPIE Thermosense XIV Conference</u> (April 1992) pp. 35-42.

Predicts that machines designed for preventive maintenance will be two-dimensional staring arrays with radiometric qualities.

Lucier, R.D. and H.L. Kaplan, <u>Infrared Thermography Guide</u>,)Electrical Power Research Institute: Palo Alto, CA) September 1990.

A how-to guide for thermographers, listing equipment to check and procedures.

- MacDavid, J.H., "Buried Steam-Line Temperature and Heat Loss Calculation," <u>SPIE Thermosense XIII Conference</u> (April 1991) pp. 2-10.
- MacNamara, N.A. and A.E. Hammett., "Development of a Comprehensive IR Inspection Program et a Large Commercial Nuclear Utility," <u>SPIE Thermosense XIV Conference</u> (April 1992) pp.30-34.

 This paper describes the development of an integrated infrared program within a nuclear operating company

from the early conceptual stages to the beginnings of a workable end product.

- Madrid, Angel, "Using IR Thermography for Quantifying Failure Rates of Electric Power Network Components," Conference on Infrared Technology XVI; Proceedings of the SPIE (July 11-13 1990), pp. 24-45. A technique based on IR thermography measurements is proposed to estimate realistic values of electric hardware failure rates corresponding to secondary failures; that is, those caused by past or present out-of-tolerance or abnormal operating conditions. The technique allows the establishment of useful correlations between these failure rates, and the corresponding relevant thermal patterns as mapped using IR thermography. The technique is applied to practical cases of secondary failures in typical AC and DC electric power network components having to do with failure modes due to abnormal stress, corrosion, and crosion. The applications of this technique to fault and failure diagnosis, and both reliability, availability, and maintainability analysis and probabilistic risk assessment of electric power networks is also briefly discussed.
- Moy, R.Q. R. Vargas, and C. Eubanks "Predicting Electronic Component Lifetime Using Thermography," <u>SPIE Thermosense XIII Conference</u> (April 1991) pp.154-160.

 Researchers are at IIT Research Institute and Aerospace Guidance and Metrology Center.
- Nuclear Maintenance Applications Center, <u>Infrared Thermography Guide, Final Report</u>, NP-6973, July 1990, Research Project 2814-18.
- Paxton, Clint, et. al., "Infrared-Thermographic Inspection Improves Service Reliability," <u>Transmission & Distribution</u> (April 1992), 4 pgs.

 A non-technical article on how Pacific Gas and Electric Co. is meeting the goal of improved service reliability while cutting some of the expense associated with outages with better maintenance, construction practices, purchasing state-of-the-art equipment and providing more technical training for employees by using infrared thermography in field-inspection programs. Discusses the basics of thermography theory, inspection strategy, and hardware/personnel requirements.
- Ridley, W.C., "Integrating Thermography into the Palisades Nuclear Plant's Electical Predictive Maintenance Program," <u>SPIE Thermosense XIII Conference</u> (April 1991) pp. 51-58.

 Author, at Consumer's Power Company, contends that integration of IR into existing PM techniques at this nuclear power plant was very successful.
- Sharma, Y.P., "Nondestructive Inspection of Surface Mount Compounds," <u>Surface Mount Technology</u> (April 1989), pp. 11-14.

 High density packaging and interconnection technologies have led to the miniaturization of surface mounted components to such a degree that even routine optical inspections are not adequate to detect defects in components. It is reported that nondestructive techniques are available for inspecting individual components prior to, during, and after their assembly on the board. The nondestructive techniques such as infrared thermal imaging, ultrasonics, and X-ray radiography are useful for detecting potentially defective components from nondefective ones, although the use of ultrasonics requires immersing parts in a fluid for proper acoustic coupling.
- Slizewski, L.S., "The Role of Infrared Surveys in Loss Prevention," <u>AIPE Facilities</u> (January/February 1992) 3pp. Technical piece intended to give electrical plant quality control engineers a closer look at thermographic inspection. Contends that thermography has proven its worth as a loss-prevention tool. Includes survey information on how much money could be saved through routine thermographic inspection.

- Snell, J.R., "Energy Management Technology Report: A Maintenance Strategy You Can't Afford to Be Without," <u>Engineer's Digest</u> (January 1989) 4 pgs.
 IR consultant-author offers several case studies of customers who have saved several times the start-up and consultant costs after getting thermographic inspections of their plant's electrical equipment, mechanical equipment, roofs, etc.
- Snell, J.R., "Developing Operational Protocol for Thermographic Inspection Programs," <u>SPIE Thermosense XIV</u>
 Conference (April 1992) pp. 12-22

 An article intended for thermographers, discussing all the factors which contribute to effective and credible thermographic inspections of equipment.
- Snell, J.R., "Infrared Thermography: Answers to Questions You've Wanted to Ask," <u>Maintenance Technology</u> (June 1992) 6 pgs.

 Introduction to IR thermography for plant equipment maintenance engineers.
- Snell, J.R., "Infrared Video Camera Improves Equipment Maintenance at Champion International," P/PM Technology (May/June 1989) pp.12-13.

 Another case study which discusses the cost savings to a company which signed up with the consultant (author).
- Snell, J.R., "Integration of Infrared Testing into Various Maintenance Philosophies," SPIE Thermosense XV Conference) (Paper 1933-02).

 Discusses IR thermography's contributions in conjunction with oil analysis, vibration analysis, etc.
- Snell, J.R., and R.W. Spring, "Surveying the Elements of Successful Infrared Predictive Maintenance Programs,"
 SPIE Thermosense XIII Conference (August 1991).
 Good background on all factors involved in good thermographic inspections, not just equipment.
- Snell, J.R., "Thermographic Inspection of Plant Electrical Systems," Maintenance Technology (May 1990) 4pgs.

 Intended to introduce plant maintenance engineers with how thermographic inspections are conducted, what the thermographer is loo 1 g for, and what the electrical plant will get out of the inspection.
- Stern, S.A, "Infrared Thermography IMaging System Multiapplications for Manufacturing," SPIE Thermosense XII (April 1990) pp. 53-63.
- Teich, Andrew C., "A Cool Box Finds Hot Spots." <u>Photonics Spectra</u> (August 1991), p. 9.

 Inframetrics, a leading industrial process IR system producer, has integrated all the necessary imaging and analysis hardware in a portable rig which can be used for failure detection. It is representative of the leading units in the field. The system can image samples from -20 to 1500 degrees celsius, with an accuracy of +- 2 degrees.
- Teich, Andrew C., "Predictive Maintenance with Thermography." Promotional Piece from Inframetrics, Inc.

 Billerica, MA, 5 pgs.

 An extremely broad overview of the utility of thermography in detecting problem areas in early stages of deterioration, thereby saving companies vast amount of money. This is just a summary piece of the other, more detailed articles written by Teich.
- Tomlingson, P.D., "Predictive Maintenance: Key to an Effective, Cost-Saving maintenance Program," Complete Building Equipment Maintenance Desk Book, S.J. Fuchs (ed), pp. 39-65 (Prentice-Hall, Englewood, NJ)

- Weil, G.J., "Steel Plant Maintenance Programs Utilizing IR NDT," <u>SPIE Thermosense XII Conference</u> (April 1990) pp. 47-51.

 Discusses how IR thermography can be used specifically in the steel industry. Dicusses the cost benefits of thermography as it applies uniquely to steel plants, and recommends specific inspection regimes.
- Wurzbach, R.N., "Increasing Maintainability and Operability of Emergency Diesel Generators with Thermogaphe Inspections," SPIE Thermosense XV Conference (April 1993) Paper 1933-03)

 Another specific case study.
- Wurzbach, R.N., "Thermographic Monitoring of Lubricated Couplings," <u>SPIE Thermosense XIII Conference</u> (April 1991) pp. 41-46.

 Case study of Philadelphis Electric Co.
- Wurzbach, R.N. and R.G. Hammaker, "The Role of Comparative and Qualitative Thermography in Predictive Maintenance," <u>SPIE Thermosense XIV Conference</u> (April 1992) pp. 3-11. Compares both techniques for preventive maintenance, concluding that although quantitative thermography is more difficult technically, it will gain more widespread appeal.

(vii) Applications of IR Sensitive Materials in Process Control

- Ahlstron, J., "Review of Industrial and Research Applications of Thermography," (SPIE Paper 1320-21), 1990, 4 pgs.

 An all-applications, no-technologies discussion of thermography, which gives a good overview of the applications for which IRFPA will be competing if costs can be brought down. These are certainly low-end of the market niches, but it is a good overview piece nonetheless.
- Anderson, C.J., "Automated Infrared Scanning in Cray Y-MP Production," SPIE Thermosense XII (April 1990) pp. 207-217.
- Back, B., "Adaptive Welding Increases Quality," Photonics Spectra (January 1991) pp. 181-185. For high-quality welds, it is critical that joints be precisely positioned. The usual way of automating welding processes has been to install arc-welding robots, who work according to a prgram that specified weld path, torch angles, welding parameters, etc. To assure faster, more consistent and higher quality welds, the authors developed a system which uses an infarared sensor to view the weld.
- Balle, M., "Automated IR-Weld Scam Control" SPIE Thermosense XII (April 1990) pp. 332-339.
- Banerjee, P, and B.A. Chin, "Gradient Technique for Dynamic Bead Width Control in Robotic Gas Tungsten Arc Welding," Conference on Recent Trends in Welding Science & Technology (June 1-5, 1992) 5 pgs.

 A novel approach for the in-process detection and control of bead width is presented. An infrared sensor is used to acqure thermal distributions on the welded surface duing the gas tungsten are welding process. In order to monitor weld bead width, these distributions were analyzed in-process.
- Bancrjee, P., and B.A. Chin, "Infrared-Sensor Based On-Line Weld Penetration Control," SPIE Thermosense XV Conference (April 1993) Paper 1933-12.

Bancrjee, P., J. Liu, B.A. Chin, "Infrared Thermography for Non-Destructive Monitoring of Weld Penetration Variations," Proceedings of the Japan USA Symposium on Flexible Automation (American Society of Mechanical Engineers, 1992) pp. 291-295.

The thermal distributions obtained during the gas tungsten are welding process were analyzed using mathematical techniques to determine if changes in the surface temperature distribution could be correlated with changes in weld penetration. An nfrared scanning camer was used to obtain the temperature profiles.

Bancrjee, P., Nagarajan, S. and B.A. Chin, "Weld Quality Control in Gas Tungsten Arc Welding Process,"

<u>Proceedings of NSF Design and Manufacturing Systems Conference</u> (1991), pp. 143-47.

An infrared sensor was used to control the quality of welds produced during gas tungsten arc welding process. Among the weld parameters, penetration depth and position of the weld pool were investigated

process. Among the weld parameters, penetration depth and position of the weld pool were investigated. Temperature distributions in the vicinity of the weld pool were measured using the infrared sensor. These measure temperature distributions were analyzed to determine penetration depth in real-time. The position of the weld pool was controlled suing the asymmetry in temperature distributions. The ability of infrared sensor to monitor more than one weld process parameter was also demonstrated. As an example, weld pool offset and width were simultaneously identified.

Banges, Edmund R. and Erland Jungert, Artificial Intelligence in the Development of Adaptive Control for Fusion Welding (SME, 1986), 18 pgs.

The ability to control fusion welding processes in an adaptive control mode and perform an inspection in real time is of interest to fabricators in the pressure vessel, aerospace, and shipbuilding industries. This paper presents a series of experiments using infrared thermography as the principal sensing mode to study artificial intelligence contained in weld puddle isotherms. The information obtained may prove valuable in the control of the welding process. Image processing computer software development was initiated in the development of algorithms that correlate geometric shape change data to changes in the critical process and procedure variables. The IR vision sensor generates a partial Raster image which is analyzed by the image processing system. Decision support for preservation of weld quality is made by an expert system.

- Bangs, E., "IR Monitors Cutting-Tool Wear," <u>Photonics Spectra</u> (November 1991) pp. 22-23.

 Millions of dollars are lost each year in the metal-removal industry in the scrapping of machined parts as a result of worn cutting tools. Research metallurgists report that the increased heat generated as a result of tool wear is readily detectable by the infrared camera. Infrared Monitoring Systems has designed a thermographic screening machine using commercialy available infrared cameras to test a tool for wear.
- Bettelheim, J. and P.G. Williams, "Research and Development and Its Contribution to Improvement in Coal-Fired Plant Performance," Power Engineering Journal (September 1988), pp. 253-258.

 The authors explain the ways in which their company, CEGB, is pursuing technologies, some of them infrared, to optimize coal-fired power plant performance. Among the techniques they have developed are flame monitoring which presently only uses two points on the flame (IRFPAs would vastly improve this technique) and sonic pyrometry to measure the furnace temperatures. Although not addressing IRFPAs directly, these two monitoring techniques could vastly benefit from IR arrays.
- Bomse, D.S., et. al., Optically Based Methods for Process Analysis, (SPIE: March 1992) 40pgs.

 The proceddings focuses on in-process analytical instrumentation used in spectroscopy, process control color measurement, and product quality measurement in industrial production environments including pharmaceutical, petrochemical, and chemical manufacturing. The papers are multidisciplinary, being contributed from scientists and engineers involved with research, plant design, process quality control, and environmental monitoring. Bickell, A., "NIR: Earning a Place in Process Control," Quality (May 1990) pp. 56-58.

Near infrared spectroscopy is being used in the process industries, such as petroleum, chemicals, polymers, textiles, pharmaceuticals, films, coatings, foods, and adhesives. Article gives several case studies and explains how other industries can stand to benefit from NIR spectroscopy.

- Burkell, R., and J. Murphy, "Infrared Imaging Systems Automate Aircraft Engine Inspection at General Electric,"

 Integrated Engineering (April 1989) pp. 28-32.

 Describes how GE thermally inspects components of its aircraft engines, specifically turbine blades which have had internal passages and surface cooling holes drilled. IR confirms that heat does circulate through those cooling passages.
- Chin, B.A., Goodling, J.S. and N.H. Madsen, <u>Infrared Thermography Shows Promise for Sensors in Robotic Welding</u> (SME: 1983), 3 pgs.

 Infrared thermography shows promise as a means of sensing errors in arc position, seam variations, and presence of contaminants in the weld path. The experiments were performed with various types of sensors (acoustic, infrared thermography, optical and on-line radiography), all categorized as direct sensors.
- Chin, B.A. and N.H. Madsen, <u>Infrared Sensors for Welding Process Control</u>: <u>Advanced Systems for Manufacturing</u> (SME: 1985), 10 pgs.

 The objective of the research is the development of closed-loop controlled welding using infrared sensors. The primary benefit of the research would be an increase in the number of welding situations that can be automated. This is a preliminary article to the 1991 one published by Banerjee.
- Coughlan, J., "Melt-temperature Detection Problems You May Not Know You Have," Modern Plastics (April 1992) pp. 101-105.

 Current systems for critical temperature measurement in plastics are outdated, relying on inadequate and insufficient temperature information. Precision melt-temperature control, using infrared temperature sensors, is a new technology which performs much better than all other existing techniques.
- Curran, R.L. and Ihab H. Farag, "Radiation Pyrometry of Glass During The Container Forming Process," IEEE Transaction Papers (Date Unknown), pp. 1092-1097.

 Radiation pyrometry is an ideal form of non-destructive testing to measure the thermal profile of glass containers during a variety of different processes. Glass production is an ideal field to employ thermal imagers because a few degree change in glass temperature can change glass viscosity by a factor of 10, significantly affecting the molding process. The authors propose that thermometry will work well in glass molding.
- Curren, R.L., I.H. Farag, "Radiation Pyrometro of Glass During the Container Forming Process," <u>IEEE Transactions</u> (Paper #88CH2565-0, 1988) pp. 1092-1098.

 Technical how-to piece on use of non-contact temperature profiling used during the forming of glass containers by a variety of idfferent processes.
- D'Agostino, S., "1991 Trends: Imaging: Application Know-How Drives Success," <u>Photonics Spectra</u> (January 1991) pp. 131-132.

 Discusses the future of machine vision. Predicts that the price/performance ration of machine vision systems will continue to improve. Whole systems could sell for <\$10,000.
- D'Amato, D.P., et. al., <u>Machine Vision Applications in Charavter Recognition and INdustrial Inspection</u> (SPIE: WA) February 1992.

There is a race to make better, smaller, faster, and less power consuming microelectronic devices, and machine vision is a technology whose time in the microelectronics manufacturing world has arrived.

Danaher, Hugh, "Thermography: Understanding the Expanded Role of Thermal Imagers in Production," Evaluation Engineering (December 1988), pp. 77-79.

Thermal imagers quantitatively and qualitatively evaluate designs, determine proper operating conditions and facilitate repair of electronics components, subassemblies and final assemblies. Thermographic and other electronic instruments rely on quantitative data to determine conformance to specification and functionality of a device-under-test. The type of data they use to draw these conclusions is irrelevant. Only the accuracy and efficiency of obtaining meaningful results matter. When considering both of these criteria, thermal imagers often are perfect adjuncts to functional and inter-circuit testers to provide the most cost-effective solution.

Decley, E.M. and P. Kontopoulous, "Strip speed measurement using distributed infrared detectors," <u>IEEE Proceedings, Part D</u> (July 1991) pp. 395-399.

A non-contact method for measuring the speed of electrically conducting strip over the range of speeds found in industry is described. The method is thermal in character and relies on the ability of ht striop to store heat for short periods of time. A wavelength-sensitive reading head consisting of an array of equally spaced infrared detectors senses the heat pattern present on the moving strip. The signals from the array elements are combined and the array acts as a spatial filter. The resultant signal is then fed back to a ehter, or writing head, placed upstream of the reading head, resulting in a closed loop time delay feedback systems which oscillates at a frequency proportional to the strip speed. Phase shifts within the feedback loop cause a departure from linearity in the speed/frequency relationship. This effect is minimised by a digital feedback loop. Use of high-performance detectors would enhance performance, particularly for low-emissivity material.

- Fike, D.K., "Using Infrared Thermography as a Manufacturing Tool to Analyze and Repair Defects in Printed Circuit Boards," <u>SPIE Thermosense XIII Conference</u> (April 1991) pp. 150-153.

 Author, at IBM corporation, explains their research into using IRFPA-based systems.
- Fuchs, E.A., et. al., "Thermal Diagnostics for Monitoring Welding Parameters in Real Time," <u>SPIE Thermosense</u> XIII Conference (April 1991) pp. 136-149.
- Gauvin, Jacqueline, "Technology Update," Robotics Today (January 1986), p. 12.

 A NSF Grant will support a study of robot positioning accuracy that will use acoustic methods to measure position. A remote maintenance robot has been developed to perform maintenance tasks on the Sandia Pulse Nuclear Reactor III in New Mexico. A Study by Frost and Sullivan (New York) predicts the market for industrial vision systems will increase to \$980 million dollars in sales by 1999 at a mean annual growth rate of 57%. An infrared charged-coupled device camera developed by RCA (Moorestown, NY) can sense slight amounts of heat, allowing the unit to "see" vehicles, observe personnel movements, track heat-emitting objects, or provide topographical data. Integrated sensor technology is being used at the University of Pennsylvania to produce microsensors small enough to allow as many as 250 sensors to fit on a single silicon chip.
- Giacobbe, F.W., "Selective Hardening of High Carbon Steel Using an Argon Thermal Plasma Flame," <u>IEEE</u>
 <u>Conference on Plasma Science</u> (May 1989), p. 117.

Thermal sensors were used in the selective hardening of high carbon steel using an argon thermal plasma flame. While continually rotating the samples, they were rapidly heated to 870 degrees celsius, kept there fore 1 minute, and then cooled. Although the approach in the article is metallurgical, it also signals a

- potential use for IR technology. Gilblom, D.L., "TDI Solves Web-Inspection Problems," <u>Photonics Spectra</u> (May 1991) pp. 189-192.
- Govardhan, S.M. and B.A. Chin, "Adaptive Penetration Control Using Infrared Measured Temperature Gradients," <u>SPIE Thermosense XV Conference</u> (April 1993) Paper 1933-13.
- Graeve, T., E.L. Dereniak, and J.A. Lamonica, "An Improved Infrared Technique for Sorting Pecans," Rev. Sci Instrum. (October 1991) pp. 2476-2479.

 Presents the rsults of a study of pecan spectral reflectances. Describes an experiment for measuring the contrast between several components of raw pecan product to be sorted. It is believed that this technique has the potential to dramatically improve the efficiency of current sorting machinery, and to reduce the cost of processing pecans for the consumer market.
- Gring, W., "It's Either Hot. or it's Not: Infrared Technology Speeds up Power Inspections at US West COs in Arizona and New Mexico," <u>Telephony</u> (July 27, 1992) pp. 22-24.

 Case study of immense financial benefits to companies which began using sophisticated IR cameras to scan power lines. Goes through the mechanics of inspections.
- Guerrieri, M., Infrared Temperature Sensing (SME: 1987), 8 pgs.

 To improve the manufacturing process in both productivity and quality, precise data must be gathered on the variables that affect production. Temperature plays a critical role at vital points in most manufacturing processes. Processing temperatures are a measure of resultant quality in metals, plastics, chemical and food processing, as well as paper making, printing, and numerous other processes. Infrared noncontact temperature sensors provide a method of gathering significant information on temperature and, when coupled with data processing electronics, can be a vital element in an automated process or manufacturing line. This paper covers recent advances in infrared thermometers and applications in which they have made major contributions in quality and/or productivity.
- Guerrieri, Matt, State of the Art in Infrared Temperature Sensors (SME: 1986), 8 pgs.

 Noncontact infrared thermometers are aiding engineers to achieve enhanced productivity and improved quality control in manufacturing processes. In virtually any process in which temperature is a significant factor, IR thermometers can provide precise heat measurement, resulting in greater yield and consistency of product. Improvements in IR sensor components, accompanied by significant price declines for the instruments, have made possible price and performance that matches almost every heat sensing requirement.
- Haugh, M.J., D.P. Stone, M. Thangavelus, "Paint Skip Detector," SPIE Thermosense XII (April 1990) pp.190-199.
- Holmsten, D. and R. Houis, "High-Resolution Thermal Scanning for Hot-Strip Mills," SPIE Thermosense XII (April 1990) pp. 322-331.
- Hospod, T., "MV Soft- and Hardware Integration -- A Practical Approach," Photonics Spectra (February 1991) pp. 177-183.

 An introduction to machine vision: discusses both machine guidance and automated inspection, common requirements, processing-hardware selection, and camera selection. A good overview article, which does not specifically address infragation.
- Hyvarinen, Timo, et. al., "Infrared Analyzers for Process Measurements." Unpublished Paper (1992) 6 pgs.

 Optical analysis techniques, infraerd spectroscopy in the front end, are rapidly achieving new applications in process control. This progress is accelerated by the development of more rugged instrument

constructions. This paper discusses two analyzer techniques especially developed for use in demanding environments: the integrated multichannel detector technique, and a miniaturized Fourier transform infrared spectrometer. The future holds more detector array style sensors rather than the singular photovoltaic sensors presently in use. This will make it possible to monitor the human body, the food we cat, and the environment we live in (ie. the authors simplified the possible applications)

Jenks, Nigel, "Transverse Temperature Measurement to Improve Hot Strip Quality," <u>Steel Times</u> (May 1989), pp. 242-44.

Accurate temperature measurement has a role to play in all modern hot strip mills in helping to achieve consistency of material properties. Infra-red scanning cameras enable hot band temperature profiles to be measured across the width and along the length of the hot band. Information on the complete temperature profile, instead of just the center line temperature as recorded by a pyrometer, enables accurate control measures to be implemented to maintain uniform properties.

Kaplan, Herbert, "Applications Unlimited: Innovations Spur Productivity," <u>Photonics Spectra</u> (September 1991), pp. 79-89.

Kaplan discusses how photonic systems are assuring quality in non-destructive testing in real time, often in automated assembly-lines. He emphasizes the linear CCD (Charge-Coupled Displays) camera, which will employ IRFPAs as soon as the technology becomes affordable. Although not a head-on articles for IRFPAs, it introduces photonics in industrial sensors well.

- Kaplan, H., "Innovations Spur Productivity," <u>Photonics Spectra</u> (September 1991) pp. 79-89.

 Outlnes four new automated industrial applications for photonic technologies which are representative of the areas in which machine inspection technologies are penetrating the market. One application discussed, in which solders on a PC board are monitored, uses infarred detectors.
- Kaplan, H., "Laser-Beam Diagnostics with Pyroelectric Cameras," Photonics Spectra (December 1992) pp. 64-65.
 Pyroelectric cameras can uniquely image over a broad spectrum, from ultraviolets to far-infarred. In the 1-25 micron region, the cameras could perform beam detection, beam alignment, and beam-dispersion analysis, since most lasers operate at those wavelengths.
- LeBeau, C.J., "Machine Vision Drives Quality to New Highs," <u>Photonics Spectra</u> (September 1991) pp. 122-126. Describes how Motorola is integrating machine vision, some infrared, into its semiconductor manufacturing processes from the early states of wafer fabrication to the ifnal stages of outgoing package inspection.
- Lin, T.T., J.S. Goodling, and K. Groom, <u>Adaptive Welding Using Infrared Sensing Techniques: Manufacturing Processes</u>, <u>Machines</u>, and <u>Systems</u> (SME: 1986), 8 pgs.

 This appears to be an intermediate article between the preliminary sensors-in-the-welding-process study by

This appears to be an intermediate article between the preliminary sensors-in-the-welding-process study by Madsen in 1985, and the final results published by Banerjee in 1991. The research investigates the feasibility of using infrared sensors to monitor the welding process. An infrared camera was trained on the molten metal pool during the welding operation. Several types of process perturbations which result in weld defects were then intentionally induced and the resulting thermal images monitored. Gas tungsten are using AC and DC currents and gas metal are welding processes were investigated using steel, aluminum, and stainless steel plate materials. The thermal images obtained in the three materials and different welding processes revealed nearly identical patterns for the same induced process perturbation. Based upon these results, infrared thermography is a method which may be applicable to automation of the welding process.

Linnander, B., "James River Uses Infrared Scanner to Investigate Off-Spec Production," Pulp & Paper (November

1992) pp. 131-132.

Case study of a paper mill which uses sophisticated infrared cameras to troubleshoot when paper quality falters. Discusses the benefits of permanent, linear arrays which image rapidly and are placed in several locations along the paper production web.

- Matthews, Thomas R., Application of Sensors in an Untended Forging Cell: A Case History (SME: 1986), 9 pgs. Sensors are important to the successful operation of any untended manufacturing process. This paper examines how sensors are integrated in the design of a turbine blade preform forging manufacturing cell. A wide range of sensors, including vision gaging, gas analyzers, infrared temperature measurements, other temperature transducers, pressure transducers and others are required to achieve untended operation of the cell. Also discusses are problems, solutions, and future requirements.
- McWalter, K., "Machine Vision on Today's High-Tech Factory Floor," <u>Photonics Spectra</u> (September 1991) pp. 97-100.

Discusses the advent of widespread machine vision, the mechanics of actually integrating cameras into assembly processes, the integration process, the benefits once a system is installed, and new industries in which inspection equipment is becoming available. Article is not strictly IR. A good overview of direction of machine vision market and machinery.

- "Microelectronics Spurs Measurement Market," Photonics Spectra (January 1992) p. 118.

 As a result of higher integrated circuit densities and pressure for low-cost, high-throughput quality control, the demand in the microelectronics industry for electro-optic test, measurement and inspection (TMI) equipment will continue to grow. This market, \$582.4 million in 1989, is forecast to reach \$1.4 billion by 1996, according to Market Intelligence Research Corp. (MIRC).
- Nagarajan, Sundaram, et. al., "Control of the Welding Process Using Infrared Sensors," <u>IEEE Transactions on Robotics and Automation</u> (February 1992), pp. 86-93.

 Preliminary results from the use of sensors in a welding system suggest that simultaneous penetration depth, bead width, and torch position control are possible using a single IR camera. The camera, produced by Inframetrics, was in the 8-12 micron range, and gave a matrix of 250 x 192 discrete temperature measurements. The experiment showed that IR sensors can indeed be successfully used to control the welding process. This is a good piece on IR research in metallurgy welding.
- Nagarajan, S., W.H. Chen, B.A. Chin, "Infrared Sensing for Adaptive Arc Welding," Welding Research Supplement (November 1989) pp. 462-466.

 Adaptive welding enables dynamic altering of the welding parameters to compensate for changing environment. Sensors providing process status information in real time are integral to an adaptive system. In this investigation, IR thermography was used as a sensor to control the position of the arc and the

In this investigation, IR thermography was used as a sensor to control the position of the arc and the penetration depth of the weld. Preliminary work on IR thermography showed that variation in these parameters produces a change in the surface temperature distributions of the plates being welded. Subsequently, to achieve computer control of these variables, image analysis techniques were developed to quantify the changes in the temperature distribution.

Nagarajan, S., H.C. Wikle III, B.A. Chin, "On-Line Weld Position Control for Fusion Reactor Welding," <u>Journal of Nuclear Materials</u> (Paper 0022-3115, 1992) pp. 1060-1064.

Infrared sensing techniques were investigated to assist remote welding systems to identify and correct weld-joint offsets in real time. During the welding process, the temperature distribution along a line of normal

to the joint and ahead of the arc was measured, using an IR detector.

- O'Connor, L., "Smart Sensors Ride the Rails," <u>Mechanical Engineering</u> (December 1991) pp. 54-55.

 Costly and dangerous freight car derailments that occur when roller bearings heat up rapidly havbe prompted the development of new sensor based systems to avert the danger. Infrared temperature sensors are one solution.
- "Optical Spectrometry," Chemical and Engineering News (March 18, 1991), pp. 46-55.

 An overview of the optical spectrometers shown at their annual instrumentation trade show. The trends were sharper detection levels, portability, and an accent on designing for specific applications. This will be a good market manufacturer survey if we identify spectrometry as an important future area of IRFPA use.
- Orlove, G.L., "Development of a Radiometric Model for the Detection of Plastic Coating Omissions on Aluminum Substrate," SPIE12 pp. 184-189.
- O'Shaughnessey, S., "Machine Vision Catches Problems Early On," Photonics Spectra (December 1990) pp. 80-81, Discusses several industries which are using state-of-the-art machine vision which uses a complete control strategy to implement a statistical process control system.
- Paxton, C., "Infrared Thermogarphic Inspection Improves Service Reliability," <u>Transmission & Distribution</u> (April 1992) pp. 32-35.

 Another electrical utility describes the economic benefits of thermographically inspecting its power lines.
- Rabie, Abdelrahman, The Use of Sensors in Part Handling (SME: 1983), 12 pgs.

 Although old, this articles discusses an important IR technology. Two laboratory techniques for part handling implement two different types of noncontact proximity light sensors. One technique used photoresistive cells for part orientation while the other used IR sensors for part detection. Both the hardware and the software are fully explained as are the major limitations of each technique.
- Raghavan, S., H.C. Wilkle, B.A. Chin, "Adaptive Control of Submerged Arc Welding Using Infrared Sensing," SPIE

 Thermosense XV Conference (April 1993) Paper 1933-11.
- Rogers, J.K., "Gaging Systems Lead March to Quality," <u>Modern Plastics</u> (November 1992) pp. 54-56. Dicusses, among other technologies infrared gages, which are used in industry whe on-line compositional analysis is necessary, such as in determining the amount of barrier material in a multilayer extrusion, or measuring the amount of polymer on a foil or paper substrate in a coating operation.
- Rose, Jennifer, "Solder Joint Inspection Systems Aid Process Control Efforts," Connection Technology (February 1989), pp. 25-27.

 Sophisticated computerized technologies for analyzing the quality of the solder joint is critical in the process control of soldering in electronics manufacturing. A vision system may be inadequate since many joints are hidden from view. Several non-destructive inspection systems are either under development or currently available. The most viable technologies for obtaining the image (data) involved either infrared detection, a combination of laser/infrared, ultrasonics, or x-rays.
- Schreiber, Rita R., "Sensors," Robotics Today (May 1983), pp. 16-17.

 Describes Ford Motor Company's plans to use the cyto-computer vision system from Synthetic Vision Systems. Inc. to verify precision circuitry. The model 815 passive infrared sensing module is described as the first practical system designed to precisely detect an object by sensing the thermal contract between the moving object and its background.

- Seitzer, T., "Industrial Vision tackels Web Inspection," <u>Advanced Imaging</u> (February 1993) pp. 32-34. Overview of web inspection markets opening up recently to machine vision. Discusses applications form steel to newsprint, continuous pavement surfaces to food harvesting. Discusses technologies which make inspection possible, some infrared.
- Setzer, J.B., M. Thangavelu, "Infrared Sensor for Automated Inspection of Hot Metal Surface," SPIE Thermosense XII (April 1990) pp. 200-206.

 Authors describe how a linear infrared sensor could be used for automated inspection of hot metal sheets. The sensor locates voids, inclusions, and surface defects characterized by a variation from background radiant flux. The sensor can be coupled with a commercially avilable processing system, developed for visible wavelength line scan cameras, to automatically track, classify, and report product flaws in real time.
- Shelley, S., "Real-Time Emissions Monitors Now Detect Smaller Quantities of More Compounds at Breakneck Speed," Chemical Engineering (November 1991) pp. 30-39.

 Discusses the growing area of continuous emissions monitoring, which would use an "open path" or "fenceline" monitoring systems based on infrared optics. The system would pick up emissions in plants such as pul-and-paper mills, petroleum refineries and waste incinerators, and monitor the level of government regulated gases entering the air.
- Smith, C., "Noncontact High-Temp Measurement," <u>Photonics Spectra</u> (July 1992) pp. 22-24. Special filtering at narrow spectral ranges makes it possible to measure high surface temperatures through glass ports, flames, and products of combustion using non-contact IR thermoemeters. This article outlines well the areas of application more likely to favor point infrared radiometers rather than linear or scanning systems.
- Stern, H., "Machine Vision Turns From Autos to Electronics: Standards Hold the Key to Success," Photonics Spectra (December 1991) pp. 101-104.
 Machine vision, its hope in automobile production diminished, has found relief in electronics inspection. The author discusses what is available, what needs to be done to integrate an inspection system into existing processes, and the mechanics of conducting automatic inspections.
- Stinson, S.C., "Advances Made in APplying IR Sensors to Process Control," Chemical and Engineering News (January 9, 1989) pp. 30-31.

 Discusses two developments in infrared spectroscopy which have deepended interest in applying IR sensors to chemical and plant and oil reginery process control. One monitors multicomponent gas flows. The other determines gasoline octane numbers from IR spectra.
- Stout, A., "IR Aids Development of High-Power Chips," Photonics Spectra (November 1992) pp. 24-26. Infrared technology is being used to test cooling integrated circuit boards for high-power computer chips that are still on the drawing board. Since a deviation of 5 degrees on any component can affect operating speed, performance, and overall integrity, infrared detectors can profile chips and confirm that temperatures remain within those ranges.
- Teich, Andrew C., "Predictive Maintenance with Thermography in Paper Mills," <u>Paper Age</u> (Forthcoming, 1992), 5 pgs.
 - A very good introductory, plain speaking article which describes how thermography is rapidly emerging as one of the most valuable resources available for predictive plant maintenance, detecting hidden problems in factories and allowing for corrective action before costly system failures occur. Applications in present use include surveying roofs for leaks, and checking rotating mechanical equipment such as electric motors,

bearings, and conveyors for signs of heat. Electrical distribution and motor control centers can be monitored for loose connections and phase imbalances. Circuit overload conditions can be detected long before burn marks for discoloration occur on the wire insulation. Other applications include refractory lining breakdown analysis, roof moisture detection, building envelope studies, steam trap conditions, heat exchanger evaluations and even the location of spontaneous combustion of stored paper products in ware houses and paper making supplies in outside yards.

- Tervo, M., Kiukaaniemi, E., and T. Kauppinen, "Applications of Aerial Thermography in Peat Production in Finland," SPIE Thermosense XV Conference (April 1993), Paper 1933-14.
- "Thermography Monitors Weld Quality," Quality (January 1992) pp. 37.

 Discusses new servo-style automated system to perform resistance welding and percussive arc welding.
- Tournerie, B., Reungoat, B. and J. Frene, "Temperature Measurements by Infrared Thermography in the Interface of a Radial Face Seal," <u>Journal of Tribology, Transactions of the ASME</u> (July 3 1991), pp. 571-76. Mechanical seal functioning can be greatly affected by thermal effects and particularly by the coupling of seal face geometry and heat dissipation in the interface. It is necessary to develop new investigation means in order to study accurately such very delicate phenomena. This paper deals with the feasibility of temperature measurements by means of infrared thermography technique. The capabilities of the infrared camera which has been used are examined.
- Travis, M., "Color Vision Helps Manufacturing and Quality of Food Products," Photonics Spectra (September 1992) pp. 139-143.

 Although IR is not discussed, author outlines all areas of food inspection, from picking to automated inspection, which could use machine vision. Describes systems design, system integration, and other parameters in putting together an automated vision system which works for food inspection.
- Valenti, M., "Infrared Sensors: Hands-Off Temperature Measurement," <u>Mechanical Engineerg</u> (October 1991) pp. 40-45.
 Survey article which discusses how noncontact heat-measurement instruments, known as radiation thermometers, have evolved into compact sophisticated devices that accurately measure temperature in a wide variety of industrial applications, from steel and glass production to the manufacture of semiconductor chips.
- Vanzetti, Riccardo, "Combining Soldering with Inspection," <u>IEEE Control Systems Magazine</u> (v.5, 1988), pp. 29-32.

A procedure is described in which an infrared detector is used to control the quality of solder joints being formed on printed circuit boards and a laser is used to inspect the quality of each joint at the same time. This approach eliminates after-the-fact inspection while making available real-time data for process control of the soldering operation. Although the joints are formed one at a time, with somewhat longer manufacturing time as compared to alternative processes, the extra time is partly compensated for by elimination of a separate inspection. Moreover, when joints of different sizes occur on the same circuit board, each one receives a tailored amount of reflow energy, thus avoiding underheating or overheating, which can occur when the entire board is soldered at once.

Vanzetti, Riccardo, Intelligent Laser Does Soldering, Inspection and Process Control (SME, 1988), 20 pgs.

A method is described in which an infrared detector controls quality of solder joints being formed by laser beam heating on printed circuit boards while, at the same time, automatically inspecting the quality of just

- made joint. It eliminates the after-the-fact inspection process while simultaneously making available real time data for process control of the soldering operation. A similar method for inspecting solder joints on previously built PCBS is addressed.
- Vanzetti, Riccardo and Dr. Alan C. Traub, <u>Laser Soldering and Inspection for SMD's and FPT</u> (SME, 1989), 11 pgs. A means of manufacturing solder joints by laser-beam reflow in combination with infrared thermal sensing controls the heating process for each joint. The method tailors the heating dosage to the heating requirements for each joint, thus accommodating variations in thermal mass or in the amount of heat sinking by adjoining parts. In this method, the surface temperature of each solder mass is brought quickly to its melting temperature, the laser power is then reduced and controlled, via feedback, in order to give the rest of the solder mass time to reflow. The thermal signature of each reflowed target, as seen by the infrared detector, indicates whether the joint is normal or whether it may have been defective due to poor preparation beforehand.
- Wallin, B., "Real-Time Temperature Measurement on PCBs, Hybrids, and Microchips," SPIE Thermosense XIII Conference (April 1991) pp. 180-187.

 Author at AGEMA Infrared explains how their systems offer the potential to perform thermographic inspections for this application.
- Warren, C., "Infrared Thermometers: Out of the Lab and into the Factory," Machine Design (November 22, 1990) pp. 85-88.

 Discusses the variety of industrial jobs in which infrared thermometers (both simple and linear) are used. Describes their advantages over contact thermometers, and basic principles behind their functioning and integration into industrial processes.
- Willis, H.A., "Review of Industrial and Process Applications of Infrared Spectroscopy," (SPIE paper 1320-01) 1990. Work mainly relates to applications under research in the United Kingdom.
- Welty, G., "When Bearings Fail...," Railway Age (December 1991) pp. 40-58.

 When journal roller bearings in railway cars fail, the \$200 components could cause millions of dollars of damage. The need for improved, early-warning, hot-bearing detectors is clear. Acoustic detectors are one approach, IR detectors are another.
- Wilson, J.S., "Thermal Analysis of the Bottle Forming Process," SPIE Thermosense XIII Conference (April 1991) pp. 219-229.

 Explains efforts at Coors to integrate IR scanners to monitor bottle production in the Vertiflow cooling system, to increase yield. Thermal imaging is used to analyze the cooling effect due to different variable changes. The goal is to achieve uniformity in the iron temperature and glass flow which improves the quality of the bottle and also allows for a reduction in the total amount of glass required for each bottle.
- Wright, J., "Infrared Measures Solder," Quality (June 1990) pp. 52-53.

 Describes how simple IR thermometers can be used potentially to meet Nave Weapons specification WS-6536E (June 10, 1985) that requires all soldering irons used on products manufactured under a Naval Air contract be checked weekly to ensure that tip temperatures meet specification requirements.
- (viii) Applications of IR Sensitive Materials in Remote Sensing

- "Airborne IR Sensors Search Out Waste Sites," Photonics Spectra (July 1991), pp. 39-42.
 - Discusses how an IRFPA based sensor is being used to scan the formerly East German countryside for forgotten toxic-waste sights. As toxic waste decomposes, it releases heat, which is shown by the sensors flown by a plane at 1000 meters altitude. A large problem was distinguishing between background noise and genuinely hotter areas. Another problem was that weather conditions, the terrain of the survey area and discovering what's naturally hot can complicate, and in some cases, increase the costs of a survey. The licensing company is booked with customers.
- Allen, A.R., S.A. Semanovich, "Thermal Analysis of Masonry Block Buildings During Construction," SPIE Thermosense XIII Conference (April 1991) pp. 99-103.
- Asker, J., "Commercial Remote Sensing Faces Challenges on Three Fronts," Aviation Week & Space Technology (July 13, 1992) pp. 53-59.

 Facing the possibility of new competitors later in the decade, the two leaders in the world satellite remote sensing market, Eosat and Spot, are planning for new technologies, grappling with US legislative uncertainly, and simultaneously nurturing established market relations while seeking new customers. IR technology is not addressed directly. Instead, the focus is on the future of the commercial satellite market.
- Asker, J., "Remote Sensing Sales Grow with Expanded Data Needs," <u>Aviation Week & Space Technology</u> (July 13, 1992) pp. 46-51.

 A survey of the most significant developments in space and information technology, along with the market trends, which will shape the space remote sensing business in the coming decade. This is a good article on the large potential for commercial satellites, and describes how new technologies will increase the versatility of the satellites, and create demand.
- Carts, Y., "Automted Spectroscopy System Measures Smog," <u>Laser Focus World</u> (June 1993) pp. 23-24. Spectrometers have been developed at the Lund Institute of Technology (Sweden) to measure a variety of atmospheric pollutants, including ozone, ammonia, nitrogen, and sulfur oxides, and aromatic hydrocarbons.
- Colantanio, A., "Metal Cladding Envelope Problems, Retrofit Solutions, and Quality Control Investigations," SPIE14 pp.64-73.

 Explains the use of IR thermography to find air leakage in complex, retrofitted, rebuilt etc. buildings.
- Everitt, J.H., "Introduction to Videography: Historical Overview, Relation to Remote Sensing, Advantages, Disadvantages," First Workshop on Videography (19-20 May 1988) 4 pgs.

 The researcher, at the US Department of Agriculture, offers an introduction to videography technology, focusing exclusively on it as a research tool.
- "Fighting Forest Fires With Remote Sensing," Photonics Spectra (August 1991), p. 66.

 A joint venture of scientists at Terra-Mar Resource Information Services and NASA's Ames Research Center plans to develop in three years a commercially viable real-time remote sensing system for monitoring such disasters as fires, oil spills, and floods. If the system works, it should take less than 30 minutes to provide fire fighters with images showing a fire's intensity and location. Current systems, relying on film, can take 6 to 12 hours.
- Fouche, P.S., "Assessment of Crop Stress COnditions by Using Low Altitude Aerial Color Infrared Photography and Computer Processing," Proceddings of the 13th Biennial Workshop on Color Aerial Photography and Videography in the Plant Sciences (6-9 May 1992) pp. 19-23.

 Infrared imagery was found useful in the detection of stress condition in various crops caused by moisture

- deficiency, nutrient deficiency, and plant diseases.
- Gordon, D.K., P.W. Mueller, M. Heric, "An Analysis of TIMS Imagery for the Identification of Manmade Objects,"

 <u>Photogrammetric Engineering & Remote Sensing</u> (December 1991) pp. 1599-1604.

 Concluded that a multispectral thermal infrared capability may have considerable value in reconnaissanc esensor packages such as Aided Target Recognition because objects such as metal- and stone-covered roofs were easily detected using the airborne Thermal Infrared Multispectral Scanner (TIMS).
- Green, R., "Remote Sensing Soars to New Heights," Photonics Spectra (August 1991) p.81.

 Leading the way to remote sensing with greater spatial, spectral and radiometric sensitivity is the Airborne Visible/ Infrared Imaging Spectrometer by the Jet Propulsion Laboratory. Using silicon and Indium antimonide line-array detectors, the instrument is bringing new capabilities to scientists studying ecology, geology, oceanography, inland water supply, snow hydrology and the atmosphere.
- Hock, J.C., "Monitoring Environmental Resouces Through NOAA's Polar Orbiting Satellites," Thermology (1: 1986) pp. 154-160.

 Good overview of the environmental monitoring missions served by infrared detectors. The MWIR and LWIR channels are mostly used for cloud and surface temperature determination, and rainfall estimates.
- Jiang, H., Y. Qian and K.T. Rhee, "High-Speed Dual-Spectra Infrared Imaging," Optical Engineering (June 1993) pp. 1281-1289.

 A nre method of achieving controlled high-speed infrared imaging is presented, which has made it possible to overcome some of the limitations in current imaging technology, particularly in disposal of high-rate data flow synchronized with the event or object being detected. This technique is employed to simultaneously capture two geometrically identical images in respective spectral bands for quantitative spectrometric data reduction.
- Jones, T,. "Lack of Photos Hurt Yellowstone Fight," Los Angeles Times (October 21, 1988) pp. 116.

 The battles against a Yellowstone national park blaze was hampered by lack of infrared aerial photos, which were slow in being supplied due to communication problems.
- Kaasinen, H.I., "Infrared Thermogrphy for Assessing the Quality of Waterproofing of Bridges Under Construction,"

 <u>SPIE Thermosense XV Conference</u> (April 1993) Paper 1933-07.

 This application appears to be very similar to roof moisture surveys, only more sophisticated and demanding of the detectors.
- Kaplan, H., "Using Laser Backscatter to Find Gas Leaks," Photonics Spectra (June 1991) pp. 98-100. Researchers at the Livermore National Laboratory developed a gas-leak detection system based on "laser backscatter/absorption gas imaging (BAGI)" for the Naval Sea Systems Command which has commercial application. It can detect gas leaks which cost companies money, and, if the gases are toxic, could detect the release of hazardous gases before anyone is harmed. The technology is being marketed by Laser Imaging Systems of Punta Gorda, FL. The systems uses a LWIR system. Article explores various applications for the BAGI system.
- Kaupinnen, R., et. al., "Renovation Concepts for Private Houses: The Use of Thermography as A Supporting Method," SPI14 pp.54-63.

 Explains various ways Finland's Department of Energy is using, and has proposed the use of, infrared imagers in weatherproofing, and checking the air-tightness of homes.

- Kettler, D.J., "Insights into Interpretability Differences Between Color Infrared Photography and Color Infrared Video Data," Proceedings of the Thirteenth Biennial Workshop on Color Aerial Photography and Videography in the Plant Sciences (6-9 May 1992) pp. 110-117.

 Typical of the many articles on detection of plant stress using near infrared video or photography. Has good review of uses and history of color infrared photography and videography.
- Knehans, A., and J. Ledford, "Impact of Aerial Infrared Roof Moisture Scans on the U.S. Army's Roofer Program," <u>SPIE Thermosense XV Conference</u> (April 1993) Paper 1933-10.
- Koskelainen, L., "Predictive Maintenance of District Heating Networks by Infrared Measurement," SPI14 pp.89-96.

 Although there were several articles over the years on this subject, the application seemed to only interest the scandinavian countries, so the application was left out of our final report.
- Lareau, A.G., "Flight Performance of an Airborne Minefield Detection and Reconnaissance System,"

 Photogrammetric Engineering & Remote Sensing (February 1991) pp. 173-178.

 Reports on how the Airborne Minefield Detection and Reconnaissance System, developed by the US Army, could succeed in detecting mines using IR technology. The system uses a passive IR linescan sensor in the LWIR. The paper reports on the performance of the system.
- Lightfoot, D., and V. Lightfoot, "Revealing the Ancient World Through High Technology," Technology Review (May/June 1989) pp. 54-61.

 Discusses how color infrared photography and videography offer a new frontier for archeologists studying and searching for ancient cultures. Features such as dwellings, agricultural fields, and footpaths have been located easily using IR imagery. Airplane archeology using IR imagery should continue, the authors predict, to be invaluable to archeologists.
- Linkous, A., B. McKnight, "Using Thermography to Detect and Measure Wall Thinning," SPIE Thermosense XV (April 1993) Paper 1933-04).

 A new buildings & structures application.
- Lyberg, M.D. and S. Ljungberg, "Thermography and Complementary Methods; A Tool for Cost-Effective Measures in Retrofitting Buildings," SPIE Thermosense XIII Conference (April 1991) pp. 104-116.
- Marsh, S.E., J.L. Walsh, C.T. Lee, L.A. Graham., "Multemporal Analysis of Hazardous Waste Sites Through the Use of a New Bi-Spectral Video Remote Sensing System and Standard Color-IR Photography," Photogrammetric Engineering & Remote Sensing (September 1991) pp. 1221-1226. Reports on a study which combined standard aerial color infarred photography, a new bi-spectral video acquisition systems, and GIS software to evaluate conditions at a waset site near Phoenix, Arizonia. Found that a video system offers several potential advantages over conventional photography for an operational monitoring program, including the immediate availability of multispectral data.
- Mausel, P.W., "Airborne Videography: Current Status and Future Perspectives," Photogrammetric Engineering & Remote Sensing (August 1992) pp. 1189-1195.

 Video imagery has only been used in remote sensing for about ten years, but new technologies, such as CCDs, offer higher resolution than had been previously available. The low resolution of videographic equipment had limited the technology's potential. Although all varieties of wavelengths are discussed, a video system used in the mid-wave IR could distinguish among plant species, determine succulent and non-succulent plant species, identify crop irrifation management potential, differentiate between variale soil surface conditions, and detect wild fires. Best survey article on the direction of photogrammetry.

- McMullan, P.C., "Masonry Building Envelope Analysis," <u>SPIE Thermosense XV Conference</u> (April 1993) Paper 1933-06.
- McMullan, P.C., "Field Documentation and Client Presentation of Infrared Inspections on New Masonry Structures," / SPIE Thermosense XIII Conference (April 1991) pp. 66-74.
- McMullan, P.C., "Case Study of Commercial Building Envelope Air Leakage Detection Using INfrared Imaging," SPI14 pp. 74-83.
- Mecham, M., "Europeans Prepare to Build on Early ERS Satellite Success," Aviation Week & Space Technology (July 13, 1989) pp. 68-69.

 The European Space Agency plans to build a second European Remote Sensing Satellite. The technology to be used (including IR) are explained, and the political and funding scenario for such a satellite are discussed.
- Morgan, W.T., "Thermographic Inspections of Air Distribution Systems," SPI14 pp. 85-8.
- Narayanan, R.M., S.E. Green, D.R. Alexander, "Soil Classifications Using Mid-Infrared Off-Normal Active Differential Reflectance Characteristics," Photogrammetric Engineering & Remote Sensing (February 1992) pp. 193-199.

 Using laser fluroescence, found that different soil samples have unique reflectance signatures in the 9-11 micron region. Recommends that wavelength's use for understanding coil composition.
- Nordstrom, R.J., "The CO2 Laser In Remote Sensing," <u>Photonics Spectra</u> (February 1992) pp.89-94

 Discusses the range of uses for the CO2 laser, which is the illuminator of choice for infrared applications because it operates optimally within the 8-12 micron range. The 8-12 micron range is called the "fingerprint region" of the spectrum because so many molecules have distinct vibration bands there. This single distinction is enough to make the CO2 an instrument of choice despite its relatively poor atmosphereic transmittance.
- Nordwall, B.D., "Airborne Surveillance Will Give Forest Service Real-Time Fire Maps," Aviation Week & Space Technology (May 29, 1989) pp. 105-107.

 Reports that the US Forest Service plans to use two aircraft equipped with dual-band IR sensors and a Navstar Global Positions System to locate fires and immediately send information to firefighters on the ground. Explains the equipment installed in two aircraft, and the techniques which have been designed for collecting and quickly relaying information to the ground.
- Olsen, J.D., "Airborne Multispectral Imaging Monitor Environment," Photonics Spectra (August 1992) p.71

 The information in the imagery significantly affected site investigations by identifying representative locations for observation and testing, detecting anomalous conditions for special investigation and refocusing investigations to an area that was initially considered fof-site. The use of remote sensing as an analytical tool resulted in reduced site-investigation time and costs, improved company and regulatory communication, and reduced time for site closure. The source of the chemical contamination at a pesticide plant was revealed on images in the near-infrared and thermal-infrared bands by vegetation stress.
- "Panel Picks Priorities for Astronomy Research," Chemical and Engineering News (March 25, 1991), pp. 6.

 A report coming from the National Research Council, entitled "The Decade of Discovery in Astronomy and Astrophysics," stresses that two technologies are liable to have the greatest impact: infrared technology and adaptive optics (that is, "giving Earth-based telescopes optics that respond quickly to eliminate atmospheric

- distorting effects.
- Parsons, M.L., et. al., "Fire Detection Systems for Aircraft Cargo Bays," (SPIE Paper 1308-29) 1990, 13pgs. Discussion of an application using linear IRFPAs designed at Pacific Scientific Co.
- Pierce, L.L., S.W. Running, G. Riggs, "Remote Detection of Canopy Water Stress in Coniferous Forests Using the NS001 Thematic Mapper Simulator and the Thermal Infrared Multispectral Scanner," Photogrammetric Engineering and Remote Sensing (May 1990) pp.579-586.

 Concluded that neither system could effectively detect moderate levels of canopy water stress, although extreme stress was easily detected.
- Proctor, P., "Japan Plans New Generation of Remote Sensing Satellites," <u>Aviation Week & Space Technology</u> (July 13, 1992) pp. 66-67.
- Schott, L.R., "Image Processing of Thermal Infrared Images," Photogrammetry Engineering and Remote Sensing (September 1989) pp. 1311-1321.

 Technical piece which discusses how to implement absolute temperature calibration algorithms, methods for registering and combining multiple thermal infrared imags, and methods for combining thermal infrared reflected visible and near-infrared data.
- Shropshire, G., and J. DeShazer, "Optical Sensors Aid Agriculture," <u>Laser Focus World</u> (May 1993) pp. 79-84. Discusses development of sensors to reduce the use of chemcials and conserve natural resources in agriculture. Optical-based sensors used in agriculture represent one area in which strides are being made to analyze and improve our environment, in soil analysis, ammonia sensing, detecting plant stress and finding weeds.
- Sopko, V., "Discussion of the Standard Practice for the Location of Wet Insulation in Roofing Systems Using Infrared Imaging (ASTM C1153-90)," SPIE Thermosense XIII Conference (April 1991) pp. 83-89.
- Sundberg, J., "Use of Thermogaphy to Register Air Temperature in Cross Sections of Rooms and to Visualize the Air Flow From Air Supply Diffusers," <u>SPIE Thermosense XV Conference</u> (April 1993) Paper 1933-08.
- Stout, A., "IR Images and Environmental Sleuths," Photonics Spectra (December 1991), p.117-120
 Discusses Nancy Del Grande, at the Lawrence Livermore Laboratory, who is putting an AGEMA infrared systems Thermovision 880 infrared burst scanner to work to search for buried and covered, as well as exposed, objects that heat and cool at rates different from those of the surrounding soil. Uses include: mine detection, aquifers, nuclear testing size verification, building structures, buried archeological sites excavation.
- Tobiasson, W., and A. Greatorex, "Use of an INfrared Scanner and a Nuclear Meter to Find Wet Insulation in a Ballasted Roof," <u>SPIE Thermosense XV Conference</u> (April 1993) Paper 1933-09.
- Tomlingson, P.D., "Predictive Maintenance: Key to an Effective, Cost-Saving Maintenance Program," Complete Building Equipment Maintenance Desk Book, S.J. Fuchs (ed.) (Prentice Hall: Englewood, N.J.) 1982 pp. 39-65.
- Tulloch, M., "IR IMaging Studies Solar Atmosphere," Photonics Spectra (September 1991) pp. 18.

 A researcher at the Smithsonian Astrophysics Observatory recorded a solar eclipse in near-IR wavelengths to detime if the sun is encircled by rings of interplanetary dust or rocks, which would be left from the early stage of development of the solar system. The camera used was based on a 128x128 lnSb focal plane array.

- Tulloch, M., "Auroral Imaging to Aid Ionosphere Monitoring," Photonics Spectra (March 1992) p.18.

 An integrated system of sensors- IR, UV, and visible, has been proposed for global space weather systems to detect occurances in the ionosphee and forecasts its fluctuations. This would help the operation of communications, navigation, and radar systems tathd epend on conditions in the Earth's upper atmosphere.
- Tulloch, M., "Photonic Technology Assists Oakland Firestorm Efforts," Photonics Spectra (December 1991) pp. 18-20.

 During an Oakland fire on October 20, research aircraft from NASA AMes Research Center tracked the firestorn with infrared scanners and camers to provide maps of the fire region. These aerial images gave fire fighters the first high-resolution overview of the firelines, hot spots and smoldering areas about to reignite.
- Vlcek, J., "Nature of Video Images," <u>First Workshops on Videography</u> (19-20 May 1988) 5 pgs.

 Focuses primarily on remote sensing aerial video, including IR, for forestly and land use applications.
- Waggoner, J., "Optical Filters a Critical Part of Environmental Monitors," <u>Photonics Spectra</u> (July 1991) p. 18. When an oil monitor is designed using an IR source, a 3.4 micron band pass filter and a detector, it is possible to easily measure concentrations as low as 1 ppm for oil. For a given absorbance signal, this simple debice is three times more sensitive than the FTIR spectrometer and ten times more sensitive than grating IR spectrometers.
- Weil, G.J., "Detecting the Defects," <u>Civil Engineering</u> (September 1989) pp. 74-77.

 Infrared thermography exposes minor structural problems before they become major catastrophes in areas such as highway pavement, sewers, bridgers, water lines. The result: lower repair costs.
- Weil, G.J., "Nondestructive Remote Sensing of Buried Tanks," <u>Unpublished</u>

 Details how infrared thermography was used during an environmental assessment of a 50 acre industrial plant site to locate buried industrial waste materials, such as underground storage tanks, and miscellaneous waste items as small as a 55 gallon drum.
- Weil, G.J., "Nondestructive Remote Sensing of Hazardous Waste Sites," <u>SPIE Thermosense XV Conference</u> (April 1993) Paper 1933-31.

 Describes EnTech Inc.'s combination Ground Penetrating Radar- IR Thermograpy technology, in use for detection of hazardous waste leaks & buried drums. Discusses the growing demand for such land surveys, and offers three case studies: a West Coast Air Force Base, a US Government testing laboratory, and a rehabilitated gasoline station.
- Weil, G.J. and R.J. Graf, "Infrared Thermography-Based Pipeline Leak Detection Systems," SPIE Thermosense XIII

 Conference (April 1991) pp. 18-33.

 Describe EnTech's technique, using GPR and IR. The technique has been used to test pipelines in chemical plants, water supply systems, steam lines, natural gas pipelines, and sewer systems. The paper details the development of a computerized system using GPR and IR, with several case studies.
- Weil, G.J., "Non-Destructive Testing of Bridge, Highway, and Airport Pavements," <u>Unpublished</u>, 13 pgs.

 Describes how GPR and IR techniques can, in conjunction, be used to inspect concrete structures rapidly and economically. Discusses in detail the requirements for an automated inspection systems, and explains with several case studies how the joint IR/GPR technique can fulfill the inspection needs.
- Wiegand, C.L., D.E. Escobar, J.H. Everitt., "Comparison of Vegetation Indices from Aerial Video and Held-held

Radiometer Observations for Wheat and Corn," <u>Proceedings of the Thirteenth Biennial Workshop on Color Aerial Photography and Videography in the Plant Sciences</u> (6-9 May 1992) pp. 99-105.

Founds that the automatic gain control in video cameras can complicate multitemporal analyses of crop health, since the overflight video imagery was much more variable day-to-day than on-ground radiometric readings. Study recommends some ways it has or recommends dealing with this auto gain control variation.

Wilson, B.A. (ed), "Sensor Systems for Space Astrophysics in the 21st Century," Workshop Proceedings from NASA conference NASA-CR-189449 (August 1, 1991) 80pgs.

This report was prepared by one of the three Integrated Technology Planning workshops initiated in 1989 by the Astrophysics Division of the Office of Space Science and Application within NASA. Its objectives were to develop an understanding of future missions requirements for electromagnetic radiation sensor systems, and to recommend a comprehensive development program to achieve the required capabilities. There is discussion of the passive IR sensors required for space in the years ahead.

(ix) Applications of IR Sensitive Materials in Surveillance

- Aikens, D.M., "Airborne Infrared and Visible Sensors Used for Law Enforcement and Drug Interdiction," <u>SPIE Conference on Surveillance Technologies</u> (April 1991) pp. 435-44.

 Discusses some of the applications of visible and IR sensors in law enforcement and the issues peculiar to their use in that community. Sensor technology which are both currently available and forthcoming are described.
- Berardomos. L.A., "No Place to Hide: The Ability to Fight at Night May have Been the Deciding Factor in the GUIf War and in Panama, but the Equipment That Makes it Possible is Still Getting Better," Machine Design (October 24, 1991) pp. 57-61.
- Blackwell, J.D., "High Performance InSb 256x256 Infrared Camera," <u>SPIE Conference on Surveillance</u> (Apri 1991) pp. 324-334.

 More a discussion of the camer's potential than a direct relation to the needs of surveillance applications.
- Bruder, J.A., et. al., "Detection of Contraband Brought into the United States by Aircraft and other Transportation Methods: A Changing Problem," <u>SPIE Conference on Surveillance</u> (April 1991) pp. 316-323. Executives at US Customs Service discuss the latest in counter-detection methods used by smugglers, and other innovative ways to avoid detection of their contraband. Intended to facilitate thinking on technologies to counter such attempts at avoidance.
- Byrd, V., "Helping Police See in the Dark," <u>New York Times</u> (September 27, 1992) pp. K9.

 Discusses NYC police use of night vision goggles to approach locales where they don't want to use a flightlight.
- Cantell, M.J., "Infrared CCD Sensor for Surveillance," <u>SPIE Conference on Surveillance Technologies and Imaging</u>
 <u>Components</u> (April 1993) 12 pgs.
- "Coast Guard Uses Hu-25 FLIR, Radar to Detect Smugglers," Aviation Week & Space Technology (January 30, 1989) pp. 42-43.

Westinghouse F-16 radar and FLIR systems have provided Coast Guard Hy-25 Falcons with the dya-night capability they need to be a more effective combat air patrol for aerial drug interdiction. Whereas radar picks up the faraway signals of suspicious planes, infrared detectors allow pursuers to sneak up without giving away their location.

- Creel, R., "Airborne Law Enforcement Association: 1992 National Database Summary," <u>Airborne Law Enforcement Association</u> (August 1, 1992) 6 pgs.

 Survey of which photonic equipment was used by the ALEA's airborne members, which were most helpful, how much money in contraband was confiscated using that equipment, how many criminals arrested with the help of that equipment, etc.
- Cullen, R.M., "Low-Cost Space Platforms for Detection and Tracking Technologies," <u>SPIE Conference on Surveillance Technologies</u> (April 1991) pp. 295-305.

 Outlines possibilities of satellites, currently and soon to be deployed, in surveillance.
- Del Grande, N.K., et. al., "Buried Object Remote Detection For Law Enforcement," SPIE Conference on Surveillance Technologies (April 1991) pp. 335-51.

 Another application for the dual-use infared detector designed by researchers at the Lawrence Livermore National Labs. Their technology could be easily modified for drug interdiction and pollution control, for finding jungle canopies and covered containers used for contraband, and to depict buried waste containers, sludge migration pathways from faulty contrainers, and the juxtaposition of groundwater channels, if present, nearly. The dual bandIR technology could detect underground epicenters of smuggling and pollution.
- Dial, O.E., "CCD Performance Model," <u>SPIE Conference on Surveillance Technologies</u> (April 1991) pp. 2-11. Relates CCD technology to applications in surveillance.
- Elerding, G.T., J.G. Thurnen, L.M. Woody, "Wedge Imaging Spectrometer: Application to Drug and Pollution Law Enforcement," <u>SPIE Conference on Surveillance Technologies</u> (April 1991) pp. 13 pgs.

 Designers at Hughes Aircraft have invented the wedge imaging spectrometer which is compact and rugged, and suitable for use in drug interdiction and pollution monitoring activities by detecting small quantities of gases remotely. Uses a focal plane array.
- "EMS Pilots Disagree on Value of Night-Vision Goggles," <u>Helicopter News</u> (October 30, 1992) pp. 1,4.

 Reports on the reactions of aeromedical pilots meeting at annual AIr Medical Transport Conference in Salt Lake City, Utah, to night vision goggles. Older pilots who used earlier NVGs disliked the technology, and constituted the majority of attendees.
- Frank, J., "Out of the Darkness," <u>Security Management</u> (August 1991) pp. 45-47.

 Discusses how focal plane array-based surveillance cameras could revolutionize nighttime security.
- "Gotcha, for Now," The Economist (March 11, 1989) pp. 32.

 Since police can no longer count on radar to detect speeders, since almost 15 percent of drivers use radar detectors, their newest weapon is a speed detector that uses infrared lasers, which of course, cnannot be sensed by radar detectors. The system, however, does not use focal plane arrays. The article is included because several people had suspected that IR could be used to detect speeding vehicles.
- Henderson, B.W., "Radar/Digital Adapting P-3 AEW Radar for Small Drug Interdiction Aircraft," Aviation Week & Space Technology (Feburary 24, 1992) pp. 128-29.

 Radar/Digital Systems is developing a system that will allow drug enforcement officlas on small aircraft to combine radar and FLIRS on a single display. The system would make it easier for drug agents to track smugglers and force them to land.
- Holton, W.C., "Tales From the Dark Side: Shedding New Light on Crime: Photonics Joint the Law Enforcement Arsenal," <u>Photonics Spectra</u> (December 1992) pp. 52-61.

- Extensive coverage of photonics technologies applied to law enforcement and surveillance, especially focal plane array based cameras for drug interdiction and police use.
- "IR, Optical Sensors Search Out Drug Labs" OE Reports (July 1992) 4.

 This is an interview with Michael Calvert (a special agent with the California Department of Justice supervising a clandestine drug laboratory investigation team) and Nancy Del Grande (principal investigator for the FAA- sponsored Dual-Band IR Imaging for Aging Aircraft Inspection Project).
- Johnson, C., "Police Tools of the 90's Are Highly Advanced, but Privacy Laws Lag," Wall Street Journal (November 12, 1990) pp. A1, 10.

 Discusses upcoming police use of Unmanned Aerial Vehicles for surveillance, which have on-bard high resolution cameras, infrared detectors, and chemical sensors.
- Kulp, T.J., et. al., "Application of Backscatter Absorption Gas Imaging to the Detection of Chemicals Related to Drug Production," SPIE Conference on Surveillance (April 1991) pp. 352-363.
 A gas detection system originally designed by the Lawrence Livermore National Labs, and transferred to Laser Imaging Systems, could be used in the surveillance of suspected drug production sites.
- Laband, S., "IR Imaging For Autonomous Pole-Mounted Surveillance," <u>Photonics Spectra</u> (January 1993) pp. 146.

 Discusses Amber's new Radiance 1 surveillance camera which is lightweight, rugged, easy to install, etc., compared with older IR systems.
- Lytle, David, "Night-Vision Devices Head for Civilian Market," <u>Photonics Spectra</u> (May 1991), pp. 68.

 A brief article which explains that the Army's decision to declassify its uncooled thermal imaging sensor technology will encourage a slew of commercial spinoffs of its night vision: for police and fire department use, and for vision enhancers for nighttime drivers.
- "Marines Respond to EMS Debate; Defend Night Vision Goggles," Helicopter News (March 19, 1993) pp. 8.

 Two officers in the US Marine Helicopter Squadron One argue that the new night vision goggles can offer great potential in EMS missions. The FAA, however, remained steadfast in opposing NVGs, considering them unsafe for civilian operations.
- Mataloni, R.J., "Application of Lighter-than-Air Platforms to Law Enforcement," S{IE Conference on Surveillance Technologies (April 1991) pp. 306-315.

 Discusses possibilities for floating balloons and other platforms in aerial surveillance, including the use of IR detectors.
- May, C., "New Devices May Stop More Bombs at the Gate," New York Times (December 25, 1988) pp. 11.

 Pan Am World Airways flight that crashed in Scotland gave impetus to installation of new devices to stop bombs at airports, including TNA explosive detectors and infrared sensors.
- McCauley, H., Auborn, J., "Image Enhancement of Infrared Uncooled Focal Plane Array Imagery," SPIE Conference on Surveillance Technologies (April 1991) pp. 416-422.

 Proposes several low-cost algorithms to enhance uncooled FPA imagery.
- Office of National Drug Control Policy, Counter-Drug Technology Assessment Center, Executive Office of the President, "Broad Agency Announcement BAA 92-15" 1992, 5 pgs.

 Agency announcement for proposals from industry for technologies in four counter-drug areas: non-intrusive inspection, wide area surveillance, targeting of drug organizations, and demand reduction.

- Robinson, C.A., "Arcane Science Sparkes in Drug Enforcement War: October Confab Showcases Array of Science to Stanch Contraband Flow," Signal (August 1992) pp. 21-27.

 Preview of various innovative technologies to be shown in October 1992 international meeting on contraband and cargo inspection. No discussion of IR technologies; they would not be helpful in this area.
- Williams, R.H., "The US Customs Service Spearheads the Drug War," <u>Signal</u> (December 1990) pp. 52-54. Overview of technologies used by US Coast Guard for drug interdiction. Includes list of equipment used, such as infrared cameras.
- Yanagimoto, S. and Seiji Yamamoto, "Thermal Imagers for Security Systems," Mitsubishi Electronic Advances (June 1991) p.2-4.

 Security systems are becoming common in an ever widening variety of fields, the environments in which they are set are becoming more diverse, and these conditions are feeding a growing demand for video-surveillance systems that can exhibit more powerful monitoring functions under lightless conditions. This article describes the basic functions of the IR-5120C, and describes how it can be used in the security field.

(x) Applications of IR Sensitive Materials in Transportation

A comparison is made with infrared imaging.

and fiber optic data buses.

- Appleby, R., et. al., "High Performance Passive Millimeter-Wave Imaging," Optical Engineering (June 1993) pp. 1370-1373.
 Discusses the current status of passive MMW radiometry as a thermal imaging technique, which is a technology competing with IR cameras for airplane enhanced vision systems. The major problems are poor spatial resolution and slow response time. Techniques for overcoming these difficulties are identified, including the use of aperture synthesis, multichannel receivers, correlation, and inverse transform techniques.
- "Army Promotes Defense Technologies for US Automakers," <u>Aerospace Daily</u> (March 9, 1993) pp. 382.

 The Army showed off a number of defense technologies, including virtual prototyping, infrared focal plane arrays, and obstacle avoidance, that it believes could meet the needs of the domestic auto industry. They presented at the Automotive Technology Exposition at the University of Michigan, by the invitation of the sponsor, the US Council for Automotive Research.
- Commander, U.S. Army CECOM, "Request for Procurement for Driver's Vision Enhancer (Solicitation Number DAAB0793RK007)," 2 March 1993.
- Dornheim, M.A., "MMW Radar Shows Commercial Utility," <u>Aviation Week & Space Technology</u> (November 2, 1992) pp. 55-59.

 The joint FAA/Defense Department/industry synthetic vision systems technology program for EVS is leaning towards radar rather than IR technology because it produces better images.
- Figueroa, L., et. al., "Photonics Technology for Aerospace Applications," <u>Photonics Spectra</u> (July 1991) pp. 117-124.

 Introduces several sophisticated control and communications systems for future aircraft and space systems. Includes fly-by-wire flight control systems, fiberoptic position sensor technology, multiplexing technology,
- Holusha, J., "Infrared Rays May Improve Night Driving," New York Times (October 28, 1987) pp. D8.

 General Motors Corp. and US automotive industry predict use of infrared lights to greatly improve night vision by year 1990!

- Hughes, D., "Affordable Systems to Drive Civil, Military Electronics," Aviation Week & Space Technology (September 7, 1992) pp. 87-90.

 Illustrates how formerly military-only firms are moving into the commercial sector with the enhanced vision system. Contrasts milimeter-wave technology with infrared; discusses firms in alliances to meet anticipated EVS demand.
- Judycki, D., Euler, G., "The Intelligent Vehicle-Highway Systems Program in the United States," <u>U.S. Department of Transportation</u>, Federal Highway Administration (Unpublished) 15 pgs.

 A complete overview of the IVHS program, discussing all programs, funding sources and scenarios, the role of private industry, and plans for the future.
- Nordwall, B.D, "HUD With IR System Extends Pilot Vision," <u>Aviation Week & Space Technology</u> (February 22, 1993) pp. 62-63.

 Reports on research at the Maryland Advanced Development Laboratory on enhanced vision systems combining heads-up displays with IR imagers.
- Scott, William B., "Hughes Testing Radar, IR Sensors to Aid Reduced-Visibility Landings," Aviation Week & Space Technology (May 6, 1991), pp.49-50.

 Hughes' new Commercial Division is seeking to further develop an IR sensor prototype which will permit commercial aircraft to land autonomously in adverse weather conditions, when pilot vision is limited. This reflects Hughes' desire to move towards a 60/40 mixture of military/commercial business by the mid-90s. The division is a bellweather for Hughes because the commercial avionics equipment is a departure from the usual military market.
- Shoemaker, C., "DoD Unmanned Ground Vehicle Program," <u>IVHS America Third Annual Meeting</u> (April 14-17, 1993) 12 pgs.
- Shulman, M., "AVCS From the Automobile Companies' Perspective," IVHS America Third Annual Meeting (April 14-17 1993) 15 pgs.

 Overview of automobile companies' desires and technological challenges regarding the advanced vehicular collision avoidance system, which is part of the IVHS plan. Mentions briefly IR technologies for aided vision.
- Tulloch, M., "Intelligent Vehicle Highway System," Photonics Spectra (February 1992) p.18

 Discusses Siemen Automotive's new IVHS technology, which will integrate IRFPAs for various systems for guidance, lane reading, collision avoidance, etc.
- "Using Cameras to See a Foggy Road," New York Times (August 8, 1990) D7.

 Engineers at BMW are working on a system using video and infrared cameras to improve automobile drivers' perception of the road under conditions of poor visibility.
- Welch, S.S., Sensors and Sensor Systems for Guidance and Navigation, (SPIE: WA) April 1992.

 The recent growth of the number of applications for sensors in guidance and navigation has spawned a rapid development of technology. This proceedings presents the latest developments in sensor technology and applications. Papers discuss design, integration, characyterization, materials, and sources for sensors operating in the IR, millimeter, radar and acoustic regimes. Several papers report innovative technology, emphasizing new materials and novel approaches to sensing, miniaturization, new sources, and signall processing.

Yazigi, M.P., "Promethean Plans for the Next Generation of Cars," New York Times (September 13, 1992) pp. E14.

A European project called Prometheus, which stands for Program for European Traffic of Highest Efficiency and Unprecedented Safety, is said to be perhaps the largest effort currently undertaken to equip automobiles with such devices as radar, lasers, and infrared cameras that are intended to enhance traffic safety. Some of the technology being put to use in the Prometheus project is discussed.

Appendix D Private Organizations Carrying out Research on Applications of Infrared Materials Database

Organization:

Acme-Ceveland Corporation

Component:

Namco Controls Division

Address:

7567 Tyler Blvd.

Contact:

Mentor, OH 44060 Jon Slaybaugh

Position:

Jon Slaybaugh General Manager

Notes:

Product oriented R&D of electronic measurement and control devices including photoelectric sensors, laser guidance, identification and tracking

devices.

Organization:

Adcole Corporation

Component:

Address:

669 forest St.

Marlborough, MA 01752

Contact: Position:

AD Cole President

Notes:

Research on sun sensing systems, scientific instruments for rockets and

satellites, linear and radial electro-optical measuring techniques, computer

controlled cylindrical coordinate gauging equipment.

Organization:

Advanced Design Corporation

Component:

Address:

8560 Cinderbed Rd

Newington, VA 22122

Contact:

Michael Coleman

Position:

Direng

Notes:

Product oriented electro-optics; night vision devices both image intensification

and thermal imaging.

Organization:

Advanced Kinetics

Component:

Address:

Unit 108, 18281 Gothard St.

Huntington Beach, CA 92648

Contact:

Ronald Huynh

Position:

Pres

Notes:

Research in laser physics and applications, including IR sources (black bodies).

Advanced Technology Materials

Component:

Address: 520-B Danbury Road

New Milford, CT 06776

Contact: Position: Glenn Tom VPres Research

Notes:

Recently awarded an SDIO contract to develop a new electronic thin-film

material to improve IR detector technology. The company will focus on using barium strontium titanate to develop new sensors capable of operating at

room temperature.

Organization:

Advanced Technology Materials

Component:

Semiconductor Products Department

Address:

7 Commerce Drive

Danbury, CT 06810

Contact: Position: C.P. Beetz, Jr.

Notes:

Mr.

Co-authored for 1992 SPIE meeting on IRFPAs "Buffer Layers for Deposition

of Supercondcuting YBaCuO Thin Film on Polycrystalline Diamond"

Organization:

AEG

Component:

Address:

D-7100 Heilbronn

GERMANY

Contact:

H. Maier

Position:

Notes:

Co-authored for 1991 MCT Workshop "Influence of Resonant Defect States

on Subband Structures in HgCdTe"

Organization:

AEG

Component:

Address:

D-7100 Heilbronn

GERMANY

Contact:

H. Maier

Position: Notes:

Co-authored for 1991 MCT Workshop "Influence of Resonant Defect States

on Subband Structures in HgCdTe*

Aerodyne Research, Inc.

Component:

Address: 45 Manning Rd.

Billerica, MA 01821-3976

Contact:

Roger Putnam

Position:

Director of Marketing

Notes:

Basic and applied product-oriented research in electro-optical and photooptical systems, combustions, atmospheric, and environmental science; molecular physics; laser development; spectroscopy; product surface chemistry;

optical signal processing; optical computing.

Organization:

Acrojet Corp.

Component:

Electronic Systems Division

Address: Contact:

Azuza, CA H. Vydyanath

Position:

Mr.

Notes:

Co-authored for 1992 MCT Workshop "Photo-Induced Excess Low Frequency

Noise in HgCdTe Photodiodes"

Organization:

Affiliated Manufacturers, Inc. (AMI)

Component:

Address:

PO Box 5049

North Branch, NJ 08876

Contact:

B Austin

Position:

CEO

Notes:

Process and manufacturing considerations of the microelectronics

manufacturing industry; innovative manufacturing processes; thick film hybrid

circuits.

Organization:

Agema Infrared Systems

Component:

Address: 550 County Avenue.

Secaucus, N.J. 07094

Contact:

Philip Smith

Position:

President

Notes:

Manufactures infrared thermal imaging systems for condition monitoring,

process monitoring and control, military/ defense research, surveillance and the

nondestructive meeasurement and analysis of materials and components.

Agema IR Systems

Component: Address:

550 County Avenue

Secaucus, NJ 07094

Contact:

Jay Lcvy

Position:

Communications Director

Notes:

Organization:

AGR International, Inc.

Component:

Address:

PO Box 149

Butler, PA 16003-0149

Contact:

John Wasylyk

Position:

Director of Research

Notes:

Development of optical inspection techniques for process control in glass

container manufacturing.

Organization:

AIL Systems, Inc.

Component:

Address:

Commack Road

Deer Park, NY 11729

Contact:

Harvey N. Kreisberg

Position:

Director Corporate Development

Notes:

Manufactures Infrared systems & equipment, alongside RF & Microwave and

other passive and active systems

Organization:

Air Products and Chemicals, Inc.

Component:

Gas Group

Address:

7201 Hamilton Blvd

Allentown, PA 18195-1501

Contact:

Brian Rushton

Position:

VP R&D

Notes:

Applications R&D for infrared spectroscopy.

Alabama University in Huntsville

Component:

Address: Huntsville, AL

Contact: Position:

Notes: Authored "Focal Plane Array Testing Support" in January 1992, 55 pages. No

author given.

Founded in 1985, the center has programs in nonlinear optics, crystal growth, high Tc superconducting infrared detectors, and optical design. Adjacent to the NASA Marshall Flight Center, US Army Missile Command, and US Army

Strategic Defense Command.

Organization:

Alcan Aluminum Limited

Component:

ManLabs 21 Erie St.

Address:

Cambridge, MA 02139

Contact:

David Morton

Position:

CEO

Notes:

Basic applied and product oriented research in metals, alloys, ceramics, and

electro-optical materials.

Organization:

Alcatel Bell-SDT S.A.

Component:

Address:

101, rue Chapelle Beaussart

6032 Mont-Sur-Marchienne BELGIUM

Contact:

J.P. Rasquin

Position: Notes: Directeur Departement de Desense Infrared Systems and Equipment

Organization:

Allen Infrared Associates

Component:

Address:

RR #1, Box 239K

Coward, SC 29530

Contact:

Lec Allen

Position:

Mr.

Notes:

active in infrared predictive maintenance

Alliant Techsystems

Component: Address:

5901 Lincoln Drive Edina, MN 55436

Contact:

Cathy Rude

Position:

Marketing Communications

Notes:

Thermal Imaging, Night vision, detectors and sensors

Organization:

AlliedSignal Aerospace

Component:

Address:

2525 W. 190th Street Torrance, CA 90504

Contact: Position: John V. Alexander Public Relations

Notes:

Thermal IMaging, detectors and sensors,

Organization:

Component:

Alpha Omega Instruments Corp

Address:

253 Mansfield Drive, P.O. Box DE

Norton, MA 02766

Contact:

RIchard Buonauito

Position:

Mr.

Notes:

Has developed an approach to manufacturing a low cost, two-dimensional array uing lead selenide or other resistive type detectors, with a targeted

manufacturing cost of under \$500 in quantitities

Organization:

Alturdyne

Component: Address:

8050 Armour

San Dicgo, CA 92111

Contact:

Frank Verbeke

Position:

President

Notes:

Infrared systems and equipment

Amber Engineering

Component: Address:

5756 Stonewood Drive

Goleta, CA 93117

Contact:

Stan Laband

Position:

Marketing Director

Notes:

Participant in DARPA's IRFPA team and producer of InSb used in medium-

wave infrared systems.

Organization:

American Electronic Laboratories, Inc.

Component:

Address: 305 Richardson Rd., PO Box 552

Landsdale, PA 19446

Contact:

Dr Leon Reibman

Position:

CEO

Notes:

Diversivied R&D and manufacturing organization specializing in state-of-theart equipment for military and industrial applications, electronic warfare and electronic warfare support measure systems, radar and fire control, antennas, supplies, technical service, system engineering services and manufacturing

services.

Organization:

American Interplex Corporation Laboratories

Component:

Address: 8600 Kanis Rd.

Little Rock, AR 72204

Contact:

Asa Morton

Position:

Pres

Notes:

R&D on thermal properties of various metals and metal coatings; research in

infrared spectroscopy and monitoring using infrared technologies.

Organization:

American Magnetics Inc

Component: Address:

PO Box 2509

Oak Ridge, TN 37831-2509

Contact:

 $(\mathcal{M}_{i}) \neq \emptyset$

Position:

Notes:

cyrogenic equipment

American Risk Management Corp.

Component:

Address: 4807 Rockside Road, Ste 500

Cleveland, OH 44131

Contact:

Ronald Lucier

Position:

Mr.

Notes:

infrared non-destructive evaluation

Organization:

American Telephone and Telegraph

Component: Address:

AT&T Bell Labs
600 Mountain Ave.

Murray Hill, NJ 07974

Contact:

Robert Allen

Position:

CEO

Notes:

Wide range of research in electronics, focusing on emerging technologies

including opto-electronics.

Organization:

Amherst Systems, Inc.

Component:

Address:

30 Wilson Road

Buffalo, NY 14221

Contact:

Robert L. Cockrell

Position:

Director, Business Development

Notes:

Passive and Active electro-optical systems, infrared systems & equipment

Organization:

AMOCO Corporation

Component:

Solarex Corp

Address:

1335 Piccard Dr.

Contact:

Rockville, MD 20850 John Wohlgemuth

Position:

John Wohlgemuth
Head of R & D

Notes:

Applied R&D including photovoltaic devices and power systems.

Amorphous Materials Inc.

Component:

Address: 3130 Benton Street

Garland, TX 75042

Contact:

A. Ray Hilton President

Position: Notes:

Infrared materials production of CdTe, GaAs, and silicon.

Organization:

AMP Incorporated

Component:

AMP Technology, Electro-optics Division

Address:

PO Box 3608

Harrisburg, PA 17105-3608

Contact:

J Hassan

Position:

Vice President for Technology

Notes:

Applied and product-oriented research and development on fiber optic,

electro-optic, passive, and interconnection devices.

Organization:

Amteck

Component:

Address:

Paoli, CA

Contact:

Position:

Notes:

Development of CdTe arrays for solar applications.

Organization:

Anacon Corp.

Component:

Address: 117 S St.

Hopkinton, MA 01748

Contact:

Theodore Prophet

Position:

Notes:

Applied research on refractometers; chlorine monitors; stack gas monitors;

ultra-violet and infrared analyzer.

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Andersen Group

Component: Address:

1280 Blue Hills Ave.

Bloomfield, CT 06002

Contact:

Francis Baker

Position:

CEO

Notes:

Research and development in photonics, telecommunications and high tech

industries.

Organization:

Andersen Instruments, Inc.

Component:

Nutech Corporation 2806 Cheek Rd

Address: 2806

Durham, NC 27704

Contact:

Reggie Stroupe

Position:

Pres

Notes:

Applied and product-oriented research in the areas of air pollution sampling,

filter systems, electronic sensors and controls, temperature control,

chromatography, and laboratory research instruments, medical electronics and

mass spectrometry.

Organization:

Andorian Cyrogenics Inc

Component:

Address:

26 Farwell Street

Newtonville, MA 02160

Contact:

Position:

Notes:

cyrogenics equipment

Organization:

Angstrom Technologies, Inc.

Component:

Address:

PO Box 607

Florence, KY 41042

Contact:

Keith Seybald

Position:

Melec Melec

Notes:

Basic and applied electro-optical vision for robotics and automated guided

vehicles; applied and product-oriented research in packaging and material

handling vision systems.

Applied Electron Corp.

Component:

Address: 2360 Owen Street

Santa Clara, CA 95054

Contact:

Francis Ziemba

Position:

VP

Notes:

Product-oriented research in the field of radiation detection, both nuclear and optical, including alpha, gamma, x-ray and radon detection, also near IR to

ì

visible optical radiation detection.

Organization:

Applied Materials, Inc.

Component: Address:

3050 Bowers Ave.

Santa Clara, CA 95054

Contact:

James Morgan

Position:

President

Notes: Research on chemical vapor deposition and plasma etching processes materials

and equipment, with particular emphasis on semiconductor materials, metals and dielectrics for the electronics industry, ion implantation of dopauts into

silicon and process control equipment.

Organization:

Applied Solar Energy corporation

Component:

Address:

15251 E Don Julian Rd.

City of Industry, CA 91749

Contact:

Gerard McLarhon

Position: Notes: CEO

Product oriented R&D of solar laser detector products.

Organization:

Component:

Arco Solar Inc

Address:

4650 Adohr Ln., PO Box 6032

Camarillo, CA 93010

Contact:

Charles Gay

Position:

Pres ;

Notes:

Advanced and applied research and development of photovotaic devices and systems. Production continues of square foot panels with Commer Indium

systems. Production continues of square foot panels with Commer Indium Disclenide (CIS) coated with Cadmium Sulfide. CIS is increasingly viewed as

the most promising material for solar power.

Aritech

Component: Address:

Aritech Corporation 1510 Tate Blvd., SE

Hickory, NC 28603

Contact:

David Miller

Position:

Gmgr

Notes:

Sensor detector and alarm system equipment.

Organization:

Component:

Arizona State University

Address:

Contact:

M.C. Shaw

Position:

Notes:

Co-authored 1983 "Application of Infrared Radiation Measurements in

Grinding Studies"

Organization:

Arvin Industries, Inc

Component:

Franklin Research Center

Address:

2600 Monroe Blvd.

Norristown, PA 19403

Contact:

Charles Stokes

Position:

Dir

Notes:

Applied research, design, and development in electronic and electrical

engineering, including electro-optics.

Organization:

Astronautics Corporation of America

Component:

Address:

4115 N. Teutonia

Milwaukee, WI 53209

Contact:

P.D. Zingen

Position:

Marketing Coordinator

Notes:

Night vision, robotics, security systems, ASW equipment, infrared systems &

equipment

119791 33 , attaca or January Line

E #31681 2

AT&T Bell Laboratories

Component:

Address: Murray Hill, NJ 07974

Contact:

B.F. Levine

Position:

Мг.

Notes:

Organization:

ATD, Inc.

Component:

Advanced Technology Division

Address:

PO Box 566

Woodinville, WA 90872

Contact:

Kenneth Kaylor

Position:

COO

Notes:

Applied R&D of video instrument systems including high-speed, IR

microscopic and related research.

Organization:

Atlantic Research Canada, Inc.

Component:

Address: 1900 City Park Drive, Suite 400

Gloucester, Ontario CANADA KIJ 1A3

Contact:

Tony Canning

Position:

Mr.

Notes:

Thermal Imaging

Organization:

Atomergic Chemetals Corporation

Component:

Address:

222 Sherwood Avenue

Farmingdale, NY 11735

Contact:

M. Hollander

Position:

National Sales Manager

Notes:

Material processing of CdTe, GaAs, Germanium, Silicon, ZnS, and ZnSe.

Auburn University

Component:

Address:

Contact:

P. Bancriee

Position: Notes:

Co-authored 1991 "Weld Quailty Control in Gas Tungsten Arc Welding Process*

Organization:

Auburn University

Component: Address:

Materials Engineering Dept

201 Ross Hall

Auburn, AL 36849-5351

Contact:

Brian Chin

Position:

Notes:

active in infrared process control

Organization:

Aurora Technoligies Corp.

Component:

Address:

San Diego, CA 92121-2410

Contact:

F.P. Doty

Position:

Mr.

Notes:

Co-authored for 1991 MCT Workshop "Properties of CdZnTc Crystals Grown

by a High Pressure Bridgman Method"

Organization:

Automatic Switch Co

Component:

Address:

50-60 Hanover Road

Florham Park, NJ 07932

Contact:

Position:

Notes:

cyrogenic equipment

AUTOMETRIC, INC.

Component:

Address: 5301 SHAWNEE ROAD

ALEXANDRIA, VA 22312

Contact:

DAVID K. GORDON

Position:

Notes:

ACTIVE IN INFRARED REMOTE SENSING

Organization:

Avimo USA, Inc.

Component:

Address:

716 S Milwaukee Ave.

Wheeling, IL 91702

Contact:

Brad Doetzel

Position:

CEO

Notes:

Product oriented research in night vision optics and custom optical

components, used mainly by the military.

Organization:

Baird Infrared Technology, Inc.

Component:

Address:

110 South Poplar Street #310

Wilmington, DE 19801-5046

Contact:

George S. Baird

Position:

Mr.

Notes:

active in infrared predictive maintenance

Organization:

Component:

Baker Hughes, Inc.

Address:

TN Technology, Inc. PO Box 800, Round Rock

TX 78680-0800

Contact:

Dr John Nelson

Position:

VP

Notes:

Applied R&D of radiation detectors and sources, acoustical transducers, and

measurements and data processing methodolgy directed toward the

development of instrumentation for the measurement of industrial process

parameters.

Ball Electro-Optics and Cryogenics Div.

Component:

Address: P.O. Box 1062

Boulder, CO 80306

Contact:

Terry Fleener

Position: Manager, Business Development

Notes: Thermal Imaging, Active and Passive EO systems

Organization:

BASF Corporation

Component: Coatings Technical Center

Address: 26701 Telegraph Southfield, MI 48034

Contact: Position: A.C. Ramamurphy

Position

infrared non-destructive evaluation

Organization:

Batelle Memorial Institute

Component: Address:

Electronic Systems

505 King Ave.

Contact: Columbus, OH 43201
Contact: James Sorenson

Position: General Manager

Notes: Advanced development and integration of complex electronic and optical

systems; development of large laser materials for interaction studies;

automated inspection systems and optical systems for tracking reentry vehicles.

Organization:

Component:

Bath Electrical Systems

Address:

5009 N Hwy 288 B, PO Box 198

Clute, TX 77531

Contact:

Thomas Soderman

Position:

Pres

Notes:

Design and development of systems for infrared scanning for energy losses

25 27

problems.

Battelle Memorial Institute

Component:

Address: 505 King Avenue

Columbus, OH 43201-2693

Contact:

Milton Seiler

Position:

Mr.

Notes:

infrared non-destructive evaluation

Organization:

BDM Federal, Inc.

Component:

Address:

1501 BDM Way

McLean, VA 22102-3204

Contact:

Duncan Campbell

Position:

Corp. V.P.

Notes:

Thermal Imaging, imaging software

Organization:

BEI Electronics Company, Inc.

Component: Address:

BEI Defense Systems Company, Inc. 11312 S Pipeline Rd., PO Box 155429

Contact:

Fort Worth, TX 76155

Position:

Michael Florimbi **CEO**

Notes:

Product-oriented research, development, testing and evaluation on

photoelectric shaft position encoders.

Organization:

Belov Technology Co. Inc.

Component:

Address:

345 Sandford Street

New Brunswick, NJ 07891

Contact:

Valery Belov

Position:

President

Notes:

Manufactures MCT, DTGS, TGS pyroelectric detectors and detector electronic

systems, and multi-element arrays. MCT room temperatuer detectors.

Related components.

Bertram Laboratories, Inc.

Component:

Address: 72 Readington Road

Somerville, NJ 08876

Contact: Position:

Leslie G. Polgar Vice President

Notes:

Organization: Component:

Bethlehem Steel Corporation Homer Research Laboratories

Address: Contact:

Bethlehem, PA 18016 Dr. Malcom Roberts

Position:

Dirres

Notes:

Investigation on new methods of measurement and instrumentation used in

the control of steel processes and product quality.

Organization:

BHP Research

Component:

Melbourne Laboratories

Address:

P.O. Box 264

Clayton, 3168, AUSTRALIA

Contact:

H. Buskes

Position:

Mr.

Notes:

Co-authored for 1992 MCT Workshop "In-Sity Ellipsometric Measurements of

the MBE Growht of CdTe/HgTe and CdTe/ZnTe Superlattices"

Organization:

Bio-Rad Laboratories

Component:

Sadtler Research Laboratories

Address:

3316 Spring Garden St. Philidelphia, PA 19104

Contact:

Richard Shaps

Position:

Dvmgr

Notes:

Raman and infrared spectroscopy.

 ${\bf Organization:}$

BMA Inc

Component:

PO Box 562

31 Willows Road Ayer, MA 01432

Contact:

Address:

Position:

Notes:

cyrogenic equipment

Organization:

Bobbit Laboratories

Component: Address:

Viggo-Spectramed 1900 Williams Dr.

Oxnard, CA 93030

Contact:

Michael Magers

Position:

Dirte

Notes:

Instrumentation and precise measurement using advanced systems, including

infrared sensors.

Organization:

Boston Electronics Corp.

Component:

Address:

72 Kent Street

Brookline, MA 02146

Contact:

Position:

Notes:

Manufacture and use of germanium and silicon.

Organization:

Component:

Brimrose Corporation of America

Address:

5020 Campbell Blvd

Contact:

Baltimore, MD 21236 John Kasprazak

Position:

Marketing Director

Notes:

Brooklyn College

Component:

Semiconductor Institute

Address:

Brooklyn, NY

Contact:

Fred H. Pollak

Position:

Dr.

Notes:

Former director of the SPIE

Organization:

Brown Group, Inc.

Component:

Research and Development Laboratory

Address:

8400 Maryland Ave. Saint Louis, MO 63166

Contact:

Lloyd Brunkhorst

Position:

VPcng

Notes:

Basic research for new manufacturing processes.

Organization:

Brown University

Component:

Address:

Providence, RI Donald E. McClure

Contact: Position:

Notes:

AUthored "Image Acquisition and Processing Equpipment for Machine

Vision" September 1990

Organization:

Component:

Brunson Instrument Co, Inc

800 E 23rd PO Box 7951

Contact:

Address:

Kansas City, MO 64129

Position:

Gary Powell

Dreng

Notes:

Research, design, and development in the optical mechanical and electro-

optical field, circular and linear developing.

Brunswick Technical Group

Component: Address:

1 Brunswick Plaza Skokie, IL 60077

Contact:

Diane R. Sheerar

Position: Notes:

Manager Marketing Services Infrared Systems and Equipment

Organization:

Component:

BSA Technology, Inc.

Address:

3812 Sepulvida Blvd, Stc 500

Torrance, CA 90505

Contact: Position: Notes:

Organization:

Buck Werke GMBH & Co.

Component:

Address:

Hans-Buck-Strasse 1

D-7844 Neuenburg, GERMANY

07631

Contact:

Walter Hanser Position: Marketing Director

Notes:

Services, Infrared Systems and Equipment

Organization:

Component:

Address:

Burleigh Instruments, Inc

Burleigh Park

Contact:

Fishers, NY 14453-9999

Position:

Notes:

Elius "ถามะ

Burleigh Instruments, Inc.

Component:

Burleigh Park

Address: Fishers, NY 14453

Contact:

Ronald Autos

Position:

drR&D

Notes:

Product oriented research in lasers, optical equipment, and micropositioning

equipment.

Organization:

California Institute of Technology

Component:

CA

Address: Contact:

R.W. Capps

Position:

Notes:

Co-authored for 1990 IEEE Meeting on Advanced IR Detectors "Space

Science APplications of Infrared Detector Technology: A Review"

Organization:

California Institute of Technology

Component:

Jet Propulsion Laboratory

Address: Contact: Pasadena, CA 91109 Anthony C. Ibbott

Position:

Mr.

Notes:

active in infrared remote sensing

Organization:

California Institute of Technology

Component:

Jet Propulsion Laboratory

Address:

4800 Oak Grove Drive

Pasadena, CA 91009-8099

Contact: Position: Marija S. Scholl

Notes:

Editor of upcoming January 1994 edition of the SPIE's Optical Engineering

journal, focusing on infrared technology.

Cambridge University

Component:

Cavendish Lab

Address:

Cambridge, UNITED KINGDOM

Contact:

T.D. Golding

Position:

Notes:

Co-authored October 1988 "MBE of HgCdTc"

Organization:

Component:

Carl Zeiss

Address:

Sondertechnik Postfach 1380

7082 Oberkochen, GERMANY

Contact:

Peter Albers Sales Manager

Position: Notes:

Thermal Imaging, Detectors and Sensors, Night Vision

Organization:

Carnegie-Mellon University

Component:

Robotics Institute Pittsburgh, PA

Address:

C. Caillas

Contact:

Position:

Notes: Auth

Authored an APril 1990 study, 100 pages, on "Thermal Imaging for Robotic

Applications in Outdoor Scenes"

Organization:

CEI Technologies, PTE Ltd.

Component:

Address:

249 Jalan Boon Lay

Singapore 2261

Contact:

Toh Kim-Huat

Position:

V.P./ General Manager

Notes:

Thermal imaging, night vision

Cerac Inc.

Component:

Address:

Milwaukce, WI

Contact: Position:

Notes:

Manufacturer of infrared materials.

Organization:

Channel Technologies

Component:

Electro-optical Industries, Inc.

Address:

859 Ward Dr.

Santa Barbara, CA 93111

Contact:

Arthur Cussen

Position:

Pres

Notes:

Research on infrared and visible blackbody radiant energy standards,

radiometry, electro-optical instrumentation, microwave standards, low-level instrumentation, industrial temperature measurement, and radiation

thermometry.

Organization:

Chemring, Ltd.

Component: Address:

Alchem Works

Fratton Trading Estate

Portsmouth, Hampshire, ENGLAND PO4 8SX

Contact:

David Radford

Position:

Marketing Director

Notes:

Infrared Systems & Equipment, passive EO systems

Organization:

CIC International, Ltd.

Component: Address:

38-01 23rd Avenue

Astoria, NY 11105

Contact:

James Chladek

Position:

Vice President

Notes:

Detectors and Sensors, infrared systems and equipment, night vision

equipment

Cincinatti Electronics

Component: Address:

7500 Innovation Way

C- -4----

Mason, OH 45040-9699

Contact:

Tom Venable

Position:

Marketing Manager for IR Detectors

Notes:

Manufactures and designs IR detectors including single-element, linear and two dimensional arrays, discrete channel amplified, multiplexed, in Ge, MCT,

InSb and InAs, 1-12 um.

Organization:

Classin College

Component:

Department of Mathematics and Physics

Address:

Orangeburg, South Carolina 29115

Contact:

Sylvester N. Ekpenuma

Position: Notes:

Co-authored for 1991 MCT Workshop "Critical Stress of HgCdTc Solid

Solutions" and "Microhardness of Hg-Containing II-Vi Alloys"

Organization:

Clarkson University

Component:

Address:

Potsdam, NY 13699

Contact:

Frederick M. Carlson

Position:

Mr.

Notes:

Attended 1992 MCT conference

Organization:

Cleveland Crystals, Inc.

Component:

Address:

19306 Redwood Avenue, P.O Box 17157 Cleveland, OH 44117

Contact:

Peter Direnzo

Position:

Gnl Mgr

Notes:

Manufacturer and research into CdTe, ZnS, and ZnSe infrared materials.

CMTEK Pty, Ltd

Component:

P.O. Box 1500

Address:

Salisbury 5108, South Australia

Contact:

M.A. Folkard

Position:

Mr.

Notes:

Co-authored for 1992 MCT Workshop "In-Situ Ellipsometric Measurements of

the MBE Growth of CdTe/HgTe and CdTe/ZnTe Superlattices"

Organization:

CNRS

Component:

Laboratiore de Physique des SOlides de Bellevue

Address:

F-92195 Meudon-Ccdex, FRANCE

Contact:

Y. Marfaing

Position: Notes:

Authored for 1991 MCT Workshop "Point Defects and Defect-Purity Interaction of CdHgTe and Other II-Vi Semiconductors: Facts and

Conjectures."

Organization:

Cochise Instruments Inc

Component:

Address:

6304 De Mello Street

Hereford, AZ 85615

Contact:

Position:

Notes:

cyrogenic equipment

Organization:

Codenoll Technology Corporation

Component:

Address:

Yonkers, NY

Contact:

Position:

Notes:

Development of InP sensors for use in optical transmitters and receivers in.

1242.20

cooperation with NYNEX.

College of William and Mary

Component:

Dept of Physics

Address: Contact: Williamsburg, VA 23185 Christopher S. Welch

Position:

Mr.

Notes:

infrared non-destructive evaluation

Organization:

Colorado Research Lab

Component: Address:

Walsenburg, CO Maruice J. Brau

Contact: Position:

Notes:

Authored January 1991 report "Ultra-high-purity Starting Materials for

Infrared Detector Crystal Growth"

and January 1991 "Traveling Heater Method Growth of Bulk Compound

Semiconductor Alloy Crystals"

Organization.

Columbia University

Component:

Address:

New York, NY

Contact: E.R. Fossum

Position:

Notes:

Co-authored for 1990 SPIE workshop on IR Detectors "GaAs CCD Readout

for Engineered Bandgap Detectors"

Organization:

Component:

Commerical Crystal Laboratories, Inc.

Address:

4406 Arnold Avenue

Naples, FL 33942

Contact:

Position:

Notes:

Manufacturer of CdTe, GaAs, silicon, ZnS, and ZnSc.

Commonwealth Scientific Corp

Component:

Address: 500 Pendleton Street

Alexandria, VA 22314

Contact:

Position:

Notes: cyrogenic equipment

Organization:

Compaq Computer

Component:

Address:

Contact:

Greg Haug

Position:

Mr.

Notes:

Organization:

Component:

Computing Devices Co.

Address: Castleham Road

St. Leonards on Sca

East Sussex, UK TN389NJ

Contact:

Position:

Mike Turley Marketing Director

Notes:

Infrared systems and Equipment

Organization:

Concept Engineering

Component:

Address:

43 Ragged Rock Rd.

Old Saybrook, CT 06475

Contact:

Ludwig Holtermann

Position:

owner

Notes:

IR-technology sensor and detector development.

Continental Optical Corp.

Component:

Address: 15 Power Drive

Hauppauge, NY 11788

Contact:

Manfred W. Grindel

Position:

President

Notes:

Manufacturer of silicon, ZnS, and ZnSe infrared materials.

Organization:

Contraves USA

Component:

Boston Electro Optic Division

Address:

170 Locke Dr.

Marlborough, MA 01752

Contact:

Max Riedl

Position: Notes: CEO Applied researach on electrical-optical systems, instruments and components

utilizing infrared, visible and ultraviolet spectrums, including infrared detectors, optical elements, and optical interference and coatings filters, radiation sources, ...diometers, combustion analyzers, navigation instruments for satellites and spacecraft and sensors for meteorological satellites; chemical and drug detection, instrumentation, target and scene simulation, models, gas

detection, measurement insstrumentation.

Organization:

Cornell University

Component:

School of Electrical Engineering and the National Nanofabrication Facility

Address:

Ithaca, NY 14853

Contact:

Y. Shacham-Diamand

Position:

Position:

Co-authored for 1992 SPIE meeting on IRFPAs "P-Channel MIS Double-

Metal Process InSb Monolithic Unit Cell for Infrared Imaging"

Organization:

Cox & Company, Inc.

Component:

Address: 200 Varick St.

New York, NY 10014

Contact:

Warren Achenbaum

Position:

Pres

Notes:

Electronic and mechanical engineering, acrodynamics, thermal engineering.

Crane Co

Component: Address:

Hydro-Aire Division 3000 Winona Ave.

Burbank, CA 91504

Contact: Position: JD Tarbet

VPeng

Notes:

Infrared tracking for wind shear detection and high response control synthesis

for extra fast control systems.

Organization:

Craver & Craver Inc

Component:

Address: 761 W Kirkham Ave.

Saint Louis, MO 63122

Contact:

Dr Clara Craver

Position:

COO

Notes:

Computer-assisted database searches in infrared spectroscopy; reference

spectra for IR.

Organization:

Cray Research

Component:

Address:

925 First Avenue

Chippewa Falls, WI 54729-1402

Contact:

Christine Anderson

Position:

Ms.

Notes:

active in infrared process control

Organization:

Component:

Crystal Specialties International

Address:

2853 Janitall Road

Colorado Springs, CO 80906

Contact:

Kelly Burke

Position:

Operations Manager

.1.

Notes:

Production of GaAs and germanium for infrared applications.

Crystal Systems Inc.

Component: Address:

Shetland Industrial Park

27 Congress St.

Salem, MA 01970

Contact:

Frederick Schmid

Position:

CEO

Notes:

Growth of semiconductors using such materials as GaAs and CdTc, and use

of silicon in infrared applications

Organization:

CVS Systems & Services, Inc.

Component: Address:

CVD Systems & Services Penn Centre Plaza

Quakertown, PA 18951

Contact:

Warner Whitmer

Position:

Pres

Notes:

Production of solar cells and sensor prototyping.

Organization:

Daedalus Enterprises, Inc.

Component:

Address:

300 Parkland Plaza, PO Box 1869

Ann Arbor, MI 48106

Contact:

Charles G Stanich

Position: Notes: Vice President Infrared and multispectral analysis.

Organization:

DALSA Inc, CCD Image Sensors

Component:

Address:

605 McMurray Road

Waterloo, Ontario CANADA N2V 2E9

Contact:

Position:

Notes:

Datametrics Corp.

Component:

Address: 8986 Comanche Avenue

Chatsworth, CA 91311

Contact:

Betty Blodgett Marketing

Position: Notes:

Thermal Imaging

Organization:

Datron Systems, Inc.

Component:

Address:

200 W Los Angeles Ave.

Simi Valley, CA 93065-1650

Contact:

Dave Derby

Position:

Prcs

Notes:

Production and research in infrared optical and laser sensors.

1

Organization:

Component:

David Sarnoff Research Center

Address:

CN5300 Washington Road

Princeton, NJ 08543-5300

Contact:

John R. Towcr

Position:

Mangager, Visible and IR Imaging Business

Notes:

Organization:

Davin Optical, Ltd.

Component:

Address:

9A Chester Road

Borchamwood, Herts, UK WD6 1LD

Contact: Position: **David Holland** Managing Director

Notes:

Night Vision, EO Systems, Infrared Systems and Equipment, Thermal Imaging

DBA Systems, Inc.

Component:

Address: P. O. Box 550

Melbourne, FL 32902

Contact:

Darrell Curtis

Position:

Director Business Development

Notes:

Thermal Imaging, infrared systems and equipment

Organization:

Decilog, Inc.

Component:

Address:

555 Broad Hollow Rd

Mclville, NY 11747-5093

Contact:

John Marchesano President

Position: Notes:

Technical support to government and industry in infrared systems and

components.

Organization:

Decision Images, Inc

Component:

Address:

196 Tamarack Circle

Skillman, NJ 08558

Contact:

Position:

Notes:

remote sensing systems, thermal infrared, multispectral

Organization:

Delco Electronics

Component:

Address:

700 East Firman Avenue

Kokomo, IN 46901

Contact:

Bill Bauson

Position:

Mr.

Notes:

active in infrared non-destructive evaluation

Delta International, Inc.

Component:

Address: 2111 Wilson Boulevard, Suite 700

Arlington, VA 22201

Contact:

Earl Thompson

Position:

President

Notes:

Thermal imagnig, detectors and sensors

Organization:

Diagnostic Retrieval Systems, Inc.

Component:

Photronics Corporation

Address:

270 Motor Pkwy.

Hauppauge, NY 11788

Contact:

Richard Ross

Position:

CEO

Notes:

Develop and manufacture optical laser ultraviolet detection components,

missile optical component and specialized coating.

Organization:

Difracto Ltd.

Component:

2835 Kcw Dr.

Windsor, ON N8T 3B7

Contact:

Address:

Omer Hageniers

Position:

Notes:

Research in vision sensors and gas lasers for measuring purposes.

Organization:

Component:

Digital Equipment Corp

Address:

Mail Stop MLO5-4/E22

Maynard, MA 01754

Contact:

Edward Cox

Position:

Mr.

Notes:

infrared non-destructive evaluation

Diversified Optical Products

Component:

Address: 282 Main St.

Salem, NH 03079

Contact:

Lawrence Kessler

Position:

Pres

Notes:

Automated IR and visible automated MTF testing.

Organization:

Dover Corporation

Component:

Universal Instrument Corp.

Address:

PO Box 825

Binghamton, NY 13902

Contact:

John Pomeroy

Position:

Pres

Notes:

Automation of electronics industry production.

Organization:

Dresden University of Technology

Component:

Institut fur Festkorperelektronik

Address:

Dresden, FEDERAL REPUBLIC OF GERMAN

Contact:

H. Budzier

Position:

Notes:

Co-authored for 1992 SPIE IRFPA meeting "Pyroclectric IR Single-Element

Detectors and Arrays Based on LiNbO3 and LiTaO3"

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Pyroelectric

Linear Array IR Detectors with CCD Multiplexer"

Organization:

DRS Photronics Corp

Component:

Address: 270 Motor Parkway

Hauppauge, NY 11788

Contact:

Patricia Williamson

Position:

Assistant VP Corp. Comm.

Notes:

Electro optical systems, night vision, infrared systems and equipment

DTX Corporation

Component:

Dynatherm Corporation

Address:

One Beaver Ct.

Cockeysville, MD 21030

Contact:

Edward Scicchitano

Position:

CEO

Notes:

Thermal systems research oriented toward industrial process temperature

control.

Organization:

Dukane Corporation

Component:

Microbiotics Division 2900 Dukane Dr.

Address:

Saint Charles, IL 60174

Contact:

JM Stone

Position:

Pres

Notes:

Precision automated alignment and laser welding systems used to manufacture

optoclectronic devices,

Organization:

Dynamics Research Corporation

Component:

Address:

60 Concord St.

Wilmington, MA 01887

Contact:

Albert Rand

Position:

Prcs

Notes:

Design and fabrication of optical digital shaft angle encoders for aerospace and

industrial applications.

Organization:

Dynatech Corporation

Component: Address:

Sensors, Inc. 6812 S State Rd

Contact:

Saline MI 48176

Position:

Tom Fournier President

Notes:

Commercial uses for infrared technology.

Organization: Component:

E-Systems, Inc. HRB Systems, Inc

Address:

300 Science Park Rd.

Contact:

State College, PA 16804 Michael Keebaugh

Position:

Notes:

Prcs

Integration of sensors into systems capable of military surveillance missions.

Organization:

E2 Technology corp.

Component: Address:

4475 Dupont Ct., No 9

Ventura, CA 93003 Earnest Emery

Contact: Position:

CEO

Notes:

Product oriented research in infrared blackbodies

Organization:

Component:

Eagle-Picher Industries, Inc.

Address:

P.O.Box 737

Quapaw, OK 74363

Contact: **Position:** Brian McLain Sales Manager

Notes:

High Purity infrared materials

Organization:

Eastman Chemical Co

Component:

Eastman Laboratory Chemicals

Address:

1001 Lee Road

Rochester, NY 14652-3512

Contact:

Position:

Notes:

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942.00

Eastman Kodak Co.

Component:

Government Systems Div.

Address:

1447 St. Paul Street

Rochester, NY 14653

Contact:

Rollo Black

Position:

Business Development

Notes:

IR Detectors work, mostly PtSi.

Organization: Component: Eastman Kodak Company Kodak Apparatus Division

Address:

901 Elmgrove Rd.

Rochester, NY 14653

Contact:

Lawrence Matteson

Position:

Manager

Notes:

Applied research in physics and engineering to establish experimental and analystical foundations for new and improved processes in electro, photo-

optical, and mechanical products. Additional research with PtSi under a contract from the Air Force Aeronautical Systems Division for use in adverse

weather landing systems.

Organization:

EDO Corporation

Component:

Barnes Engineering Company

Address:

88 Long Hill Cross Rd. Shelton, CT 06484

Contact:

Frank Fariello

Position:

Pres

Notes:

Product oriented research in infrared sensors.

Organization:

EEV Ltd.

Component:

Address:

Waterhouse Lane

Chelmsford, Essex ENGLAND CM1 2QU

Contact: Position: David Taylor Sales Manager

Notes:

Active and passive co systems, infrared systems and equipment, night vision.

EG & Mound Applied Technology

Component:

Address:

Box 3000

Manisburg, OH 45342 Jonathan H. Mohler

Contact: Position:

Mr.

Notes:

active in infrared remote sensing

Organization:

EG&G Princeton Applied Research

Component:

Address:

375 Phillips Boulevard

Trenton, NJ 08618

Contact:

S.E. Mohr

Position:

Mr.

Notes:

Co-authored for 1992 SPIE Workshop on IRFPAs "Popcorn Noise in Linear

InGaAs Detector Arrays"

Organization:

Component:

EG&G Reticon Corp.

345 Potrero Avenue Address:

Sunnyvalc, CA 94086-4197

Contact:

John Skurla Position: Sales Manager

Notes:

Organization:

EG&G, Inc.

Component: Address:

EG&G Judson 221 Commerce Dr.

Montgomeryville, PA 18936

Contact:

Andrew Allen

Position:

VP Sales

Notes:

Application of infrared materials including germanium and mercury cadmium

telluride.

Elbit Systems, Inc.

Component:

Address: 16 Esquire Road

North Billerica, MA 01862

Contact:

Joseph A. Parini

Position:

President

Notes:

EO systems, infrared systems and equipment, night vision

Organization:

Electric Power Research Institute

Component:

Address:

3 Industrial Highway

Contact:

Eddystone, PA 19022 Robert G. Hammaker

Position:

Mr.

Notes:

active in infrared predictive maintenance

Organization:

Component:

Electro Optical Industries, Inc

Address:

859 Ward Drive

Santa Barbara, CA 93111

Contact: Position: Notes:

Organization:

Electronic Devices, Inc.

Component:

Address:

Urbana, IL

Contact:

Position:

Notes:

Participated in DARPA's initial Electronic Services HgCdTe program. 4 41 :

Electronic Space Products International (ESPI)

Component:

Address: 5310 Derry Avenue

Agoura Hills, CA 91301

Contact: Position:

Notes: Manufacture and application of CdTe, GaAs, germanium, ZnS, and ZnSe

infrared systems.

Organization:

Component:

Electrophysics

373 Route 46 West, Building E

Fairfield, NJ 07004

Contact: Position:

Address:

Frank J. Vallesc General Manager

Notes:

Night Vision, thermal imaging

Organization:

Component:

Elettronica S.p.A.

Address: via Tiburtina KM 13.7

1-00131 Rome, ITALY

Contact: Position: Camillo Pariset P.R. Manager

Notes:

Infrared systems and equipment

Organization:

Elop-Electro Optics Industries

Component:

Address:

P.O. Box 1165

Rehovot, Israel 76110 Tuvia Charmey

Contact:

Position:

Advertising Manager

Notes:

Infrared systems and equipment, thermal imaging, detectors and sensors, night

vision

Emcore Corp.

Component: Address:

35 Elizabeth Avenue

Contact:

Somerset, NJ 08873

William J. Burns

Position:

President

Notes:

Material production of GaAs, CdTe, silicon, ZnS, and ZnSe for infrared

applications.

Organization:

Emerson Electric Co

Component: Address:

Rosemount Inc. 12001 technology Dr.

Eden Prairie, MN 55344

Contact:

Robert Cox

Position: Notes:

President Applied research on sensors and instruments for measurements of

temperature, flow level, pressure, and other industrial applications.

Organization:

Entec

Component:

Address:

Suite 100, 2817 Garden Hwy

Sacramento, CA 95833

Contact:

Robert Ngyen

Position:

COO

Notes:

Basic research in photovoltaics.

Organization:

Component:

EnTech Engineering, Inc.

Address:

111 Marine Lane

St. Louis, MO 63146

Contact:

Leann M. Forister

Position:

Notes:

active in infrared remote sensing

Enterprise for Semiconductor Devices

Component:

Address: ROMANIA

Contact: M.N. Udrea-Spenca

Position: Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Accurate

Method for Neutraon Fluence Control Used in Improving Neutron-

Transmutation-Doped Silicon Detectors"

Organization:

Environmental Technology Group, Inc.

Component:

Address: 1400 Taylor Avc., PO Box 9840

Baltimore, MD 21284-9840

Contact:

John Spelman

Position:

Pres

Notes: Applied research in detectors for explosives, hazardous drugs and chemical

warfare agents.

Organization:

Environmetrics, Inc.

Component: Address:

2345 Millpark Dr.

Maryland Heights, MO, 63043

Contact:

Dr Eugene Scheide

Position:

Notes:

Development of "smart sensors," interest in using IR, esp. sensitive MCT

variety

Organization:

EOIS

Component:

Address:

Suite 501, 710 Wilshire Blvd.

Santa Monica, CA 90401

Contact:

John Fitts

Position:

Pres

Notes:

Smart sensor technology development.

EPI Crystal Supplies Pty, Ltd.

Component:

Address: Monbulk, Victoria, 3793 Australia

Mr.

Contact:

G.N. Pain

Position: Notes:

Authored for 1991 MCT Workshop "Effects of mixed-valence Mercury and

Indium on the Electrical Properties of HgCdTe"

Organization:

EPIR, Ltd.

Component:

Address:

Oak Brook, IL 60521 P.S. Wijewarnasuriha

Contact: Position:

Notes:

Co-authored for 1992 MCT Workshop "Influence of CdZnTe (211)B Substrate

on Electrical Properties of HgCdTe Grown by MBE"

Organization:

Component:

Epitaxx, Inc.

Address:

3490 Route 1,

Princeton, NJ 08540

Contact:

Ken Fujiwara

Position:

President

Notes:

Long-wavelength high speed sources and detectors for fiberoptic

communcations (InGaAs photodiodes, 1300 & 1500 nm edge LED and laser diode), large area InGaAs detectors for test and measurement rangefinding. Develops 512 element InGaAs arrays of cutoff wavelengths of 2.6um.

Organization:

ERIM - Environmental Research Inst of Michigan

Component:

Address:

PO Box 8618

Ann Arbor, MI 48107-8618

Contact:

Position:

Notes:

remote sensing systems, thermal infrared, multispectral

ESA-ESTEC

Component:

Address: Keplerlaan 1,

NL-2200 AZ Noordwijk, THE NETHERLANDS

Contact:

Marino Babbricotte

Position:

Mr.

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Comparative Study of SWIR

and MWIR Schottky-Barrier Imagers."

Organization:

Euromissile Dynamics Group

Component:

Eltro

Address:

Germany

Contact:

Position:

Notes:

Produces HgCdTe-based infrared guideance systems for military applications.

Organization:

Evans & Sutherland

Component:

Address:

600 Komas Drive

Salt Lake City, UT 84108

Contact:

Jeff Edwards

Position:

Communications Manager

Notes:

Night Vision, thermal imaging

Organization:

Evey Engineering Co Inc

Component:

Address:

154 Center Street

Groveland, MA 01834-1016

Contact:

Position:

Notes:

cyrogenic equipment

Exotech, Inc

Component: Address:

8502 Dakota Dr.

Gaithersburg, MD 20877

Contact:

Robert Lyle

Position:

Pres

Notes:

Electo-optical and electronic instrumentation.

Organization:

Exotic Materials, Inc,

Component:

2930 Bristol St.

Address:

Costa Mesa, CA 92626

Contact:

Roderick R. Randolph

Position:

Sales Manager

Notes:

Applied, product-oriented research as related to electro-optical materials,

vacuum deposited coatings and devices for government, industrial and military

systems applications.

Organization:

Fermionics

Component: Address:

4555 Runway St.

Simi Valley, CA 93063

Contact:

Peter Wang

Position:

CEO

Notes:

Produces wholesale CdTe and participant in CECOMs night vision advanced

research.

Organization:

FIBERTEK, Inc. Component:

Address:

Herndon, VA 22070 Horacio R. Verdun

Contact: Position:

Mr.

Notes:

Co-authored for 1992 MCT Workshop "Tunnelling Current Probe for

Contactless Electrical Performance Measurements of Infrared Focal Plane

Detector Arrays*

FJW Optical Systems, Inc

Component:

Address: 629 S Vermont St.

Palatine, IL 60067

Contact: Position:

Edward Wood President

Notes:

Electro-optical systems and infrared viewing devices for production.

Organization:

FLIR Systems, Inc.

Component:

Address: 16505 SW 72nd Avenue

Portland, OR 97224

Contact:

Frans Eberth

Position:

Mr.

Notes:

infrared non-destructive evaluation

Organization:

Ford Motor Co.

Component:

Scientific Research Laboratory

Address:

P.O. Box 2053

Dearborn, MI 48121

Contact:

R.P. Cooper

Position:

Mr.

Notes:

infrared non-destructive evaluation

Organization:

Frascr-Volpe Corporation

Component:

Address:

Warminster Industrial Park, 1025 Thomas Dr.

Warminster PA 18974

Contact:

David Fraser

Position:

Pres

Notes:

Electro-optics and electronic systems; design and development of systems for inspection of fluid-filled vials and other glass containers to detect chips, cracks

and foreign particles, stabilization systems for optical viewing devices,

television and motion picture cameras, laser stabilization.

Fraunhofer-Institut fur Angewadnte Festkorperphysik

Component:

Address: Tullastr. 72

D-7800 Freiburg, Germany

Contact:

D.D. Edwall

Position: Notes:

AUthor of "Characterization of MCT Heterostructures by Thermoelectric

Measurements*

Organization:

FSI International

Component:

Address:

322 Lake Hazeltine Dr.

Chaska, MN 55318

Contact:

Joel Elftmann

Position:

Prcs

Notes:

Research for semiconductor production equipment.

Organization:

FTS Sys Inc

Component:

Address:

PO Box 158

Stone Ridge, NY 12484

Contact:

Position:

Notes:

cyrogenic equipment

Organization:

Fujitsu Laboratories, Ltd.

Component:

Atsugi Infrared Devices Laboratory

Address:

10-1 Morinosato-Wakamiya

Atsugi 243-01 JAPAN

Contact:

K. Awamoto

Position:

Mr.

Notes:

Co-authored for 1992 SPIE Workshop on IRFPAs "Resolution Improvement

for HgCdTe IRCCD*

Future Technology Services

Component:

Address: 700 Indian Trail Road

Atlanta, GA 30247

Contact:

Position:

Notes: Prepared a study on the potential IR thermography market

in 1988.

Organization:

Galileo Electro-Optics Corp.

Component:

Address: Galileo Park, PO Box 550

Sturbridge, MA 01566

Contact:

William Hanley

CEO

Position: Notes:

Develops fiber-optic and electro-optic components which transmit, intensify or

sense light images.

Organization:

Galtech Semiconductor Materials Corp.

Component:

Address: 265 North State Street

Mt. Plcasant, UT 84647

Contact: Position:

Melvin J. Carr President

Notes:

Manufacture of CdTe infrared materials, germanium, wafers and ingots,

monocrystalline and polycrystallins. Polishing and slicing series for CdTe and

CdZnTc.

Organization:

GE Acrospace

Component:

Electronics Lab Syracuse, NY

Address: Contact:

Bob Yanka

Position:

Notes: Scientist working on MBE, past work on advanced iRFPA concepts for

WRight Patterson AFB April 1987-DeCember 1990

GEC Ferranti

Component:

Address:

Ferry Road

Edinburgh, Scotland EH5 2XS

Contact:

John Ford

Position:

Public Relations Manager

Notes:

night vision, detectors and sensors, active and passive consystems

Organization:

Component:

GEC Ferranti Defence Systems, Ltd.

Address:

Navigation and Electro Optics Division

Silverknowes, Ferry Road Edinburgh, UK EH4 4AD

Contact:

F.J. Graham

Position:

Marketing Support Exec

Notes:

Infrared systems and equipment, night vision e/o systems

Organization:

Component:

GEC Hirst Research Centre

Address:

Wembley, UNITED KINGDOM

Contact:

L.M. Smith

Position:

Mr.

Notes:

Co-authored May 1990 report "Integrated Technology in MCT/GaAs and

MCT/Si for Medium and Long Wavelength Infrared"

Organization:

GEC Marconi Dynamics, Ltd.

Component:

Address: The Grove

Warren Lane

Stanmore, Middlesex, UK HA7 4LY

Contact:

R. Coltart

Position:

Press Officer

Notes:

infrared systems and equipment, MMW radar, etc.

GEC Sensors

Component:

Hirst Infrared Division

Address:

East Lane.

Wembley, Middlesex, HA9 7PP, UK

Contact:

Position:

Notes:

Production of a wide variety of HgCdTe-based systems, including sensors for the Tornado, Harrier, and Lynx. Most HgCdTe material is purchased from

Philips. The company also has invested heavily in internal research on InSb

and dual-wave band sensor technology.

Organization:

General Dynamics

Component: Address:

Space Systems Division 2945 Arcola Avenue

Sand Dicgo, CA 92117

Contact:

Douglas Burleigh

Position:

Notes:

active in infrare! r. mote sensing, predictive maintenance, non-destructive

evaluation

Organization:

General Dynamics Corporation

Component:

Address:

Electronics Division 5011 Kearny Villa Rd.

San Diego, CA 92123-1447

Contact:

Terry Straetten

Vice President

Position: Notes:

Product oriented research in automatic test equipment and electronics,

communications, electronic warfare, signal processing, and displays and

950

imagery, lasers.

Organization:

General Electric Company

Component:

Aerospace Electronics Systems Department

Address:

French Rd.

Utica, NY 13503

Contact:

Alexander Horvath

Position:

General Manager

Notes:

Research into pattern recognition.

General Microwave Corp.

Component: Address:

5500 New Horizon Blvd Amityville, NY, 11701

Contact:

Sherman Rinkel

Position:

Notes:

Applied sensor technology for industrial and automative applications.

Organization:

General Motors Corporation

Component:

Hughes Aircrast Co., Research Laboratories

Address:

3011 Malibu Canyon Rd

Malibu, CA 90265

Contact:

Arthur Chester

Position:

Notes:

Production of GaAs and InP integrated circuits; infrared sensors, especially

monolithic focal plane arrays.

Organization:

General Motors, Corporation Santa Barbara Research Center

Component: Address:

75 Coromar Dr.

Contact:

Golcta, CA 93117

Position:

Fletcher Phillips

President

Notes:

Manufacture of infrared photodetectors and associated components, packages and infrared focal plane arrays; electro-optical instrumentation for space;

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particularly multispectral earth observation sensors and weather sensors; specialized military equipment such as vehicle fire sensors and missle proximity

fuses.

Organization:

Geonex Verde Technologies

Component: Address:

734 E. Lake Avenue

Watsonville, CA 95076

Contact:

Paul Reising

Position:

Notes:

active in infrared remote sensing

Georgia Institute of Technology

Component:

Address:

Contact:

C.J. Summers

Position: Notes:

On Program Committee of 1991 & 1992 MCT Workshop

For 1991 Workshop, "Selected-area Epitaxy on CdTe," and "Gas Source IOdine

Doping and Characterization of MBE Grown CdTc"

Organization:

Georgia Tech Research Institute

Component:

Physical Sciences Laboratory

Address:

Room 128 Baker Bldg

Atlanta, GA 30332
Contact: R.G. Benz

Position:

inact. R.O. Deli

Notes: Authored "CdTe and HgTe Growth Kinetics During Gas SOurce Molecular

Beam Epitaxy" for 1992 MCT Workshop For 1991, "Selected-area Epitaxy of CdTe"

Organization:

GFI Advanced Technologies, Inc.

Component:

Address:

112-41 69th Avenue

Forest Hills, NY 113754

Contact:

Karl Lisschitz

Position:

Chief Executive

Notes:

Manufacture of GaAs, germanium, ZnS, and ZnSe for infrared applications.

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Organization:

Glenro, Inc.

Component:

Address:

29 McBride Avc.

Paterson, NJ 07501

Contact:

Hervert Van Denend

Position:

Pres

Notes:

Research into infrared system production.

Graduate Center for the City Univ of NY Dept of Electrical Engineering and Physics

Component: Address:

Institute for Ultrafast Spectroscopy & Lasers, Photonics Appl Lab

New York, NY 10031

Contact:

K.M. Yoo

Position:

Dr.

Notes:

active in infrared biomedical thermography

Organization:

Groton Technology, Inc.

Component:

Address:

45 Winthrop St.

Concord, MA 01742

Contact:

George Barringer

Position:

Prcs

Notes:

Applied and product-oriented research in optical inferometry and solid state

optical detectors. Application of infrared technologies to scientific

spectroscopy.

Organization:

Grumman Aircrast Systems

Component:

Address:

MS B46-35

Bethpage, NY 11714

Contact:

Michel Engelhardt

Position:

Notes:

active in infrared process control

Organization:

Component:

Grumman Corporate Research Center

Address:

Bethpage, NY 11714-3580

Contact:

M.B. Lcc

Position:

Mr.

Notes:

Co-authored for 1992 MCT workshop "White Beam X-ray Synchroton

Topography Analysis of CdTe (111)B Substrates and Epilayers"

Hardin Optical Company

Component: Address:

P.O. Box 219

1320 Oregon Avenue Bandon, OR 97411

Contact: Position:

Larry Hardin President

Notes:

Manufacture of GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications.

Organization:

Hairis Corporation

Component:

Government Communications Systems Division

Address: 256 SE Palm Bay Rd., PO Box 9100

Melbourne, FL 32902

Contact:

alan Henry

Position: Notes:

Satellite and terrestrial communications, electro-optics, imagery and voice

privacy systems.

Organization:

Harris RF Communications

Component:

Address:

1680 University Avenue

Rochester, NY 14610

Contact:

John Cicotta

Position:

Marketing Communications Manager

Notes:

Thermal imaging, digital imaging systems, imaging software

Organization:

Harvard University

Component:

Division of Applied Sciences

Address:

Cambridge, MA 92138

Contact: Position:

Position: Notes:

Co-Authored "Augur Lifetimes in Ideal InGaSb/InAs Superlattices" for 1992

. .;

MCT Workshop.

H. Ehrenreich

Component:

Helix Technology Corp CTI Cyrogenics Div Nine Hampshire Street

Mansfield, MA 02048

Contact: **Position:**

Address:

Notes:

cyrogenic equipment

Organization:

HGH Ingenerie Systemes

Component:

Address:

au Parc d'Activities du Moulin de Massy

3, rue du Saule Trapu Massy, 91300 FRANCE

Contact:

Michel Balle

Position:

Notes:

active in infrared process control

Organization:

Honeyhill Technical Corporation

Component:

Address:

193 East Avenue

Norwalk, CT 06855

Contact:

Herbert Kaplan

Position:

President

Notes:

Contributing editor to Photonics Spectra, consultant in IR business. Someone

good for exposure of IDT study

Organization:

Honeywell Corp.

Component:

Sensor and System Development Center

Address: Contact: Bloomington, MN 55420

B.R. Johnson

Position:

Mr.

Notes:

Co-authored for 1992 SPIE Workshop on IRFPAs "YBa2Cu3O7

Superconducting Microbolometer Linear Arrays" supported by DARPA with

Office of Naval Research as contracting agency.

Honeywell, Inc.

Component:

Solid State Sensors Group

830 E. Arapaho Road Richardson, TX 75081

Contact:

Address:

J. Buie

Position:

Marketing Manager

Notes:

Manufactures IR optoelectronic components and assemblies, fiberoptic

components, and modules.

Organization:

Huazhong University of Science and Technology

Component:

Address:

Wuhan, Hubei 430074

REPUBLIC OF CHINA

Contact:

Wang Lingjie

Position:

Notes:

Authored for 1992 SPIE IRFPA meeting "Optimum Design Model for the

Injection of IRCCD"

Organization:

Hughes Aircrast Co.

Component:

Electron Dynamics Division

Address:

3100 W. Lomita

Torrance, CA 90509-2999

Contact:

J.A. Christensen

Position:

Marketing Director

Notes:

Organization:

Hughes Aircraft Company

Component:

Address:

328 Ellen Street

Midland, Ontari, L4R 2H2, CANADA

Contact:

J. Mactaggart

Position:

VP Marketing

Notes:

ICI America

Component:

Address:

Wilmington, DE

Contact: Position:

Notes:

A varity of work with InP, primarily for solar applications.

Organization:

II-VI Inc.

Component:

Address:

375 Saxonburg Blvd

Saxonburg, PA 16056

Contact:

Carl Johnson

Position:

President and CEO

Notes:

Manufacture of CdTe, GaAs, germanium, silicon, ZnS, ZnSe for infrared

applications.

Organization:

Imago Machine Vision Inc.

Component:

Address:

1354 Wellington Street

Ottaws, Ontario, CANADA K1Y 3C3

Contact:

Roy Ball

Position:

President

Notes:

Security systems and equipment, robotics, c/o systems, infrared sysetms and

cquipment

Organization:

Imagraph Corp.

Component:

Address: 11 Elizabeth Drive

Chelmsford, MA 01824

Contact:

Joseph Plonski

Position:

V.P. Sales and Marketing

Notes:

thermal imaging

 ${\bf Organization:}$

IMEC

Component:

Address: Jaoekdreef 75

B-3001 Leuven, BELGIUM

Contact:

Jan Vermeiren

Position:

Ms.

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Comparative study of SWIR

and MWIR Schottky-Barrier Imagers"

Organization:

Imo

Component: Address:

Varian Industries
Palo Alto, CA
Alan Bennett

Contact: Position:

V Pres R&D

Notes:

Producer of a wide variety of military thermal systems. Development of InP-

and HgCdTe-based infrared sensors, as well as the use of GaAs materials.

Organization:

Indiana State University

Component:

Department of Geography and Geology

Address:

Terre Haute, IN 47809

Contact:

David J. Kettler

Position:

Mr.

Notes:

active in infrared remote sensing

Organization:

Inframetrics

Component:

Address:

16 Esquire Road

North Billerica, MA 01862

Contact:

Charles Alicandro

Position:

Commercial Sales

Notes:

Infrared Engineering Services

Component:

Address: 110 Shadow Oaks Drive

Easley, SC 29642

Contact:

William T. Morgan

Position:

Mr.

Notes:

infrared non-destructive evaluation

Organization:

Infrared Industries

Component:

Address:

12151 Research Pkwy, Orlando, FL 32826

Contact:

Ed Patton

Position:

COO

Notes:

Lead sulphide, lead sclenide, indium antimonide and silicon infrared detectors and thin film optical filters for government and industrial applications; hybrid

preamplifier microcircuits.

Organization:

Infrared Monitoring Systems

Component:

Address:

10 West 35th Street

Chicago, IL 60616

Contact:

Ed Bangs

Position:

Notes:

active in infrared process control

Organization:

Infrared Optical Products, Inc.

Component:

Address:

P.O. Box 3033

South Farmingdale, NY 11735

Contact:

Barry Bassin

Position:

President

Notes:

Manufacture of CdTe, GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications.

Infrared Research, Inc.

Component:

Address:

100 Park City Road

Roosville, GA 30741

Contact:

James Garner

Position: Notes:

Mr. active in infrared predictive maintenance

Organization:

Component:

Infrared Scanning, Inc.

Address:

3955 Pleasantdale Rd.

Atlanta, GA 30340

Contact:

Robert Lacer

Position:

Notes:

Infrared inspection techniques and applications.

Organization:

Component:

Infraspection Institute

Address:

1971 Shelburne Road, Suite C

Shelburne, VT 05482

Contact:

Paul Grover

Position:

Mr.

Notes:

active in infrared predictive maintenance

Organization:

Innovation Industries, Inc.

Component:

Address:

Hwy 64E PO Box K

Russcliville, AR 72801

Contact:

Tom Benson

Position:

CEO

Notes:

Opto-electronics product oriented for patent and manufacture.

Institute for Atomic Physics

Component: Address:

ROMANIA

Contact:

D.N. Lazarovici

Position:

Notes: Co-authored for 1991 SPIF meeting on Growth of

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Accurate Method for Neutron Fluence Control Used in Improving Neutron-

Transmutation-Doped Silicon Detectors"

Organization:

Intergraph Corp.

Component: Address:

2051 Mercator Drive Reston, VA 22091

Contact:

John Dahmes

Position: Notes: Executive Manager, Marketing Thermal Imaging, imaging software

Organization:

International Advanced Materials Inc.

Component:

Address:

2 North Circle Avenue

Spring Valley, NY 10977

Contact:

JoElaine Cary

Position:

CEO

Notes:

Manufacture of CdTe, GaAs, germanium, silicon, ZnS, and ZnSe materials for

infrared systems.

Organization:

International Crystal Laboratories

Component:

Address: 11 Eric St.

Garfield, NJ 07026

Contact:

Theresa Herpst

Position:

Pres

Notes:

Applied research for growing crystals for infrared transmission.

International Imaging Systems

Component:

Address: 1500 Buckeye Drive

Milpitas, CA 95035

Contact:

Position:

Notes: remote sensing systems, thermal infrared, multispectral

Organization:

Component:

International Machine & Tool Corp.
Instrument & Development Laboratory

Address:

115 Maple St.

Contact:

Warwick, RI 02888

Position:

WJ Elsdoefer Pres

Notes:

Electronic and optical measurement development.

Organization:

International Optical Telecommuncations

Component:

Address:

18 E Blithedale Ave.

Mill Valley, CA 94941-1916

Contact:

Dr. Herbert Elion

Position:

CEO

Notes:

Hardware and software market research including lab facilities, design

improvement and patenting technology assistance.

Organization:

International Research and Evaluation

Component:

Address:

21098 IRE Control Ctr.

Eagan, MN 55121

Contact:

Randall Voight

Position:

CEO

Notes:

Product-oriented with emphasis on photovotaic cells.

International Sensor Systems, Inc.

Component:

Industrial Park, PO Box 345 Address:

Aurora, NE 68818

Contact:

Clifford Williams

Position:

Pres

Notes:

Research in hybrid thick film technology and optical relays.

Organization:

International Solar Electric Technologies

Component:

Address: Englewood, CA

Contact:

Position: Notes:

Development research on a variety of infrared materials, including CIS, for

solar applications.

Organization:

Interscan Corporation

Component:

Address:

21700 Nordhoff St. PO Box 2496

Chatworth, CA 91313-2496

Contact:

Dr Manny Shaw

Position:

Pres

Notes:

Gas analyzer and sensor developments.

Organization:

Component:

IR Scientific Inc

Address:

PO Box 110

Carlisle, MA 01741

Contact:

R Sommer

Position:

Pres

Notes:

Product-oriented near infrared research and development manufacturing and

infrared consulting services.

Iri Vision

Component:

Address: Suite D, 6231 Yarrow Dr.

Carlsbad, CA 92009

Contact:

Lawrence Goshorn

Position:

CEO

Notes:

Product-oriented research of light-based vision systems.

Organization:

Irtronics Instruments, Inc.

Component: Address:

132 Forest Blvd.

Ardsley, NY 10502

Contact:

John Jenkofsky

Position:

Gmgr

Notes:

Standard and custom infrared radiation pyrometers for measuring temperature

in industrial research applications.

Organization:

Irvine Sensors Corp.

Component:

3001 Redhill Ave Bldg 3 Costa Mesa, CA 92626

Contact:

Address:

James Alexiou

Position:

Drac

Notes:

Applied research in military detection system (infrared sensing).

Organization:

Component:

Iscan, Inc.

Address:

125 Cambridgepark Drive Cambridge, MA 02140

Contact:

Rikki Razdan

Position:

Marketing Manager

Notes:

Infrared systems and equipment, e/o systems

ISI Group

Component: Address:

211 Conchas SE

Albuquerque, NM 87123

Contact:

James Fritz

Position:

Mr.

Notes:

active in infrared process control

Organization:

ISPRA - Israel Product Research Co. Ltd.

Component:

Address:

Galgal Haplada Street, Industrial Zone

Herzelia, Israel 052-555464

Contact: Position:

NI-A

Notes: Manufacture of germanium, silicon, ZnS, and ZnSe for infrared applications.

Organization:

Israel Aircraft Industries, Ltd.

Component:

Address:

Ben-Gurion International Airport

Israel 70100

Contact:

F.P. Hermann

Position:

Corp. Foreign Press and Adv. Mgr.

Notes:

passive and active e/o components, detectors and sensors, infrared systems and

equipment

Organization:

ITD - Space Remote Sensing Center

Component:

Address:

Building 1103 Suite #118

Stennis Space Center, Mississippi 39529

Contact:

George A. May

Position:

Mr

Notes:

active in infrared remote sensing

ITI Electro-Optics Corp.

Component:

11500 W Olympic Blvd

Address:

Los Angeles, CA 90064

Contact:

Richard Caserio Sales Manager

Position: Notes:

Manufacture of CdTe, GaAs, germanium, ZnS, and ZnSe for infrared

technologies.

Organization:

ITT Defense and Electronics

Component:

Address:

1000 Wilson Boulevard, Suite 3000

Arlington, VA 22209

Contact:

Brandon Belote

Position:

Director Marketing Communications

Notes:

Night vision, active and passive e/o systems, infrared systems and components

Organization:

Component:

JA Noll Co.,

Address:

PO Box 312

Monroeville, PA 15146

Contact:

JA Noll

Position:

CEO

Notes:

Research in optical metrology.

Organization:

Component:

Jamieson Science and Engineering

Address:

Contact: Position: James Jamieson President

Notes:

Advocate of MCT being able to overcome cost barriers to break into

commercial market. Long history of involvement in IR since advent.

Janos Technology, Inc.

Component:

Address:

HCR #33, Box 25

Townshead, VT 05353-7702

Contact:

Bruce Gardner

Position:

Pres

Notes:

Manufacturer of CdTe, GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications.

Organization:

Component:

Jodon Engineering

Address: 62 Enterprise Dr.

Ann Arbor, MI 48103

Contact:

John Gillespi

Position:

Pres

Notes:

Optical engineering for machine vision.

Organization:

John Snell & Associates

Component:

Address:

17 First Avenue

Montpelier, VT 05602

Contact:

Robert W. Spring

Position:

Mr.

Notes:

active in infrared predictive maintenance

Organization:

Johns Hopkins University

Component:

Center for NDE ad Applied Physics Laboratory

Address:

Laurel, MD 20723

Contact:

James C. Murphy

Position:

Mr.

Notes:

infrared non-destructive evaluation

JTT International Inc.

Component:

Address: 3045 Technology Pkwy

Orlando, FL 32826

Contact:

Dr. M.Y. Hwang

Position:

Ch. Sci

Notes:

Manufacturer of germanium, silicon, ZnS, and ZnSe infrared systems.

Organization:

Kappler Crystal Optics Inc.

Component:

Address: 1244 Highland Street

Holliston, MA 01746

Contact: Position:

Ronald Kappler Pres.

Notes:

Manufacturer of ZnS and ZnSe for infrared applications.

Organization:

Kemet Electronics Corporation

Component:

Address:

2605 Laurens Hwy., PO Box 5928, Greenville, SC 29606

Contact:

DE Maguire

Position:

Pres

Notes:

Applied research and development on passive electronic components.

Organization:

Kidron Microelectronics Research Center

Component: Address:

Department of Electrical Engineering Technion-Israel Institute of Technology

Haifa 32000, ISRAEL

Contact:

A. Bezinger

Position:

Notes: "UV Photon Assisted Control of Interface Charge Between CdTe Substrates

and Metal Organic Chemical Vapor Deposition CdTe Epilayers" for 1992

MCT Workshop.

King's College

Component: Address:

Thermal Biology Research Unit Campden Hill Road, Kensington

London, W8 7AH, UNITED KINGDOM

Contact:

Ray P. Clark

Position:

Dr.

Notes:

active in infrared biomedical thermography

Organization:

King's College London, University of London

Component:

Thermal Biology Research Unit

Address:

Campden Hill Road

Kensington, Longon W8 7AH UNITED KINGDOM

Contact:

Ray P. Clark

Position:

Notes:

President of European Academy of Thermology. Interviewed 1-16

Organization:

Kistler-Morse Corporation

Component:

Address:

10201 Willows Rd., NE, PO Box 3009, Rcdmond, WA 98073

Contact:

Charlie Morse

Position:

Pres

Notes:

R&D of seminconductor displacement sensors.

Organization:

Kollmorgen Corp.

Component:

Address:

347 King Street

Northampton, MA 01060

Contact:

Doug James

Position:

Systems Engineer

Notes:

Detectors and sensors, infrared systems and equipment, night vision

Kollmorgen Corporation

Component: Address:

Photo Research 9330 DeSoto Dr.

Chatsworth, CA 91311

Contact:

James Fogle

Position:

VP

Notes:

Optical and electromechanical light measuring devices.

Organization:

Kollsman Division of Sequa Corp.

Component:

Address: 220 Daniel Webster Highway

Merrimack, NH 03054

Contact:

Jeannette Neff

Position:

Mgr. Marketing Communications

Notes:

E/O Systems, infrared systems and equipment, night vision

Organization:

Korca University

Component:

Address:

Chong Am Dong

Sung-Buk-Ku

Seoul, KOREA 11136-701

Contact:

Position:

Sun Ung Kim

Notes: Attended 1992 MCT Workshop

Organization:

KRS Electronics Corporation

Component:

Address:

Suite 16, 11649 Chairman Dr.

Dallas TX, 75243

Contact:

Steve Zimmerman

Position:

Pres

Notes:

Optical electronic sensing of liquids gases and temperatures.

Kussmaul Electronics Company, Inc.

Component:

Address: 170 Cherry Ave.

West Sayville, NY 11796

Contact:

Ernest Kussmaul

Position:

Prcs

Notes:

R&D of photoelectronic controls.

Organization:

Lab de Physique des Solides/INSA

Component:

Address:

Contact: R. Granger

Position:

Mr.

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Infrared

Reflectivity: A tool for bond Investigation in II-VI Ternaries"

Organization:

LaBarge Inc.

Component: Address:

LaBarge Electronics 11616 E 51st St.

Tulsa, OK 74146

Contact:

Bob Stauder

Position:

VP

Notes:

Intrusion detection systems and components, telemetry systems and

components and other eletromechanical systems and components for airborne and space applications; atmospheric, weather and data measuring systems and

components.

Organization:

Laboratory for Infrared Physics

Component:

Academia Sinica

Address:

420 Zhong Shan Bei Yi Road

Shanghai, 200083, CHINA

Contact:

Qian Dingrong

Position:

- -

Notes:

Authored for 1992 SPIE meeting on IRFPAs "Element of a new Infrared

Detector Plasma Edge Detector"

Laser Diode Inc.

Component:

205 Forrest Street

Metuchen, NJ 08840-1292

Contact:

Address:

Bob Gill

Position:

President

Notes:

Manufacturer of GaAs and germanium materials for infrared applications.

Organization:

Component:

Laser Fare, Inc.

Address: One Industrial Dr S

Esmond, RI 02917

Contact:

Terry Feeley

Position:

Pres

Notes:

Applied laser technology to industrial materials processing; research in

aerospace, medical and electronic applications.

Organization:

Laser Focus World

Component: Address:

One Technology Park Drive

P.O. Box 989

Westford, MA 01886

Contact:

David Kales

Position:

Senior Editor, Markets

Notes:

Wrote November 1992 article "Detector Makers Seek Dual-Use Technology

for Survival." F lends with David Leech.

Organization:

Laser SOS Limited

Component:

Address: 4B Bartholomew's Walk

Cambridgeshire Bus. Pk., ANgel Drove

Ely, Camb. CB74EAG

Contact:

A.W. Koszykowski

Position:

7. W. IXU

Notes:

Manufacture of CdTe, GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications.

Lasermike, Inc.

Component:

Address:

6060 Executive Blvd

Dayton, OH 45424

Contact:

Steve Cox

Position:

Pres

Notes:

Development of intelligence sensors.

Organization:

Lattice Materials Corp.

Component:

Address:

516 E. Tamrack

Bozeman, MT 59715

Contact:

John Tengelsen

Position:

Prcs.

Notes:

Manufacturer of silicon for infrared applications.

Lawrence Livermore National Laboratories

Organization:

Component: Address:

Livermore, CA 94551

Contact: Position:

Nancy C. DelGrande Ms.

Notes:

active in infrared remote sensing

Organization:

LETI (CEA - Technologies Avancees)

Component:

DOPT - CEN/G - 85 X

Address:

F38041 Grenoble Cedex FRANCE

Contact:

G. Destefanis

Position:

Mr.

Notes:

Co-authored for 1992 MCT Workshop "Large Improvement in HgCdTe

Photovoltaic Detector Performances at LETI"

Life Support, Inc.

Component:

Address: 2926 State St.

Erie, PA 16509

Contact:

Dr Eskil Karlson

Position:

Dir

Notes:

Optical system design including IR detection and systems.

Organization:

ization: Liquid Carbonic

Component: Address:

135 LaSalle

Chicago, IL 60603

Contact:

Position:

Notes:

cyrogenic equipment

Organization:

Litton Corporation

Component:

Address:

1725 Jefferson Davis Highway

Suite 601, Crystal Square Two

Arlington, VA 22203

Contact:

John Georg

Position:

Public Relations Manager

Notes:

e/o systems, night vision, infrared systems and equipment, detectors & sensors

Organization:

Component:

Litton Electron Devices

Address:

1215 S. 52nd Street Tempe, AZ 85281

Contact:

Paul Everett

Position:

Manager, Business Development

Notes:

Litton Electron Devices Product Group

Component: Address:

1215 South 52nd Street

Tempe, AZ 85281

Contact: Position: Notes:

Organization:

Litton Industries, Inc.

Component:

Applied Technology Division

Address:

4747 Hellyer Avc., PO Box 7012 San Jose, CA 95150-7012

Contact:

Clayton Williams

Position:

Pres

Notes:

Electro-optic and acouto-optic systems.

Organization:

Lockheed Corporation

Component:

Lockheed Palo Alto Research Laboratories

Address:

3251 Hanover St., Orgn 90-01 Palo Alto, CA 94304

Contact:

JB Rcagan

Position:

General Manager

Notes:

Research and development of electro-optic systems, including HgCdTe under

DARPA's Electronic Sciences program.

Organization:

Lockheed Missiles & Space Co., Inc.

Component:

Address:

1111 Lockheed Way

Sunnyvalc, CA 94088

Contact:

Larry M. Klynn

Position:

Mr.

Notes:

infrared non-destructive evaluation

Lockheed Sanders, Inc.

Component:

Address: NHO-1-735

> 68 Spit Brook Road Nashua, NH 03061

Contact:

Marvin L. Braman

Position:

Director of Public Relations

Notes:

Infrared systems and equipment, passive and active e/o devices

Organization:

Loral Corporation Component: Loral Fairchild Systems

Address:

300 Robbins Ln.

Syosset, NY 11791

Contact:

James Dunn Prcs

Position: Notes:

Development of electro-optical imaging systems.

Organization:

Loral Corporation

Component:

Loral Infrared & Imaging Systems, Inc.

Address:

2 Forbes Rd.

Lexington, MA 02173

Contact:

R.A. Bell

Position:

Director of Marketing

Notes:

Organization:

Loral Electro-Optical Systems

Component:

Address:

300 North Halstead Street

Pasadena, CA 91107

Contact:

Jim Carey

Position:

Marketing Director

Notes:

Infrared systems and equipment, e/o systems

Lousiana Tech University

Component:

Address:

Contact:

David H. Cowling

Position: Notes:

Co-authored 1990 "A Simplified Vision System With Robotic Assembly and

Manufacturing Applications"

Organization:

LTV Acrospace and Defense Company

Component:

Address:

Mail Stop PT-88

Dallas, TX 75265

Contact:

Y.L. Tyan

Position:

Mr.

Notes:

Co-authored for 1991 MCT Workshop "Analysis of Excess Carrier Lifetime in

p-Type HgCdTe Using a Three-Level Shockley-Read Model"

Organization:

Component:

Luoyang Optic-Electronic Institute

Address:

P.O. Box 030-12, 471009, Luoyang, Henan, P.R. CHINA

Contact: Position: Yongping Ni

Notes:

Authored for 1992 SPIE meeting on IRFPAs "Auto-Gain-Control

Characteristics of InSb P+/N Diode with High Sheet Resistance*

Organization:

MacDonald, Dettwiler & Associates, Ltd

Component:

Address:

13800 Commerce Parkway

Richmond, BC, V6V 2J3

CANADA

Contact:

Position:

Notes:

remote sensing systems, thermal infrared

MacVicar Associates

Component:

Address: 1171 Buckingham Drive

Los Altos, VA 94024

Contact:

Duncan MacVicar

Position: Notes:

Consultant, President Consultant on electro-optics

Organization:

Magna Industries, Inc

Component:

Address:

2201 W 110th St., PO Box 734

Cleveland, OH 44107

Contact:

Larry Whited

Position:

Pres

Notes:

Research in infrared products.

Organization:

Magnavox Corporation

Component:

Address:

1313 Production Road

Fort Wayne, IN 46808

Contact: Position:

Notes:

Participant in Army's night vision investigation program to develop advanced

thermal night vision systems.

Organization:

Magnavox Electronic Systems Company

Component: Address:

Elecrto-Optical Systems 46 Industrial Avenue

Mahwah, NJ 07430-2206

Contact:

Dan Laerfeld

Position:

Marketing Manager

Notes:

्र

Marconi Radar and Control Systems, Ltd.

Component:

Address: P.O. Box 133

Chobham Road, Frimley

Camberley, Surrey, UK GU16 5PE

Contact:

Mark Broughton

Position:

Head of public Relations

Notes:

Thermal Imaging, detectors and sensors, night vision

Organization:

Marine-Air Systems

Component:

Address:

24 Bridge Street

P.O. Box 30-248

Lower Hutt, NEW ZEALAND

Contact:

David Clist

Position:

Business Development Manager

Notes:

c/o systems, detectors & sensors, infrared systems & equipment, thermal

imaging

Organization:

Marlow Industries, Inc.

Component:

Address:

10451 Vista Park Road

Dallas, TX 75238-1645

Contact:

Bill Kolander

Position:

Product Marketing Manager

Notes:

infrared systems & equipment, night vision, detectors and sensors, e/o systems

:√: ...

Organization:

Component:

Martin Marietta

Address:

103 Chesapeake Park Plaza

Mail point 110

Baltimore, MD 21220

Contact:

William Greenlaw

Position:

Mr.

Notes:

Matrix Scientific Systems

Component:

Address:

Contact: Ken Matz

Position:

Mr.

Notes:

Organization:

Maury Microwave Corp

Component:

Address: 2900 Inland Empire Blv

Ontario, CA 91764

Contact: Position:

Notes:

cyrogenic equipment

Organization:

McCallum & Associates, Inc.

Component:

Address:

330 Pearl Street, Suite 3A

New York, NY 10038

Contact:

Alex McCallam

Position:

President

Notes:

Represents MediScience, Inc, which funded Alfano's work at CCNY on breast cancer detection. Interests in additional funding. Sees use in cancer pre-

diagnosis and cardiology during operations.

Organization:

Component:

McDonnel Douglas Tech Inc.

Address:

11955 Bajada Road

San Diego, CA 92128-2023

Contact:

Bob Madding

Position:

Mr.

Notes:

active in infrared remote sensing

McDonnell Douglas Aerospace

Component:

Address:

1801 E. St. Andrew Place

Santa Ana, CA 92705

Contact: Position: Nick Willick Scnior Manager

Notes:

Night Vision, thermal imaging, e/o systems

Organization:

McDonnell Douglas Corporation

Component:

MD Research Laboratories PO Box 516

Address:

Saint Louis, MO 63166

Contact:

John Dimmock

Position:

Gmgr

Notes:

Infrared detectors and fluid dynamics.

Organization:

Component:

McGill University

Address:

Contact:

L. Kops

Position: Notes:

Co-authored 1983 "Application of Infrared Radiation Measurements in

Grinding Studics"

Organization:

MCP Wafer Technology

Component:

Address:

Unit 34, Maryland Road, Tongwell, Milton Keynes, Bucks, MK158HJ

UNITED KINGDOM

Contact:

K.C. Lamb

Position:

Marketing Manager

Notes:

Production of CdTe and GaAs for infrared applications.

व्यक्तिः १ -

MDA Scientific, Inc.

Component:

Address: Suite 185, 3000 Northwoods Pkwy

Norcross, GA 30071

Contact:

Orman Simpson

Position:

Pres

Notes:

Optical remote sensing techniques.

Organization:

Melles Griot

Component:

Address: 1770 Kettering St.

Irvine, CA 92714

Contact:

Jan Melles

Position:

CEO

Notes:

Research into optical sciences and optical thin films.

Organization:

Merlin Engineering

Component:

Address:

1888 Embarcadero Road

Palo Alto, CA 94303

Contact:

Dan Dusci

Position:

Vice President

Notes:

thremal imaging, infrared systems & equipment

Organization:

MET, Inc.

Component:

Address:

Dallas, TX

Contact:

Position:

Notes:

A joint effort between Hughes and Texas Instruments to develop large

scanning arrays for use on the RAH-66 helicopter.

Metaleurop

Component:

Langelsheim, Germany

Address: Contact:

Position:

Notes:

Manufacture of germanium for infrared applications.

Organization:

Microwave Technology Incorporated

Component:

Address:

4268 Solar Way

Fremont, CA 94538

Contact:

Bill Wilson

Position:

Pres

Notes:

Research on GaAs and silicon for infrared applications.

Organization:

Mikron Instruments

Component:

Address:

445 W. Main Street

Wyckoff, NJ 07481

Contact:

Position:

K. Irani

Notes:

infrared non-destructive evaluation

Organization:

Component:

Minco Prods Inc

Address:

7300 Commerce Lane Minneapolis, MN 55432

Contact:

Position:

Notes: cyrogenic equipment

Minnesota University

Component:

Department of Electrical Engineering

Address:

Minneapolis, MN

Contact:

P.H. Handel

Position:

Notes:

Co-authored August 1991 "Quantum Noise in Solid-State Devices in Particular

HgCdTe Diodes"

Organization:

Mission Research Corporation

Component:

Address:

Newington, VA 22122

Contact: Position: James P. Karins Mr.

Notes:

Authored for 1992 SPIE workshop on IRFPAs "Models of Nonlinearities in

Focal Plane Arrays"

Organization:

MIT

Component:

Address:

Cambridge, MA 02139

Contact:

R.L. Aggarwal

Position:

Notes:

On Program Committee of 1991 & 1992 MCT Workshop

Organization:

Mitsubishi Electric Corporation

Component:

LSI Laboratory

Address:

4-1, Mizujara

Contact:

Itami, Hyogo, 664 JAPAN

Contact:

Hirofumi Yagi

Position:

Mr.

Notes:

Co-authored for 1992 SPIE Workshop on IRFPAs "Improved 512X512 IRCSD

with Large FIII Factor and High Saturation Level"

Mitsubishi Electronics America, Inc.

Component:

Address: 5665 Plaza Drive

Cypree, CA 90630

Contact:

Position: Notes:

Organization:

MMR Technology Inc

Component:

Address:

1400 North Shoreline Blvd, Ste A-5

Mountain View, CA 94043-1312

Contact:

Position:

Notes:

cyrogenic equipment

Organization:

Mobil Oil Corp.

Component: Address:

Mobil Solar Energy Corp. 4 Suburban Park Dr.

Billerica, MA 01821

Contact:

BM Gillespi

Position:

Pres

Notes:

Solar cell and photovotaic power components and systems development.

Organization:

Monitck Technologies, Inc.

Component:

Address:

1495 Zephyr Ave.

Hayward, CA 94544

Contact:

Kenneth Anderson

Position:

Pres

Notes:

Optical and electronic measurement systems to detect particulate matter, oils

and color in fluids.

Organization: Component:

Morton International CVD Incorporated 185 New Boston St.

Address:

Woburn, MA 01801

Contact:

Robert Donadio

Position:

Pres

Notes:

Material sciences, novel optical concepts and laser applications.

Organization:

Component:

MOSET Corporation

Address:

El Toro, CA 92630

Contact:

Ken Zanio

Position:

Mr.

Notes:

Authored for 1992 SPIE Workshop on MCT "HgCdTe on Si for Monolithic

Focal Plane Arrays" supported by NRL contract from Dean Scribner

Organization:

Motorola Corporation

Component:

Address:

1303 East Algonquin Road

Schaumberg, IL 60196

Contact: Position:

Ravi Bhatla

Notes:

infrared non-destructive evaluation

Organization:

Component:

MR Semicon, Inc.

Address:

276 Route 59

Tall Pincs Industrial Park Monsey, NY 10952-3407

Contact:

Roger Waldock

Position:

Pres.

Notes:

Manufacture of CdTe and GaAs for infrared applications.

MS2i

Component: Address:

38 Bd Paul Cezanne BP 235 78052 St Quentin en Yvelines

FRANCE

Contact:

Position:

Notes:

remote sensing systems, multispectral

Organization:

Mussoletto Optical Company, Inc.

Component:

Address:

6100 Everall Ave.

Baltimore, MD 21206

Contact:

Rose Jones

Position:

Pres

Notes:

Design and development of optical systems for underwater, laboratory and

space applications.

Organization:

Nalorac Cyrogenics Corp

Component:

Address:

837 Arnold Drive, Ste 600

Martinez, CA 94553

Contact:

Position:

Notes:

cyrogenic equipment

Organization:

NASA

Component:

Langley Research Center

Address:

MS 231

Hampton, VA 23665

Contact:

Elliot Cramer

Position:

Mr

Notes:

infrared non-destructive evaluation

NASA, Langley Research Center

Component:

Analytical Services and Manufacturing, Inc.

Address:

c/o MS 231

Contact:

Hampton, VA 23665 Patricia A. Howell

Position:

Me

Notes:

infrared non-destructive evaluation

Organization:

National Institute of Standards and Technology

Component:

Semiconductor Electronics Division

Address:

Gaithursburg, MD 20899

Contact:

J.R. Lowncy

Position: Notes:

Co-Authored "Heavily Accumulated Surfaces of MCT Detectors: Theory and

Experiment" for 1992 MCT Workshop.

For 1991 Workshop, "Investigation of Mercury Interstititals in MCT Alloys

Using Resonant Impact-Ionization Spectroscopy*

Organization:

National Taiwan University

Component:

Department of Electrial Engineering Taipei, Taiwan, REPUBLIC OF CHINA

Address: Contact:

Shi-Chen Chao

Position:

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Electrolyte Eletroreflectance

Specttoscopies for the lon-Implanted HgCdTe with Thermal Annealing"

Organization:

NEC Corporation

Component:

Address:

4-1-1 Miyazaki

Miyamac, Kawasaki, 216 JAPAN

Contact:

T. Sasaki

Position:

of an Mr.

Notes:

Co-authored for 1991 MCT Workshop "Study of CdTe Epitaxial Growthn on

(211)B GaAs by MBE"

NEC Corporation

Component:

Microelectronics Research Laboratories 1120, Shimokuzawa, Kanagawa 229, JAPAN

Address: Contact:

A. Tanabe

Position:

Mr.

Notes:

Co-authored for 1992 SPIE workshop on IRFPAs "Optimum Barrier Height in

Schottky-Barrier Infrared CCD Image Sensor"

Organization:

NESLAB Instruments Inc

Component:

PO Box 1178

Address:

Portsmouth, NH 03802-1178

Contact:

Position:

Notes:

cyrogenic equipment

Organization:

New Jersey Institute of Technology

Component:

Address:

Newark, NJ 07102

Contact:

N.M. Ravindra

Position:

Notes:

Authored for 1992 SPIE meeting on IRFPAs "HgCdTe Photovoltaic Detectors

and Some Related Aspects"

Organization:

Component: Address:

Newport Corporation

18235 Mount Baldy Circle

Fountain Valley, CA 92708

Contact:

Dr Tom Galantowicz

Position:

CEC

Notes:

Electro-optic and electro-mechanical components and systems for laser optical

applications.

Newport Industrial Glass Inc.

Component: Address:

2044-C Placentia Avenue Costa Mesa, CA 92627

Contact: Position:

Ray Larsen Director

Notes:

Manufacturer of CdTe, GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications.

Organization:

Nichols Research Corp.

Component:

Address: 4040 South Memorial Parkway

Huntsville, AL 35802

Contact:

Patsy Hattox Vice President

Position: Notes:

Infrared systems and equipment, imaging software

Organization:

Nicolet Instrument Corporation

Component:

Spectra Tech Inc.

Address:

652 Glenbrook Rd, PO Box 2190-G

Stamford, CT 06906

Contact:

Donald Sting

Position:

CEO

Notes:

Infrared spectroscopy instruments and applications.

Organization:

Night Vision Equipment Co., Inc.

Component:

Address:

P.O. Box 266

Emmaus, PA 18049

Contact:

Gene Adcock

Position:

Dir. U.S. Govt. Programs

Notes:

e/o systems, infrared systems and equipment, night vision equipment

19

Norman Axelrod, Associates

Component:

Norman N. Axelrod Associates Development Laboratory

Address:

28 W 44th St

Contact:

New York, NY 10036

Norman Axelrod

Position:

Pres

Notes:

Planning, development, and fabrication of electro-optical, laser, and machine vision systems for on-line sensing and control, digital and analog information;

computer automated optical systems.

Organization:

North Atlantic Industries, Inc.

Component:

Address: 60 Plant Avenue

Hauppauge, NY 11788-3890

Contact: Position: Marvin Friedman Director of Marketing

Notes:

Thermal imaging

Organization:

North Carolina State University

Component:

Department of Physics Raleigh, NC 27695-8202

Address: Contact:

P.K. Baumann

Position:

Notes:

Authored for 92 MCT workshop "Growth of HgSe and HgCdSe Thin Films by

11:1

Molecular Beam Epitaxy"

Organization:

North Texas State University

Component:

Department of Physics

Address:

Denton, TX

Contact: **Position:** Chris L. Littler

Notes:

Authored July 1990 "Two-Photon Absorption Characterization of HgCdTe"

Northrop Corp.

Component:

Electronics Systems Division

Address:

600 Hicks Road

Rolling Meadows, IL 60008-1098

Contact:

Laurel Chivari

Position: Notes:

Manager, Public Relations infrared systems and equipment

Organization:

Northrop Corporation

Component: Address:

Hawthorne Site 2301 W120th St

Hawthorne CA 90250-5032

Contact: Position: Kent Kresa

Notes:

CEO

Precision inertial sensors and lasers.

Organization: Component:

Northrop Corporation Rolling Meadows Site

Address:

600 Hicks Rd.

Contact:

Rolling Meadows, IL 60008

Northwestern University

James Owlswey VP

Position Notes:

Development of electronic and infrared detection systems.

Organization:

Component:

Address:

Contact:

Manijeh Razeghi

Position:

Dr.

Notes:

Presented at December 1992 DARPA IRFPA Technology Program Reviews on "Physics and Performance of GaInP/GaAs Quantum Wells and New

Infrared III-V Compound InTiSb

Organization: Component: Northwick Park Hospital Dept of Orthopaedics

Address:

Watford Road

Harrow, UNITED KINGDOM

Contact:

Leonard Klenerman

Position:

Dr.

Notes:

active in infrared biomedical thermography

Organization:

Notre Dame University
Physics Department

Component: Address:

255 Nieuwland Hall Notre Dame, IN 46556

Contact:

Hong Luo

Position:

Notes: Attended 1992 MCT workshop

Organization:

ation: ORS Automation

Component: Address:

402 Wall St.

Princeton, NJ 08540

Contact:

Edward Kornstein

Position:

Pres

Notes:

Controls and guidance directed towards problems in machine vision for

individual usc.

Organization:

Officine Galileo

Component:

Address:

V.A. Einstein 35

50013 Campi Bisenzio, Florence

ITALY

Contact:

Michele Pimpinenelli

Position:

Marketing

Notes:

Night vision, thermal lamging, infrared systems & equipment

Ohio State University

Component: Address:

469 Dreese Lab 2015 Knil Avenue

Columbus, OH 43210-1210

Contact:

Kim Boyer

Position: Notes:

active in infrared process control

Organization:

Omnidata International Inc.

Component:

Address: 750 W 200 North, PO Box 3489

Logan, UT 84321

Contact:

Gilbert Larson

Position:

Pres

Notes:

Development of environmental and industrial sensors, hardware and software

for data collection systems.

Organization:

Optical Energy

Component:

Address:

472 Westover Rd

Stamford, CT 06902

Contact:

Gerald Falbel

Position:

Chmn

Notes:

Research into electro-optical engineering.

Organization:

Component:

Optical Radiation Corp.

Address:

1300 Optical Dr.

Azusa, CA 91702

Contact:

Richard Wood

Position:

Notes:

Development of electro-optical systems.

Optical Research Associates

Component:

Address: 550 N Rosemead Blvd.

Pasadena, CA 91107

Contact:

Thomas Harris

Position:

Pres

Notes:

Research in optical design engineering.

Organization:

Optical Semiconductors Inc.

Component:

Address:

8 John Walsh Blvd, Suite 421

Peckskill, NY 1 66-5330

Contact:

Brian Fitzpatrick

Position:

President

Notes:

Manufacture of ZnS and ZnSe for infrared systems.

Organization:

Optical Technologies, Inc.

Component:

Address:

Suite 1200, 360 Herndon Pkwy

Herndon, VA 22070

Contact:

Robert Einzig

Position:

Pres

Notes:

Research and development of fiber optic sensors for the measurement of

Ĺ

physical parameters.

Organization:

Optoelectronics- Textron

Component:

Address:

1309 Dynamics St. PO Box 750039

Petaluma, CA 94975-0039

Contact:

Peter McGrath

Position:

General Manager

Notes:

Manufactures lead salt infrared detectors and related components

Optotex, Ltd.

Component:

62 Stencie Drive

Address:

Kanata, Ontario, CANADA K2K 2A9

Contact:

David Kennedy

Position: Notes: Marketing Manager
GaAs gate arrays, infrared systems and equipment, rf systems and components

Oriel Corp

Organization: Component:

Component: Address:

250 Long Beach Blvd., PO Box 872, Stratford, CT 06497

Contact:

Eugene Arthurs

Position:

Dir

Notes:

Optics and detectors for ultraviolet through infrared systems.

Organiz An:

Osprey Sub-Sca, Inc

Compe wat:

Address:

1225 Stone Dr.

San Marcos, CA 92069

Contact:

Tony Gardiner

Position:

Pres

Notes:

Night vision equipment and acoustic tracking systems.

Organization:

Overhead Door Corp

Component:

Horton Automatics Division

Address:

1900 Crown Dr.

Farmers Branch, TX 75234

Contact:

Robert Haugh

Position:

Pres

Notes:

Microwave and infrared sensing technology.

Overhoff Technologies Corporation

Component:

1160 US RT 50, PO Box 182

Millford, OH 45150

Contact:

Address:

Dr MW Overhoof PhD

Position:

Pres

Notes:

Infrared, other optical, ultraviolet and nuclear, gaging.

Organization:

Oxley Developments Co., Ltd.

Component:

Address:

Priory Park

Ulverston

Cumbria, UK LA12 9QG

Contact:

J.A. Pickup

Position:

Sales Admin. Manager

Notes:

detectors and sensors, infrared systems and equipment

Organization:

Component:

Oxley, Inc.

Address:

25 Business Park Drive

P.O. Box 814

Branford, CT 06405

Contact:

Audra Kurelaitis

Position:

Sales Manager

Notes:

c/o systems, night vision, infrared systems & equipment

Organization:

Component:

Pacer Systems, Inc.

Address:

900 Technology Park Drive

Billerica, MA 01803

Contact:

Joe Straub

Position:

Manager, Signal Processing Systems

Notes:

infrared systems & equipment

Paramax Systems Corp.

Component:

8201 Greensboro Drove, Suite 1000

McLean, VA 22102

Contact:

Address:

Gary Teagarden

Position:

Dir. Marketing Communications

Notes:

passive and active e/o systems, e/o systems, infrared systems and equipment

Organization:

Pattern Processing Technologies

Component:

Address:

Suite 170, 10025 Valley View Rd.

Eden Prairie, MN 55344

Contact:

Joseph Christenson

Position:

Pres

Notes:

Product oriented machine vision systems.

Organization:

PCI Inc.

Component:

Address:

50 West Wilmot Street, Unit 3

Richmond Hill, Ontario L4B 1M5

CANADA

Contact:

Position:

Notes:

REMOTE SENSING SYSTEMS, THERMAL INFRARED,

MULTISPECTRAL

Organization:

Peda-Scan Infrared Service, Inc.

Component:

Address:

1932 Olde Eisenbath Ln.

Foristell, MO 63348

Contact:

Steven Eisenbath

Position:

Pres

Notes:

Research for industry; thermal evaluation of performance of products.

Perceptronics Incorporated

Component:

Address: 21135 Erwin Street

Woodland Hills, CA 91365-4198

Contact:

Christopher Harz

Position:

VP Mkt.

Notes:

Has been awarded several government contracts to conduct research and development of computer aided manufacturing processes for IRFPAs.

Organization:

Pharm-Eco Laboratorics

Component:

Address:

2355 Chain Dr.

Simi Valley, CA 93065

Contact:

DR Kurt Grimm

Position:

Pres

Notes:

Infrared research, gas chromatography and wet chemical tests.

Organization:

Pharos Inc.

Component:

Agema Infrared Systems

Address:

595 Skippack Pike Blue Bell, PA 19128

Contact:

Phillip Smith

Position:

Pres

Notes:

Infrared measurement systems.

Organization:

Phase 4 Infrared

Component:

Address:

P.O. Box 2647

Acton, MA 01720

Contact:

R. Gentilman

Position:

Pres.

Notes:

Manufacturer of ZnS and ZnSe for infrared applications.

Philadelphia Electric Company

Component:

Peach Bottom Atomic Power Station

Address:

Rd #1 Box 208 Delat, PA 17314

Contact:

Robert N. Wurzbach

Position:

Mr.

Notes:

active in infrared predictive maintenance

Organization:

Philips Infrared Defense Components

Component:

Address:

Milbrook Industrial Estate,

Southampton, SO9 7BH UNITED KINGDOM

Contact:

Position:

Notes:

A large producer of 64X64 HgCdTe FPAs. Primarily sold to GEC Sensors for use on a wide variety of systems. Manufactures and supplies infrared detectors

based on MCT, TGS, and other materials for use in night vision and industrial

applications.

Organization:

Photon Energy

Component:

Address:

El Paso, TX

Contact:

Position:

Notes:

Mass production of CdTe for solar applications.

Organization:

Photox Optical Systems

Component:

Address:

P.O. Box 274

Headington, Oxford, OX3 OBJ UNITED KINGDOM

Contact:

Jean Aitchison

Position:

Gen Mgr.

Notes:

Manufacture of GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications.

Photronics Corp.

Component: Address:

270 Motor Parkway

P.O. Box 11368

Hauppauge, NY 11788

Contact:

Peter C. Connolly

Position:

Business Development Manager

Notes: e/o systems, infrared systems and equipment, night vision

Organization:

Picker International, Ltd.

Component: Address:

Engineering Dept

P.O. Box 2, East Lane

Wembley, HA9 7PR, UNITED KINGDOM James E. Cuilcy

Contact: Position:

osition:

Notes: active in infrared biomedical thermography

Organization:

Pilkington Optronics

Component:

Address:

Caxton Street

Anniesland, Glasgow GL13 1HZ

Contact:

Tom O'Neill

Position:

CEO

Notes:

Thermal imaging and surveillance systems, laser rangefinders, etc. visible and IR optical systems. Producer of HgCdTe-based FPSs for a variety of military

systems, including the IRST on the EFA.

Organization:

Pilkington Visioncare

Component: Address:

Coburn Optical Industries Suite 200, 4606 S Garnett

Tulsa, OK 74146

Contact:

John Blocha

Position:

President

Notes:

Development of infrared products for military and commerical applications.

PJ Wolfson Co Inc

Component:

Address: 50 Kewanec Road

New Rochelle, NY 10804

Contact:

Position:

Notes:

cyrogenic equipment

Organization:

Plasma Physics Corp.

Component:

Address: PO Box 548

Locust Valley, NY 11560

Contact:

John Coleman

Position:

CEO

Notes:

Development and manufacture of photoreceptor drums, solar cells and

imaging, polymer laminating, and laser isotope separation.

Organization:

Plessey Semiconductors Ltd.

Component: Address:

Unit 1, Crompton Road

Groundwell Ind. Estate, Scindon, Wilts SN2 5AY

UNITED KINGDOM

Contact:

Ernie Pusey

Position:

Mkt. Dir.

Notes:

Manufacture of a wide variety of HgCdTc-based infrared systems.

Organization:

PPM Pure Metals

Component:

Address:

111 Richmond Street, West, Suite 418 Toronto, Ontario, CANADA M5H 2G4

Contact:

Raymond Wary

Position:

Sls Mgr

Notes:

Manufacture of germanium for infrared technologies.

Preh Electronic Inc.

Component:

Address: 470 E. Main

Lake Zurich, IL 60047

Contact:

Pat Jones

Position:

Sales Manager

Notes:

Infrared systems & equipment

Organization:

Pulse Instruments

Component:

Address: 1234 Francisco Street

Torrance, CA 90502

Contact:

Ron Perry

Position:

Dir. Sales and Marketing

Notes:

e.o systems, infrared systems & equipment

Organization:

Pure Tech Inc.

Component:

Address:

P.O. Box 1319

Carmel, NY 10512

Contact: Position:

Earle Ellessen

Position: Notes: Pres.

Manufacture of CdTe, germanium, silicon, ZnS, and ZnSe for infrared

applications.

Organization:

Qingdao University

Component:

Department of Computer and Information Science

Address:

Qingdao, Shandong, CHINA

Contact:

Yan Jing-Xuan

Position: Notes:

Co-authored for 1992 SPIE conference on IRFPAs "The Dependence of Fermi

Level of HgCdTe on Impurity Concentration and Temperature"

R&D Institute for Semiconductor Devices

Component: Address:

ROMANIA

Contact:

E.T. Harlmagean

Position: Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Accurate

Method for Neutraon Fluence Control Used in Improving Neutron-

Transmutation-Doped Silicon Detectors*

Organization:

Component:

Ramey Aerospace

Address: **Box 39**

Carmel, CA 93924

Contact: Position:

Tom Ramey President

Notes:

Thermal Imaging, Infrared systems & equipment

Organization:

Ramtek Corporation

Component:

Address:

1525 Atteberry Lane

San Jose, CA

Contact:

Position:

Notes:

remote sensing systems, multispectral

Organization:

Ranco, Inc

Component:

Paragon Electric Comp.

Address:

606 Parkway Blvd.

Two Rivers, WI 54241

Contact:

T Growcock

Position:

VP

Notes:

Photo-electric controls.

111 5 JOHN CO.

Raytheon Submarine Signal Division

Component:

Address: 1847 West Main Road

Portsmouth, RI 02871

Contact:

Paul Hitchen

Position:

Marketing Comm. Mgr.

Notes:

Thermal imaging, detectors and sensors

Organization:

Component:

Recognition Concepts, Inc.

Address:

5200 Convair Drive

Contact:

Carson City, NV 89706 Debra Withrow

Position:

Advertising Manager

Notes:

infrared systems & equipment, imaging software

Organization:

Renssalaer Polytechnic Institute

Component:

Physics Department and Center for Integrated Electronics

Address:

Troy, NY 12180

Contact:

E.Y. Lee

Position:

Notes:

Co-authored for 1992 meeting of SPIE on IRFPAs "Fundamental Studies of Schottky Barrier IR Detectors by Ballistic Electron Emission Microscopy"

Organization:

Rensselaer Polytechnic Institute

Component:

ECSE Department Troy, NY 12180

Address: Contact:

Ishwara B. Bhat

Position:

Notes:

Co-authored "Improved CdTe Layers on GaAs and Si Substrates, Grown by

Atomic Layer Epitaxy" for 1992 MCT Workshop.

Co-authored for 1991 MCT Workshop "Low Temperature Epitaxy of HgTe, CdTe, and HgCdTe Using Flow Modulation Techniques" and "Reduced Metal-

Insulator Semiconductor Tunneling in MOCVD MC(111)Te Films"

Research Devices, Inc.

Component:

Address:

121 Ethel Road West

Piscataway, NJ 08854 Michael Schneider

Contact:

IVIICII

Position:

Mr.

Notes:

AUthored for 1992 SPIE Workshop on MCT "Hybridizing Focal Plane

Arrays."

Organization:

Research Opportunities, Inc.

Component:

Address:

2200 Hamipola Court Suite 101

Torrance, CA 90501

Contact:

William De La Torre

Position:

Mr,

Notes:

infrared non-destructive evaluation

Organization:

RGB Spectrum

Component:

Address:

950 Marine Village Parkway

Alameda, CA 94501

Contact:

Robert P. Marcus

Position:

President

Notes:

Thermal imaging

Organization:

Component:

RICOR Ltd.

Adding

Address:

En Haros (IHUD)

18960

Isracl

Contact:

N. Pundak

Position:

Mr.

Notes:

Authored for 1992 SPIE IRFPA workshop "Miniature Closed Cycle Cooler for

FPA Detectors*

Robotron Corp.

Component: Address:

21300 W Eight Mile Rd.

PO Box 5090, Southfield, MI 48086

Contact:

Leonard Brzozwski

Position:

Pres

Notes:

Ion processing and other non-traditional heat treating processes, welding of

ferrous and non ferrous metals

Organization:

Rockwell Engineering Co., Inc.

Component:

Address:

2121 E. 45th St

Indianapolis, IN, 46205

Contact:

Tom Rockwell

Position:

CEO

Notes:

Optical radiation research.

Organization:

Rockwell International Corp.

Component:

Government Business Division

Address:

1201 S Second St. Milwaukee, WI 53204

Contact: George Brooks

Position:

George Brooks
Group Vice President

Notes:

Passive electronic components.

Organization:

Rockwell International Corporation

Component:

Defense Electronics

Address:

3370 Miraloma Avc.

Anaheim, CA 92803

Contact:

J.A. McLuckey

Position:

President

Notes:

Electro-optical products and systems.

Rockwell International Corporation

Component:

Electro-Optical Center 3370 Miraloma Ave. Anaheim, CA 92803

Contact:

Address:

J.B. Gilpin

Position:

Manger Detector Products

Notes:

Also their representative in the JM consortium

Organization:

Rockwell International Corporation

Component:

Industrial Control Group

Address:

1201 S Second St. Milwaukee, WI 53204

Larry Yost

Contact: Position:

SrVP

Notes:

Automation systems and industrial controls.

Organization:

Rockwell International Corporation

Component:

Science Center

Address:

1049 Camino Do Rios PO Box 1085

Thousand Oaks, CA 91358

Contact:

Joseph Longo

Position:

VP

Notes:

Basic applied research in electro-optics.

Organization:

Rocky Mountain Instrument Co.

Component:

Address:

1501S Sunset St.

Longmont, CO, 80501

Contact:

Yubong Hahn

Position:

Pres

Notes:

Manufacture of precision optical components and multilayer thin film coatings.

Rodenstock Industrial Optics

Component:

P.O. Box 14 04 40

Jsartalstrasse 43

D-8000 Munich 5, GERMANY

Contact: Position:

Address:

Mangred Schuck Senior Manager

Notes:

infrared systems & equipment, e/o systems, thermal imaging

Organization:

Rosemount Inc.

Component: Address:

Aerospace Division 14300 Judicial Road Burnsville, MN 55337

Contact:

Sol Mirelez

Position:

Marketing Communications Manager

Notes:

Organization:

S.I. Vavilov State Optical Institute

Component:

Address:

Moscow, RUSSIA M.M. Miroshnikov

Contact: Position:

Mr.

Notes:

Authored for 1991 SPIE meeting on Infrared Technology "Infrared in the USSR: Brief Historical Survey of Infrared Development in the Soviet Union*

Organization:

Sam Houston State University

Component: Address:

Department of Physics Huntsville, TX 77341

Contact:

W. Covington

Position:

ane

Notes:

Co-authored "Properties of InAs/(Ga,In)Sb Strained Layer Superlattices

Grown on the (111) Orientations" for 1992 MCT Workshop

Sandia National Labs

Component:

Address:

ORG 8246

P.O. Box 969

Livermore, CA 94511

Contact:

Elizabeth A. Fuchs

Position:

Notes:

active in infrared remote sensing

Organization:

Santa Barbara Focalplane

Component:

Address:

69 Santa Felicia Drive

Golcta, CA 93117

Contact: Position:

Brett Rosner Scnior Engineer

Notes:

Organization:

SAT

Component:

Address:

41, ruc Cantagrel

F-75361 Paris Cedex 13 FRANCE

Contact:

Bernard Christophe

Position:

Notes:

Along with Thomson CSF, places HgCdTe-based sensors on a variety of

military products, including the Rafale fighter. Also produces own InSb-based

IRFPAs for use in missile guideance.

Organization:

Component:

Satcon Technololgy Corp.

Address:

12 Emily ST.

Cambridge, MA 02139-4507

Contact:

David Eisenhaure

Position:

Prcs

Notes:

Power electronics and system integration.

Scandinavian Avionics

Component:

Address:

Billund Airport

P.O. Box 59

7190 Billund, DENMARK

Contact:

E.M. Talund

Position:

Defece Sales

Notes:

infrared systems and equipment, thermal imaging, night vision

Organization:

Component:

Schlumberger Limited Statham Transducers

2230 Statham Rd.

Contact:

Address:

Oxnard, CA 93033 Malcom Unsworth

Position:

Gmgr

Notes:

Micromachined silicone and thin film sensors.

Organization:

Schott Glaswerke

Component:

Address:

Mainz, Germany

Contact:

Position:

Notes:

Manufacture of ZnS and ZnSe for infrared applications.

Organization:

Schwartz Electro-Optics

Component:

Address:

3404 N Orange Blossom Trail

Orlando, FL 32804

Contact:

WC Schwartz

Position:

President

Notes:

Medical and industrial applications of mid infrared solid state systems.

Science & Engineering Consultants, Inc.

Component:

Address: Suite 300, 1820 discovery St.

Reston, VA 22090-5610

Contact:

Dr Joseph Siewick

Position:

CEO

Notes:

Research in imaging and remote sensing.

Organization:

Science & Technology Corp

Component:

Address: 10

101 Research Dr., PO Box 7390

Hampton, VA 23666

Contact:

A. Deepak

Position:

Presidnent

Notes:

Development and manufacture of electro-optic sensors.

Organization:

Scisco Inc

Component:

Address: 6020 Academy, NE PO Box 25446

Albuquerque, NM 87125)

Contact:

AZ Lazzara

Position:

Pres

Notes:

Optical sensor data reduction.

Organization:

Scott-White Clinic

Component:

Address:

Temple, TX 76501

Contact:

Mitchell R. Smigield

Position:

Dr.

Notes:

active in infrared biomedical thermography

Semcor Inc

Component:

Address: 815 E Gate Dr.

Mount Laurel, NJ 08054

Contact:

Vincent Vidas

Position:

CEO

Notes:

Optical, infrared, and ultraviolet detection systems.

Organization:

Semi-conductor Devices, Inc.

Component:

Address: D.N. Misgav

20179 ISRAEL

Contact:

A. Kepten

Position:

Mг.

Notes: Co-authored for 1992 SPIE Workshop on IRFPAs "p-Channel MIS Double-

Metal Process InSh Monolithic Unit Cell for Infrared Imaging"

Organization:

Semiconductor Processing Co., Inc.

Component:

Address: 409 East First Street

Boston, MA 02127

Contact:

Nicholas Sink Gcn. Mgr.

Position: Notes:

Manufacturer of GaAs, germanium, and silicon for infrared applications.

Organization:

Sensor Control Corporation

Component:

Gentran

Address:

49050 Milmont Dr.

Fremont, CA 94538

Contact:

Paul Page

Position:

Mgr

Notes:

Infrared temperature measurements.

Sensors Unlimited, Inc.

Component:

Address: Contact:

Princeton, NJ Greg Olsen

Position:

Mr.

Notes:

Start up company founded by former persident and CEO of EPITAXX, Inc., to advance recent developments in III-V compound device tech fro sensing and imaging applications in the 1000-3000 nm near-infrared spectrym. Ongoing development projects include a monolithic InGaAs detector for NASA Jet Propulsion Labs and 2000-5000 DFB lasers for Kirtland Air Force Base

Phillips Lab.

Organization:

Sequa Corporation

Component:

Kollsman Military Systems

Address:

220 Daniel Webster Merrimack, NH 03054

Contact:

Ronald Wright

Position:

President

Notes:

A variety of infrared research using primarily HgCdTe and InSb. Most

HgCdTe is reportedly supplied by Sofradir.

Organization:

Component:

Servo Corporation of America

Address:

111 New South Road Hicksville, NY 11802

Contact:

Alan Doctor

Position:

Sales & Marketing Manager

Notes:

Organization:

Shandong University

Component:

Infrared and Remote Sensing

Address: Contact:

Jinan, Shandong, CHINA

Position:

Hu Xicrong

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Study of the Recombination

Mechanisms and Carrier Lifetimes in HgCdTe Alloy"

Shanghai Institute of Technical Physics

Component: Address:

Academia Sinica China 200083 Xu Guosen

Contact:

Position: Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "The Effect of Shockley-Read

Recombination on Minority Carrier Lifetime of HgCdTe*

Organization:

Component:

Siemens AG

Address:

SI SM MA

Landsluter Strassc 26

8044 Unterschleissheim, GERMANY

Contact:

U. Zinnegger

Position:

Marketing Manager

Notes:

Infrared systems & equipment, night vision

Organization:

Component:

Silicon Casting Inc.

Address:

2616 Mercantile Drive

Rancho Cordova, CA 95742

Contact:

Joseph DeSimone

Position:

Pres.

Notes:

Manufacturer of silicon for infared applications.

Organization:

Silicon Sensor Inc

Component:

Address:

Hwy 18 E PO Box 137

Dodgeville, WI 53533

Contact:

Robert Bachner

Position:

CEO

Notes:

Manufacture of light sensitive products.

Silicon Valley Group, Inc.

Component:

Address: 2240 Ringwood Ave.

San Jose CA 95131

Contact:

Vahne Farkissian

Position:

Pres

Notes:

Semiconductor wafer processing equipment.

Organization:

Silonex Inc

Component: Address:

Silonex, Inc 2150 Ward St.

Montreal CANADA PQ H4M 1T7

Contact:

Alex Kalil

Position:

Pres

Notes:

Optoelectronics automation of manufacturing.

Organization:

Component:

Societe Anonyme de Telecommunications

Address: 41, ruc Cantagrel

75631 Paris, Cedex 13 FRANCE

Contact:

D. Lorans

Position:

Notes:

Co-authored for 1992 MCT Workshop "Substrate Issues for Mercury Cadmium

Telluride"

Organization:

Societe de Fabrication d'Instruments de Mesure

Component:

Address:

13 avenue Ramolfo Garnier

F91344 Massy Dedex FRANCE

Contact:

Ginette Sarrazin

Position:

> 9 Service Publicite

Notes:

thermal imaging, night vision equipment

Sofradir

Component: Address:

43-47 rue Camille-Pellctan

92290 Chatenay-Malabry, FRANCE

Contact:

Position:

Notes: Thomson CSF owns 40 percent, SAT owns 40 percent, and CEA owns 20

percent of this company, which is France's largest producer of infrared

materials. There are currently over 20 programs underway utilyzing HgCdTe.

Organization:

Sogem-Afrimet Inc.

Component:

Address:

1212 Avenue of the Americas

New York, NY 10036

Contact:

Edward Kielty

Position:

Mr.

Notes:

Manufacturer of germanium for infrared applications.

Organization:

Solar Power Engineering Company

Component:

Address:

PO Box 91

Morrison, CO 80465

Contact:

Harrison Wroton

Position:

Pres

Notes:

Tracking photovotaic tracking power systems.

Organization:

Sorcq Nuclear Research Center

Component: Address:

ISRAEL

Contact:

D. Eger

Position:

Mr.

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Anodic

Oxides on HgZnTe"

Southern Illinois Univ School of Medecine

Component:

Address: P.O. Box 9230

Springfield, IL 62794-9230

Contact:

Roger B. Traycoff

Position:

Dr.

Notes:

active in infrared biomedical thermography

Organization:

Southern Methodist University

Component:

Address:

Contact:

A.R. Khotanzad

Position:

Notes: Co-authored for 1992 SPIE meeting on Machine Vision "Automated Vision

System for INspection of Wedge Bonds"

Organization:

Component:

Southern Nuclear Operating Center

Address: 40 Inverness Center Parkway

Birmingham, AL 35242

Contact:

Albert E. Hammett

Position:

Mr.

Notes:

active in infrared predictive maintenance

Organization:

Component:

Southwest Engineering

Address:

714 First National Bank Bldg.

Fort Smith, AR 72901

Contact:

Myles Friedman

Position:

Pres MyPres

Notes:

Computer/electronic controls for manufacturing processes.

SPAR Aerospace, Ltd.

Component:

Advanced Technology Systems Group

Address:

9445 Airport Road

Brampton, Ontario, CANADA L6S 4J3

Contact:

G. Stan Boyington

Position:

Director Business Development

Notes:

Infrared systems and equipment, e/o systems, thermal imaging

Organization:

Spar Acrospace, Ltd.

Component:

Applied Systems Group

Address:

365 March Road

Kanata, Ontario, CANADA K2K 1X3

Contact: Position: Bruce Hinman Dir. Business Development and Contracts

Notes:

c.o systems, infrared systems & equipment, night vision

Organization:

SPEC Industries

Component:

Address:

Edison, NJ

Contact:

Position:

Notes:

Produces a 1024 X 256 pixel format CCD detector array that doubles the

specral coverage avilable from SPEC industries

Organization:

Component:

Specac Ltd.

Address:

River House, Lagoon Rd.

St. Mary Cray, Orpington, Kent BR5 3QX

UNITED KINGDOM

Contact:

W.R. Bradbury

Position:

Mktg. Dir.

Notes:

Manufacture of germanium, silicon, ZnS, and ZnSe for infrared applications.

Spectrogram Corp.

Component:

385 State St.

Address: North Haven, CT 06473

Contact:

Herbert Gram

Position:

Pres

Notes:

General research in the field of electro-optics, with a major effort on

computer-based optical spectrum analysis as applied to analytical systems.

Organization:

Spectron Engineering Inc.

Component:

Address: 255 Yuma Court

Denver, CO 80223

Contact:

Position:

Notes:

remote sensing systems, thermal infrared, multispectral

Organization:

Component:

Spire Corp

Address:

Onc Patriots Park

Bedford, MA 01730

Contact:

Roger Little

Position:

President

Notes:

Photovoltaics, solar cells, compound, semiconductor thin films, and high temperature super conductors. Recently opened a new facility in Oman to

produce solar cells. Manufacture of CdTc, GaAs, germanium, and silicon for

infrared applications.

Organization:

Component:

SRI International

Address:

Menlo Park, CA 94025

Contact:

M.A. Berding

Position: Notes:

Co-Authored "Native Defect Equilibria in HgZnTe and HgCdTe Alloys" for

1992 MČT Workshop.

For 1991 Workshop, "Defect Equilibrium in HgTc"

SRS Technology

Component: Address:

Suite 402 3501 Jamboree

Contact:

Newport Beach, CA 92660 MS Sandhu

Position:

Pres

Notes:

Development of smart sensors, conformal-array antennas, image processing,

field measurements, and process control systems.

Organization:

Stanford University

Component:

Address:

McCullough MS 251

Stanford, CA 94305

Contact:

Jose L. Melendez

Position:

Notes:

Attended 1992 MCT Workshop

Organization:

State Univ of NY at Buffalo

Component:

Dept of Elec & Computer Engineering

Address:

Bell Hall

Buffalo, NY 14214

Contact:

Darold C. Wobschall

Position:

Dr.

Notes:

active in infrared biomedical thermography

Organization:

State University of NY at Buffalo

Component:

Dept of Biophysiacl Sciences

Address:

120 Cary Hal!

Buffalo, NY 14214

Contact:

Robert A. Spangler

Position:

Dr.

Notes:

active in infrared biomedical thermography

4 10 44 1

Stocker & Yale, Inc

Component:

Address: 133 Brimbal Ave.

Beverly, MA 01915

Contact:

J Bickman

Position:

Pres

Notes:

Optical measuring units for manufacturing controls.

Organization:

Structure Probe

Component:

Address:

569 E Gray St., PO Box 656

West Chester, PA 19381-0656

Contact:

Dr Charles Garber

Position: Notes: Pres

X-ray diffraction and thermal analysis.

Organization:

Sumitomo Metal Mining Co. Ltd

Component:

Address:

Tokyo, Japan

Contact:

Position:

Notes:

Manufacture of CdTe and GaAs for infrared applications.

Organization:

Sunstrand Corp.

Component:

Analytical Productions Division

Address:

820 Linden Ave.

Rochester, NY 14625

Contact:

Harry Stonecipher

Position:

Pres

Notes:

Image analysis equipment systems and color spectrometry.

SUNY at Stony Brook

Component:

Department Materials Sci & Eng Stony Brook, NY 11794-2275

Address: Contact:

Michael Dudley

Position:

Mr.

Notes:

Attended 1992 MCT conference

Organization:

SUNY College of Technology

Component:

Address:

Contact:

Abdelrahman Rabie

Position:

Notes:

AUthored 1983 "The Use of Sensors in Part Handling" available from S.M.E.

Organization:

Superior Evaporants

Component:

Address:

6965 Highway 9

Feiton, CA 95018

Contact:

Christopher Toth

Position:

President

Notes:

Manufacturer of germanium, silicon, ZnS, and ZnSe for infrared systems.

Organization:

Surveillance Research Laboratory

Component:

Address:

DSTO

O,I, Bix 1500

· . . . 3~

Salisbury, South Australia, 5108

Contact:

R.H. Hartley

Position:

Mr.

Notes:

Co-authored for 1991 MCT Workshop "Real Time Control of the MBE Growth of CdHgTe and CdTe/GhTe Superlattices Using Ellipsometry"

 ${\bf Organization:}$

Swedish Space Corporation

Component:

Address: PO Box 4207, S-171 04

Solna, SWEDEN

Contact:

Position:

Notes: remote sensing systems, thermal infrared

Organization:

Syracuse Research Corp.

Component:

Defense Electronics Engineering

Address:

Merrill Ln.

Syracuse, NY 13210

Contact:

Kenneth Kun

Position:

Pres

Notes:

Optical and IR systems analysis.

Organization:

Component:

Target Corp.

Address:

8400 Lakeview Parkway, Suite 200

Kenosha, WI 53142-7404

Contact:

Carol L. Oxley

Position:

President

Notes:

infrared systems and equipment, passive and active e/o devices

Organization:

Tau Corporation

Component:

Address:

Los Gatos, CA

Contact:

Donald Hutchinson

Position:

Marketing Director

Notes:

Technical Research Center of Finland

Component:

Building Laboratory

Address:

P.O. Box 167

Contact:

SF-90101 Oulu, FINLAND

Timo Kaupinnen

Position:

Notes:

Organization:

infrared non-destructive evaluation

Component:

Technion University

Address:

Technion City

Haifa, Israel 3200 Yael Nemirovsky

Contact: Position:

IIT Department of Electrical Engineering

Notes:

Attended 1992 MCT Workshop

Organization:

Technische Universtat

Component: Address:

Phsik-Department E-16 mUNCHEN, d-8046

GERMANY

Contact:

F. Koch

Position:

Notes:

Co-authored for 1991 MCT Workshop "Influece of Resonant Defect States on

Subband Structures in HgCdTe"

Organization:

Technology, Architectural, and Engineering Services

Component:

Public Works Canada

Address:

Riverside Drive

Ottawa, Ontario, CANADA KIA OM2

Contact:

Antonio Colantonio

Position:

Mr.

Notes:

infrared non-destructive evaluation

Tektronix, Inc.

Component: Address:

26600 Southwest Parkway

Beaverton, OR 97077

Contact:

Robert Dixon

Position:

Mr.

Notes:

infrared non-destructive evaluation

Organization:

Teltron, Inc.

Component: Address:

2 Riga Ln.

Birdsboro, PA 19508

Contact:

Arthur Mengel

Position:

Pres Pres

Notes:

Development and production of UV, IR, and TV cameras.

Organization:

Texas Brazing Inc

Component:

Microwave Products Grp

Address:

400 E Highway 80

Forney, TX 75126

Contact:

Position:

Notes:

cyrogenic equipment

Organization:

Texas Instruments

Component:

Central Research Laboratories

Address:

P.O. Box 655936, MS 154

Dallas, TX 75265

Contact:

Luigi Colombo

Position:

Mr.

`iotes:

Texas Instruments

Component:

Defense Systems and Electronics Group

Address:

POB 660246 MS 3139

Contact:

Dallas, TX 75266

Ronny Dunn

Position:

Infrared Program Manager

Notes:

Organization:

Texas Instruments

Component:

Infrared Devices Laboratory

Address: Contact:

Dallas, TX 75265 J.D. Luttmer

Position:

Mr.

Notes:

The Microelectronics Manufacturing Science and Technology Progarm at Tl is developing a generaic semiconductor device manufacturing technology for the mid-1990's. Although the program goal is to develop and demonstrate low volume, fast cycle time, cost effective silicon microelectronic manufacturing the

technology also is applicble to MCT, Ga As and other materials.

Organization:

Texas Instruments

Component:

Infrared Materials Laboratory

Address:

POB 655936 MS150 Dallas, TX 75265

Contact:

M.A. Kinch

Position:

Dr.

Notes:

Head of their IR producibility effort; representative to JM consortium on

producibility

Organization:

Texas Instruments Inc

Component:

Central Research Laboratories

Address:

PO Box 655936, MS 136

Dallas, TX 75265

Contact:

Robert Stratton

Position:

VP

Notes:

Production of HgCdTe-based infrared imagers.

Texas Tech University

Charles W. Myles

Component:

Department of Physics and Engineering Physics

Address: Contact:

Lubbock, TX 79409-1051

Position:

Notes:

Co-authored for 1991 MCT workshop "Critical Stress of HgCdTe Solid

Solutions." and "Microhardness of Hg-Containing II-VI Alloys"

Organization:

Textron Defense Systems

Component:

Address:

201 Lowell Street

Wilmington, MA 01887

Contact:

Nancy Parker

Position:

Business Communications

Notes:

Infrared systems and equipment, GaAs arrays, active and passive e/o systems,

detectors and sensors

Organization:

Textron Inc Component:

Address:

Scnsor Systems 201 Lowell St

Wilmington, MA 01887

Contact:

Robert Wilson

Position:

VP

Notes:

Sensor systems for target discriminations, detections, and tracking.

Organization:

Component:

The Aerospace Corporation

Address:

Electronic Technology Center P.O. Box 92957

Los Angeles, CA 90009

Contact:

R.C. Lacoe

Position:

Notes:

¿Co-authored for 1992 SPIE workshop on IRFPAs "Modified Wuantum Well

Infrared Photodector Designs for High Temperature and Long Wavelength

Operation*

The Boeing Company

Component:

7755 E Marginal Way S, PO Box 3707 Scattle, WA 98124

Address: Contact:

Frank Schrontz

Position:

CEO

Notes:

Research in the field of aerospace including sensor systems.

Organization:

on: The Pyrometer Instrument Company

Component:

Address: 234 Industrial Pkwy.

Northvale, NJ 07647

Contact:

EK Matthews Pres

Position: Notes:

Design and production of infrared temperature measurement systems.

Organization:

Thermo Electron Corp.

Component:

Address:

101 First Ave.,

Waltham, MA 02254

Contact:

George Hatsopoulos

Position:

Prcs

Notes:

Production of optics, electro-optics, electro-acoustic systems.

Organization:

Thomson Components & Tubes Corp

Component:

TCS Division

Address:

40 G Commerce Eay Totowa, NJ 07511

Contact:

Gregg Herbison

Position:

National Sales Manager

Notes:

Infrared systems and equipment, GaAs gate arrays, detectors & sensors

Thomson Composants Militarires et Spatiaux

Component:

Address:

50, rue j.-Pierre Thimbaud

Courbevoie, 92402, FRANCE

Contact: Position:

R. Besamat Chief Executive

Notes:

Manufactures semiconductors for the high end professional, military, and space

amrkets. Oferrs linear and matrtic CCDs.

Organization:

Thomson CSF

Component:

Address:

Cedex 67

F-92056 Paris- La Defense

FRANCE

Contact:

Position:

Notes:

Producer of a variety of HgCdTc-based military sensors, including the IRST

for the Rafale.

Organization:

Thorton Associates Inc

Component:

Address:

1432 Main St.

Waltham, MA 02154

Contact:

Charles Staples

Position:

Pres

Notes:

Production of electronic control devices.

Organization:

Component:

Timeco Inc

Address:

1035 26th St.

Huntington, WV 25705

Contact:

Wilson Twohig

Position:

Pro

Notes:

Timing controls, photoelectric controls, and load sensors.

Titronics Inc

Component: Address:

RR 1, Box 53B

Oxford, IA 52322

Contact:

Roger Titrone

Position:

Pres

Notes:

Infrared terrain scanning.

Organization:

Tomsk Polytechnic Institute

Component:

Address:

Tomsk, RUSSIA

Contact:

V.P. Vavilov

Position:

Notes:

Authored for 1991 SPIE meeting on IR Technology "Soviet IR IMagers and

THeir Applications: Short State of the Art"

Organization:

Toshiba Corporation

Component:

Research and Development Center

Address:

Komukai Works

Kawasaki, Japan

Contact:

Position:

K. Shigenaka

Notes:

Co-authored for 1992 MCT Workshop "Effects of Growth Rate and Mercury

Partial Pressure on Twin Formation in HgCdTc (111) Layers Grown by

MOCVD"

Organization:

Total Vision Photonics

Component: Address:

39 Vaughn Street, Suite 202

Ottawa, CANADA K1M1W9

Contact:

Peter Gaylord

Position:

Notes:

active in infrared process control

TRW Inc

Component:

TRW Electronic Systems Group E Bldg., Rm 5076, One Space Park

Address:

Redondo Beach, CA 90278

Contact:

Timothy Hannemann

Position:

VP

Notes:

Development of advanced infrared sensor technologies.

Organization:

TSI Thermo-Scan Energy Management

Component:

Address: 15658 North Gray Road, Box 705

Carmel, IN 46032

Contact:

Phillip C. McMullan

Position:

Notes:

active in infrared predictive maintenance

Organization:

Component:

Tsing-Hua University Material Center

Address:

101, Sec 2 Kunag-Rd.

Hsingchu, Taiwan, ROC

Contact:

Position:

Chao Huang

Notes:

Organization:

Tusts University

Component:

Electro-Optics Technology Center

Address:

Mcdford, MA 02155

Contact:

Jorge Jimenez

Position:

Notes:

Co-authored for 1992 meeting of SPIE on IRFPAs "Fundamental Studies of

Schottky Barrier IR Detectors by Ballistic Electron Emission Microscopy"

UDT Sensors Inc

Component:

Address: 12525 Chadron Ave.

Hawthorne, CA 90250

Contact:

Deepak Chopra

Position:

Pres

Notes:

Development of light-based sensors.

Organization:

Union Miniere

Component:

Address: A. Greinerstraat 14

B-2660 Hoboken-Belgium

Contact:

Guy Knockaert

Position:

Technico-commercial Manager

Notes:

Organization:

United Mineral and Chemical Corp.

Component:

Address:

1100 Valley Brook Avenue

Lyndhurst, NJ 07071-3608

Contact:

Irwin Drangel

Position:

Sales Manager

Notes:

Manufacture of CdTe, GaAs, germanium, and ZnS for infrared applications.

Organization:

United Technologies Corp.

Component:

United Technologies Research Center

Address:

Silver Ln.

East Hartford, CT 06108

Contact:

Dr Wayne Burwell

Position:

Dir His

Notes:

Development of advanced infrared electronic systems.

Unitron, Inc

Component:

Address:

170 Wilbur Pl., PO Box 469

Bohemia NY 11716

Contact:

Thomas Zappetti

Position:

Pres

Notes:

Development of advanced optical systems.

Organization:

Univ of Illinois College of Medecine

Component: Address:

Carle Foundation
611 West Park Street

Urbanna, IL 61801

Contact:

Ralph Nelson

Position:

Dr.

Notes:

active in infrared biomedical thermography

Organization:

University of Texas at Arlington

Component:

Dept of Computer Science Engineering

Address:

P.O. Box 19015

Arlington, TX 76019-0015

Contact:

Position:

Diane Cook

Notes: active in infrared process control

Organization:

Universal Energy Systems

Component:

Address:

4401 Dayton-Xenia Rd.

Dayton, OH 45432

Contact:

Shan Joshi

Position:

Prcs

Notes:

Development and application of laser and electro-optic systems.

Universal Sensors, Inc.

Component:

Address:

Suite D, 5258 Veterans Blvd.

Metairie, LA 70006

Contact:

George Guilbalt

Position:

President

Notes:

Development of advanced biosensors and immunosensors for medical

applications.

Organization:

Component:

Address:

Universal Technology Corp.

4031 Colonel Glenn Hwy.

Dayton, OH 45431

Contact:

Robert Guyton Pres

Position:

Notes: Development of advanced manufacturing technologies for metal working and

electronic research and development.

Organization:

Component:

Universitat de Barcelona

Address:

Avd. Diagonal 647

E-08028 Barcelona, SPAIN

Contact:

Elisanda Roca

Position:

Notes:

Co-author at 1992 SPIE IRFPA meeting of "Comparative Study of SWIR and

MWIR Schottky-barrier Imagers*

Organization:

University of Arizona

Component:

Arizona Remote Sensing Center

Address:

845 North Park Avenue

Tucson, AZ 45719

Contact:

Stuart E. Marsh

Position:

Mr.

Notes:

active in infrared remote sensing

Organization: Component:

University of Arizona Optical Sciences Center Tucson, AZ 85721

E.L. Dcrenial

Address:

Contact:

Position:

Notes:

Co-Author in 1992 SPIE meeting of "Development of a High-Speed PtSi

IRCCD Camera System"

Organization:

Component: Address:

University of Arizona **Optical Sciences Center**

Tucson, AZ 85721 Thorsten Graeve

Contact: Position:

Mr.

Notes:

active in infrared process control

Organization:

Component:

University of California in Los Angeles

Address:

Contact:

Position:

T. Maxworthy

Authored February 1991 study "Laboratoty Modelling of the Dynamics of Notes: Coastal Upwelling" which studies the dynamics of the filamentary structured

that have been repeatedly observed by satellite by IR imagery taken from the

West Cost.

Organization:

University of California, Los Angeles Component: Department of Chemical Engineering

Address:

Los Angeles, CA 90024-1592 F. Hicks

Contact:

Position: Notes:

Co-authored for 1991 MCT Workshop "Photoassisted Organometallic VPE on

CdTe"

Organization: Component:

University of California, Los Angeles **Electrical Engineering Department**

Address:

Los Angeles, CA 90024

Contact:

C.R. Viswanathan

Position:

Notes:

For 1991 MCT Workshop, wrote "Compositional Analysis of HgCdTe

Epitaxial Layers Using Secondary Ion Mass Spectrometry"

Organization:

University of Erlangen

Component: Address:

Erlangen, GERMANY

Contact:

W.A. Cabanski

Position:

Notes: Co-authored for 1991 SPIE meeting on Growth of IR Materials "Electronic

and Optical Properties of Silicide/ Silicon IR Detectors"

Organization:

University of Florida

Component:

Department of Electrical Engineering

Address:

Gaincsville, FL 32611

Contact:

Sheng S. Li

Position: Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "A Noval Grating Coupled

Step-Bound-to-Miniband Transition InGaAs/GaAs/AlGaAs Multiquantum

Well Infrared Photodetector"

Organization:

University of Houston

Component:

Department of Physics and Space Vacuum Epitaxy Center

Address: Contact: Houston, TX 77204

Position:

T.D. Golding

Notes:

Co-authored "Properties of InAs/(Ga,In)Sb Strained Layer Superlattices

Grown on the (111) Orientations" for 1992 MCT Workshop

University of Illinois at Chicago

Component:

Microphysics Laboratory, Physics Department

Address:

P.O. Box 4348 Chicago, IL 60680

Contact:

Y.P. Chen

Position:

Notes:

Authored "Structure of CdTe(111)B grown by MBE on Misoriented Si(001)"

for 1992 MCT Workshop.

For 1991 Workshop, "Current Status of Direct Growth of CdTe and HgCdTe

on Silicon by MBE"

Organization:

University of Maryland

Component:

Address:

College Park, MD

Contact:

J.R. Anderson

Position:

Notes:

Co-authored 1987 study "Magnetophonon Effect in HgCdTe"

Co-authored 1987 study "Phase Differences between Quantum Oscillations of

the Magnetoresistance and the Hall Effect in HgMnTe and HgCdTe"

Organization:

University of Maryland

Component:

Maryland Agricultural Experiment Station

Address:

College Park, MD 20742

Contact:

Gary Stutte

Position:

Mr.

Notes:

active in infrared remote sensing

Organization:

University of Maryland

Component:

Medical School Baltimore, MD

Address: Contact:

Joseph Lakowicz

Position:

Mr.

Notes:

Speaking at OE/LASE Laser Market '93 seminar on wavelength requirements

for medical diagnostics in the near-infrared spectral regions. The wavelength in such applications determines not only which molecules will absorb the

light, but how deeply the light will penetrate biological tissues.

University of Michigan

Component:

Department of Electrical Engineering and Computer Science

Address:

Ann Arbor, MI 48109

Contact:

J. Singh

Position: Notes:

Co-Authored "Recent Advances on HgCdTe Mid Infrared Diode Lasers" for

1992 MCT Workshop.

Organization:

University of Minnesota School of Medecine

Component: Address:

Minneapolis Clinic of Neurology 305 East Nichola Boulevard

Ridgeview Medical Bldg, Suite 185

Burnesville, MN 55337

Contact:

Jack Hubbard

Position:

Dr.

Notes:

active in infrared biomedical thermography

Organization: Component:

University of Montana School of Forestry Missoula, MT 59812

Address: Contact:

Lars L. Pierce

Position:

Mг.

Notes:

active in infrared remote sensing

Organization: Component:

University of Nebraska
Center for Electro-Optics

Address: Contact: Lincoln, NE 69588 Ram M. Narayanen

Position:

Notes:

active in infrared remote sensing

University of New South Wales

Component:

School of Physics

Address:

Kensington 2033 AUSTRALIA

Contact:

M. Gal

Position:

Notes:

Co-Authored "In-Situ Ellipsometric Measurements of the MBE Growth of

CdTe/HgTe and CdTe/AnTe Superlattices" for 1992 MCT Workshop

Organization:

University of Nort Texas

Component:

Department of Physics

Address:

Denton, TX 76203

Position:

Contact: C.L. Littler

Notes:

Co-Authored "Heavily Accumulated Surfaces of MCT Detectors: Theory and

Experiment" for 1992 MCT Workshop.

For 1991 Workshop, "Investigation of Mcrcury Interstititals in MCT alloys

Using Resonant Impact-Ionization Spectroscopy"

Organization:

University of North Carolina at Chapel Hill

Component:

Department of Physics and Astronomy

Address:

Chapel Hill, NC 27599-3255

Contact:

J.C. Austin

Position: Notes:

Co-Authored "Observation of Indium-Vacancy and Indium Hydrogen

Interactions in (HgCd)Te Using PAC

Organization:

University of Notre Dame

Component:

Address:

Notre Dame, IN 46556

Contact:

J.K. Furdyna

Position: Notes:

On Program Committee of 1992 MCT Workshop

For 1991 Workshop co-authored "Magnetic Generation of Electrons and Holes

in Semimetallic HgTe-CdTe Superlattices"

University of Pittsburgh at Greensburg

Component:

Address:

Contact:

Guy M. Nicoletti

Position: Notes:

Authored 1988 "Optoelectronic Proximity Sensors for Automated Deburring"

Organization:

Component: Address:

University of Southampton

Engincering Materials Southampton, SO9 5NH

UNITED KINGDOM

Contact:

N.A. Archer

Position:

Notes: Authored "Growth Method, Composition, and Defect Structure Dependence of

Mercury Diffusion in CdHgTe" for 1992 MCT Workshop.

Organization:

University of Southern California

Component:

Department of Materials Science and Engineering

Address: Los Angeles, CA 90089-0241

Contact:

Position:

K.T. Chang

Notes:

Co-authored for 1991 MCT Workshop "Ordered Phase in (HgCd)Te Grown by

LPE on CdTe (111)B Substrate"

Organization:

University of West Australia

Component:

Department of EE

Address:

Nedlands, Perth, Western Australia 6009

Contact:

Lorenzo Faraone

Position: Notes:

Attended 1992 MCT conference

University of Wurzburg

Component:

Address: **GERMANY**

Contact:

R.N. Bicknell-Tassius

Position:

Notes:

Authored for SPIE 1991 meeting on Growth of IR materials "Growth of

CdTc-CdMnTc Heterostructures by MBE"

Organization:

USDA - ARS

Component:

Remote Sensing Research Unit

Address:

2413 E. Highway 83 Weslaco, TX 79586

Contact:

David E. Escobar

Position:

Mr.

Notes:

active in infrared remote sensing

Organization:

UTI Instruments

Component:

Address:

Contact: Hugh Danaher

Position:

Mr.

Notes:

Organization:

Vicon Infrared

Component:

Address:

Four Scneca Court

Acton, MA 01720

Contact:

Ralph Rotolante

Position:

Notes:

Former founder and president of the now defunct New England Research

Center. Private consultant

Vinten-Penarroya Inc.

Component:

Address: 17151 Newhope Street, Suite 208

Fountain Valley, CA 92708

Contact:

F. Fernandez President

Position: Notes:

Manufacture of germanium for infrared applications.

Organization:

Virginia Polytechnic Institute

Component:

Address:

P.R. Norton

Contact: Position:

Notes:

On Program Committee of 1992 MCT Workshop.

On Program Committee of 1991 MCT Workshop, as a representative of

SBRC.

Organization:

Virginia University

Component:

Department of Electrical Engineering

Address:

Charlottesville, VA

Position:

Contact: Boris Gelmont

Notes:

Co-authored May 1992 report "Monte Carlo Simulation of Electron Transport

in HgCdTe"

Organization:

Visidyne Inc

Component:

Address:

10 Corporate Pl.,

Burlington, MA 01803

Contact:

J Carpenter

Position:

Pres

Notes:

Development of electro-optical instrumentation.

Vision Harvest

Component:

Address: HCR Box 36

Hatch, NM 87937

Contact:

Craig Davidson

Position:

Mr.

Notes:

active in infrared process control

Organization:

Wahl Instruments, Inc.

Component: Address:

5750 Hunnum Ave.,

Culver City, CA 90231

Contact:

Carol Smith

Position:

Ms.

Notes:

Production of non-contact IR thermometers for industrial processes.

Organization:

Washington University

Component:

Department of Materials Science and Engineering

Address:

Scattle, WA

Contact:

Ryoichi Kikuchi

Position:

Notes:

Authored February 1988 study "Migration and Stability of HgCdTe Lattice

Defects"

Organization:

Wayne State University

Component:

Address:

Detroit, MI

Contact:

L.D. Favro

Position:

Notes: Authored in 1990 a 7 page "Noise Suppression in IR Thermal-Wave Video

Images by Real-Time Processing in Synchronism with Active Stimulation of

the Target"

Organization: Component:

Wayne State University Department of Physics

Address:

Detroit MI

Contact:

S. Goettig

Position:

Notes: Co-authored 1990 "FOrmation Mechanisms of Interstitial Defect States"

Organization:

Component:

Wayne State University

Dept of Physics and Inst for Manufacturing Research

Address: **Contact:**

Detroit, MI 48202

Position:

D.J. Crowther

Notes:

infrared non-destructive evaluation

Organization:

Wayne State University

Component:

Institute for Manufacturing Research

Address:

Detroit,MI T. Ahmed

Contact: Position:

Notes:

Authored in 1991 an 8 page "Infrared Thermal Wave Studies of Composites." Authored 1990 paper entitled "Real-time Thermal wave Imaging of Plasma-Sprayed Coatings and Adhesive Bonds Using a Box-Car Video Technique." Authored 1989 paper "Parallel Thermal Wave IR Video Imaging of Polymer Coatings and Adhesive Bonds." Authored 1987 paper "Characterization of Plasma Sprayed Coatings Using Thermal Wave IR Video Imaging."

Organization:

West Virginia University

Component:

P.O. Box 6315

Address:

Morgantown, WV 26506-6315

Contact:

Thomas H. Myers Physics Department

Position: Notes:

Attended 1992 MCT Workshop

Westinghouse Research Center

Component: Address:

Westinghouse Building, Gateway Center

Pittsburg, PA 15222

Contact: Position:

Notes:

Producer of a variety of PtSi staring IRFPAs for the Army. The Center is also

involved in DARPA's electronic sciences program.

Organization:

Westinghouse Corp.

Component:

Advanced Technology Division

Address: Contact:

Baltimore, MD 21203 Arthur S. Jensen

Position:

Mr.

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Superconductive Circuits for

On-FPA IR Digital Signal Processing"

Organization:

Westinghouse Electric Corp.

Component:

Electronics Systems Division

Address:

P.O. Box 17319

MS A255

Baltimore, MD 21203-6812

Contact:

Ann Grizzel

Position:

Manager, Pubilc Relations

Notes:

Infrared systems and equipment, detectors and sensors, c/o systems

Organization:

Westmark Systems, Inc

Component:

Tracor-GIE

Address:

1652 W 820 North Provo, UT 84601

Contact:

william Wallace

Position:

Pres

Notes:

Development of infared and far-infared systems.

Whittaker Electronics

Component:

Address: 1785 Voyager Avenue

Simi Valley, CA 93063-3349

Contact:

R. La Polla

Position:

Marketing Manager

Notes:

infrared systems & equipment

Organization:

Willey Corporation

Component: Address:

PO Box 670

Melbourne, FL 32902

Contact:

Ronald Willey

Position:

Pres

Notes:

R&D of unique and sophisticated infrared reflectance spectrophotometry.

Organization:

Williamson Corporation

Component:

Address: 70 Domino Dr., PO Box 1270

Concord, MA 01742

Contact:

CF Langenhagen

Position:

Pres

Notes:

R&D of infrared radiometers for temperature measurement and control.

Organization:

Worcester Polytechnic Institute

Component:

Address:

Worchester, MA 01609

Contact:

L.R. Ram-Mohan

Position: Notes:

Co-authored for 1991 MCT Workshop "Magnetic Generation of Electrons and

Holes in Semimetallic HgTe-CdTe Superlattices"

Worcester Polytechnic Institute

Component: Address:

Department of Physics Worcester, MA 01609 L.R. Ram-Mohan

Contact:

Position: Notes:

Co-Authored "States Confined in the Barriers of Type-III HgTe/CdTe

Superlattices" for 1992 MCT Workshop

Organization:

Worchester Institute of Technology

Component: Address:

Center for Imaging Science One Lomb Memorial Drive

Rochester, NY 14623

Contact:

James R. Schott

Position:

Mr

Notes:

active in infrared remote sensing

Organization:

Component:

Xedar Corp

Address:

2500 Central Avenue

Boulder, CO 80301

Contact:

Cindy Zeidler

Position:

Ms

Notes:

infrared non-destructive evaluation

Organization:

Young Design

Component:

Address:

7110 Sca Cliff Road

McLean, VA 22101

Contact:

Michael F. Young

Position:

President

Notes:

Infrared systems & equipment

Appendix E

Professional and Trade Organizations

Serving the Infrared Community

Air Force Association 1501 Lee Highway Arlington, VA 22209 (703) 247-5800

American Association of Engineering Societies 1111 19th Street, NW, #608 Washington, DC 20036 (202) 296-2237

American Chemical Society 1155 16th Street, NW Washington, DC 20036 (202) 872-4600

American Consulting Engineers Council 1015 15th St., NW, #802 Washington, DC 20005 (202) 347-7474

American Defense Preparedness Association 2101 Wilson Boulevard, Suite 400 Arlington, VA 22201 (703) 522-1820

Their annual symposium and exhibition on night operations brings together experts on IR technologies in night vision equipment, military applications of smart sensors, technology for autonomous weapons, and electro-optic applications. All sessions are unclassified. It is scheduled usually in September.

American Electronics Association 1225 Eye Street, NW #950 Washington, DC 20005 (202) 682-9110

American Gear Manufacturers Association 1500 King Street, #201 Alexandria, VA 22314 (703) 684-0211

American Institute of Aeronautics and Astronautics 370 L'Enfant Promenade, SW #1000 Washington, DC 20024 (202) 646-7400

American Institute of Chemical Engineers 1707 L Street, NW #333 Washington, DC 20036 (202)223-0650

American Institute of Physics 335 E. 45th Street New York, NY 10017 (212) 661-9404

Publishes the Journal of Vacuum Science and Technology, which prints articles on state of the art technological breakthroughs on semiconductor materials, much of it on Mercury cadmium telluride. Also help organize annual US Workshop on Physics and Chemistry of Mercury Cadmium Telluride and Other II-VI Compounds, held usually in October.

American Institute of Thermography 138 Church Street, NE, Suite C Vienna, VA 22180 (703) 938-6140

Kathryn Werner heads the office. Recently formed to inform public about prospects for infrared biomedical imaging. Its members are predominantly researchers at universities and at small, start-up businesses. Chairman is Dr. Michael Anbar at the State University of New York in Buffalo. Publishes occasional Journal of Thermology which is on hold until funding can be found to print it. Apparently funding was pulled from the IR imaging companies which sought military business rather than what they saw as the small biomedical market.

American Iron and Steel Institute 1101 17th Street, NW, #1300 Washington, DC 20036 (202) 452-7100

American Machine Tool Distributors Association 1335 Rockville Park, #300 Rockville, MD 20852 (202) 738-1200

American Paper Institute 1250 Connecticut Avenue, NW #210 Washington, DC 20036 (202) 463-2420

American Public Power Association 2301 M Street, NW, #300 Washington, DC 20037 (202) 775-8300

American Society of Mechanical Engineers 1828 L Street, NW #906 Washington, DC 20036 (202) 785-3756

American Society for Metals International Materials Park, OH 44073 (216) 338-5151

This is the major metallurgical society worldwide. Since IRFPAs are being increasingly used in metallurgy for thermal imaging of steel, aluminum, etc. in real-time as they roll off the production line, this society may become valuable. They do not have a working group, however, concerned with non-destructive testing.

American Society for Nondestructive Testing

4153 Arlingdale Plaza Columbus, OH 43228 (614) 274-6003

Thermal sensors are becoming increasingly important in non-destructive testing, and the ASNT is taking an interest in infrared technology. Although it has no working groups or smaller societies on IR work, it will be able to refer us to people in specific industries who can speak about using IR sensors in their production systems.

American Society for Photogrammetry and Remote Sensing 5401 Grosvenor Lane #210 Bethesda, MD 20814 (301) 493-0290

American Society for Testing and Materials

1916 Race Street Philadelphia, PA 19103 (215) 299-5400

Among the oldest and broadest based organizations in its field in the U.S. They have no working groups or publications which address the use of IRFPAs or IR technology in industrial sensors, but they are taking an increasing interest in the industrial applications and will offer names in specific industries if we need them.

American Society for Quality Control

611 E. Wisconsin Avenue Milwaukee, WI 53202-4606 (414) 272-8575

Since they are a society to which quality control managers belong, IR sensor may play a growing part in their field. They have both a measurement division, led by Joel Simmons at 301-975-2005, and an inspections division, headed by Charles Carter at 214-234-3296. They have both been extremely helpful in locating articles and experts.

Armed Forces Communications and Electronics Association 4400 Fair Lakes Court Fairfax. VA 22033 (703) 631-6100

Association for Manufacturing Technology 7901 Westpark Drive McLean, VA 22102 (703) 893-2900

Association of Science-Technology Centers 1025 Vermont Avenue, NW #500 Washington, DC 20005 (202) 783-7200

Association of the United States Army 2425 Wilson Boulevard Arlington, VA 22201 (703) 841-4300 Center for Non-Destructive Evaluation

Iowa State University 1915 Scholl Road Ames, IA 50011

This center organizes the annual Review of Progress in Quantitative Nondestructive evaluation conference, and publishes its proceedings. The conference serves as an annual meeting place for engineers and scientists working on highly analytical and complex nondestructive evaluation. Although ultrasonic techniques are more often discussed, specifically eddy current, thermal imaging has been discussed increasingly. This conference and its attendees have been at the forefront of aging aircraft inspection.

Chemical Manufacturers Association.

2501 N Street, NW 20037 Washington, DC 20037 (202) 887-1100

Electric Power Research Institute 1019 19th Street, NW #1000 Washington, DC 20036 (202) 872-9222

Electronics Industries Association 2001 Pennsylvania Avenue, NW #1100 Washington, DC 20006 (202) 457-4900

Infrared Information Analysis Center

P.O. Box 134001 Ann Arbor, MI 48113-4001 (313) 994-1200

At the Environmental Research Institute of Michigan, the IRIA is a DTIC- sponsored DoD Information Analysis Center. It is the leading training facility for program managers in military-industrial work on classified IR projects. It can not disburse any papers or professional lists or program of events until we have a DTIC identification number.

Infraspection Institute

1971 Shelburne Road Suite C Shelburne, VT 05482 (802) 985-2500

Headed by Paul Grover, the Institute supports those who use and provide infrared thermographic services through their training, continuing education, and certification programs. It is a leader in training inspectors who use IR in their factories and plants. Their newsletter is seasonal, and called simply the "Infraspection Institute Newsletter."

Institute for Electrical and Electronic Engineers (IEEE)

345 East 47th Street New York NY 10017 (212) 705-7900

A society which has a wealth of information on IR technologies, especially concerning applications. They have many working groups which publish papers with a decidedly technical bent, and working groups which may be of interest are "Aerospace and Electronic Systems," "Components, Hybrids, and Manufacturing Technology," and "Lasers and Electro-Optics." They have a yearly meeting on "Thermosense," organized usually by Professor Bill Wolfe at the University of Arizona.

Institute of the Ironworking Industry
1750 New York Avenue, NW #400
Washington, DC 20006
(202) 783-3998

International Society for Optical Engineering (SPIE)

P.O. Box 10

Bellingham, WA 98227-0010

The oldest and grandest of the societies to which infrared researchers belong. In addition to working groups addressing optical technologies, they hold their annual Thermosense meeting in April, which is the major crossroads for commercial infrared detector manufacturers. They also organize yearly conference on FTIR spectrometers, surveillance, machine vision and automated inspection, remote sensing, and scientific research using IR detectors.

Laser Institute of America 12424 Research Parkway, SUite 130 Orlando, FL 32826 (407) 380-1553 John Sallik National Academy of Engineering 2101 Constitution Avenue, NW #218 Washington, DC 20418 (202) 334-3200

National Aeronautic Association of the U.S.A. 1815 N. Fort Myer Drive, #700 Arlington, VA 22209 (703) 527-0226

National Assocation of Manufacturers 1331 Pennsylvania Avenue, NW #1500 Washington, DC 20004 (202) 637-3000

National Electrical Contractors Association 7315 Wisconsin Avenue, #1300-W Bethesda, MD 20814 (301) 657-3110

National Electrical Manufacturers Association 2101 L Street, NW, #300 Washington, DC 20037 (202) 457-8400

National Society of Professional Engineers 1420 King Street Alexandria, VA 22314 (703) 684-2800

National Tooling and Machining Association 9300 Livingston Road Fort Washington, MD 20744 (301) 248-6200

Palisades Institute for Research Services, Inc.
201 Varick Street, Suite 1140
New York, N.Y. 10014
(212) 620-3371
Organizes a yearly Workshop on the Physics

Organizes a yearly Workshop on the Physics and Chemistry of Mercury Cadmium Telluride and Related II-VI Materials. The organizer is Jay Morreale.

Robotic Industries Association

900 Victors Way P.O. Box 3724 Ann Arbor, MI 48106 (313) 994-6088

Incorporates three other associations of interest to infrared firms: Robotic Industries Association, Automated Imaging Asosciation, National Service Robot Association. All are leading associations for manufacturers and integrators of automated inspection and machine guidance machines and systems. Almost all the CCD manufacturers are members, as are the major photonics firms that are interested in the imaging market. Organizes an annual International Robots & Vision Automation Conference in APril, and another International Symposium on Industrial Robots, usually in October.

Society of American Military Engineers 607 Prince Street Alexandria, VA 22314 (703) 549-3800

Society for Imaging Science and Technology 7003 Kilworth Lane Springfield, VA 22151 (703) 642-9090

Society of Manufacturing Engineers (SME)

1 SME Drive P.O. Box 930 Dearborn, MI 48121-0930 (313) 271-2861

The SME, through its publication <u>Manufacturing Engineering Magazine</u>, is very concerned with thermal imagers, because it boosts productivity, saves on maintenance, is a form of non destructive testing, etc. They do not have any working groups or individual societies focused on infrared sensors, but they have groups by industry, so several industries may be interesting to DFI research because they employ IR sensors.

Society for the Advancement of Materials and Process Engineering

1161 Park View Drive Covina, CA 91724 (818) 331-0616

Their technical director, Dr. Hammernesh, says that they do not yet cover IRFPAs materials, or IRFPAs as used by process engineers, because they have not yet become prevalent. However, they will be able to put us in touch with engineers and research scientists in specific industries when we target a few industries.

Specialty Steel Industry of the U.S. 3050 K Street, NW #400 Washington, DC 20007 (202) 342-8400

Valve Manufacturers Association of America 1050 17th Street, NW #701 Washington, DC 20036 (202) 331-8105

Appendix F Individuals Carrying out Research on Applications of Sensitive Infrared Materials Database

Contact Name:

Margaret Abernathy

Position:

Medical Doctor

Organization:

Georgetown University Medical Center

Component:

Address: Kober-Cogan 320

3800 Reservoir Road Washington, D.C. 20007

Notes:

Active in development of infrared biomedical thermography

applications, systems design. Active in American Academy of

Thermology.

Contact Name:

Warren Achenbaum

Position:

President

Organization:

Cox & Company, Inc.

Component:

Address:

200 Varick St.

New York, NY 10014

Notes:

Electronic and mechanical engineering, aerodynamics, thermal

engineering, mostly for military markets.

Contact Name:

Position:

Roshan L. Aggarwal

Organization:

Materials Scientist

O gamzanon

MIT

Component:

Electronics Research Lab

Address:

Room 13-3030

77 Massachusetts Avenue Cambridge, MA 02139

Notes:

Materials scientist on program committee of 1991 and 1992 MCT

workshop hosted by Palisades Research Center. Co-authored January

1987 "Infrared Nonlinear Optics"

graduri en Alberten

F-1

Jean Aitchison

Position:

Gen Mgr.

Organization:

Photox Optical Systems

Component:

Address:

P.O. Box 274

Headington, Oxford, OX3 OBJ UNITED KINGDOM

Notes:

Manufacture of GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications.

Contact Name:

Peter Albers

Position: Organization: Sales Manager Carl Zeiss

Component:

Address:

Sondertechnik

Postfach 1380

7082 Oberkochen, GERMANY

Notes:

Thermal Imaging, Detectors and Sensors, Night Vision for military markets.

Contact Name:

Position:

John V. Alexander

Public Relations

Organization:

AlliedSignal Aerospace

Component:

Address:

2525 W. 190th Street

Torrance, CA 90504

Notes:

Thermal Imaging, detectors and sensors, for military

Contact Name:

James Alexiou

Position:

Pres

Organization:

Irvine Sensors Corp.

Component:

3001 Redhill Ave Bldg 3

Address:

Costa Mesa, CA 92626

Notes: . :tit. - *

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Applied research in military detection system (infrared sensing). Designs, develops and manufactures proprietary focal planes and focal plane assemblies,

Proprietary assemblies include proprietary line arrays amd stacked-circuitry

mosaic with on-focal-plane signal processing.

R.R. Alfano

Position:

Research PhD

Organization:

Institute for Ultrafast Spectroscopy and Lasers

Component:

Photonics Appl. Lab

Address:

Department of Electrical Engineering and Physics, Graduate Center of the

City Univ of NY, New York, NY 10031

Notes:

Active in infrared biomedical thermography as system designer for multiwavelength, MCT-based systems which overcome emissivity problems.

Contact Name:

Charles Alicandro

Position:

Commercial Sales

Organization:

Inframetrics

Component:

Address:

16 Esquire Road

North Billerica, MA 01862

Notes:

Manufactures IR thermal imaging systems (radiometers) for noncontact temperature measurements. Radiometers feature TV compatible color and b/w imaging with direct temperature measurement capabilities. Image processing systems provide easy detailed analysis of data collected with the thermal camera. A leading supplier for non-destructive evaluaton, predictive

maintenance IR camer markets.

Contact Name:

Lcc Allen

Position:

Organization:

Allen Infrared Associates

Component:

Address:

RR #1, Box 239K

Coward, SC 29530

Notes:

Active in infrared predictive maintenance development regimes and community

.10

dere

7500

Contact Name:

Position:

Robert Allen CEO

Organization:

American Telephone and Telegraph

Component: Address:

AT&T Bell Labs 600 Mountain Ave.

Murray Hill, NJ: 07974

Notes:

Wide range of research in electronics, focusing on emerging technologies

including opto-electronics.

Robert Allen

Position:

CEO

Organization:

American Telephone and Telegraph company

Component: Address:

AT&T Bell Labs 600 Mountain Ave. Murray Hill, NJ 07974

Notes:

Wide range of research in electronics, focusing on emerging technologies

including opto-electronics.

Contact Name:

Andrew Allen

Position: Organization:

VP Sales EG&G, Inc.

Component:

EG&G Judson 221 Commerce Dr.

Address:

Montgomeryville, PA 18936

Notes:

Manufactures infrared detectors and arrays, including Ge, InAs, InSb, MCT, and doped GE. Appliations include carbon dioxide laser detection, fiberoptics,

spectroscopy, and radiometry.

Contact Name:

Kurt Ammer

Position:

Dr

Organization:

Ludwig Boltzmann Forschungsstelle fue

Component:

Physikalische Diagnostik Heinrick Collinstr. 30

Address:

A-1140 Wien AUSTRIA

Notes:

Active in infrared biomedical thermography system design

i deficier Maoritz

Contact Name:

Michael Anbar

Position:

Dr.

Organization:

State University of NY at Buffalo Dept of Biophysical Sciences

Component: Address:

120 Cary Hall as 59%

Buffalo, NY 14214

Notes:

Active in infrared biomedical thermography. Has own biomedical marketing

firm to sell infrared technology. Current advisor of the American Institute of

Thermology.

F-4

Michael Anbar

Position:

Chairman, Department of Biophysical Sciences

Organization:

SUNY Buffalo School of Medicine

Component: Address:

120 Cary Hall Buffalo, NY 14214

Notes:

Also has own biomedical ir company called AMARA, Inc. at his home address, 145 Deer Run Road, Williamsville, NY 14221. Chief advisor to American Institute of Thermography. Has worked on biomedical IR for 8 years; grants

from NSF and NIH.

Contact Name:

Christine Anderson

Position:

Ms.

Organization:

Cray Research

Component:

Address:

925 First Avenue

Chippewa Falls, WI 54729-1402

Notes:

Active in infrared process control.

Contact Name:

Kenneth Anderson

Position:

Organization:

Monitck Technologies, Inc.

Component:

Address:

1495 Zephyr Ave.

Hayward, CA 94544

Notes:

Optical and electronic measurement systems to detect particulate matter, oils

and color in fluids.

Contact Name:

J.R. Anderson

Position:

Organization:

University of Maryland

Component:

Address:

College Park, MD

Notes:

SHIPSH

Co-authored 1987 study "Magnetophonon Effect in HgCdTe"

Co-authored 1987 study "Phase Differences between Quantum Oscillations of

the Magnetoresistance and the Hall Effect in HgMnTe and HgCdTe"

Martin Andonian

Position: Organization: President, Chief Scientist Andonian Cyrogenics Inc

Component:

Address:

26 Farwell Street

Newtonville, MA 02160

Notes:

Manufactures cryogenic equipment, storage dewars, cryorefrigerators, research cryostats, cold traps, transfer lines, level gauges, and control. Distributes cryogenic liquids, speciality gases, gas handling, and distribution equipment.

Contact Name:

N.A. Archer

Position:

Organization: Component:

University of Southampton **Engineering Materials** Southampton, SO9 5NH

Address:

UNITED KINGDOM

Notes:

Authored "Growth Method, Composition, and Defect Structure Dependence of

Mercury Diffusion in CdHgTe" for 1992 MCT Workshop.

Contact Name:

Eugene Arthurs

Position:

Dir

Organization: Component:

Oriel Corp

Address:

Notes:

250 Long Beach Blvd., PO Box 872, Stratford, CT 06497 Optics and detectors for ultraviolet through infrared systems.

Contact Name:

Monique Attar

Position: Organization: Marketing Administrator Loral Fairchild Systems

Component:

Address:

300 Robbins Lane

Syosset, NY 11791

Notes:

Detectors and sensors, e/o systems, night vision, thermal imaging,

predominantly for military markets.

B Austin

Position:

CEO

Organization:

Affiliated Manufacturers, Inc. (AMI)

Component:

Address:

PO Box 5049

North Branch, NJ 08876

Notes:

Process and manufacturing considerations of the microelectronics

manufacturing industry; innovative manufacturing processes; thick film hybrid

ì

circuits.

Contact Name:

J.C. Austin

Position:

Organization:

University of North Carolina at Chapel Hill

Component:

Department of Physics and Astronomy

Address:

Chapel Hill, NC 27599-3255

Notes:

Co-Authored "Observation of Indium-Vacancy and Indium Hydrogen

Interactions in (HgCd)Te Using PAC

Contact Name:

Ronald Autos

Position:

drR&D

Organization:

Burleigh Instruments, Inc.

Component:

Address:

Burleigh Park

Fishers, NY 14453

Notes:

Product oriented research in lasers, optical equipment, and micropositioning

equipment. Sells a leading tunable solid-state IR laser good from 1.45 to 1.75

microns, or 2.3 to 3.45 microns.

Contact Name:

K. Awamoto

Position:

Organization:

Fujitsu Laboratories, Ltd.

Component:

Atsugi Infrared Devices Laboratory

Address:

10-1 Morinosato-Wakamiya Atsugi 243-01 JAPAN

Notes:

Co-authored for 1992 SPIE Workshop on IRFPAs "Resolution Improvement

for HgCdTc IRCCD"

49**5**49

Norman Axelrod

Position:

Pres

Organization:

Norman Axelrod, Associates

New York, NY 10036

Component:

Norman N. Axelrod Associates Development Laboratory

Address:

28 W 44th St

Notes:

Planning, development, and fabrication of electro-optical, laser, and machine vision systems for on-line sensing and control, digital and analog information;

computer automated optical systems.

Contact Name:

J.W. Baars

Position:

Organization:

Fraunhofer-Institut fur Angewandte Festkorperphysik

Component:

Address:

Tullastr. 72

Notes:

D-7800 Freiburg, Germany Co-authored for 1991 SPIE meeting on Growth of IR Materials

"Characterization of Anodic Fluoride Films on HgCdTe"

Contact Name:

Marino Babbricotte

Position:

Organization:

ESA-ESTEC

Component:

Address:

Keplerlaan 1.

NL-2200 AZ Noordwijk, THE NETHERLANDS

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Comparative Study of SWIR

and MWIR Schottky-Barrier Imagers."

Contact Name:

Robert Bachner

Position:

CEO

Organization:

Silicon Sensor Inc

Component:

Address:

Hwy 18 E PO Box 137

Notes:

Dodgeville, WI 53533

Manufacture of light sensitive products. Manufactureres of SI semiconductor detectors and optocouplers/optoisolators, custom assembly for OEMs, long-

ા. i

100001

line strip detectors, optics hybrid assemblies, etc.

R.B. Bailey

Position:

Dr.

Organization:

Rockwell International Science Center

Component: Address:

1049 Camino Dos Rios Thousand Oaks, CA 91360

Notes:

One of top few scientists conducting Rockwell's alternative substrate programs.

Contact Name:

George S. Baird

Position:

Organization:

Baird Infrared Technology, Inc.

Component:

Address:

110 South Poplar Street #310

Wilmington, DE 19801-5046

Notes:

Active in infrared predictive maintenance as private consultant conducting

inspections

Contact Name:

Francis Baker

Position:

CEO

Organization:

Andersen Group

Component:

Address: 1280 Blue Hills Ave.

Bloomfield, CT 06002

Notes:

Research and development in photonics, telecommunications and high tech

industries.

Contact Name:

Roy Ball

Position:

President

Organization:

Imago Machine Vision Inc.

Component:

Address:

1354 Wellington Street

Ottaws, Ontario, CANADA K1Y-3C3

Notes:

Security systems and equipment, robotics, e/o systems, infrared systems and

equipment, commercial and military.

Michel Balle

Position:

Organization:

HGH Ingeneric Systemes

Component: Address:

au Parc d'Activities du Moulin de Massy

3, rue du Saule Trapu Massy, 91300 FRANCE

Notes:

Active in infrared process control at HGH Ingenerie.

Contact Name:

Position:

Probal Banerjee Graduate student Auburn University

Organization:

College of Engineering and Engineering Experiment Station

Component: Address:

Materials Engineering

201 Ross Hall

Auburn University, AL 36849-5351

Notes:

Co-authored 1991 "Weld Quailty Control in Gas Tungsten Arc Welding

Process" as graduate student for Dr. Chin.

Contact Name:

Position:

Ed Bangs

Organization:

Infrared Monitoring Systems

Component:

Address:

10 West 35th Street

Chicago, IL 60616

Notes:

Active in development of infrared process control regimes. Integrator and

consultant.

Contact Name:

George Barringer

Position:

Pres

Organization:

Groton Technology, Inc.

Component:

Address:

45 Winthrop St.

Concord, MA 01742

Notes:

Applied and product-oriented research in optical inferometry and solid state

optical detectors. Application of infrared technologies to scientific

spectroscopy.

Barry Bassin

Position:

President

Organization:

Infrared Optical Products, Inc.

Component:

Address: P.O. Box 3033

South Farmingdale, NY 11735

Notes:

Manufacture of CdTe, GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications, both military and commercial.

Contact Name:

P.K. Baumann

Position:

Organization:

North Carolina State University

Component: Address:

Department of Physics Raleigh, NC 27695-8202

Notes:

Authored for 92 MCT workshop "Growth of HgSe and HgCdSe Thin Films by

Molecular Beam Epitaxy"

Contact Name:

Bill Bauson

Position:

Organization:

Delco Electronics

Component:

Address:

700 East Firman Avenue

Kokomo, IN 46901

Notes:

Active in infrared non-destructive evaluation. His firm conducts research in automotive audio equipment and systems, vehicular heat and air conditioner controls, automotive microcomputer-based control systems, integrated circuits, semiconductor devices, thick film hybrid microcircuits, printed circuit boards, automotive electronics, automotive sensors, automotive instruments and displays.

Contact Name:

P. Belia

Position:

Organization:

MIT

Component:

Address:

Dept. of Materials Sci. & Eng.

Room 13-5099

Cambridge, MA 02139

Notes:

Author of "Growth and Characterization of Device Quality Bulk HgZnTe

Crystals" at 1992 MCT Workshop

For 1991 Workshop "Nonlinear Optical Effects in Rotationally Twinned CdTe

and CdMnTc Crystals," and "Long Wavelength HgMnTc Avalanche

Photodiodes*

Piotr Becla

Position:

Organization:

MIT

Component: Address:

Electronics Research Lab 77 Massachussets Avenue Cambridge, MA 02139

Notes:

Co-authored January 1987 "Infrared Nonlinear Optics"

Contact Name:

C.P. Beetz, Jr.

Position:

Organization:

Advanced Technology Materials
Semiconductor Products Department

Component: Address:

7 Commerce Drive Danbury, CT 06810

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Buffer Layers for Deposition

of Supercondcuting YBaCuO Thin Film on Polycrystalline Diamond"

Contact Name:

R.A. Bell

Position: Organization:

Director of Marketing Loral Corporation

Component:

Loral Infrared & Imaging Systems, Inc.

Address:

2 Forbes Rd.

Lexington, MA 02173

Notes:

Contact Name:

Brandon Belote

Position:

Director Marketing Communications

Organization:

ITT Defense and Electronics

Component: Address:

1000 Wilson Boulevard, Suite 3000

Arlington, VA 22209

Notes:

Night vision, active and passive e/o systems, infrared systems and components

for military applications.

-- **I**/

Valery Belov President

Position: Organization:

Belov Technology Co. Inc.

Component:

Address:

345 Sandford Street

New Brunswick, NJ 07891

Notes:

Manufactures MCT, DTGS, TGS pyroclectric detectors and detector electronic

systems, and multi-element arrays. MCT room temperature detectors, and

related components.

Contact Name:

Position:

Alan Bennett V Pres R&D

Organization:

Imo

Component:

Varian Industries

Address: 3100 Hansen Way

Palo Alto, CA 94304

Notes:

Producer of a wide variety of military thermal systems. Development of InP-

and HgCdTe-based infrared sensors, as well as the use of GaAs materials.

Contact Name:

Position:

Tucker Bens

Organization:

Marketing Loral Fairchild Imaging Sensors

Component:

Address:

1801 McCarthy Blvd

Milpitas, CA 95035

Notes:

Contact Name:

Tom Benson

Position:

CEO

Organization:

Innovation Industries, Inc.

Component:

Address:

Hwy 64E PO Box K

Russellville, AR 72801

Notes:

Opto-electronics product oriented for patent and manufacture, interest in IR

detectors.

R.G. Benz

Position:

Organization: Component:

Georgia Tech Research Institute Physical Sciences Laboratory

Address:

Room 128 Baker Bldg Atlanta, GA 30332

Notes:

Authored "CdTe and HgTe Growth Kinetics During Gas SOurce Molecular

Beam Epitaxy" for 1992 MCT Workshop For 1991, "Selected-area Epitaxy of CdTe"

Contact Name:

M.A. Berding

Position:

Organization:

SRI International

Component:

Address:

Menlo Park, CA 94025

Notes:

Co-Authored "Native Defect Equilibria in HgZnTe and HgCdTe Alloys" for

1992 MCT Workshop.

For 1991 Workshop, "Defect Equilibrium in HgTe"

Contact Name:

Position:

Organization:

Leif Bergstron Chairman

Pharos Inc.

Component:

Agema Infrared Systems

Address:

595 Skippack Pike Bluc Bell, PA 19128

Notes:

Pharos is the parent company for Agema in Secaucus.

Contact Name:

Enrique Bernal

Position:

VP Advanced Materials

Organization:

Morton International Advanced Materials

Component:

Address:

185 New Boston Street

Woburn, MA 01801

Notes:

Manufacture of ZnS and ZnSc for infrared applications.

R. Besamat

Position:

Chief Executive

Organization:

Thomson Composants Militarires et Spatiaux

Component: Address:

50, rue j.-Pierre Thimbaud

Courbevoie, 92402, FRANCE

Notes:

Manufactures semiconductors for the high end professional, military, and space

amrkets. Oferrs linear and matric CCDs.

Contact Name:

ct Name: A. Bezinger

Position:
Organization:
Component:

Kidron Microelectronics Research Center
Department of Electrical Engineering
Technion-Israel Institute of Technology

Haifa 32000, ISRAEL

Notes:

Address:

"UV Photon Assisted Control of Interface Charge Between CdTe Substrates and Metal Organic Chemical Vapor Deposition CdTe Epilayers" for 1992

MCT Workshop.

Contact Name:

Ishwara B. Bhat

Position:

Organization:

Rensselaer Polytechnic Institute

Component: Address:

ECSE Department 110 Eight Street

Troy, NY 12180

Notes:

Co-authored "Improved CdTc Layers on GaAs and Si Substrates, Grown by

Atomic Layer Epitaxy" for 1992 MCT Workshop.

Co-authored for 1991 MCT Workshop "Low Temperature Epitaxy of HgTe, CdTe, and HgCdTe Using Flow Modulation Techniques" and "Reduced Metal-

Insulator Semiconductor Tunneling in MOCVD MC(111)Tc Films"

. 11

4:00

Contact Name:

Ravi Bhatla

Position:

Address:

Organization:

Motorola Corporation

Component:

1303 East Algonquin Road

Schaumberg, IL 60196

Notes:

Designs infrared non-destructive evaluation techniques at Motorola.

بدويو

Jacob Biali

Position:

Sales Manager

Organization:

ISPRA - Israel Product Research Co. Ltd.

Component: Address:

Galgal Haplada Street, Industrial Zone

Herzelia, Israel 052-555464

Notes:

Manufacture of germanium, silicon, ZnS, and ZnSe for infrared applications.

Contact Name:

Lucien Biberman

Position:

Institute for Defense Analysis

1801 North Beauregard Street

Organization: Component:

Address:

Alexandria, VA 22311

Notes:

Delivered an August 1987 speech delivered to IRIS meeting entitled

"Perspective on Focal Plane Arrays" in which he argues that the military establishes hard-to-achieve standards for its IRFPAs, and that costs could be

readily reduced without such stringency.

Contact Name:

J Bickman

Position:

Prcs

Organization:

Stocker & Yale, Inc

Component: Address:

133 Brimbal Ave.

Beverly, MA 01915

Notes:

Optical measuring units for manufacturing controls.

Contact Name:

R.N. Bicknell-Tassius

Position:

Organization: University of Wurzburg

Component:

GERMANY

Address: Notes:

Authored for SPIE 1991 meeting on Growth of IR materials "Growth of

CdTc-CdMnTe Heterostructures by MBE"

Rollo Black

Position: Organization:

Business Development Eastman Kodak Co. Government Systems Div.

Component: Address:

1447 St. Paul Street Rochester, NY 14653

Notes:

IR Detectors work, mostly PtSi.

Contact Name:

Edward Blanchet

Position:

President

Organization:

Santa Barbara Infrared Inc.

Component:

312A North Nopal Street Santa Barbara, CA 93101

Address: Notes:

Manufactures commercial and military IR test equipment. Products include differential blackbody sources, collimators, IR target projects, FLIR test equipment. ALsdo provides applications engineering and custom design engineering for commercial, custom and militarized IR test systems for

laboratory and field use.

Contact Name:

John Blocha

Position:

Address:

President Pilkington Visioncare

Organization: Component:

Coburn Optical Industries Suite 200, 4606 S Garnett

Tulsa, OK 74146

Notes:

Development of infrared products for military and commercial applications.

Contact Name:

Betty Blodgett

Position:

Marketing

Organization:

Datametrics Corp.

Component: Address:

8986 Comanche Avenue

Chatsworth, CA 21311

Notes:

Thermal Imaging for military applications.

Glenn D. Boreman

Position:

Organization:

University of Central Florida

Component: Electrical Engineering Department and Center for Research in Electro-Optics

and Lasers

Address:

12424 Research Parkway, Suite 400

Orlando, FL 32828

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Use of Narrowband Laser

Speckle for MTF Characterization of CCDs"

Contact Name:

John D. Bossler

Position:

Address:

Organization: Component:

Ohio State University Center For Mapping 1216 Kinnear Road

Columbus, OH 43212

Notes:

Active in infrared remote sensing for scientific research.

Contact Name:

K.A. Bowers

Position:

Organization:

North Carolina State University

Component: Address:

Department of Physics Raleigh, NC 27695-8202

Notes:

Co-Authored for 1991 MCT Workshop "Properties of CdZnTe Crystals Grown

by a High Pressure Bridgman Method"

Contact Name:

Position:

Kim Boyer

Organization:

Address:

Ohio State Univeristy

Component:

469 Dreese Lab

2015 Knil Avenue Columbus, OH 43210-1210

Notes:

Active in process control community as leader of SPIE's workshop on machine

vision. Has good overview of machine vision markets.

G. Stan Boyington

Position:

Director Business Development

Organization:

SPAR Aerospace, Ltd.

Component:

Advanced Technology Systems Group

Address:

9445 Airport Road

Notes:

Brampton, Ontario, CANADA L6S 4J3

Infrared systems and equipment, c/o systems, thermal imaging for military

applications.

Contact Name:

W.R. Bradbury

Position:

Mktg. Dir.

Organization:

Specac Ltd.

Component:

Address:

River House, Lagoon Rd.

St. Mary Cray, Orpington, Kent BR5 3QX

UNITED KINGDOM

Notes:

Manufacture of germanium, silicon, ZnS, and ZnSe for infrared applications.

Contact Name:

Marvin L. Braman

Position:

Director of Public Relations

Organization:

Lockheed Sanders, Inc.

Component:

Address:

NHQ-1-735

68 Spit Brook Road Nashua, NH 03061

Notes:

Infrared systems and equipment, passive and active e/o devices for military

markets.

Contact Name:

Position:

Maruice J. Brau

 ${\bf Organization:}$

Colorado Research Lab

Component:

Address:

Walsenburg, CO

Notes:

Authored January 1991 report "Ultra-high-purity Starting Materials for

diss

Infrared Detector Crystal Growth"

and January 1991 "Traveling Heater Method Growth of Bulk Compound

Semiconductor Alloy Crystals"

Richard A. Bredthauer

Position:

Organization:

MIT

Component:

Lexington Lincoln Lab 244 Wood Street

Address:

Lexington, MA 02173-9108

Notes:

Co-authored August 1989 study entitled "128 X 128 Element IrSi Schottky-

Ì

Barrier Focal Plane Arrays for LWIR Imaging"

Contact Name:

D. Brink

Position:

Organization:

Fraunhofer-Institut fur Angewandte Festkorperphysik

Component:

Address: Tullastr. 72

D-7800 Freiburg, Germany

Notes:

AUthor of "Characterization of MCT Heterostructures by Thermoelectric

Measurements"

Contact Name:

George Brooks

Position: Organization: Group Vice President Rockwell International Corp.

Component:

Government Business Division

Address:

1201 S Second St.

Milwaukee, WI 53204

Notes:

Passive electronic components, including IR detectors.

Contact Name:

Mark Broughton

Position:

Head of public Relations

Organization:

Marconi Radar and Control Systems, Ltd.

Component: Address:

P.O. Box 133

Chobham Road, Frimley

Camberley, Surrey, UK GU16 5PE

Notes:

Thermal Imaging, detectors and sensors, night vision for military markets.

ផ្ទះជាប

Lloyd Brunkhorst

Position:

VPeng

Organization:

Brown Group, Inc.

Component:

Research and Development Laboratory

Address:

8400 Maryland Avc. Saint Louis, MO 63166

Notes:

Basic research for new manufacturing processes, including IR detectors.

Contact Name:

Robert Bruno

Position: Organization: VP Marketing

Component:

Inframetrics

Address:

16 Esquire Road

North Billerica, MA 01862

Notes:

Contact Name:

Leonard Brzozwski

Position:

Pres

Organization:

Robotron Corp.

Component:

Address:

21300 W Eight Mile Rd.

PO Box 5090, Southfield, MI 48086

Notes:

Ion processing and other non-traditional heat treating processes, welding of

ferrous and non ferrous metals

Contact Name:

L.O. Bubulac

Position:

Organization:

Fraunhofer-Institut fur Angewandte Festkorperphysik

Component:

Address: Tullastr. 72

D-7800 Freiburg, Germany

Notes:

AUthor of "Characterization of MCT Heterostructures by Thermoelectric . ag 975

Measurements"

Hans Bucher

Position:

Pres

Organization:

Xedar Corp.

Component:

Address: 2500 Central Ave..

Boulder, CO 80301

Notes:

Electro-optical research applied to field of infrared and thermal imagery.

Contact Name:

Position:

Hans Bucher

Organization:

Xedar Corp.

Component:

Address:

2500 Central Avenue

Boulder, CO 80301

Notes:

infrared non-destructive evaluation

Contact Name:

Position:

H. Budzier

Organization: Component:

Dresden University of Technology Institut fur Festkorperelektronik

Address:

Dresden, FEDERAL REPUBLIC OF GERMANY

Notes:

Co-authored for 1992 SPIE IRFPA meeting "Pyroclectric IR Single-Element

Detectors and Arrays Based on LiNbO3 and LiTaO3"

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Pyroelectric

Linear Array IR Detectors with CCD Multiplexer"

Contact Name:

J. Buic

Position:

Marketing Manager Honeywell, Inc.

Organization:

Component: Address:

....

Solid State Sensors Group

830 E. Arapaho Road

15 . . 1.571 1 1

Richardson, TX 75081

Notes:

Manufactures IR optoelectronic components and assemblies, fiberoptic

components, and modules.

RIchard Buonauito

Position:

Organization:

Alpha Omega Instruments Corp

Component:

Address: 253 Mansfield Drive, P.O. Box DE

Norton, MA 02766

Notes: Has developed an approach to manufacturing a low cost, two-dimensional

array uing lead selenide or other resistive type detectors, with a targeted

manufacturing cost of under \$500 in quantitities.

Contact Name:

Kelly Burke

Position:

Address:

Operations Manager

Organization:

Crystal Specialties International

Component:

2853 Janitall Road

Colorado Springs, CO 80906

Notes:

Production of GaAs and germanium for infrared applications for both military

and commercial markets.

Contact Name:

Richard Burkel

Position:

Manager, Inspection Automation

Organization:

General Electric Co.

Component: Address:

General Electric Aircrast Engines 1 Neumann Way, P.O. Box 156301

Cincinnati, OH 45215-6301

Notes:

Designed GEAE's thermographic inspection equipment for non-destructive

evaluation of jet engine parts, orginally from Air Force funding

Contact Name:

Douglas Burleigh

Position:

Organization:

General Dynamics

Component:

Space Systems Division

Address:

2945 Arcola Avenue

Notes:

Sand Diego, CA 92117

Active in infrared remote sensing, predictive maintenance, non-destructive

evaluation, for both military and commercial applications.

William J. Burns

Position: Organization:

President Emcore Corp.

Component:

Address:

35 Elizabeth Avenue

Somerset, NJ 08873

Notes:

Material production of GaAs, CdTe, silicon, ZnS, and ZnSe for infrared

applications, both military and commercial.

Contact Name:

Position:

Bernard Burns
Director of Sales

Organization:

II-VI Inc.

Component:

Address:

375 Saxonburg Blvd

Saxonburg, PA 16056

Notes:

Contact Name:

Dr Wayne Burwell

Position:

ation.

Organization:

United Technologies Corp.

Component:

United Technologies Research Center

Address:

Silver Ln.

Dir

East Hartford, CT 06108

Notes:

Development of advanced infrared electronic systems.

Contact Name:

Position:

H. Buskes

Organization:

BHP Research

Component:

Melbourne Laboratorics

Address:

P.O. Box 264

Notes:

Clayton, 3168, AUSTRALIA

Co-authored for 1992 MCT Workshop "In-Sity Ellipsometric Measurements of

10,00

the MBE Growth of CdTe/HgTe and CdTe/ZnTe Superlattices."

F-24

Walter Butler

Position:

Gmgr

Organization: Component:

General Electric Company Electronics Laboratory Bldg 3, Electronic Park

Address:

Syracuse, NY 13221

Notes:

Development of infrared arrays with particular focus on HgCdTe and InSbbased systems. Programs include the IRST for the F-14D and AADEOS.

Contact Name:

W.A. Cabanski

Position:

Organization:

University of Erlangen

Component:

Address:

Erlangen, GERMANY

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Electronic

and Optical Properties of Silicide/ Silicon IR Detectors"

Contact Name:

C. Caillas

Position:

Organization: Carnegic-Mellon University

Component:

Robotics Institute 5000 Forbes Avenue

Address:

Pittsburgh, PA 15213

Notes:

Authored an April 1990 study, 100 pages, on "Thermal Imaging for Robotic

Applications in Outdoor Scenes" available from DTIC. Artificial intelligence

automation inspection his speciality.

Contact Name:

Duncan Campbell

Position:

Corp. V.P.

Organization:

BDM Federal, Inc.

Component: Address:

1501 BDM Way

McLcan, VA 22102-3204

Notes:

Thermal Imaging, imaging software, for military.

Tony Canning

Position:

Address:

Organization:

Atlantic Research Canada, Inc.

Component:

1900 City Park Drive, Suite 400

Gloucester, Ontario CANADA KIJ 1A3

Notes:

Thermal Imaging, predominantly for military applications

Contact Name:

Position:

R.W. Capps

Organization:

California Institute of Technology

Component: Address:

1201 East California Boulevard

Pasadena, CA 91125

Notes:

Co-authored for 1990 IEEE Meeting on Advanced IR Detectors "Space

è

Science APplications of Infrared Detector Technology: A Review"

Contact Name:

Pamela E. Carcy

Position:

Ms.

Organization:

BDM Inc.

Component:

Address:

4001 North Fairfax Drive

Arlington, VA 22203

Notes:

Authored for 1992 SPIE workshop on IRFPAs "Modeling the Cost and Producibility Impacts of IRFPA Operability." Expert on cost-operability

tradeoffs with focal plane arrays.

Contact Name:

G.P. Carey

Position:

Organization:

Fraunhofer-Institut fur Angewandte Festkorperphysik

Component:

Address:

Tullastrasse 72

D-7800 Freiburg, GERMANY

Notes:

Authored "XPD Investigation of Substrate Crystallinity at HgCdTe (111B) and

CdTc(111)B Surfaces Upon Ag and Al Overlayer Formation."

Jim Carey

Position:

Marketing Director

Organization:

Loral Electro-Optical Systems

Component:

Address:

300 North Halstead Street

Pasadena, CA 91107

Notes:

Infrared systems and equipment, e/o systems predominantly for military

applications.

Contact Name:

Frederick M. Carlson

Position:

Organization:

Clarkson University

Component:

Address:

Potsdam, NY 13699

Notes:

Attended 1992 MCT conference. Works on MCT related semiconductor

research.

Contact Name:

DR James Carnesca

Position:

Pres

Organization:

SRI International

Component:

David Sarnoff Research Center

Address:

201 Washington Rd

Princeton, NJ 08543-5300

Notes:

Manufacturing materials, consumer electronics and information sciences, and

solid state systems.

Contact Name:

J Carpenter

Position:

Prcs

Organization:

Visidyne Inc

Component:

Address:

10 Corporate Pl.,

Burlington, MA 01803

Notes:

Development of electro-optical instrumentation.

Melvin J. Carr

Position:

President

Organization:

Galtech Semiconductor Materials Corp.

Component: Address:

265 North State Street

Mt. Pleasant, UT 84647

Notes:

Manufacture of CdTe infrared materials, germanium, wasers and ingots,

monocrystalline and polycrystallins. Polishing and slicing series for CdTe and

CdZnTe.

Contact Name:

John C. Carson

Position:

Senior Vice President

Organization:

Irvine Sensors Corp.

Component:

Address: 3001 Redhill Ave Bldg 3

Costa Mesa, CA 92626

Notes:

Applied research in military detection system (infrared sensing).

Contact Name:

Kent Carson

Position:

Director, Infrared Materials Lab

Organization:

Texas Instruments

Component: Address:

P.O. Box 655936, MS 150

Dallas, TX 75265

Notes:

Contact Name:

Kent R. Carson

Position:

Director

Organization:

Texas Instruments

Component:

Infrared Materials Laboratory

14

Address:

P.O. Box 655936, MS 150

Dallas, TX 75265

Notes:

JoElaine Cary

Position:

CEO

Organization:

International Advanced Materials Inc.

Component:

Address: 2 North Circle Avenue

Spring Valley, NY 10977

Notes:

Manufacture of CdTe, GaAs, germanium, silicon, ZnS, and ZnSc materials for

infrared systems, military and commercial.

Contact Name: Position:

Richard Caserio Sales Manager

Organization:

ITI Electro-Optics Corp.

Component:

Address: 11500 W Olympic Blvd

Los Angeles, CA 90064

Notes:

Manufacture of CdTe, GaAs, germanium, ZnS, and ZnSe for infrared

technologies.

Contact Name:

J-P. Chamonal

Position:

Organization:

LETI (CEA- Technologies Avancees)

Component:

DOPT - CEN/G - 85 X-

Address:

38041 Grenoble Cedex FRANCE

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Recent Developments on

12.5 um Infrared Detection Buttable Linear Arrays."

Contact Name:

Tin-Fung Chang

Position:

Organization:

Chung-Shan Institute of Science and Technology

Component:

Address: Lung-Tan, Taiwan, REPUBLIC OF CHINA

Notes:

Co-authored for 1992 SPIE IRFPA meeting "Electrolyte Electroreflectance

Spectroscopies for the Ion-Implanted HgCdTe with Thermal Annealing"

C. Chang

Position:

Organization:

University of Maryland

Component:

Address:

Baltimore, MD

Notes:

Co-authored for 1992 SPIE meeting on Infrared Imaging Systems "Single-

ì

frame Multispectral Thermal Imagery"

Contact Name:

K.T. Chang

Position:

Organization:

University of Southern California

Component:

Department of Materials Science and Engineering

Address:

Los Angeles, CA 90089-0241

Notes:

Co-authored for 1991 MCT Workshop "Ordered Phase in (HgCd)Tc Grown by

LPE on CdTe (111)B Substrate"

Contact Name:

Shi-Chen Chao

Position:

Organization:

National Taiwan University

Component: Address:

Department of Electrial Engineering Taipei, Taiwan, REPUBLIC OF CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Electrolyte Eletroreflectance

Specrtoscopies for the Ion-Implanted HgCdTe with Thermal Annealing"

Contact Name:

Tuvia Charmey

Position:

Advertising Manager

Organization:

Elop-Electro Optics Industries

Component:

Address:

P.O. Box 1165

Rehovot, Israel 76110

Notes:

Infrared systems and equipment, thermal imaging, detectors and sensors, night

vision for military applications.

J.P. Chatard

Position:

Dr. Sofradir

Organization: Component:

Address:

43/47 rue Camille Pelletan

92290 Chatenay-Malabry

FRANCE

Notes:

Head research scientist working on SOFRADIR's process for reduction of IRFPA costs, presented paper on analysis criteria selection for IRFPA

detector production at 1992 SPIE Orlando meeting.

Contact Name:

An-Ban Chen

Position:

Organization:

Auburn University

Component:

Physics Department Auburn, AL 36849

Address: Notes:

Author of "Comparison of InTiSb and HgCdTe as Infrared Material." at 1992

MCT Workshop. Has done MCT producibility-related research.

Contact Name:

C.K. Chen

Position:

Organization:

MIT

Component:

Lexington Lincoln Lab 244 Wood Street

Address:

Lexington, MA 02173-9108

Notes:

Co-authored April 1990 study entitled "PtSi Schottky-Barrier Focal Plane

Arrays for Multispectral Imaging in Ultraviolet, Visible, and Infrared Spectral

Bands"

Contact Name:

Y.P. Chen

Position:

Organization:

University of Illinois at Chicago

Component:

Microphysics Laboratory, Physics Department

Address:

P.O. Box 4348 Chicago, IL 60680

Notes:

Authored "Structure of CdTc(111)B grown by MBE on Misoriented Si(001)"

for 1992 MCT Workshop.

For 1991 Workshop, "Current Status of Direct Growth of CdTc and HgCdTc

on Silicon by MBE"

Arthur Chester

Position:

VP

Organization:

General Motors Corporation

Component:

Hughes Aircraft Co., Research Laboratories

Address:

3011 Malibu Canyon Rd

Malibu, CA 90265

Notes:

Production of GaAs and InP integrated circuits; infrared sensors, especially

monolithic focal plane arrays, for military markets.

Contact Name:

Arthur N. Chester

Position:

Vice President and Director Hughes Research Laboratories

Organization: Component:

Address:

3011 Malibu Canyon Road

Malibu, CA 90265

Notes:

The research laboratories conduct long range applied scientific research in

physics, chemistry, electronics, and information sciences.

Contact Name:

A.C. Childs

Position:

Organization:

Rockwell International Corporation

Component:
Address:

Electro-Optics Center 3370 Miraloma Avenue

Anahcim, CA 92803

Notes:

Production of MCT-based arrays on alternative substrates under company

funding and PACE I and PACE II contracts from military.

Contact Name:

B.A. Chin

Position:

Organization:

Auburn University

Component:

Address:

Notes:

Co-authored 1991 "Weld Quailty Control in Gas Tungsten Arc Welding

Process"

Bryan Chin

Position:

Organization:

Auburn University

 ${\bf Component:}$

Address:

Notes:

Co-authored 1984 "Automatic Welding: Infrared Sensors for Process Control

Computer Based Factory Automation"

Contact Name:

Brian Chin

Position:

Professor

Organization:

Auburn University

Component:

College of Engineering and Engineering Experiment Station

Address: 201 Ross Hall

Auburn, AL 36849-5351

Notes:

Designs automated welding systems using IR detectors for machine vision.

Contact Name:

Laurel Chivari

Position:

Manager, Public Relations

Organization:

Northrop Corp.

Component:

Electronics Systems Division

Address:

600 Hicks Road

Rolling Meadows, IL 60008-1098

Notes:

Infrared systems and equipment for military applications.

Contact Name:

James Chladek

Position:

Vice President

Organization:

CIC International, Ltd.

Component:

Address:

38-01 23rd Avenue

Astoria, NY 11105

Notes: .

Detectors and Sensors, infrared systems and equipment, night vision

equipment for military.

J. Choi

Position:

Organization:

University of Maryland

Component:

Address: College Park, MD

Notes: Co-authored 1987 study "Magnetophonon Effect in HgCdTe"

Contact Name:

Deepak Chopra

Position:

President

Organization:

UDT Sensors Inc

Component:

Address: 12525 Chadron Avc.

Hawthorne, CA 90250

Notes:

Development of light-based sensors.

Contact Name:

Deepak Chopra

Position:

Pres

Organization:

UDT Sensors Inc

Component:

Address: 12525 Chadron Ave.

Hawthorne, CA 90250

Notes: Development of light-based sensors.

Contact Name:

J.A. Christensen

Position: Organization:

Marketing Director Hughes Aircraft Co.

Component:

Electron Dynamics Division

Address: 3100 W. Lomita

Torrance, CA 90509-2999

Notes:

Joseph Christenson

Position:

Pres

Organization:

Pattern Processing Technologies

Component:

Address:

Suite 170, 10025 Valley View Rd.

Eden Prairie, MN 55344

Notes:

Product oriented machine vision systems, some IR experience.

Contact Name:

Bernard Christophe

Position:

SAT

Organization:

Component: Address:

41, rue Cantagrel

F-75361 Paris Cedex 13 FRANCE

Notes:

Along with Thomson CSF, places HgCdTe-based sensors on a variety of

military products, including the Rafale fighter. Also produces own InSb-based

IRFPAs for use in missile guideance.

Contact Name:

J.H. Chu

Position:

Organization: Component:

Shanghai Institute of Technical Physics National Laboratory for Infrared Physics

Address:

Academia Sinica Shanghai 200083

CHINA

Notes:

Co-authored for 1991 MCT Workshop "Influece of Resonant Defect States on

Subband Structures in HgCdTe"

Contact Name:

John Cicotta

Position:

Marketing Communications Manager

Organization:

Harris RF Communications

Component:

Address:

1680 University Avenue

Rochester, NY 14610

Notes:

Thermal imaging, digital imaging systems, imaging software for military.

Ray P. Clark

Position:

Dr.

Organization:

King's College

Component: Address:

Thermal Biology Research Unit Campden Hill Road, Kensington

Notes:

London, W8 7AH, UNITED KINGDOM Active in infrared biomedical thermography as system designer and leading

researcher, developing new applications. Widely published.

Contact Name:

Ray P. Clark

Position:

Dr.

Organization:

King's College London, University of London

Component:

Thermal Biology Research Unit

Address:

Campden Hill Road

Notes:

Kensington, Longon W8 7AH UNITED KINGDOM President of European Academy of Thermology 1993-1994.

Contact Name:

David Clist

Position:

Business Development Manager

Organization:

Marine-Air Systems

Component:

Address:

24 Bridge Street

P.O. Box 30-248

Lower Hutt, NEW ZEALAND

Notes:

E/o systems, detectors & sensors, infrared systems & equipment, thermal

imaging for military markets.

Contact Name:

Robert L. Cockrell

Position:

Director, Business Development

Organization:

Amherst Systems, Inc.

Component:

Address:

30 Wilson Road

Buffalo, NY 14221

Notes:

Passive and Active electro-optical systems, infrared systems & equipment

mainly for military.::

C.A. Cockrum

Position:

Organization:

SBRC

Component:

Address:

75 Coromar Drive

Goleta, CA 93117

Notes:

Predominantly MCT-based IR systems, focal planes arrays, and components,

including dewar assemblies, for military use.

Research scientist involved in SBRC's MCT IRFPA projects; substrate work

too.

Contact Name:

Antonio Colantonio

Position:

Organization:

Technology, Architectural, and Engineering Services

Component:

Public Works Canada

Address:

Riverside Drive

Notes:

Ottawa, Ontario, CANADA K1A OM2 infrared non-destructive evaluation

Contact Name:

Position:

AD Cole Pres

Organization:

Adcole Corporation

Component:

Address:

669 forest St.

Marlborough, MA 01752

Notes:

Research on sun sensing systems, scientific instruments for rockets and

satellites, linear and radial electro-optical measuring techniques, computer

controlled cylindrical coordinate gauging equipment.

Contact Name:

Michael Coleman

Position:

Direng

Organization: Component:

Advanced Design Corporation

Address:

8560 Cinderbed Rd

aren ha

Notes:

Newington, VA 22122

Product oriented electro-optics; night vision devices both image intensification

and thermal imaging. Military.

John Coleman

Position:

CEO

Organization:

Plasma Physics Corp.

Component:

Address: PO Box 548

Locust Valley, NY 11560

Notes:

Development and manufacture of photoreceptor drums, solar cells and

imaging, polymer laminating, and laser isotope separation.

Contact Name:

D.A. Collins

Position:

Dr.

Organization:

California Institute of Technology

Component:

Address:

1201 East California Boulevard

Pasadena, CA 91125

Notes:

Reported at the DARPA Program Review on Infrared Focal Plane Array Technology in December, 1992, on "InAs/GalnSb Superlattices: Growth

Involving Anion Switching"

Contact Name:

Luigi Colombo

Position:

Texas Instruments

Organization: Component:

Central Research Laboratories

Address:

P.O. Box 655936, MS 154

Dallas, TX 75265

Notes:

Contact Name:

R. Coltart

Position:

Press Officer

Organization:

GEC Marconi Dynamics, Ltd.

Component:

Address:

The Grove

Warren Lane

Stanmore, Middlesex, UK HA7 4LY

Notes:

Infrared systems and equipment, MMW radar, etc. for military applications

Ervin Colton Chief Executive

Organization:

Cerac Inc.

Component:

Position:

Address: P.O. Box 1178

Milwaukce, WI 53201

Notes: Manufacturer of infrared materials, as well as specialty inorganic chemicals,

evaporation materials, and sputtering targets in both R&D and bulk quantities.

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Specializes in materials of well defined purity and size including oxides, fluorides, silicides, borides, nitrides, carbides, sulfides, and intermetallic

powders.

Contact Name:

Thomas Connolly

Position:

Organization:

Oricl Corp.

Component:

Address: 250 Long Beach Blvd

Stratford, CT 06497

Notes:

Manufacture of GaAs, germanium, silicon, and ZnSe for infrared applications,

for both military and commercial markets.

Contact Name:

Peter C. Connolly

Position:

Business Development Manager

Organization:

Photronics Corp.

Component: Address:

270 Motor Parkway

P.O. Box 11368

Hauppauge, NY 11788

Notes:

E/o systems, infrared systems and equipment, night vision for military

applications.

Contact Name:

Augusto Contc-Matos

Position:

Organization:

Georgia Tech Research Institute

Component:

Physical Sciences Laboratory
Room 128 Baker Bldg

Address: Room 128 Baker E

Atlanta, GA 30332

Notes:

Co-authored for 1991 MCT Workshop "Gas Source Iodine Doping and

Characterization of MBE Grown CdTe*

J.W. Cook

Position:

Organization:

North Carolina State University

Component: Address:

Department of Physics Raleigh, NC 27695-8202

Notes:

Co-AUthored "Integrated Heterostructure Devices Based on II-VI Compound

ě

Semiconductors" for 1992 MCT Workshop

Co-Authored for 1991 MCT Workshop "Quantum Hall Effect adn Setback

Modulation Doping HgTe-CdTe Heterostructures"

Contact Name:

J.W. Cook

Position:

Organization:

North Carolina State University

Component: Address:

Department of Physics Raleigh, NC 27695-8202

Notes:

Authored for 92 MCT workshop "Growth of HgSc and HgCdSc Thin Films by

Molecular Beam Epitaxy"

Contact Name:

Diane Cook

Position:

Organization:

University of Texas at Arlington

Component: Dept of Computer Science Engineering

Address:

P.O. Box 19015

Arlington, TX 76019-0015

Notes:

active in infrared process control

Contact Name:

R.P. Cooper

Position:

Organization: Ford Motor Co.

Component:

Scientific Research Laboratory

Address:

· 5. 5.

P.O. Box 2053

Dcarborn, MI 48121

Notes:

Interested in designing IR systems to nondestructively test cars for paint

W 15 .

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dittill.

delamination and rust

F-40

W. Covington

Position:

Organization: Sam Houston State University

Component: Address:

Department of Physics Huntsville, TX 77341

Notes:

Co-authored "Properties of InAs/(Ga,In)Sb Strained Layer Superlattices

Ì

Grown on the (111) Orientations" for 1992 MCT Workshop

Contact Name:

David H. Cowling

Position:

Organization: Lousiana Tech University
Component: College of Engineering

Address:

Tech Station, P.O. Box 10348

Ruston, LA 70803-0301

Notes:

Co-authored 1990 "A Simplified Vision System With Robotic Assembly and

Manufacturing Applications"

Contact Name:

Edward Cox

Position:

Organization:

Digital Equipment Corp

Component:

Address:

Mail Stop MLO5-4/E22

Maynard, MA 01754

Notes:

Has conducted research on the use of infrared non-destructive evaluation of

integrated circuit boards

Contact Name:

Robert Cox

Position:

President

Organization:

Emerson Electric Co

Component:

Rosemount Inc.

Address:

12001 technology Dr. Eden Prairie, MN 55344

Notes:

Applied research on sensors and instruments for measurements of

temperature, flow level, pressure, and other industrial applications. Uses IR

detectors for various spectrometers, FTIR, gas analysis and detection

applications.

Steve Cox

Position:

Pres

Organization:

Address:

Lasermike, Inc.

Component:

6060 Executive Blvd

Dayton, OH 45424

Notes:

Development of intelligent sensors; although work is more involved in

è

software and image processing, some work with IR sensors.

Contact Name:

Elliot Cramer

Position:

Organization:

NASA

Component:

Langley Research Center

Address:

MS 231

Hampton, VA 23665

Notes:

Infrared non-destructive evaluation, mainly advanced composites, esp. aging

aircrast skins.

Contact Name:

Dr Clara Craver

Position:

COO

Organization:

Craver & Craver Inc

Component:

Address:

761 W Kirkham Avc.

Saint Louis, MO 63122

Notes:

Computer-assisted database searches in infrared spectroscopy; reference

spectra for IR.

Contact Name:

B. Scott Crews

Position:

Organization:

NASA

Component:

Langley Research Center

Address:

Analytical Services and Materials, Inc.

MS 231

Hampton, VA 23655

Notes:

Infrared non-destructive evaluation, mainly of aging aircraft skins.

Paul D. Croissant

Position:

Dr.

Organization:

Component:

Address:

1711 Woodward Avenue

Bloomfield, MI 48103

Notes:

Doctor in private practive active in infrared biomedical thermography

associations

Contact Name:

D.J. Crowther

Position:

Organization:

Wayne State University

Component:

Dept of Physics and Inst for Manufacturing Research

Address:

Detroit, MI 48202

Notes:

infrared non-destructive evaluation

Contact Name:

James E. Culley

Position:

Address:

Organization: Picker International, Ltd.

Component:

Engineering Dept P.O. Box 2, East Lanc

Wembley, HA9 7PR, UNITED KINGDOM Notes:

Active in infrared biomedical thermography, has written extensively about the

broad applications for IR thermography.

Contact Name:

Darrell Curtis

Position:

Director Business Development

Organization:

DBA Systems, Inc.

Component:

Address: P. O. Box 550

Melbourne, FL 32902

Notes:

Thermal Imaging, infrared systems and equipment for military applications

Richard Curtiss

Position:

Gmgr

Organization:

Raythcon Comp.

Component:

Electromagnetic Systems Division

Address:

6380 Hollister Avc. Goleta, CA 93117

Notes:

Infrared countermeasures and high frequency microwave and antennas.

ì

Contact Name:

Armur Cussen

Position:

Pres

Organization:

Channel Technologies

Component:

Electro-optical Industries, Inc.

Address:

859 Ward Dr.

Santa Barbara, CA 93111

Notes:

Research on infrared and visible blackbody radiant energy standards, radiometry, electro-optical instrumentation, microwave standards, low-level

instrumentation, industrial temperature measurement, and radiation

thermometry.

Contact Name:

J.A. Cutts

Position:

Organization:

California Institute of Technology

Component: Address:

1201 East California Boulevard Pasadena, CA 91125

Notes:

Co-authored for 1990 IEEE Meeting on Advanced IR Detectors "Space

Science Applications of Infrared Detector Technology: A Review*

Contact Name:

John Dahmes

Position:

Executive Manager, Marketing

Organization:

Intergraph Corp.

Component:

Address:

2051 Mercator Drive

Reston, VA 22091

Notes:

Thermal Imaging, imaging software for military applications.

M. Dal Colle

Position:

Organization:

Fraunhofer-Institut fur Angewandte Festkorperphysik

Component:

Address: Tullastr. 72

D-7800 Freiburg, Germany

Notes: Co-authored for 1991 SPIE meeting on Growth of IR Materials

"Characterization of Anodic Fluoride Fllms on HgCdTe"

Contact Name:

Position:

Organization:

UTI Instruments

Hugh Danaher

Component: Address: Notes:

Contact Name:

Craig Davidson

Position:

Organization:

Vision Harvest

Component:

Address:

HCR Box 36

Hatch, NM 87937

Notes:

active in infrared process control

Contact Name:

C. de Cambray

Position:

Public Relations Executive

Organization:

SAGEM

Component:

Address:

6, avenue d'Iena

75783 Paris, Decex 16, FRANCE

Notes:

Infrared equipment & systems, detectors and sensors, e.o systems, night vision,

robotics for military applications.

William De La Torre

Position:

Mr.

Organization:

Research Opportunities, Inc.

Component:

Address: 2200 Hamipola Court Suite 101

Torrance, CA 90501

Notes:

Designer of infrared non-destructive evaluation system at research

*

opportunities.

Contact Name:

Li Dc-Chun

Position:

Shandong University

Organization: Component:

Infrared and Remote Sensing Re.

Address:

Jinan, Shandong, CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "The Dependence of Fermi

Level of HgCdTe on Impurity Concentration and Temperature"

Contact Name:

A. Dccpak

Position:

Presidnent

Organization:

Science & Technology Corp

Component:

Address:

101 Research Dr., PO Box 7390

Hampton, VA 23666

Notes:

Remote sensing, laser beams, e/o sensors, and lidars, aerosols, fogs and hazes,

climate, space, and environmental quailty.

Contact Name:

John Dehne

Position:

Pres

Organization:

Loral Corporation

Component:

Loral Infrared & Imaging Systems, Inc.

Address:

2 Forbes Rd.

Lexington, MA 02173

Notes:

R&D of electro-optical systems and components.

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Contact Name:

Nancy C. DelGrande

Position:

Ms.

Organization:

Lawrence Livermore National Laboratories

Component:

Address:

Livermore, CA 94551

Notes:

Active in infrared remote sensing, designed dual-band IR system using MWIR

and LWIR detectors simulateneously to overcome emissivity problems.

Contact Name:

Brian Denley

Position: Organization:

Loral Corporation

Component:

Loral Infrared & Imaging Systems, Inc.

Address:

2 Forbes Rd.

Lexington, MA 02173

Notes:

Contact Name:

Roberta L. Denny

Position:

Ms.

Organization:

Rockwell International Corporation

Component: Address:

Electro-Optics Center 3370 Miraloma Avenue

Anahcim, CA 92803

Notes:

Leader of Rockwell EOC's Man/Tec research including producibility work on

focal plane arrays.

Contact Name:

Dave Derby

Position:

Prcs

Organization:

Datron Systems, Inc.

Component:

Address:

200 W Los Angeles Ave.

Simi Valley, CA 93065-1650

Notes:

Production and research in infrared optical and laser sensors.

Eustace Dereniak

Position:

Organization: University of Arizona
Component: Optical Sciences Center
Address: Tucson, AZ 85721

Notes:

active in infrared process control

Contact Name:

E.L. Derenial

Position:

Organization: University of Arizona
Component: Optical Sciences Center
Address: Tucson, AZ 85721

Notes:

Co-Author in 1992 SPIE meeting of "Development of a High-Speed PtSi

IRCCD Camera System"

Contact Name:

M.R. Descour

Position: Organization: Component:

University of Arizona
Optical Sciences Center

Address:

Tucson, AZ 85721

Notes:

Co-authored for 1992 IRFPA SPIE meeting "Functional aspects of the retina

relating to infrared focal plane arrays"

Contact Name:

Joseph DeSimone

Position:

Pres.

Organization:

Silicon Casting Inc.

Component:

Address: 2616 Mcrcantile Drive

Rancho Cordova, CA 95742

Notes:

Manufacturer of silicon in various shapes for infrared applications.

G. Destefanis

Position:

Organization:

LETI (CEA - Technologies Avancees)

Component:

DOPT - CEN/G - 85 X

Address:

F38041 Grenoble Cedex FRANCE

Notes:

Co-authored for 1992 MCT Workshop "Large Improvement in HgCdTe

Photovoltaic Detector Performances at LETI"

Contact Name:

Bob Deuple

Position:

Dr.

Organization:

Thayer School of Engineering

Component:

Biophysics Dept

Address: Notes: Hanover, NH 03755

active in infrared biomedical thermography

Contact Name:

Roger DeVilbiss

Position:

Product Marketing Manager

Organization:

Marlow Industries, Inc.

Component:

Address:

10451 Vista Park Road

Dallas, TX 75238

Notes:

Manufactures thermoelectric cooling devices, thermoelectric cooling

assemblies, and related power supplies and temperature controllers

Contact Name:

itact Name:

C.F. Dewcy

Position: Organization:

Component:

MIT

Address:

Cambridge, MA 02139

Notes:

Co-authorrd for 1991 MCT Workshop "Nonlinear Optical Effects in

Rotationally Twinned CdTe and CdMnTe Crystals"

John Dimmock

Position:

Gmgr

Organization:

McDonnell Douglas Corporation MD Research Laboratories

Component:

PO Box 516

Address:

Saint Louis, MO 63166

Notes:

Infrared detectors and fluid dynamics.

Contact Name:

Qian Dingrong

Position:

Organization:

Laboratory for Infrared Physics

Component:

Academia Sinica

Address:

420 Zhong Shan Bei Yi Road Shanghai, 200083, CHINA

Notes:

Authored for 1992 SPIE meeting on IRFPAs "Element of a new Infrared

Detector Plasma Edge Detector"

Contact Name:

Peter Direnzo

Position:

Gnl Mgr

Organization:

Cleveland Crystals, Inc.

Component:

Address:

19306 Redwood Avenue, P.O Box 17157 Cleveland, OH 44117

Notes:

Manufacturer and research into CdTe, ZnS, and ZnSe infrared materials for

both military and commercial markets.

Contact Name:

Robert Dixon

Position:

Organization:

Tektronix, Inc.

Component:

Address:

26600 Southwest Parkway

Beaverton, OR 97077

Notes:

infrared non-destructive evaluation

M. Dobrowolska

Position: Organization:

University of Notre Dame Department of Physics

Component: Address:

Notre Dame, IN 46556

Notes:

Co-authored for 1991 MCT Workshop "Magnetic Generation of electrons and

Holes in Semimetallic HgTe-CdTe Superlattices"

Contact Name:

Alan Doctor

Position: Organization:

Sales & Marketing Manager Servo Corporation of America

Component:

Address:

111 New South Road

Hicksville, NY 11802

Notes:

Manufactures thermistors and pyroelectric IR detectosr, IR optical

components, IR telescope assemblies, custom IR systems, and coating

materials.

Contact Name:

Brad Doetzel

Position:

CEO

Organization:

Avimo USA, Inc.

Component:

Address:

716 S Milwaukce Ave.

Wheeling, IL 91702

Notes:

Product oriented research in night vision optics and custom optical

components, used mainly by the military.

Contact Name:

Robert Donadio

Position:

🤔 Pres

Organization: Component:

Morton International CVD Incorporated 185 New Boston St.

Address:

Woburn, MA 01801

Notes:

Material sciences, novel optical concepts and laser applications.

D. Donnelly

Position:

Organization: Sam Houston State University

Component: Address:

Department of Physics Huntsville, TX 77341

Notes:

Co-authored "Properties of InAs/(Ga,In)Sb Strained Layer Superlattices

Grown on the (111) Orientations" for 1992 MCT Workshop

Contact Name:

F.P. Doty

Position:

Organization:

Aurora Technologies Corp.

Component:

Address:

San Diego, CA 92121-2410

Notes:

Co-authored for 1991 MCT Workshop "Properties of CdZnTe Crystals Grown

by a High Pressure Bridgman Method." Has conducted CZT related research

Contact Name:

Position:

Irwin Drangel Sales Manager

Organization:

United Mineral and Chemical Corp.

Component:

Address:

1100 Valley Brook Avenue

Lyndhurst, NJ 07071-3608

Notes:

Manufacture of CdTe, GaAs, germanium, and ZnS for infrared applications.

Contact Name:

Alfred D. Ducharme

Position:

Organization:

University of Central Florida

Component:

Electrical Engineering Department and Center for Research in Electro-Optics

and Lasers

Address:

12424 Research Parkway, Suite 400

Orlando, FL 32828

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Use of Narrowband Laser

Speckle for MTF Characterization of CCDs"

Michael Dudley

Position:

Organization: SUNY at Stony Brook

Component: Address:

Department Materials Sci & Eng Stony Brook, NY 11794-2275

Notes:

Attended 1992 MCT conference

Contact Name:

Benjamin Duhow

Position: Organization: V.P. Defense Programs

Component:

Thomson-CSF

Address:

2231 Crystal Drive, Suite 814

Arlington, VA 22202

Notes:

Infrared equipment and systems, detectors and sensors

Contact Name:

James Dunn

Position:

Prcs

Organization:

Loral Corporation

Component:

Loral Fairchild Systems

Address:

300 Robbins Ln.

Syosset, NY 11791

Notes:

Development of electro-optical imaging systems.

Contact Name:

Ronny Dunn

Position:

Infrared Program Manager

Organization:

....

Texas Instruments

Component:

Defense Systems and Electronics Group

Address:

POB 660246 MS 3139

Dallas, TX 75266

Notes:

210

J.A. Dura

Position:

Organization:

University of Houston

Component: Address:

Department of Physics and Space Vacuum Epitaxy Center Houston, TX 77204

Notes:

Co-authored "Properties of InAs/(Ga,In)Sb Strained Layer Superlattices

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Grown on the (111) Orientations" for 1992 MCT Workshop

Contact Name:

Dan Duscl

Position:

Vice President, marketing.

Organization:

Merlin Engineering

Component: Address:

1888 Embarcadero Road

Palo Alto, CA 94303

Notes:

Thermal imaging, infrared systems & equipment for military markets.

Contact Name:

Frans Eberth

Position:

Organization:

FLIR Systems, Inc.

Component:

Address:

16505 SW 72nd Avenue

Portland, OR 97224

Notes:

Infrared non-destructive evaluation specialist.

Contact Name:

Position:

Kip Edgley

Electrical/Instrumentation Specialist

Organization: Component:

Envirotech Operating Services

Address:

18820 Aurora Avenue North

Vancouver, WA 98133

Notes:

Large western thermographic predictive maintenance firm, consultants

D.D. Edwall

Position:

Organization: Fraunhofer-Institut fur Angewadnte Festkorperphysik

Component:

Address: Tullastr. 72

D-7800 Freiburg, Germany

Notes: AUthor of "Characterization of MCT Heterostructures by Thermoelectric

Measurements"

Contact Name:

Jeff Edwards

Position:

Communications Manager

Organization:

Evans & Sutherland

Component:

Address: 600 Komas Drive

Salt Lake City, UT 84108

Notes:

Night Vision, thermal imaging for military applications.

Contact Name:

D. Eger

Position:

Organization:

Sorcq Nuclear Research Center

Component:

Address:

ISRAEL

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Anodic

Oxides on HgZnTe"

Contact Name:

Position:

H. Ehrenreich

Organization:

Harvard University

Component:

Division of Applied Sciences

Address:

29 Oxford Street

Cambridge, MA 92138

Notes:

Co-Authored "Augur Lifetimes in Ideal InGaSb/InAs Superlattices" for 1992

MCT Workshop.

2 (1) 645 t

Hassan Ehsani

Position:

Organization:

Rensselaer Polytechnic Institute

Component: Address:

110 Eight Street Troy, NY 12180

Notes:

Co-authored "Improved CdTe Layers on GaAs and Si Substrates, Grown by

Atomic Layer Epitaxy" for 1992 MCT Workshop

Co-Authored for 1991 Workshop "Low Temperature Epitaxy of HgTe, CdTe, and HgCdTe Using FLow Modulation Techniques" and "Reduced Metal-Insulator Semiconductor Tunnelling in MOCVD HgCd(111)Te Films"

Contact Name:

Robert Einzig

Position:

Address:

Pres

Organization:

Optical Technologies, Inc.

Component:

Suite 1200, 360 Herndon Pkwy

Herndon, VA 22070

Notes:

Research and development of fiber optic sensors for the measurement of

physical parameters.

Contact Name:

Steven Eisenbath

Position:

Pres

Organization:

Peda-Scan Infrared Service, Inc.

Component:

Address:

1932 Olde Eisenbath Ln.

Foristell, MO 63348

Notes:

Consultant doing research for industry; thermal evaluation of performance of

products.

Contact Name:

David Eisenhaure

Position:

Address:

Pres

Organization:

Satcon Technology Corp.

70 35 Berod. 45/10\-

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17.11

Component:

12 Emily ST.

Cambridge, MA 02139-4507

Notes:

Power electronics and system integration.

Jan Eklund President

Organization:

Eklund Infrared

Component:

Position:

Address: 142 Sunset Avenue

Verona, NJ 07044

Notes:

Eklund Infrared markets AGEMA's systems in US. Eklund is on SPIE's

Thermosense steering committee

Contact Name:

Sylvester N. Ekpenuma

Position: Organization:

Classin College

Component:

Department of Mathematics and Physics Orangeburg, South Carolina 29115

Address: Notes:

Co-authored for 1991 MCT Workshop "Critical Stress of HgCdTe Solid

Solutions" and "Microhardness of Hg-Containing II-Vi Alloys"

Contact Name:

Joel Elftmann

Position:

Pres

Organization:

FSI International

Component:

Address:

322 Lake Hazeltine Dr.

Chaska, MN 55318

Notes:

Research for semiconductor production equipment.

Contact Name:

Dr. Herbert Elion

Position:

CEO

Organization:

International Optical Telecommunications

Component:

18 E Blithedale Ave.

Address:

Mill Valley, CA 94941-1916

Notes:

Hardware and software market research including lab facilities, design

improvement and patenting technology assistance.

Earle Ellefsen

Position:

Pres.

Organization:

Pure Tech Inc.

Component: Address:

P.O. Box 1319

Carmel, NY 10512

Notes:

Manufacture of CdTe, germanium, silicon, ZnS, and ZnSe for infrared

applications.

Contact Name:

WJ Elsdoefer

Position:

Pres

Organization: Component:

International Machine & Tool Corp.
Instrument & Development Laboratory

Address:

115 Maple St. Warwick, RI 02888

Notes:

Electronic and optical measurement development.

Contact Name:

Earnest Emery

Position:

CEO

 ${\bf Organization:}$

E2 Technology corp.

Component:

Address:

4475 Dupont Ct., No 9

Ventura, CA 93003

Notes:

Product oriented research in infrared blackholes.

Contact Name:

Michel Engelhardt

Position:

Organization:

Grumman Aircraft Systems

Component:

Address:

MS B46-35

Bethpage, NY 11714

Notes:

Active in infrared process control design and integration for Grumman.

Gerald Entine

Position:

Pres

Organization:

Radiation Monitoring Devices, Inc.

Component:

Address:

44 Hunt St.

Watertown, MA 02172

Notes:

Manufacture of cadium telluride for infrared applications.

è

Contact Name:

David E. Escobar

Position:

Organization:

USDA - ARS

Component:

Remote Sensing Research Unit

Address:

2413 E. Highway 83 Wesiaco, TX 79586

Notes:

active in infrared remote sensing

Contact Name:

I. Esquivias

Position:

Organization:

Fraunhofer-Institut fur Angewandte Festkorperphysik

Component:

Address:

Tullastr. 72

Notes:

D-7800 Freiburg, Germany Co-authored for 1991 SPIE meeting on Growth of IR Materials

"Characterization of Anodic Fluoride Films on HgCdTe"

Contact Name:

Paul Everett

Position:

Manager, Business Development

Organization:

Litton Electron Devices

Component:

Address:

1215 S. 52nd Street

Tempe, AZ 85281

Notes:

E/O systems, night vision devices, infrared systems and equipment, produced

for military markets.

James H. Everitt

Position:

Organization:

USDA - ARS

Component:

Remote Sensing Research Unit

Address:

2413 E. Highway 83 Weslaco, TX 79596

Notes:

active in infrared remote sensing

Contact Name:

Gerald Falbel

Position:

Chmn

Organization:

Optical Energy

Component:

Address: 472 Westover Rd

Stamford, CT 06902

Notes:

Research into electro-optical engineering.

Contact Name:

Mary Fallon

Position:

Ms.

Organization:

Inframetrics

Component:

Address: 16 Esquire Drive

Billerica, MA 01862

Notes:

Contact Name:

T. Fanning

Position:

SUNY at Stony Brook

Organization: Component:

Department of Materials Science & Engineering

Address:

Stony Brook, NY 11794-2275

Notes:

AUthor of "White Beam X-ray Synchroton Topography Analysis of CdTe

(111)B Substrates and Epilayers

Lorenzo Faraone

Position:

University of West Australia

Organization: Component:

Department of EE

Address:

Nedlands, Perth, Western Australia 6009

Notes:

Attended 1992 MCT conference

Contact Name:

Frank Fariello

Position:

Pres

Organization:

EDO Corporation

Component:

Barnes Engineering Company

Address:

88 Long Hill Cross Rd. Shelton, CT 06484

Notes:

Manufactures thermal and photon detectors, micro-thermal imagers, spectrum

analyzers, space instrumentation, neluding horizon sensors, IR microscopes,

and IR instrumentation for research and industry.

Contact Name:

Vahne Farkissian

Position:

Pres

Organization:

Silicon Valley Group, Inc.

Component:

Address:

2240 Ringwood Avc.

San Jose CA 95131

Notes:

Semiconductor wafer processing equipment.

Contact Name:

Cathleen M. Farley

Position:

Ms.

Organization: Component: BDM Inc.

Address:

4001 North Fairfax Drive

Arlington, VA 22203

Notes:

Authored for 1992 SPIE workshop on IRFPAs "Modeling the Cost and

Producibility Impacts of IRFPA Operability"

Diane Farrar

Position:

Ms.

Organization:

NASA Ames Research Center

Component:

Address:

Mountain View, CA 94035-1000

Notes:

Designed airborne fire monitoring system used, most notably, to assist oakland

Ì

firefighters during October 1991 blaze

Contact Name:

Heinz Fassmer

Position:

Organization:

Eltro GmBH, Gesellschaft fur Strahlungstechnik

Component:

Euromissile Group

Address:

W-2878 Berne 2/ Motzen-Weser

Germany

Notes:

Produces HgCdTe-based infrared guidance systems for military applications.

Contact Name:

Position:

Jcan-Paul Fauric

Organization:

University of Illinois Microphysics Lab

Component: Address:

Chicago, IL

Notes:

Authored November 1989 "MBE Growth: Characterization and Electronic

Device Processing of HgCdTc, HgZnTc. Related Heterojunctions and

HgCdTe-CdTe Superlattics"

Contact Name:

Position:

J.P. Fauric

Organization:

University of Illinois at Chicago

Component:

Microphysics Laboratory, Physics Department

Address:

PO Box 4348, M/C 273

Chicago, IL 60680

Notes:

Authored "Structure of CdTe(111)B grown by MBE on Misoriented Si(001),"

and "Influence of CdZnTe(211)B Substrate on Electrical Propoerties of

HgCdTe Grown by MBE" for 1992 MCT Workshop.
On Program Committee of 1991 & 1992 MCT Workshop

For 1991 Workshop, "Current Status of Direct Growth of CdTe and HgCdTe

on Silicon by MBE"

L.D. Favro

Position:

Organization: Wayne State University

Component:

Insitute for Manufacturing Research

Address:

Detroit, MI 48202

Notes:

Expert in infrared NDE. Authored in 1990 a 7 page "Noise Suppression in IR Thermal-Wave Video Images by Real-Time Processing in Synchronism with

Active Stimulation of the Target"

Contact Name:

Terry Feeley

Position:

Pres

Organization:

Laser Fare, Inc.

Component: Address:

One Industrial Dr S

Esmond, RI 02917

Notes:

Applied laser technology to industrial materials processing; research in

aerospace, medical and electronic applications, includes IR illumination.

Contact Name:

Wu Fci-fei

Position:

Organization:

Shandong University

Component:

Infrared and Remote Sensing Re.

Address:

Jinan, Shandong, CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "The Dependence of Fermi

Level of HgCdTe on Impurity Concentration and Temperature"

Contact Name:

A. Fenigstein

Position:

Organization:

Kidron Microelectronics Research Center

Component: Address:

Department of Electrical Engineering
Technion-Israel Institute of Technology

Haifa 32000, ISRAEL

Notes:

For 1991 MCT.; Workshop Co-authored "Covered Electrode HgCdTe

Photoconductor Under High Illumination Levels"

F. Fernandez

Position:

President

Organization:

Vinten-Penarroya Inc.

Component:

Address:

17151 Newhope Street, Suite 208

Fountain Valley, CA 92708

Notes:

Manufacture of germanium for infrared applications.

Contact Name:

E. Finkman

Position:

Organization:

Kidron Microelectronics Research Center

Component: Address:

Department of Electrical Engineering Technion-Israel Institute of Technology

Haifa 32000, ISRAEL

Notes:

For 1991 MCT Workshop Co-authored "Covered Electrode HgCdTe

Photoconductor Under High Illumination Levels"

Contact Name:

Patrick Finney

Position:

Organization:

FLIR Systems, Inc.

Component:

Address:

16505 SW 72nd Avenue

Portland, OR 97224

Notes:

Active in setting up infrared predictive maintenance and IC board inspection

regimes for FLIR systems

Contact Name:

John Fitts

Position:

Pres

Organization:

EOIS

Component:

Suite 501, 710 Wilshire Blvd.

Address:

Santa Monica, CA 90401

Notes:

High-energy laser beam control systems, smart sensor technology, moir

interferometry, wavefront sensors, algorithm development.

Brian Fitzpatrick

Position:

President

Organization:

Optical Semiconductors Inc.

Component:

Address: 8 John Walsh Blvd, Suite 421

Peekskill, NY 10566-5330

Notes:

Manufacture of ZnS and ZnSe for infrared systems for both military and

3

commercial markets.

Contact Name:

L.M. Flath

Position:

Organization: Component:

University of Arizona Optical Sciences Center

Address:

Tucson, AZ 85721

Notes:

Author in 1992 SPIE meeting of "Development of a High-Speed PtSi IRCCD

Camera System"

Contact Name:

Terry Fleener

Position:

Manager, Business Development

Organization:

Ball Electro-Optics and Cryogenics Div.

Component:

Address:

P.O. Box 1062

Boulder, CO 80306

Notes:

Thermal Imaging, Active and Passive EO systems for military market.

Contact Name:

Michael Florimbi

Position: Organization:

CEO

Component:

BEI Electronics Company, Inc.
BEI Desense Systems Company, Inc.

Au vess:

11312 S Pipeline Rd., PO Box 155429

Fort Worth, TX 76155

Notes:

Product-oriented research, development, testing and evaluation on

photoelectric shaft position encoders.

James Fogle

Position:

VP

Organization:

Kollmorgen Corporation

Component: Address:

Photo Research 9330 DeSoto Dr.

Chatsworth, CA 91311

Notes:

Optical and electromechanical light measuring devices.

Contact Name:

S. Robert Foley

Position:

VP Marketing and Planning

Organization:

Raythcon Company

Component: Address:

141 Spring Street

Lexington, MA 02173

Notes:

Contact Name:

M.A. Folkard

Position:

Organization:

CMTEK Pty, Ltd

Component:

Address:

P.O. Box 1500

Salisbury 5108, South Australia

Notes:

Co-authored for 1992 MCT Workshop "In-Situ Ellipsometric Measurements of

the MBE Growth of CdTc/HgTe and CdTe/ZnTe Superlattices"

Contact Name:

John Ford

Position:

Public Relations Manager

Organization:

GEC Ferranti

Component:

Address:

Ferry Road

,

Edinburgh, Scotland EH5 2XS

Notes:

Night vision, detectors and sensors, active and passive eo systems for military

applications.

Leann M. Forister

Position:

Ms

Organization:

EnTech Engineering, Inc.

Component:

Address: 111 Marine Lane

St. Louis, MO 63146

Notes:

Active in infrared remote sensing, having devised the IR/GPR technique.

Contact Name:

Position:

E.R. Fossum

Organization:

Columbia University

Component:

Address:

New York, NY

Notes:

Co-authored for 1990 SPIE workshop on IR Detectors "GaAs CCD Readout

for Engineered Bandgap Detectors"

Contact Name:

Position:

Tom Fournier

Organization:

President

Dynatech Corporation

Component: Address:

Sensors, Inc. 6812 S State Rd

Saline MI 48176

Notes:

Commercial uses for infrared technology, infrared gas analysis, zirconia oxygen

analyzer on OEM basis

Contact Name:

David Fraser

Position:

Pres

Organization:

Fraser-Volpe Corporation

Component:

Address:

Warminster Industrial Park, 1025 Thomas Or.

Warminster PA 18974

Notes:

Electro-optics and electronic systems; design and development of systems for inspection of fluid-filled vials and other glass containers to detect chips, cracks

and foreign particles, stabilization systems for optical viewing devices,

television and motion picture cameras, laser stabilization.

James Frey

Position:

Pres

Organization: Component:

Litton Industries, Inc. Itek Optical Systems

Address:

10 Maguire Rd. Lexington, MA 02173

Notes:

Optics, electro-optics and systems research for image based systems.

Contact Name:

John Fried

Position:

Vice President

Organization: Component:

Batelle Memorial Institute Manufacturing Systems

Address:

505 King Avc.

Columbus OH 43201

Notes:

Assists manufacturing with front-end planning and analysis aimed at increasing

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productivity and quality, reducing cost and improving capacity.

Contact Name:

Marvin Friedman

Position:

Director of Marketing

Organization:

North Atlantic Industries, Inc.

Component:

Address:

60 Plant Avenue

Hauppauge, NY 11788-3890

Notes:

Thermal imaging for military applications.

Contact Name:

Myles Friedman

Position:

Pres MyPres

Organization:

Southwest Engineering

Component:

Address:

714 First National Bank Bldg.

Fort Smith, AR 72901

Notes:

Computer/electronic controls for manufacturing processes, has experimented

with IR detectors.

James Fritz

Position:

Organization:

ISI Group

Component:

211 Conchas SE

Address:

Albuquerque, NM 87123

Notes:

Active in infrared process control development. ISI group manufactures

thermal-imaging TV systems based on pyroelectric vidicon tubes.

Contact Name:

Elizabeth Fuchs

Position:

Organization:

Sandia National Laboratory

Component:

ORG 8246

Address:

P.O. Box 969 Levermore, CA 94551

Notes:

Specialist in NDE thermal imagers. On SPIE's Thermosense steering

committee.

Contact Name:

Elizabeth A. Fuchs

Position:

Ms.

Organization:

Sandia National Labs

Component:

Address: **ORG 3246**

P.O. Box 969

Livermore, CA 94511

Notes: Active in infrared remote sensing system design, using dual-band MWIR and

LWIR IR technology technique.

Contact Name:

Position:

Ken Fujiwara President

Organization:

Epitaxx, Inc.

Component:

Address:

3490 Route 1,

Princeton, NJ 08540

Notes:

Long-wavelength high speed sources and detectors for fiberoptic

communcations (InGaAs photodiodes, 1300 & 1500 nm edge LED and laser diode), large area InGaAs detectors for test and measurement rangefinding. Develops 512 element InGaAs arrays of cutoff wavelengths of 2.6um.

J.K. Furdyna

Position:

Organization:

University of Notre Dame

Component: Address:

Notre Dame, IN 46556

Notes:

On Program Committee of 1992 MCT Workshop

For 1991 Workshop co-authored "Magnetic Generation of Electrons and Holes

in Semimetallic HgTe-CdTe Superlattices"

Contact Name:

Kevin Fynn

Position:

Organization:

University of Western Australia

Component:

Department of Electrical Engineering Nedlands, Perth, Western Australia

Address: Notes:

Attended 1992 MCT Workshop

Contact Name:

M. Gal

Position:

Organization:

University of New South Wales

Component:

School of Physics

Address:

Kensington 2033 AUSTRALIA

Notes:

Co-Authored "In-Situ Ellipsometric Measurements of the MBE Growth of

CdTe/HgTe and CdTe/AnTe Superlattices" for 1992 MCT Workshop

Contact Name:

Dr Tom Galantowicz

Position:

CEO

 ${\bf Organization:}$

Newport Corporation

Component: Address:

18235 Mount Baldy Circle

Fountain Valley, CA 92708

ការប្រាស់ ប្រើបាន

Notes:

Electro-optic and electro-mechanical components and systems for laser optical

applications.

Mosten Gale

Position:

Organization:

SBRC

Component:

Address:

75 Coromar Drive

Goleta, CA 93117

Notes:

Contact Name:

Dr Charles Garber

Position:

Pres

Organization:

Structure Probe

Component:

Address:

569 E Gray St., PO Box 656

West Chester, PA 19381-0656

Notes:

X-ray diffraction and thermal analysis.

Contact Name:

Tony Gardiner

Position:

Pres

Organization:

Osprey Sub-Sea, Inc

Component:

Address:

1225 Stone Dr.

San Marcos, CA 92069

Notes:

Night vision equipment and acoustic tracking systems for military applications.

Contact Name:

Bruce Gardner

Position:

Pres.

Organization:

Janos Technology, Inc.

Component:

Address:

HCR #33, Box 25

Townshead, VT 05353-7702

Notes:

Manufacturer of CdTe, GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications.

James Garner

Position:

Infrared Research, Inc.

Organization: Component:

100 Park City Road

Address:

Roosville, GA 30741
Active in infrared predictive maintenance as a consultant who helps set up

inspection regimes.

Contact Name:

Bill Gary

Position:

Organization:

Vision Harvest

Component:

Address: HCR Box 36

Hatch, NM 87937

Notes:

active in infrared process control

Contact Name:

Charles Gay

Position:

Pres

Organization:

Arco Solar Inc

Component: Address:

4650 Adohr Ln., PO Box 6032

Camarillo, CA 93010

Notes:

Advanced and applied research and development of photovotaic devices and systems. Production continues of square foot panels with Commer Indium Diselenide (CIS) coated with Cadmium Sulfide. CIS is increasingly viewed as

the most promising material for solar power.

Contact Name:

Peter Gaylord

Position: Organization:

Total Vision Photonics

Component:

39 Vaughn Street, Suite 202

Address:

Ottawa, CANADA K1M1W9 active in infrared process control

Notes:

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Contact Name:

Boris Gelmont

Position:

Virginia University

Organization: Component:

Department of Electrical Engineering

Address:

Charlottesville, VA

Notes:

Co-authored May 1992 report "Monte Carlo Simulation of Electron Transport

in HgCdTe"

Contact Name:

R. Gentilman

Position:

Pres.

Organization:

Phase 4 Infrared

Component:

Address:

P.O. Box 2647

Acton, MA 01720

Notes:

Manufacturer of ZnS and ZnSc for infrared applications, both military and

commercial.

Contact Name:

John Gcorg

Position:

Public Relations Manager

Organization:

Litton Corporation

Component:

Address:

1725 Jefferson Davis Highway

Suite 601, Crystal Square Two

Arlington, VA 22203

Notes:

E/o systems, night vision, infrared systems and equipment, detectors & sensors

for military.

Contact Name:

S.K. Ghandhi

Position:

Address:

Organization:

Rensselaer Polytechnic Institute

Component:

110 Eight Street

Troy, NY 12180

Notes:

Co-Chairman along with Loral's P.W. Norton of the 1992 MCT Workshop.

On Program Committee of 1991 MCT Workshop

Co-authored for 1991 WOrkshop "Low Temperature Epitaxy of HgTc, CdTc,

HgCdTc using Flow Modulation Techniques"

David Gilblom

Position:

Address:

Organization:

Sierra Scientific

Component:

605 West California Avenue

Sunnyvale, CA 94086

Notes:

Active in infrared process control. Sierra designs, develops, and manufactures high performance CCD and tube cameras, video display monitors, x-ray image intensifiers and digital angiography subtraction systems. Used for machine vision, robotics, industrial radiology inspection, scientific research, microscopy

and various custom applications.

Contact Name:

Ken Gilkey

Position: Organization:

VP for Marketing Cincinatti Electronics

Component:

Device & Microcircuits Labs Div

Address:

7500 Innovation Way Mason, OH 45040-9699

Notes:

Manufactures and designs IR detectors including single-element, linear and

two dimensional arrays, discrete channel amplified, multiplexed, in Ge, MCT,

InSb and InAs, 1-12 um.

Contact Name:

Bob Gill Position: President

Organization:

Laser Diode Inc.

Component:

Address:

205 Forrest Street

Metuchen, NJ 08840-1292

Notes:

Manufacturer of GaAs and germanium materials for infrared applications.

Contact Name:

John Gillespi

Position:

Address:

Prcs

Organization:

Jodon Engineering

Component:

62 Enterprise Dr.

Ann Arbor, MI 48103

Notes:

Optical engineering for machine vision, interest in IR detectors.

BM Gillespi

Position:

Pres

Organization:

Mobil Oil Corp.

Component:

Mobil Solar Energy Corp.

Address:

4 Suburban Park Dr.

Billerica, MA 01821

Notes:

Solar cell and photovotaic power components and systems development.

Contact Name:

J.E. Gilpin

Position:

Address:

Manger Detector Products

Organization:

Rockwell International Corporation

Component:

Electro-Optical Center

3370 Miraloma Avc. Anahcim, CA 92803

Notes:

Has represented Rockwell EOC's representative in the JM consortium

Contact Name:

S. Gocttig

Position:

Organization: Component:

Wayne State University Department of Physics

Address:

Detroit MI

Notes:

Co-authored 1990 "FOrmation Mechanisms of Interstitial Defect States"

Contact Name:

Mcrivn Goff

Position:

Dr.

Organization:

King's College

Component:

Thermal Biology Unit

Address:

Campden Hill Road, Kensington

London, W8 7AH, UNITED KINGDOM

Notes:

Active in infrared biomedical thermography, widely published. System

designer, longtime researcher.

Martin Goland

Position:

Pres

Organization:

Southwestern Research Institute

Component:

Address: Program Development Office, PO Drawer 28510

San Antonio, TX 78228-0510

Notes:

Infrared research including automation and space research applications.

3

Contact Name:

T.D. Golding

Position:

Organization:

Cambridge University

Component:

Cavendish Lab

Address:

Cambridge, UNITED KINGDOM

Notes:

Co-authored October 1988 "MBE of HgCdTc" available from DTIC. Active in

MCT-based research for military applications.

Contact Name:

T.D. Golding

Position:

Organization:

University of Houston

Component:

Department of Physics and Space Vacuum Epitaxy Center

Address:

Houston, TX 77204

Notes:

Co-authored "Properties of InAs/(Ga,In)Sb Strained Layer Superlattices

Grown on the (111) Orientations" for 1992 MCT Workshop

Contact Name:

E. Goo

Position:

Organization:

University of Southern California

Component:

Department of Materials Science and Engineering

Address:

Los Angeles, CA 90089-0241

Notes:

Co-authored for 1991 MCT Workshop "Ordered Phase in (HgCd)Te Grown by

LPE on CdTe (111)B Substrate"

J.S. Goodling

Position:

Auburn University

Organization: Component:

Address:

Notes:

Co-authored 1988 "Adaptive Welding Using Infrared Sensing Techniques

Manufacturing Processes, Machines and Systems"

Contact Name:

DAVID K. GORDON

Position:

Marketing Director

Organization:

Autometric, Inc.

Component:

Address: 5301 Shawnee Road

Alexandria, VA 22312

Notes:

Active in IR remote sensing. Broad spectrum remote sensing and

reconnaissance systems organization, photogrammetric engineering, image interpretation and analysis, photogrammetric mapping and map-based

information system development

Contact Name:

Lawrence Goshorn

Position:

CEO Iri Vision

Organization:

Component:

Suite D, 6231 Yarrow Dr.

Carlsbad, CA 92009

Notes:

Address:

Product-oriented research of light-based vision systems, interest in IR systems.

Contact Name:

Srini Govindan

Position:

Address:

Dr.

Organization:

Component:

Professional Center 1, Suite 206

Medical Park

Wheeling, WV 26003

Notes:

Doctor in private practice, active in infrared biomedical thermography

Thorsten Graeve

Position:

Organization: Component:

University of Arizona **Optical Sciences Center** Tucson, AZ 85721

Address: Notes:

active in infrared process control

Contact Name:

Position:

Notes:

Thorsten Graeve

Organization:

Component: Address:

University of Arizona **Optical Sciences Center**

Tucson, AZ 85629

Graduate student who oversaw the center's study on the use of infrared spectra reflectances to sort pecans. Believes his technique has many other applications

in food sorting in general

Contact Name:

Richard J. Graf

Position:

Organization:

EnTech Engineering, Inc.

Component: Address:

111 Marine Lane

St, Louis, MO 63146

Notes:

Active in infrared sensing. Designed joint IR/GPR technique.

Contact Name:

F.J. Graham

Position:

Marketing Support Exec

Organization:

GEC Ferranti Defence Systems, Ltd.

Component: Address:

Navigation and Electro Optics Division

Silverknowes, Ferry Road Edinburgh, UK EH4 4AD

Notes:

Infrared systems and equipment, night vision c/o systems for military

applications.

Herbert Gram

Position:

Pres

Organization:

Spectrogram Corp.

Component:

Address:

385 State St.

Notes:

North Haven, CT 06473

General research in the field of electro-optics, with a major effort on

computer-based optical spectrum analysis as applied to analytical systems.

Contact Name:

R. Granger

Position:

Organization:

Lab de Physique des Solides/ INSA

Component:

Address:

FRANCE

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Infrared

Reflectivity: A tool for bond Investigation in II-VI Ternaries"

Contact Name:

R.W. Grant

Position:

Organization:

California Institute of Technology

Component:

Address:

1201 East California Boulevard

Pasadena, CA 91125

Notes:

Reported at the DARPA Program Review on Infrared Focal Plane Array

2 198 E.

a Bigs

. . .

Technology in December, 1992, on "InAs/GalnSb Superlattices: Growth

Involving Anion Switching"

Contact Name:

Steven E. Green

Position:

Organization:

University of Nebraska Center for Electro-Optics

Address:

Component:

Lincoln, NE 68588

Notes:

active in infrared remote sensing

William Greenlaw

Position:

Organization:

Martin Marietta

Component: Address:

103 Chesapeake Park Plaza

Mail point 110

Baltimore, MD 21220

Notes:

Contact Name:

C.H. Grein

Position:

Organization:

Harvard University

Component:

Division of Applied Sciences

Address:

29 Oxford Street

Cambridge, MA 02138

Notes:

Co-Authored "Augur Lifetimes in Ideal InGaSh/InAs Superlattices" for 1992

MCT Workshop.

Contact Name:

DR Kurt Grimm

Position:

Pres

Organization:

Pharm-Eco Laboratorics

Component:

Address:

2355 Chain Dr.

Simi Valley, CA 93065

Notes:

Infrared research, gas chromatography and wet chemical tests.

Contact Name:

Manfred W. Grindel

Position:

President

Organization:

Continental Optical Corp.

Component:

Address:

15 Power Drive

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BLU T

Ha

Hauppauge, NY 11788

Notes:

Manufacturer of silicon, ZnS, and ZnSe infrared materials for both military...

and commercial markets.

Ann Grizzel

Position:

Manager, Pubilc Relations Westinghouse Electric Corp.

Organization: Component:

Electronics Systems Division

Address:

P.O. Box 17319

MS A255

Baltimore, MD 21203-6812

Notes:

Infrared systems and equipment, detectors and sensors, c/o systems

Contact Name:

K. Groom

Position:

Organization:

Auburn University

Component:

Address:

Notes:

Co-authored 1988 "Adaptive Welding Using Infrared Sensing Techniques

Manufacturing Processes, Machines and Systems"

Contact Name:

Paul Grover

Position:

Organization:

Infraspection Institute

Component:

Address:

1971 Shelburne Road, Suite C

Shelburne, VT 05482

Notes:

Active in infrared predictive maintenance as a training and information

dissemination and trade society for thermographers.

Contact Name:

George Guilbalt

Position:

President

Organization:

Universal Sensors, Inc.

Component:

Address:

Suite D, 5258 Veterans Blvd.

Metairie, LA 70006

Notes:

Development of advanced biosensors and immunosensors for medical

applications.

Xu Guo-Sen

Position:

Organization:

Shanghai Institute of Technical Physics

Component:

Acadmia Sinica

Address:

Shanghai, 200081 CHINA

Notes:

Co-authored for 1992 SPIE conference on IRFPAs "The Dependence of Fermi

Level of HgCdTe on Impurity Concentration and Temperature*

Contact Name:

Position:

Xu Guosen

Organization:

Shanghai Institute of Technical Physics

Component:

Academia Sinica China 200083

Address: Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "The Effect of Shockley-Read

Recombination on Minority Carrier Lifetime of HgCdTe"

Contact Name:

Position:

Xu Guoxen

Organization:

Shanghai Institute of Technical Physics

Component: Address:

Academia Sinica Shanghai, CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Study of the Recombination

Mechanisms and Carrier Lifetimes in HgCdTe Alloy"

Contact Name:

Robert Guyton

Position:

Pres

Organization:

Universal Technology Corp.

Component: Address:

4031 Colonel Glenn Hwy.

Dayton, OH 45431

Notes:

Development of advanced manufacturing technologies for metal working and

. 50

electronic research and development.

ribom r

Omer Hageniers

Position:

Pres

Organization:

Difracto Ltd.

Component:

Address:

2835 Kew Dr.

Notes:

Research in vision sensors and gas lasers for measuring purposes for industry.

Contact Name:

Yubong Hahn

Position:

Pres

Organization:

Rocky Mountain Instrument Co.

Component:

Address:

1501S Sunset St.

Longmont, CO, 80501

Windsor, ON N8T 3B7

Notes:

Manufacture of precision optical components and multilayer thin film coatings.

Contact Name:

Robert G. Hammaker

Position:

Organization:

Electric Power Research Institute

Component:

Address:

3 Industrial Highway

Eddystone, PA 19022

Notes:

Active in infrared predictive maintenance, activist among electric power utilities with inspecito of overhead power lines as well as plant equipment.

Contact Name:

Position:

Albert E. Hammett

Organization:

Southern Nuclear Operating Center

Component:

Address:

40 Inverness Center Parkway

Birmingham, AL 35242

Notes:

Active in infrared predictive maintenance. Set up Southern nuclear's

inspection regime, purchased their equipment.

P.H. Handel

Position:

Organization:

Minnesota University

Component:

Department of Electrical Engineering

Address:

Minneapolis, MN

Notes:

Co-authored August 1991 "Quantum Noise in Solid-State Devices in Particular

HgCdTe Diodes"

Contact Name:

William Hanley

Position:

CEO

Organization:

Galileo Electro-Optics Corp.

Component:

Galileo Park, PO Box 550

Address:

Sturbridge, MA 01566

Notes:

Develops fiber-optic and electro-optic components which transmit, intensify or

sense light images.

Contact Name:

Timothy Hannemann

Position:

VP

Organization:

TRW Inc

Component: Address:

TRW Electronic Systems Group E Bldg., Rm 5076, One Space Park

Redondo Beach, CA 90278

Notes:

Development of advanced infrared sensor technologies.

Contact Name:

Position:

Walter Hanser

Marketing Director

Organization:

Buck Werke GMBH & Co.

Component:

Address:

Hans-Buck-Strasse 1

D-7844 Neuenburg, GERMANY

07631

Notes:

Services, Infrared Systems and Equipment for military markets.

Yuan Haoxin

Position:

Organization:

Shanghai Institute of Technical Physics

Component: Address:

Chinese Academy of Sciences Shanghai, 20092 CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "HgCdTe Photovoltaic

è

Detectors and Some Related Aspects"

Contact Name:

Position:

Larry Hardin President

Organization:

Hardin Optical Company

Component:

Address:

P.O. Box 219

1320 Oregon Avenue Bandon, OR 97411

Notes:

Manufacture of GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications, commercial and military.

Contact Name:

Position:

E.T. Harlmagean

Organization:

Component:

R&D Institute for Semiconductor Devices

Address:

ROMANIA

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Accurate

Method for Neutraon Fluence Control Used in Improving Neutron-

Transmutation-Doped Silicon Detectors"

Contact Name:

Thomas Harris

Position:

Pres

Organization:

Optical Research Associates

Component: Address:

550 N Rosemead Blvd. Pasadena, CA 91107

Notes:

Research in optical design engineering, some for IR detectors.

R.H. Hartley

Position:

Address:

Surveillance Research Laboratory

Organization: Component:

DSTO

O.I. Bix 1500

Salisbury, South Australia, 5108 Notes:

Co-authored for 1991 MCT Workshop "Real Time Control of the MBE Growth of CdHgTe and CdTe/GhTe Superlattices Using Ellipsometry"

Contact Name:

Christopher Harz

Position:

VP Mkt.

Organization:

Perceptronics Incorporated

Component: Address:

21135 Erwin Street

Woodland Hills, CA 91365-4198

Notes:

Has been awarded several government contracts to conduct research and development of computer aided manufacturing processes for IRFPAs.

Contact Name:

J Hassan

Position:

Vice President for Technology

Organization:

AMP Incorporated

Component:

AMP Technology, Electro-optics Division

Address:

PO Box 3608

Harrisburg, PA 17105-3608

Notes:

Applied and product-oriented research and development on fiber optic,

electro-optic, passive, and interconnection devices.

Contact Name:

George Hatsopoulos

Position:

Pres

Organization:

Thermo Electron Corp.

Component:

Address:

101 First Avc.,

Waltham, MA 02254

Notes:

Production of optics, electro-optics, electro-acoustic systems.

Patsy Hattox

Position: Organization: Vice President Nichols Research Corp.

Component:

Component: Address:

4040 South Memorial Parkway

Huntsville, AL 35802

Notes:

Infrared systems and equipment, imaging software for military markets.

Contact Name:

Greg Haug

Position:

Organization:

Compaq Computer

Component:

Address:

P.O. Box 692000

Houston, TX 77269-2000

Notes:

Set up infrared inspection regime for compaq's computer chips and IC boards

Contact Name:

Robert Haugh

Position:

Pres

Organization:

Overhead Door Corp

Component:

Horton Automatics Division

Address:

1900 Crown Dr.

Farmers Branch, TX 75234

Notes:

Applied research on pneumatics, electrical and fluidic technology, door-andwindow automation and associated sensing devices, microwave and infrared

sensing technology.

Contact Name:

Shahram Hcjazi

Position:

Dr.

Organization:

Eastman Kodak Company Health Sciences Division

Component:

100 Carlson Road

Address:

Rochester, NY 14653-9015

Notes:

Formerly at SUNY Buffalo, where he patented a multi-band IR biomedical

thermography instrument.

Shahram Hejazi Senior Engineer

Position: Organization:

Eastman Kodak, Inc. Health Sciences Division

Component: Address:

100 Carlson Road

Rochester, NY 14653-9015

Notes:

Doctoral research discussed in Nov. 92 OE article on using thermal imagers,

MCT-based, at multiwavelengths, to determine skin temperature.

Contact Name:

Donald Heller

Position:

Sales and Marketing

Organization:

Agema Infrared Systems

Component:

142 Sunsct Avenue Address:

Verona, NJ 07044

Notes:

Active in infrared predictive maintenance application development at Agema

Contact Name:

C.R. Helms

Position:

Organization:

Stanford University Solid State Lab

Component:

McCulloufh 114

Address:

Notes:

Stanford, CA 94305 On Program Committee of 1992 MCT Workshop, Co-Chairman of 1991 MCT

WOrkshop. For 1991 Workshop, co-authored "Thermodynamic Description of metal

Hg(Cd)Tc Systems"

Contact Name:

alan Henry

Position:

Gmgr

Organization:

Harris Corporation

Component:

Government Communications Systems Division

Address:

256 SE Palm Bay Rd., PO Box 9100

Melbourne, FL 32902

Notes:

Satellite and terrestrial communications, electro-optics, imagery and voice

privacy systems for military.

Gregg Herbison

Position:

National Sales Manager

Organization:

Thomson Components & Tubes Corp

Component:

TCS Division

Address:

40 G Commerce Eay Totowa, NJ 07511

Notes:

Infrared systems and equipment, GaAs gate arrays, detectors & sensors

Contact Name:

Mathew Heric

Position:

Autometric, Inc.

Organization: Component:

Address: 5301 Shawnee Road

Alexandria, VA 22312

Notes:

Also active in IR remote sensing research and system design

Contact Name:

F.P. Hermann

Position:

Corp. Foreign Press and Adv. Mgr.

Organization:

Israel Aircraft Industries, Ltd.

Component:

Address: Ben-Gurion International Airport

Israel 70100

Notes:

Passive and active e/o components, detectors and sensors, infrared systems and

equipment for military applications.

Contact Name:

Theresa Herpst

Position:

Organization:

International Crystal Laboratories

Component:

Address:

11 Eric St. 41.

Garfield, NJ 07026

Notes:

Applied research for growing crystals for infrared transmission.

N. Hess

Position:

Organization: Component:

Dresden University of Technology Institut für Festkorperelektronik

Address:

Dresden, FEDERAL REPUBLIC OF GERMANY

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Pyroelectric

}

Linear Array IR Detectors with CCD Multiplexer"

Contact Name:

F. Hicks Position:

Organization:

University of California, Los Angeles Department of Chemical Engineering

Component: Address:

Los Angeles, CA 90024-1592

Notes:

Co-authored for 1991 MCT Workshop "Photoassisted Organometallic VPE on

CdTc"

Contact Name:

A. Ray Hilton

Position:

President

Organization:

Amorphous Materials Inc.

Component:

Address:

3130 Benton Street

Garland, TX 75042

Notes:

Infrared materials production of CdTe, GaAs, and silicon, mainly for military.

Contact Name:

Bruce Hinman

Position:

Dir. Business Development and Contracts

Organization:

Spar Aerospace, Ltd. **Applied Systems Group**

Component: Address:

365 March Road

Kanata, Ontario, CANADA K2K 1X3

Notes:

E.o systems, infrared systems & equipment, night vision for military

applications.

LaVerne Hinsen

Sales Manager Fermionics Corp.

Organization: Component:

Address:

Position:

4555 Runway Street

Simi Valley, CA 93063

Notes:

Contact Name:

Position:

Paul Hitchen

Marketing Comm. Mgr.

Organization:

Raytheon Submarine Signal Division

Component:

Address:

1847 West Main Road

Portsmouth, RI 02871

Notes:

Thermal imaging, detectors and sensors for military applications.

Contact Name:

Position:

G. Hofmann

Organization:

Component:

Dresden University of Technology Institut für Festkorperelektronik

Address:

Dresden, FEDERAL REPUBLIC OF GERMANY

Notes:

Co-authored for 1992 SPIE IRFPA meeting "Pyroelectric IR Single-Element

Detectors and Arrays Based on LiNbO3 and LiTaO3"

Co-authored for 1991 SPIE meeting on Growth of IR materials "Pyroelectric

Linear Array IR Detectors with CCD Multiplexer"

Contact Name:

D.K. Hohnke

Position:

Organization:

Ford Motor Company

Component:

Scientific Research Laboratory

Address:

Room S-2308

P.O. Box 2053

CONTACTOR

Notes:

Dearborn, MI 48121-2053

Interested in designing IR inspection system to nondestructively test paint delaminations in cars

Position:

Organization:

David Holland Managing Director Davin Optical, Ltd.

Component:

Address:

9A Chester Road

Borehamwood, Herts, UK WD6 1LD

Notes:

Night Vision, EO Systems, Infrared Systems and Equipment, Thermal Imaging

for military applications

Contact Name:

M. Hollander

Position:

National Sales Manager

Organization:

Atomergic Chemetals Corporation

Component:

Address:

222 Sherwood Avenue

Farmingdale, NY 11735

Notes:

Material processing of CdTe, GaAs, Germanium, Silicon, ZnS, and ZnSe, predominantly for military markets. For commercial markets, basic and applied research involving inorganic chemistry, rare elecments and ultra-purity metals and chemicals, spherical and submicron powders, single crystald, electronic and solid state materials, hotpressed ceramics, stable isotopes

deuterated compounds, liquid crystals, pharmaceuticals, etc.

Contact Name:

Dag Holmsten

Position:

Organization:

Total Vision Photonics, Inc.

Component:

Address:

39 Vaughn Street, Suite 202 Ottowa, CANADA K1M1W9

Notes:

active in infrared process control

Contact Name:

Ludwig Holtermann

Position:

owner

Organization:

Concept Engineering

Component:

Address:

43 Ragged Rock Rd.

Old Saybrook, CT 06475

Notes:

Manufactures optical tset and measurement equipment including IR

thermoemters, radiant fluxmeters, and solar radiometers/ photometers. IR-

technology sensor and detector development.

Alexander Horvath General Manager

Organization:

General Electric Company

Component:

Aerospace Electronics Systems Department

Address:

Position:

French Rd.

Utica, NY 13503

Notes:

Research into pattern recognition, using IR detectors.

Contact Name:

Warren Howell

Position:

Dvmgr

Organization:

Bio-Rad Laboratories, Inc.

Component:

Digitab Division 237 Putnam Avc.

Cambridge, MA 02139

Notes:

Address:

Product-oriented research in applications for existing technology in new fields

including Transform-Infrared spectroscopy, gas chromatography and infrared

technology.

Contact Name:

Patricia A. Howell

Position:

Ms.

Organization:

NASA, Langley Research Center

Component:

Analytical Services and Manufacturing, Inc.

Address:

c/o MS 231

Hampton, VA 23665

Notes:

Infrared non-destructive evaluation, mainly for aging aircraft skins and

advanced composites.

Contact Name:

Kuo-Tung Hsu

Position:

Organization:

Chung-Shan Institute of Science and Technology

Component:

Lung-Tan, Taiwan, REPUBLIC OF CHINA

Address: Notes:

Co-authored for 1992 SPIE IRFPA meeting "Electrolyte Electroreflectance

Spectroscopies for the Ion-Implanted HgCdTe with Thermal Annealing"

Position:

Kuo-Tung Hsu

Organization: Component:

National Taiwan University

Address:

Department of Electrial Engineering Taipei, Taiwan, REPUBLIC OF CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Electrolyte Electroreflectance

Ì

Specrtoscopies for the Ion-Implanted HgCdTe with Thermal Annealing*

Contact Name:

Position:

Chao Huang

Organization:

Component:

Tsing-Hua University Material Center

Address:

101, Sec 2 Kunag-Rd.

Hsingchu, Taiwan, ROC

Notes:

Contact Name:

Position:

Organization:

Component:

Address:

Jack Hubbard

Dr.

University of Minnesota School of Medecine

Minneapolis Clinic of Neurology 305 East Nichola Boulevard

Ridgeview Medical Bldg, Suite 185

Burnesville, MN 55337

Notes:

active in infrared biomedical thermography

Contact Name:

Position:

Organization:

Frank Huerta

SBRC

Component:

Address:

75 Coromar Drive Goleta, CA 93117

Notes:

9,40.3 417 3

John Hughes

Position:

Dr.

Organization: Component: Clinical Research Centre Division of Rheumatology Watford Road, Harrow,

Address:

UNITED KINGDOM

Notes:

Active in use of infrared biomedical thermography for arthritis and

rheumatism.

Contact Name:

William C. Hughes

Position:

Organization:

University of North Carolina at Chapel Hill

Component: Address:

Department of Physics and Astronomy

Phillips Hall, CB #3255 Chapel Hill, NC 27599-3255

Notes:

Co-Authored "Observation of Indium-Vacancy and Indium Hydrogen

Interactions in (HgCd)Te Using PAC"

Contact Name:

Paul Hughett

Position:

Organization:

Hughett Research

Component:

Address:

2110 Ccdar Street #B

Berkeley, CA 94709-1515

Notes:

Active in infrared predictive maintenance regime design.

Contact Name:

Position:

Donald Hutchinson Marketing Director Tau Corporation

Organization: Component:

Address: Los Gatos, CA

Notes:

Ronald Huynh

Position:

Pres

Organization:

Advanced Kinetics

Component:

Unit 108, 18281 Gothard St.

Address:

Huntington Beach, CA 92648

Notes:

Research in laser physics and applications, including IR sources (black bodies).

Ì

Contact Name:

Dr. M.Y. Hwang

Position:

Ch. Sci

Organization:

JTT International Inc.

Component:

Address:

3045 Technology Pkwy

Orlando, FL 32826

Notes:

Manufacturer of germanium, silicon, ZnS, and ZnSe infrared systems.

Contact Name:

Anthony Charles Ibbott

Position:

Address:

Organization:

California Institute of Technology

Component:

Jet Propulsion Laboratory 4800 Oak Grove Drive

Pasadena, CA 91109-8099

Notes:

Designed airborne fire monitoring system for JPL

Contact Name:

Position:

Anthony C. Ibbott

Organization:

: California Institute of Technology

Component:

Jet Propulsion Laboratory 4800 Oak Grove Drive

Address: 4800 Oak Grove Drive Pasadena, CA 91109-8099

Notes:

active in infrared remote sensing

K. Irani

Position:

Organization:

Mikron Instruments

Component:

Address: 445 W. Main Strect

Wyckoff, NJ 07481

Notes:

Manufactures and markets non-contact infrared temperature measurement and control systems, portable infrared thermometers, thermal imaging systems, temperature sensors for OEM applications and black body calibration sources.

Contact Name:

Bernard J. Isker III

Position:

Organization:

Hughes Aircraft Company

Component: Address:

Technology Center 6155 El Camino Real Carlsbad, CA 92009

Notes:

Authored for 1992 SPIE Workshop on IRFPAs "Cryoprober Test

Development*

Contact Name:

Anthony Jacobini

Position:

VP Mfg

Organization:

International Crystal Laboratories

Component:

Address:

11 Eric St.

Garfield, NJ 07026

Notes:

Manufacture of CdTe, GaAs, germanium, silicon, ZnS, and ZnSe for infrared

products.

Contact Name:

Doug James Systems Engineer

Position: Organization:

Kollmorgen Corp.

Component:

Address:

347 King Street

Northampton, MA 01060

Notes:

Detectors and sensors, infrared systems and equipment, night vision for

military applications.

James Jamieson

Position:

President

Organization:

Jamieson Science and Engineering

Component:

Address:

7315 Wisconsin Avenue, Suite 447W

Washington, DC 20814

Notes:

Advocate of MCT being able to overcome cost barriers to break into commercial market. Long history of involvement in IR since advent.

Contact Name:

Gwo-Jen Jan

Position:

Organization:

National Taiwan University

Component:

Department of Electrial Engineering Taipei, Taiwan, REPUBLIC OF CHINA

Address: Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Electrolyte Eletroreflectance

Specrtoscopies for the Ion-Implanted HgCdTe with Thermal Annealing"

Contact Name:

P. Tom Jenkins

Position:

General Manager

Organization:

DALSA Inc, CCD Image Sensors

Component:

Address:

605 McMurray Road

Waterloo, Ontario CANADA N2V 2E9

Notes:

Specializes in manufacture, design, research and development of high performance, solid-state CCD image sensors and cameras. has a standard product line of 35 different CCD image sensors and 75 models of CCD imaging cameras, and actively pursues custom contracts and strategic alliances

for CCD technology development.

Contact Name:

John Jenkofsky

Position:

Gmgr

Organization:

Irtronics Instruments, Inc.

Component:

Address:

132 Forest Blvd.

Ardsley, NY 10502

Notes:

Standard and custom infrared radiation pyrometers for measuring temperature

in industrial research applications.

Geir U. Jensen

Position:

Organization:

Virginia University

Component:

Department of Electrical Engineering

Address:

Charlottesville, VA

Notes:

Co-authored May 1992 report "Monte Carlo Simulation of Electron Transport

in HgCdTe"

Contact Name:

Arthur S. Jensen

Position:

Organization:

Westinghouse Corp.

Component:

Advanced Technology Division

Address:

Baltimore, MD 21203

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Superconductive Circuits for

On-FPA IR Digital Signal Processing"

Contact Name:

Fang Jia-Xiong

Position:

Organization:

Shanghai Institute of Technical Physics

Component:

Academia Sinica

Address:

Shanghai, 200081 CHINA

Notes:

Co-authored for 1992 SPIE conference on IRFPAs "The Dependence of Fermi

Level of HgCdTe on Impurity Concentration and Temperature"

Contact Name:

Fang Jiaxiong

Position: Organization:

Shanghai Institute of Technical Physics

Component:

Academia Sinica Shanghai, CHINA

Address: Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Study of the Recombination

Mechanisms and Carrier Lifetimes in HgCdTc Alloy"

Fang Jiaxong

Position:

Shanghai Institute of Technical Physics

Organization: Component:

Academia Sinica

Address:

Shanghai, China 200083

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "The Effect of Shockley-Read

}

Recombination on Minority Carrier LIfetime of HgCdTe"

Contact Name:

Jorge Jimenez

Position:

Organization: Tu

Tufts University

Component:

Electro-Optics Technology Center

Address:

Mcdford, MA 02155

Notes:

Co-authored for 1992 meeting of SPIE on IRFPAs "Fundamental Studies of Schottky Barrier IR Detectors by Ballistic Electron Emission Microscopy"

Contact Name:

Yan Jing-Xuan

Position:

Organization:

Qingdao University

Component:

Department of Computer and Information Science

Address:

Qingdao, Shandong, CHINA

Notes:

Co-authored for 1992 SPIE conference on IRFPAs "The Dependence of Fermi

Level of HgCdTe on Impurity Concentration and Temperature"

Contact Name:

Position:

Yan Jingxuan

Organization:

Qingdao University

Component:

Department of Computer and Information Science

Address:

266071 Qingdao, Shandong, CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Study of the Recombination

Mechanisms and Carrier Lifetimes in HgCdTe Alloy"

Raymond Johnson General Manager

Position: Organization:

General Electric Company

Component:

Aircraft Controls Systems Department

Address:

PO Box 5000

.

Binghamton, NY 13902

Notes:

Research and development of sensing and sensors, in part with IR detectors.

Ì

Contact Name:

Position:

B.R. Johnson

Organization:

Honeywell Corp.

Component:

Sensor and System Development Center

Address:

10701 Lyndale Avenue South Bloomington, MN 55420

Notes:

Co-authored for 1992 SPIE Workshop on IRFPAs "YBa2Cu3O7

Superconducting Microbolometer Linear Arrays" supported by DARPA with

Office of Naval Research as contracting agency.

Contact Name:

Carl Johnson

Position:

President and CEO

Organization:

II-VI Inc.

Component:

Address:

375 Saxonburg Blvd

Saxonburg, PA 16056

Notes:

Manufacture of CdTe, GaAs, germanium, silicon, ZnS, ZnSe for infrared

applications.

Contact Name:

Jim Johnson

Position:

Dir. Commercial Products

Organization:

Loral Fairchild Imaging Sensors

Component:

Address:

1801 McCarthy Boulevard

Milpitas, CA 95035

Notes:

Detectors and sensors, c/o systems, infrared systems & equipment,

predominantly for military.

C. Barbara Johnson Division Administrator

Position: Organization:

Raytheon Co.

Component:

Electromagnetic Systems Div.

Address:

6380 Hollister Avenue

Goleta, CA 93117

Notes:

Detectors & sensors, e/o systems, infrared systems & equipment

Contact Name:

R.B. Johnson

Position:

Organization:

University of Maryland

Component:

Address: College Park, MD

Notes:

Co-authored 1987 study "Phase Differences between Wuantum Oscillations of

Ì

the Magnetoresistance and the Hall Effect in HgMnTe and HgCdTe⁻

Contact Name:

Rose Jones

Position:

Pres

Organization:

Muffoletto Optical Company, Inc

Component:

Address:

6100 Everall Avc.

Baltimore, MD 21206

Notes:

Design and development of optical systems for underwater, laboratory and

space applications.

Contact Name:

Pat Jones

Position:

Sales Manager

Organization:

Preh Electronic Inc.

Component:

Address:

470 E. Main

Lake Zurich, IL 60047

Notes:

Infrared systems & equipment for military applications.

A.M. Joshi

Position:

Organization:

EPITAXX, Inx.

Component: Address:

3490 U.S. Route One

Princeton, NJ 08540

Notes:

Co-authored for 1992 SPIE Workshop on IRFPAs "Popcorn Noise in Linear InGaAs Detector Arrays" Firm manufactures long-wavelength high speed

sources and detectors for fiveroptic communications, esp. InGaAs.

Contact Name:

Shan Joshi

Position:

Pres

Organization:

Universal Energy Systems

Component:

Address:

4401 Dayton-Xenia Rd.

Dayton, OH 45432

Notes:

Development and application of laser and electro-optic systems.

Contact Name:

Position:

Feng-Yuh Juang

Organization:

Component:

Chung-Shan Institute of Science and Technology

Address:

Lung-Tan, Taiwan, REPUBLIC OF CHINA

Notes:

Co-authored for 1992 SPIE IRFPA meeting "Electrolyte Electroreflectance Spectroscopies for the Ion-Implanted HgCdTe with Thermal Annealing"

Contact Name:

Suc Justice

EG&G, Inc.

Position:

Marketing Director

Organization: Component:

EG&G Judson

Address:

221 Commerce Dr.

Notes:

Montgomeryville, PA 18936

Manufactures infrared detectors and arrays including Ge, InAs, InSb, MCT,

and doped Ge

David Kales

Position:

Senior Editor, Markets Laser Focus World

Organization: Component:

Address:

One Technology Park Drive

P.O. Box 989

Westford, MA 01886

Notes:

Wrote November 1992 article "Detector Makers Seek Dual-Use Technology

Ì

for Survival." Friends with David Leech.

Contact Name:

Alex Kalil Position:

Organization:

Pres Silonex Inc Silonex, Inc

Component: Address:

2150 Ward St. Montreal CANADA PQ H4M 1T7

Notes:

Optoclectronics automation of manufacturing. Includes CdS photoconductive cells, optoisolators, LEDs, photodiodes and photodiode arrays, photovoltaic

cells, photransistors and photodarlingtons.

Contact Name:

Position:

Herbert Kaplan President

Organization:

Honeyhill Technical Corporation

Component:

Address:

193 East Avenue

Norwalk, CT 06855

Notes:

Contributing editor to Photonics Spectra, consultant in IR business, longtime

SPIE leader of Thermosense meetings. Teaches courses for predictive

maintenance engineers.

Contact Name:

Ronald Kappler

Position:

Pres.

Organization:

Kappler Crystal Optics Inc.

Component: Address:

1244 Highland Street Holliston, MA 01746

Notes:

Manufacturer of ZnS and ZnSe for infrared applications.

N.H. Karam

Position:

Organization:

Spire Corporation

Component:

Address:

Notes:

Bedford, MA 01730

Co-authored for 1991 MCT Workshop "Low Temerpature Epitaxy on HgTe,

CdTe, and HgCdTe Using Flow Modulation Techniques*

Contact Name:

James P. Karins

Position:

Organization:

Mission Research Corporation

Component: Address:

735 State Street

Santa Barbara, CA 93102

Notes:

Authored for 1992 SPIE workshop on IRFPAs "Models of Nonlinearities in

Focal Plane Arrays"

Contact Name:

Dr Eskil Karlson

Position:

Dir

Organization:

Life Support, Inc.

Component:

Address:

2926 State St.

Eric, PA 16509

Notes:

Optical system design including IR detection and systems for both military and

commercial markets.

Contact Name:

Position:

John Kasprazak Marketing Director

Organization:

Brimrose Corporation of America

Component:
Address:

5020 Campbell Blvd

Baltimore, MD 21236

Notes:

Manufactures custom acousto-optic tunable filters, acousto-optic modulators

and scanners, RF driver, and mercury manganese telluride infrared detectors.

Provides to military and industry.

Timo Kaupinnen

Position:

Organization:

Technical Research Center of Finland

Component:

Building Laboratory

Address:

P.O. Box 167

SF-90101 Oulu, FINLAND

Notes:

infrared non-destructive evaluation

Contact Name:

Kenneth Kaylor

Position:

COO ATD, Inc.

Organization: Component:

Advanced Technology Division

Address:

PO Box 566

Woodinville, WA 90872

Notes:

Applied R&D of video instrument systems including high-speed, IR

microscopic and related research.

Contact Name:

Michael Kecbaugh

Position:

Prcs

Organization: Component:

E-Systems, Inc. HRB Systems, Inc 300 Science Park Rd.

Address:

State College, PA 16804

Notes:

Integration of sensors into systems capable of military surveillance missions.

Contact Name:

David Kennedy

Position:

Marketing Manager

Organization:

Optotex, Ltd.

Component: Address:

62 Stencie Drive

Kanata, Ontario, CANADA K2K 2A9

Notes:

GaAs gate arrays, infrared systems and equipment, rf systems and components

A. Kepten

Position:

Organization:

Semi-conductor Devices, Inc.

Component:

Address: D.N. Misgav

20179 ISRAEL

Notes: Co-authored for 1992 SPIE Workshop on IRFPAs "p-Channel MIS Double-

Metal Process InSb Monolithic Unit Cell for Infrared Imaging"

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Contact Name:

W.D. Kerns

Position:

Organization: Johns Hopkins University

Component:

Center for NDE and Applied Physics Laboratory

Address:

Laurel, MD 20723

Notes:

infrared non-destructive evaluation

Contact Name:

Lawrence Kessler

Position:

Pres

Organization:

Diversified Optical Products

Component:

Address:

282 Main St.

Salem, NH 03079

Notes:

Automated IR and visible automated MTF testing.

Contact Name:

David J. Kettler

Position:

Organization: Indiana State University

Component:

Department of Geography and Geology

Address:

Terre Haute, IN 47809

Notes:

Active in infrared remote sensing for a variety of natural resource assesments.

A.R. Khotanzad

Position:

Organization:

Southern Methodist University

Component:

Address:

Notes:

Co-authored for 1992 SPIE meeting on Machine Vision "Automated Vision

3

System for INspection of Wedge Bonds"

Contact Name:

Edward Kielty

Position:

Organization:

Sogem-Afrimet Inc.

Component:

Address:

1212 Avenue of the Americas

New York, NY 10036

Notes:

Manufacturer of germanium for infrared applications.

Contact Name:

Position:

Ryoichi Kikuchi

Organization: Washington University

Component:

Department of Materials Science and Engineering

Address:

Scattle, WA

Notes:

Authored February 1988 study "Migration and Stability of HgCdTe Lattice

Defects"

Contact Name:

Sun Ung Kim

Position:

Organization:

Korea University

Component: Address:

Chong Am Dong

Sung-Buk-Ku

Scoul, KOREA 11136-701

Notes:

Attended 1992 MCT Workshop, a materials researcher.

Ki-Sang Kim

Position:

Organization: Virginia University

Component:

Department of Electrical Engineering

Address:

Charlottesville, VA

Notes:

Co-authored May 1992 report "Monte Carlo Simulation of Electon Transport

in HgCdTe"

Contact Name:

Toh Kim-Huat

Position: Organization: V.P./ General Manager CEI Technologies, PTE Ltd.

Component:

Address:

249 Jalan Boon Lay

Singapore 2261

Notes:

Thermal imaging, night vision for military markets.

Contact Name:

M.A. Kinch

Position:

Dr.

Organization:

Texas Instruments

Component:

Infrared Materials Laboratory

Address:

POB 655936 MS150 Dallas, TX 75265

Notes:

Head of their IR producibility effort; representative to JM consortium on

producibility

Contact Name:

Tom Kinstle

Position:

Vice President Marketing Martin Marietta Corp.

Organization: Component:

Address:

6801 Rockledge Drive

Bethesda, MD 20817

Notes:

Night vision, infrared systems & equipment for military markets.

R. Klauser

Position:

Organization:

Fraunhofer-Institut für Angewadnte Festkorperphysik

Component:

Address:

Tullastr. 72

D-7800 Freiburg, Germany

Notes:

AUthor of "Characterization of MCT Heterostructures by Thermoelectric

Measurements*

Contact Name:

Leonard Klenerman

Position:

Organization: Component:

Northwick Park Hospital Dept of Orthopaedics

Address:

Watford Road

Notes:

Harrow, UNITED KINGDOM Active in research using infrared biomedical thermography for othopaedic

medicine.

Contact Name:

Position:

Hans Kluge President

Organization:

Automatic Switch Co

Component:

Division of Emerson Electric Co.

Address:

50-60 Hanover Road

Florham Park, NJ 07932

Notes:

Cyrogenic equipment for both commercial and military markets. Also

product-oriented research of electric-power controls and fluid control devices

to automate machinery, equipment, and industrial processes.

Contact Name:

Larry M. Klynn

Position:

Organization: Lockheed Missiles & Space Co., Inc.

Component: Address:

1111 Lockheed Way

Sunnyvale, CA 94088

Notes:

Infrared non-destructive evaluation of thermal profiles for smart missiles and

automatic target recognition systems.

Guy Knockaert

Position:

Technico-commercial Manager

Organization:

Union Miniere

Component: Address:

A. Greinerstraat 14

B-2660 Hoboken-Belgium

Notes:

Contact Name:

F. Koch

Position:

Organization:

Technische Universtat Phsik-Department E-16

Component: Address:

mUNCHEN, d-8046

GERMANY

Notes:

Co-authored for 1991 MCT Workshop "Influece of Resonant Defect States on

3

Subband Structures in HgCdTe"

Contact Name:

Bill Kolander

Position:

Product Marketing Manager

Organization:

Marlow Industries, Inc.

Component:

Address:

10451 Vista Park Road

Dallas, TX 75238-1645

Notes:

Infrared systems & equipment, night vision, detectors and sensors, c/o systems

for military markets.

Contact Name:

L. Kops

Position:

Organization:

McGill University

Component:

Address:

845 Sherbrook St. W.,

Montreal, PQ H3A 2T5

Notes:

Co-authored 1983 "Application of Infrared Radiation Measurements in

XI

Grinding Studies"

Edward Kornstein

Position:

Address:

Pres

Organization:

O R S Automation

Component:

402 Wall St.

Princeton, NJ 08540

Notes:

Controls and guidance directed towards problems in machine vision for

individual use, some work with IR.

Contact Name:

A.W. Koszykowski

Position:

Pres.

Organization:

Laser SOS Limited

Component:

Address:

4B Bartholomew's Walk

Cambridgeshire Bus. Pk., ANgel Drove

Ely, Camb. CB74EAG

Notes:

Manufacture of CdTe, GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications.

Contact Name:

Lester J. Kozlowski

Position:

Dr.

Organization:

Rockwell International Science Center

Component:

Address:

1049 Camino Dos Rios

Thousand Oaks, CA 91360

Notes:

Chief scientist conducting their alternative substrate programs; probably best

connected and longest tenured Rockwell scientist doing IR

Contact Name:

Position:

M.G. Krauss

Organization:

Dresden University of Technology Institut für Festkorperelektronik

Component:

Dresden, FEDERAL REPUBLIC OF GERMANY

Address: Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Pyroelectric

Linear Array IR Detectors with CCD Multiplexer"

Harvey N. Kreisberg

Position:

Director Corporate Development

Organization:

AIL Systems, Inc.

Component:

Address:

Commack Road

Deer Park, NY 11729

Notes:

Manufactures Infrared systems & equipment, alongside RF & Microwave and

other passive and active systems

Contact Name:

Kent Kresa

Position:

CEO

Organization:

Northrop Corporation

Component:

Hawthorne Site 2301 W120th St

Address:

Hawthorne CA 90250-5032

Notes:

Precision inertial sensors and lasers.

Contact Name:

Vikram Krishnamurthy

Position:

Organization:

Stanford University

Component:

Department of Electrical Engineering

Address:

Stanford, CA 94305

Notes:

Co-Authored for 1991 MCT Workshop "Thermodynamic Description of metal

HgCdTe Systems"

Contact Name:

Kenneth Kun

Position:

Pres

Organization:

Syracuse Research Corp.

Component:

Defense Electronics Engineering

Address:

Merrill Ln.

Syracuse, NY 13210

Notes:

Optical and IR systems analysis.

Pao-Kuang Kuo

Position:

Organization:

Wayne State University

Component:

Inst for Manufacturing Research

Address:

Detroit, MI 48202

Notes:

infrared non-destructive evaluation

Contact Name:

Position:

Audra Kurelaitis Sales Manager

Organization:

Oxley, Inc.

Component:

Address:

25 Business Park Drive

P.O. Box 814

Branford, CT 06405

Notes:

E/o systems, night vision, infrared systems & equipment for military

applications.

Contact Name:

Ernest Kussmaul

Position:

Pres

Organization:

Kussmaul Electronics Company, Inc.

Component:

Address:

170 Cherry Ave.

West Sayville, NY 11796

Notes:

R&D of photoelectronic controls, interest in IR detectors.

Contact Name:

R. La Polla

Position: Organization: Marketing Manager Whittaker Electronics

Component:

Address:

1785 Voyager Avenue

Simi Valley, CA 93063-3349

Notes:

infrared systems & equipment

Stan Laband

Position:

Marketing Director Amber Engineering

Organization: Component:

Component: Address:

5756 Stonewood Drive

Goleta, CA 93117

Notes:

Participant in DARPA's IRFPA team and producer of InSb used in medium-

wave infrared systems for both commercial and military systems

Contact Name:

Robert Lacer

Position:

Pres

Organization:

Infrared Scanning, Inc.

Component: Address:

3955 Pleasantdale Rd.

Atlanta, GA 30340

Notes:

Anfrared inspection techniques and applications.

Contact Name:

Position:

R.C. Lacoe

Organization: Component:

The Aerospace Corporation Electronic Technology Center

Address:

P.O. Box 92957

Los Angeles, CA 90009

Notes:

Co-authored for 1992 SPIE workshop on IRFPAs "Modified Wuantum Well

Infrared Photodector Designs for High Temperature and Long Wavelength

Operation"

Contact Name:

Dan Laerfeld

Position:

Marketing Manager

Organization:

Magnavox Electronic Systems Company

Component: Address:

Electro-Optical Systems 46 Industrial Avenue

Mahwah, NJ 07430-2206

Notes:

1916. 100

Joseph Lakowicz

Position:

Organization: University of Maryland

Component: Address:

Medical School Baltimore, MD

Notes:

Speaking at OE/LASE Laser Market '93 seminar on wavelength requirements

for medical diagnostics in the near-infrared spectral regions. The wavelength in such apsplications determines not only which molecules will absorb the

light, but how deeply the light will penetrate biological tissues.

Contact Name:

K.C. Lamb

Position:

Marketing Manager MCP Wafer Technology

Organization: Component:

Address:

Unit 34, Maryland Road, Tongwell, Milton Keynes, Bucks, MK158HJ

UNITED KINGDOM

Notes:

Production of CdTc and GaAs for infrared applications.

Contact Name:

John Lamonica

Position:

President

Organization:

Farmers Investment Company

Component:

Address:

P.O. Box 7

Ahuarita, AZ 85629

Notes:

Invests in technologies which could benefit local farmers. Invested in infrared sorting technique for pecans which shows promise for sorting of many other

sorting technique for pecans which shows promise for so

varieties of fruits and vegetables.

Contact Name:

M.D. Lange

Position: Organization:

University of Illinois at Chicago

Component:

Microphysics Laboratory, Physics Department

Address:

P.O. Box 4348

Chicago, IL 60680

Notes:

For 1991 Workshop, "Current Status of Direct Growth of CdTe and HgCdTe

on Silicon by MBE"

CF Langenhagen

Position:

Pres

Organization:

Williamson Corporation

Component:

Address:

70 Domino Dr., PO Box 1270

Concord, MA 01742

Notes:

R&D of infrared radiometers for temperature measurement and control.

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Contact Name:

Y. Lansari

Position:

Organization:

North Carolina State University

Component: Address:

Department of Physics 6 Cox Hall, M/S 8202

Raleigh, NC 27695-8202

Notes:

Authored "Integrated Heterostructure Devices Based on II-VI Compound

Semiconductors"

Contact Name:

Y. Lansari

Position:

Organization:

North Carolina State University

Component:

Department of Physics Raleigh, NC 27695-8202

Address: Notes:

Authored for 92 MCT workshop "Growth of HgSc and HgCdSc Thin Films

by Molecular Beam Epitaxy"

For 1991 Workshop, authored "Quantum Hall Effect and Schback Modulation

Doping in HgTe-CdTe Heterostructures"

Contact Name:

Ray Larsen

Position:

Director

Organization:

Newport Industrial Glass Inc.

Component:

Address: 2044-C Placentia Avenue

ıbb

Costa Mesa, CA 92627

Notes: Manu

Manufacturer of CdTe, GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications.

Gilbert Larson

Position:

Pres

Organization:

Omnidata International Inc.

Component:

Address:

750 W 200 North, PO Box 3489

Logan, UT 84321

Notes:

Development of environmental and industrial sensors, hardware and software

for data collection systems.

Contact Name:

D.N. Lazarovici

Position:

Organization:

Institute for Atomic Physics

Component:

Address:

ROMANIA

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Accurate

Method for Neutron Fluence Control Used in Improving Neutron-

Transmutation-Doped Silicon Detectors"

Contact Name:

AZ Lazzara

Position:

Pres

Organization:

Scisco Inc

Component:

Address:

6020 Academy, NE PO Box 25446

Albuquerque, NM 87125)

Notes:

Optical sensor data reduction, including some IR work.

Contact Name:

M.B. Lcc

Position:

Organization:

Grumman Corporate Research Center

Component:

Address:

MS A002-26

Bethpage, NY 11714

Notes:

Co-authored for 1992 MCT workshop "White Beam X-ray Synchroton

1100

Topography Analysis of CdTe (111)B Substrates and Epilayers"

E.Y. Lee

Position:

Organization:

Renssalaer Polytechnic Institute

Component:

Physics Department and Center for Integrated Electronics

Address:

110 Eight Street Troy, NY 12180

Notes:

Co-authored for 1992 meeting of SPIE on IRFPAs "Fundamental Studies of

Schottky Barrier IR Detectors by Ballistic Electron Emission Microscopy*

Contact Name:

David Leech

Position:

Organization:

TASC

Component:

Address:

1101 Wilson Boulevard

Arlington, VA 22209

Notes:

Complete study for Air Force on US industrial base for focal plane arrays.

Contact Name:

Dick Leftwich

Position:

Product Manager, Thermal Imaging Sensors

Organization:

Magnavox

Component:

Government and Industrial Electronics

Address:

46 Industrial Avenue

Mahwah, NJ 07430-2206

Notes:

infrared materials and equipment for military use.

Contact Name:

Richard F. Leftwich

Position: Organization: Product Manager, Thermal Imaging Sensors Magnavox Electronic Systems Company

Component:

Electro-Optical Systems 46 Industrial Avenue

Address: 46 la

Mahwah, NJ 07430-2206

Notes:

Robert J. Leonard

Position:

Manager, Business Planning

Organization:

Eastman Kodak Co.

Component:

Government Systems Div.

Address:

1447 St. Paul Street Rochester, NY 14653

Notes:

IR Detectors work, mostly PtSi.

Contact Name:

B.F. Levinc

Position:

Organization:

AT&T Bell Laboratories

Component:

Address:

600 Mountain Avenue

Murray Hill, NJ 07974

Notes:

Contact Name:

M. Levine

Position:

Marketing Manager Honcywell, Inc.

Organization: Component:

Solid State Sensors Group

Address:

830 E. Arapaho Road Richardson, TX 75081

Notes:

Manufactures IR optoelectronic components and assemblies, fiberoptic

18%

components, and modules.

Contact Name:

Jay Lcvy

Position:

Communications Director

Organization:

Agema IR Systems

Component:

Address:

550 County Avenue

Secaucus, NJ 07094

Notes:

Source of printed information about AGEMA

Al Lewis

Position:

Mgr

Organization:

Raytheon Comp.

Component:

Special Microwave Devices Operation

Address:

55 Bearfoot Rd.

Northboro, MA 01532

Notes:

Laser and infrared detectors.

Contact Name:

Al Lewis

Position:

Mgr

Organization:

Raythcon Comp.

Component:

Special Microwave Devices Operation

Address:

55 Bearfoot Rd.

Northboro, MA 01532

Notes:

Laser and infrared detectors.

Contact Name:

Thomas Lewis

Position:

President

Organization:

Silicon Detector Corporation

Component:

Address:

1240 Avenida Acaso

Camarillo, CA 93012-8727

Notes:

Manufactures and distributes stock and custom NIR/IR LEDs, InGaAs, and silicoon photodetectors for a variety of commercial and military applications. Includes single element, bi-cell, quadrant, multi-element arrays, filtered,

position sensors, opti hybrids, custom hybrids, opto assmelbies, fiberoptics, etc.

Contact Name:

Sheng Li

Position:

Dr.

Organization:

University of Florida

Component:

Address:

Notes:

Working in DARPA Produciblity program, reported at Program Review

Meeting in December 1992 on "Novel Grating Coupled III-V Quantum Well

INfrared Photodetectors for FPA Applications"

Sheng S. Li

Position:

University of Florida

Organization: Component:

Department of Electrical Engineering

Address:

Gainesville, FL 32611

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "A Noval Grating Coupled Step-Bound-to-Miniband Transition InGaAs/GaAs/AlGaAs Multiquantum

Well Infrared Photodetector"

Contact Name:

Karl Lisschitz

Position:

Chief Executive

Organization:

GFI Advanced Technologies, Inc.

Component: Address:

112-41 69th Avenue

Forest Hills, NY 113754

Notes:

Manufacture of GaAs, germanium, ZnS, and ZnSe for infrared applications,

both commercial and military.

Contact Name:

T.T. Lin

Position:

Organization:

Auburn University

Component:

Address:

Notes:

Co-authored 1988 "Adaptive Welding Using Infrared Sensing Techniques

Manufacturing Processes, Machines and Systems"

Chung-Shan Institute of Science and Technology

Contact Name:

Jing-Hwa Lin

Position:

sition:

 $g \in I$

Organization:

P.O. Box 90008-8-7, Lung-tan, Tao-Yuan

Component: Address:

REPUBLIC OF CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "A Novel CID Emulator for

InSb Array"

Hao-Hsiung Lin

Position:

Organization: National Taiwan University

Component:

Department of Electrical Engineering

Address:

1, Sec. 4, Roosevelt Road

Notes:

Taipei, TAIWAN, 10764, REPUBLIC OF CHINA Co-authored for 1992 SPIE meeting on IRFPAs "A Novel CID Emulator for

inSb Array"

Contact Name:

Wang Lingjie

Position: Organization:

Huazhong University of Science and Technology

Component: Address:

Wuhan, Hubei 430074 REPUBLIC OF CHINA

Notes:

Authored for 1992 SPIE IRFPA meeting "Optimum Design Model for the

Injection of IRCCD"

Contact Name:

Benkt Linnander

Position:

Address:

Technical Support Director AGEMA Infrared Systems

Organization:

Component:

550 County Avenue

Secaucus, N.J. 07094

Notes:

Develops specific new applications for individual companies using AGEMA's

cameras

Contact Name:

Position:

Roger Little President

Organization:

Address:

Spirc Corp

Component:

One Patriots Park

Bedford, MA 01730

Notes:

Photovoltaics, solar cells, compound, semiconductor thin films, and high

temperature super conductors. Recently opened a new facility in Oman to produce solar cells. Manufacture of CdTe, GaAs, germanium, and silicon for

infrared applications.

Chris L. Littler

Position:

Organization: North Texas State University

Component:

Department of Physics

Address:

Denton, TX

Notes:

Authored July 1990 "Two-Photon Absorption Characterization of HgCdTe"

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Contact Name:

Position:

C.L. Littler

Organization: Component:

University of Nort Texas Department of Physics Denton, TX 76203

Address: Notes:

Co-Authored "Heavily Accumulated Surfaces of MCT Detectors: Theory and

Experiment" for 1992 MCT Workshop.

For 1991 Workshop, "Investigation of Mercury Interstititals in MCT alloys

Using Resonant Impact-Ionization Spectroscopy"

Contact Name:

Jiy-Chen Liu

Position:

Organization:

Chung-Shan Institute of Science and Technology

Component:

Address:

P.O. Box 90008-8-7, Lung-tan, Tao-Yuan

REPUBLIC OF CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "A Novel CID Emulator for

InSb Array"

Contact Name:

B. Liu

Position:

Organization:

University of California, Los Angeles Department of Chemical Engineering

Component: Address:

Los Angeles, CA 90024-1592

Notes:

Co-authored for 1991 MCT Workshop "Photoassisted Organometallic VPE on

CdTc"

Art Lockwood President

Position: Organization:

Amber Engineering

Component:

Anner Engineering

Component: Address:

5756 Thornwood Drive Goleta, CA 93117

Notes:

Contact Name:

Joseph Longo

Position:

VP

Organization:

Rockwell International Corporation

Component:

Science Center

Address:

1049 Camino Do Rios PO Box 1085

Thousand Oaks, CA 91358

Notes:

Basic applied research in electro-optics, including IR systems and equipment.

Contact Name:

Position:

D. Lorans

Organization:

Societe Anonyme de Telecommunications

Component:

Address:

41, rue Cantagrel

75631 Paris, Cedex 13 FRANCE

Notes:

Co-authored for 1992 MCT Workshop "Substrate Issues for Mercury Cadmium

Telluride*

Contact Name:

Dr Paul Lovoi

Position:

Pres

Organization:

Inta

Component:

Address:

2281 Calle De Luna

Santa Clara, CA 95054

Notes:

3-D laser based machine vision systems, interest in IR guidance.

J.R. Lowney

Position:

Organization: National Institute of Standards and Technology

Composient:

Semiconductor Electronics Division

Address: Notes:

Gaithursburg, MD 20899 Co-Authored "Heavily Accumulated Surfaces of MCT Detectors: Theory and

Experiment" for 1992 MCT Workshop.

For 1991 Workshop, "Investigation of Mercury Interstititals in MCT Alloys

Using Resonant Impact-Ionization Spectroscopy"

Contact Name:

Ronald Lucier

Position:

Address:

Organization:

American Risk Management Corp.

Component:

4807 Rockside Road, Ste 500

Cleveland, OH 44131

Notes:

Active in predictive maintenance regimes, especially with nuclear power plants,

as well as infrared non-destructive evaluation.

Contact Name:

Bjornar Lund

Position:

Organization:

Virginia University

Component:

Department of Electrical Engineering

Address:

Charlottesville, VA

Notes:

Co-authored May 1992 report "Monte Carlo Simulation of Electon Transport

in HgCdTe"

Contact Name:

H. Luo

Position:

Organization:

University of Notre Dame Department of Physics Notre Dame, IN 46556

Component: Address:

Notes:

Co-Authored "Staes Confined in the Barriers of Type-III HgTc/CdTc

Superlattices" for 1992 MCT Workshop

J.D. Luttmer

Position:

Organization:

Texas Instruments

Component:

Infrared Devices Laboratory

Address:

Dallas, TX 75265

Notes:

The Microelectronics Manufacturing Science and Technology Progarm at TI is developing a general semiconductor device manufacturing technology for the mid-1990's. Although the program goal is to develop and demonstrate low volume, fast cycle time, cost effective silicon microelectronic manufacturing the

technology also is applicble to MCT, Ga As and other materials.

Contact Name:

Robert Lyle

Position:

Pres

Organization:

Exotech, Inc

Component:

Address:

8502 Dakota Dr.

Gaithersburg, MD 20877

Notes:

Electo-optical and electronic instrumentation

Contact Name:

Ncal A. MacNamara

Position:

Organization:

Southern Nuclear Operating Center

Component:

Address:

40 Inverness Center Parkway

Birmingham, AL 35242

Notes:

Active in infrared predictive maintenance, helped purchase their equipment.

Contact Name:

Position:

J. Mactaggart VP Marketing

Organization:

Hughes Aircrast Company

Component:

Address: 328 Ellen Street

23.00

Midland, Ontari, LAR 2H2, CANADA

Notes:

Position:

Duncan MacVicar Consultant, President MacVicar Associates

Organization: Component:

Address:

1171 Buckingham Drive

Los Altos, VA 94024

Notes:

Offers marketing and management consulting services for domestic and

international high technology industry, including electro-optics. No direct IR

experience, a one man operation.

Contact Name:

Position:

Organization:

McDonnel Douglas Tech Inc.

Component:

Address:

11955 Bajada Road

Bob Madding

San Diego, CA 92128-2023

Notes:

Active in infrared remote sensing. He is a respected authority with an

overview of the market.

Contact Name:

Position:

Robert P. Madding

Organization:

Component:

McDonnell Douglas Technologies, Inc.

Address:

11955 Bajada Road

San Diego, CA 92128-2023

Notes:

Active in infrared predictive maintenance, a respected authority on predictive

maintenance regimes.

Contact Name:

Position:

N.L. Madsen

Organization:

Auburn University

Component:

Address:

Notes:

Co-authored 1984 "Automatic Welding: Infrared Sensors for Process Control

Computer Based Factory Automation"

Michael Magers

Position:

Dirtc

Organization: Component: Address:

Bobbit Laboratories Viggo-Spectramed 1900 Williams Dr. Oxnard, CA 93030

Notes:

Instrumentation and precise measurement using advanced systems, including

ì

infrared sensors.

Contact Name:

DE Maguire

Position:

Prcs

Organization:

Kemet Electronics Corporation

Component:

Address:

2605 Laurens Hwy., PO Box 5928, Greenville, SC 29606

Notes:

Applied research and development on passive electronic components.

Contact Name:

Position:

Organization:

AEG

H. Maicr

Component:

Address:

D-7100 Heilbronn

GERMANY

Notes:

Co-authored for 1991 MCT Workshop "Influence of Resonant Defect States

on Subband Structures in HgCdTc"

Contact Name:

Position:

E. Maldonado

Organization: University of Nort Texas Component: Department of Physics Address: Denton, TX 76203

Notes:

For 1991 Workshop, "Investigation of Mercury Interstititals in MCT alloys

Using Resonant Impact-Ionization Spectroscopy"

R.G. Mani

Position:

Organization:

University of Maryland

Component:

Address: College Park, MD

Notes: Co-authored 1987 study "Magnetophonon Effect in HgCdTe"

Co-authored 1987 study "Phase Differences Between Quantum Oscillations of

ì

the Magnetoresistance and the Hall Effect in HgMnTe and HgCdTe"

Contact Name:

John Marchesono

Position:

President Decilog, Inc.

Organization: Component:

Address: 555 Broad Hollow Rd

Melville, NY 11747-5093

Notes:

Technical support to government and industry in infrared systems and

components.

Contact Name:

Robert P. Marcus

Position:

President

Organization:

RGB Spectrum

Component:

950 Marine Village Parkway

Alameda, CA 94501

Notes:

Address:

Thermal imaging, predominantly for military applications.

Contact Name:

Y. Marfaing

Position:

CNRS

Organization: Component:

Laboratiore de Physique des SOlides de Bellevue

Address:

F-92195 Meudon-Cedex, FRANCE

Notes:

Authored for 1991 MCT Workshop "Point Defects and Defect-Purity Interaction of CdHgTe and Other II-Vi Semiconductors: Facts and

Conjectures."

David Marlow

Position:

International Marketing Manager

Organization:

Marlow Industries, Inc.

Component:

Address: 10451 Vista Park Road

Dallas, TX 75238

Notes:

Manufactures thermoelectric cooling devices, thermoelectric cooling assemblies, and related power supplies and temperature controllers

Contact Name:

Philip D. Marlowe

Position:

Salcs Manager

Organization:

Cleveland Crystals, Inc.

Component:

Address:

19306 Redwood Avenue, P.O Box 17157 Cleveland, OH 44117

Notes:

Manufacturer and research into CdTe, ZnS, and ZnSe infrared materials, specialty in II-VI naterials. For both military and commercial markets.

d

Contac: Name:

Stuart E. Marsh

Positica.

Organization:

University of Arizona

Component:

Arizona Remote Sensing Center

Address:

845 North Park Avenue

Tucson, AZ 45719

Notes:

active in infrared remote sensing

Contact Name:

C. Martino

Position: Organization:

IR Marketing Manager Hughes Aircraft Co.

Component:

Address:

2051 Palomar Airport Road

Carlsbad, CA 92009

Notes:

K. Maruyama

Position:

Organization: Georgia Tech Research Institute Component: Physical Sciences Laboratory 225 North Avenue, NW

Address:

Atlanta, GA 30332-0800

Notes:

Co-authored for 1991 MCT Workshop "Gas Source Iodine Doping and

Characterization of MBE Epitaxially Grown CdTe"

Contact Name:

Lawrence Matteson

Position:

Manager

Organization: Component:

Eastman Kodak Company Kodak Apparatus Division

Address:

901 Elmgrove Rd. Rochester, NY 14653

Notes:

Applied research in physics and engineering to establish experimental and analystical foundations for new and improved processes in electro, photooptical, and mechanical products. Additional research with PtSi under a contract from the Air Force Aeronautical Systems Division for use in adverse

weather landing systems.

Contact Name:

EK Matthews

Position:

Pres

Organization:

The Pyrometer Instrument Company

Component:

Address:

234 Industrial Pkwy.

Northvale, NJ 07647

Notes:

Design and production of infrared temperature measurement systems.

Contact Name:

John-Paul Mattia

Position: Organization:

MIT

Component:

Lexington Lincoln Lab 244 Wood Street

Address:

Lexington, MA 02173-9108

Notes:

Co-authored April 1990 study entitled "PtSi Schottky-Barrier Focal Plane

Arrays for Multispectral Imaging in Ultraviolet, Visible, and Infrared Spectral

Bands"

R.B. Mattson

Position:

Organization:

MIT

Component:

Lexington Lincoln Lab

Address:

244 Wood Street Lexington, AM 02173-9108

Notes:

Co-authored August 1989 study entitled "128 X 128 Element IrSi Schottky-

Barrier Focal Plane Arrays for LWIR Imaging"

Contact Name:

Mario Maury

Position:

Organization:

Maury Microwave Corp

Component:

Address:

2900 Inland Empire Blv

Ontario, CA 91764

Notes:

Cyrogenic equipment for military markets, some commercial.

Contact Name:

P.W. Mausel

Position:

Organization:

Indiana State University

Component:

Department of Geography and Geology

Address:

Terre Haute, IN 47809

Notes:

Active in infrared remote sensing, has done studies which favored infrared videography over infrared photos; interested in developing the technology.

Contact Name:

Position:

T. Maxworthy

Organization:

University of California in Los Angeles

Component:

Address:

Notes:

Authored February 1991 stud; "Laboratory Modelling of the Dynamics of

Coastal Upwelling" which studies the dynamics of the filamentary structured that have been repeatedly observed by satellite by IR imagery taken from the

West Cost.

George A. May

Position:

Organization:

ITD - Space Remote Sensing Center

Component:

Address:

Building 1103 Suite #118

Stennis Space Center, Mississippi 39529

Notes:

Active in infrared remote sensing, military and commercial.

Contact Name:

lame: Alex McCallam

Position:

Address:

President

Organization:

McCallum & Associates, Inc.

Component:

330 Pearl Street, Suite 3A

New York, NY 10038

Notes:

Represents MediScience, Inc, which funded Alfano's work at CCNY on breast

cancer detection. Interests in additional funding. Sees use in cancer pre-

diagnosis and cardiology during operations.

Contact Name:

Donald E. McClure

Position:

Organization:

Brown University

Component:

Center for Advanced Materials Research

Address:

182 Hope Street, P.O. Box D

Providence, RI 02912

Notes:

Authored "Image Acquisition and Processing Equipment for Machine Vision"

September 1990, distributed by Defense Technical Information Center

Contact Name:

William P. McCracken

Position:

Texas Instruments, Inc.

Organization: Component:

Image Sensor Technology Center

Address:

P.O. Box 650311, Mail Stop 3966

Dallas, TX 75265

Notes:

Involved in electronics imaging, designing advanced video cameras at TI,

specifically CCD cameras. Prefers CCDs to conventional IR detectors.

Tom McGill

Position:

Dr.

Organization: Component:

California Institute of Technology

Address:

1201 East California Boulevard

Pasadena, CA 91125

Notes:

Reported at the DARPA Program Review on Infrared Focal Plane Array Technology in December, 1992, on "InAs/GaInSb Superlattices: Growth

Involving Anion Switching"

Contact Name:

T.C. McGill

Position:

Organization:

California Institute of Technology

Component: Address:

1201 East California Boulevard

Pasadena, CA 91125

Notes:

Co-Authorrd "Augur Lifetimes in Ideal InGaSb/InAs Superlattices" for 1992

MCT Workshop.

Contact Name:

Position:

Peter McGrath General Manager

Organization:

Optoelectronics- Textron

Component: Address:

1309 Dynamics St. PO Box 750039

Petaluma, CA 94975-0039

Notes:

Manufactures lead salt infrared detectors and related components

Contact Name:

Brian McLain

Position:

Sales Manager

Organization:

Eagle-Picher Industries, Inc.

Component:

Address:

P.O.Box 737

Quapaw, OK 74363

Notes:

Gerard McLarhon

Position:

CEO

Organization:

Applied Solar Energy corporation

Component: Address:

15251 E Don Julian Rd.

City of Industry, CA 91749

Notes:

Product oriented R&D of solar laser detector products, including CdTe

Contact Name:

J.A. McLuckey

Position:

President

Organization:

Rockwell International Corporation

Component: Address:

Defense Electronics

3370 Miraloma Ave. Anaheim, CA 92803

Notes:

Electro-optical products and systems, including IR equipment and components.

Contact Name:

Phillip C. McMullan

Position:

Organization:

TSI Thermo-Scan Energy Management

Component:

Address:

15658 North Gray Road, Box 705

Carmel, IN 46032

Notes:

active in infrared predictive maintenance

Contact Name:

Position:

Phillip C. McMullan

Organization:

TSI Thermoscan Energy Management

Component:

Address: 15658 North Gray Road, Box 705

Carmel, IN 46032

Notes:

infrared non-destructive evaluation

Brett McNeil

Position:

Advanced Products Manager

Organization:

SBRC

Component:

Address:

Notes:

Knows diversification opportunities and Military work at SBRC.

Contact Name:

Michael J. McNutt

Position:

Organization:

MIT

Component:

Lexington Lincoln Lab

Address:

244 Wood Street Lexington, AM 02173-9108

Notes:

Co-authored August 1989 study entitled "128 X 128 Element IrSi Schottky-

ì

Barrier Focal Plane Arrays for LWIR Imaging"

Contact Name:

DL McPherson

Position:

Gmgr

Organization:

General Dynamics Corporation

Component:

General Dynamics Air Defense Systems Division

Address:

Notes:

PO Box 50800

Ontario, CA 91761-1085
Exploration of new sensor concepts for electro-optical detection, guidance, and

measurement applications for military markets.

Contact Name:

Position:

D.L. McPherson

Organization:

General Manager
General Dynamics Corporation

Component:

General Dynamics Air Defense Systems Division

Address:

PO Box 50800

Ontario, CA 91761-1085

Notes:

Exploration of new sensor concepts for electro-optical detection, guidance, and

measurement applications for military markets.

Thomas McRae President and CEO

Position: Organization:

Laser Imaging Systems, Inc.

Component:

Address: 204A E. McKenzie

Punta Gorda, FL 33950

Notes: Has developed MCT-based gas detection cameras used for fugitive gas leaks as

well as in factory testing for gas leaks. Marketed through Inframetrics.

Contact Name:

P. Meisen

Position:

Organization:

Fraunhofer-Institut fur Angewandte Festkorperphysik

Component:

Address:

D-7800 Freiburg, GERMANY

Notes:

Authored "XPD Investigation of Substrate Crystallinity at HgCdTe (111B) and

Ì

CdTc(111)B Surfaces Upon Ag and Al Overlayer Formation."

Contact Name:

Position:

Jan Melles CEO

Organization:

Melles Griot

Component:

Address:

1770 Kettering St.

Irvinc, CA 92714

Notes:

Research into optical sciences and optical thin films.

Contact Name:

Arthur Mengel

Position:

Pres

Organization:

Teltron, Inc.

Component:

Address:

2 Riga Ln.

Birdsboro, PA 19508

Notes:

Development and production of UV, IR, and TV cameras.

Heather Messenger Senior Editor, Markets Laser Focus World

Organization: Component:

Position:

Address: One Technology Park Drive

P.O. Box 989

Westford, MA 01886

Notes: Wrote November 1992 article "Detector Makers Seek Dual-Use Technology

for Survival." Friends with David Leech.

Contact Name:

Name: Z.Y. Mi

Position:

Organization: Shanghai Institute of Technical Physics
Component: National Laboratory for INfrared Physics

Address: Academia Sinica

Shanghai 200083

CHINA

Notes: Co-authored for 1991 MCT Workshop "Influece of Resonant Defect States on

Subband Structures in HgCdTe"

Contact Name:

Joel Milelli Gmgr

Position: Organization:

Loral Corporation

Component:

Loral-Fairchild Imaging Sensors

Address:

Notes:

1801 McCarthy Blvd.

Milpitas, CA 95035

Development of IR sensing systems.

Contact Name:

David Miller

Position: Organization:

Gmgr Aritech

Component:

Aritech Corporation

Address:

1510 Tate Blvd., SE

Hickory, NC 28603

Notes:

Sensor detector and alarm system equipment.

Sol Mirelez

Position:

Marketing Communications Manager

Organization:

Rosemount Inc.

Component:

Aerospace Division

Address:

14300 Judicial Road Burnsville, MN 55337

Notes:

Contact Name:

M.M. Miroshnikov

Position:

Organization:

S.I. Vavilov State Optical Institute

Component:

Address:

Moscow, RUSSIA

Authored for 1991 SPIE meeting on Infrared Technology "Infrared in the Notes:

USSR: Brief HIstorical Survey of Infrared Development in the Soviet Union"

Contact Name:

K.L. Moazed

Position:

Organization:

North Carolina State University at Raleigh

Component:

Department of Materials Science and Engineering

Address:

Ralcigh, NC

Notes:

Authored June 1980 paper "MBE Growth of HgCdTe"

Contact Name:

Jonathan H. Mohler

Position:

Organization:

EG & Mound Applied Technology

Component:

Address: Box 3000

Manisburg, OH 45342

Notes:

active in infrared remote sensing

S. Mohling

Position:

Organization: Dresden University of Technology Institut fur Festkorperelektronik

Component: Address:

Dresden, FEDERAL REPUBLIC OF GERMANY

Notes:

Co-authored for 1992 SPIE IRFPA meeting "Pyroelectric IR Single-Element

Ì

Detectors and Arrays Based on LiNbO3 and LiTaO3"

Contact Name:

S.E. Mohr

Position:

Organization:

EG&G Princeton Applied Research

Component:

Address:

375 Phillips Boulevard

Trenton, NJ 08618

Notes:

Co-authored for 1992 SPIE Workshop on IRFPAs "Popcorn Noise in Linear

InGaAs Detector Arrays"

Contact Name:

Chrsitine Monestier Advertising Manager

Position: Organization:

Litton Electron Devices

Component:

Address:

960 Industrial

San Carlos, CA 94070

Notes:

Infrared systems and equipment, c/o systems, night vision for military markets.

Contact Name:

John Moore

Position:

Business and Marketing Manager

Organization:

BSA Technology, Inc.

Component: Address:

3812 Sepulveda Blvd, Stc 500

Torrance, CA 90505

Notes:

Infrared detectors in 1-14 micrometer range (MCT), HgMnTc, InSb, and

others), infarred pyrometers, copper and molybdenum mirrors, laser power and

energy measurement systems, crystals operiteal elements, solar energy

collection mirrors, etc.

James Morgan

Position:

President

Organization:

Applied Materials, Inc.

Component:

Address: 3050 Bowers Ave.

Santa Clara, CA 95054

Notes:

Research on chemical vapor deposition and plasma etching processes materials and equipment, with particular emphasis on semiconductor materials, metals and dielectrics for the electronics industry, ion implantation of dopants into

silicon and process control equipment.

Contact Name:

William T. Morgan

Position:

Organization:

Infrared Engineering Services

Component:

Address: 110 Shadow Oaks Drive

Easley, SC 29642

Notes:

Infrared non-destructive evaluation firm, doing mostly thermal building

surveys.

Contact Name:

C.G. Morgan-Pond

Position:

Organization: Wayne State University
Component: Department of Physics

Address:

Detroit MI

Notes:

Co-authored 1990 "FOrmation Mechanisms of Interstitial Defect States"

And 1991 "Present Status and Future of Theoretical Work on Point Defects

and Diffusion in Semiconductors"

And 1990 "Structural Energies of Defects in CdTe and HgCdTe"

and APril 1990 "Point Defects with Lattice Distortion in CdTe and HgCdTe"

Contact Name:

Walter Morrow

Position:

Deputy Director of Visionics lab

Organization:

Army Night Vision Labs

Component: Address:

Fort Belvoir, VA

Notes:

Secy: -1760. Wrote "Common Modules: A Success Story" in 1988.

Charlie Morse

Position:

Pres

Organization:

Kistler-Morse Corporation

Component:

Address: Notes:

R&D of seminconductor displacement sensors.

10201 Willows Rd., NE, PO Box 3009, Redmond, WA 98073

Contact Name:

David Morton

Position:

CEO

Organization:

Alcan Aluminum Limited

Component: Address:

ManLabs

21 Erie St.

Notes:

Cambridge, MA 02139

Basic applied and product oriented research in metals, alloys, ceramics, and

electro-optical materials.

Contact Name:

Asa Morton

Position:

Pres

Organization:

American Interplex Corporation Laboratories

Component:

Address:

8600 Kanis Rd.

Little Rock, AR 72204

Notes:

R&D on thermal properties of various metals and metal coatings; research in

infrared spectroscopy and monitoring using infrared technologies.

Contact Name:

S. Motakef

Position:

Organization:

MIT

Component:

Address: Cambridge, MA 01742

Notes:

Co-authored "Long Wavelength HgMnTe Avalanche Photodiodes" for 1991

MCT Workshop.

Paul Mullen Manager

Organization:

Position:

Laser Diode Inc.

Component:

Address:

205 Forrest Street

Metuchen, NJ 08840-1292

Notes:

Manufacturer of GaAs and germanium materials for infrared applications.

Contact Name:

Jimmy Murphy

Position:

Program Manager, Integrated Blade Inspection Systems

Organization:

General Electric Co.

Component: Address:

General Electric Aircraft Engines 1 Neumann Way, P.O. Box 156301

Cincinnati, OH 45215-6301

Notes:

Helped design GEAE's thermographic inspection equipment for non-

destructive evaluation of jet engine parts, orginally from Air Force funding

Contact Name:

James C. Murphy

Position:

Organization:

Johns Hopkins University

Component:

Center for NDE and Applied Physics Laboratory

Address:

Laurel, MD 20723

Notes:

Infrared non-destructive evaluation of advanced materials, leading researcher.

Contact Name:

Position:

Thomas H. Myers

Physics Department West Virginia University

Organization: Component:

P.O. Box 6315 Morgantown, WV 26506-6315

Notes:

Address:

Attended 1992 MCT Workshop

Charles W. Myles

Position:

Organization:

Texas Tech University

Component:

Department of Physics and Engineering Physics

Address:

Lubbock, TX 79409-1051

Notes:

Co-authored for 1991 MCT workshop "Critical Stress of HgCdTe Solid

à

Solutions." and "Microhardness of Hg-Containing II-VI Alloys"

Contact Name:

S. Nagarajan

Position:

Organization:

Auburn University

Component:

Address:

Notes:

Co-authored 1991 "Weld Quailty Control in Gas Tungsten Arc Welding

Process"

Contact Name:

Albert Narath

Position:

President

Organization:

American Telephone and Telegraph

Component:

Sandia National Laboratories

Address: Notes: Albuquerque, NM 87185-5800

Basic and applied research for US DoE in solid state materials, science,

physics, opto-electronics, aerospace sciences, solar, geothermal, fossil, fission

and fusion energy.

Contact Name:

Albert Narath

Position:

Pres

Organization:

American Telephone and Telegraph Co.,

Component: Address:

Sandia National Laboratories Albuquerque, NM 87185-5800

Notes:

Basic and applied research for US DoE in solid state materials, science,

physics, opto-electronics, aerospace sciences, solar, geothermal, fossil, fission

and fusion energy.

Ram M. Narayanen

Position:

Organization: University of Nebraska Component: Center for Electro-Optics

Address:

Lincoln, NE 69588

Notes:

active in infrared remote sensing

Contact Name:

Donald Neamen

Position:

Organization:

University of New Mexico

Component:

Department of Electrical and Computer Engineering

Address:

Albuquerque, NM 87131

Notes:

Co-authored with Eustace Dereniak for 1992 SPIE IRFPA meeting "Computer

Simulation of a Switched FET Readout Multiplexer"

Contact Name:

Position:

J.G. Needham General Manager

Organization:

MCP Wafer Technology

Component:

Address:

Unit 34, Maryland Road, Tongwell, Milton Keynes, Bucks, MK158HJ

UNITED KINGDOM

Notes:

Production of CdTe and GaAs for infrared applications.

Contact Name:

Position:

Jeannette Neff

Organization:

Mgr. Marketing Communications Kollsman Division of Sequa Corp.

Component:

Address:

220 Daniel Webster Highway

Merrimack, NH 03054

Notes:

E/O Systems, infrared systems and equipment, night vision for military.

Dr John Nelson

Position:

VP

Organization: Component:

Baker Hughes, Inc. TN Technology, Inc.

Address:

PO Box 800, Round Rock

TX 78680-0800

Notes:

Applied R&D of radiation detectors and sources, acoustical transducers, and

è

measurements and data processing methodolgy directed toward the

development of instrumentation for the measurement of industrial process

parameters.

Contact Name:

Craig R. Nelson

Position:

VP for New Business Development

Organization:

Emcore Corp.

Component: Address:

35 Elizabeth Avenue

Somerset, NJ 08873

Notes:

Material production of GaAs, CdTe, silicon, ZnS, and ZnSe for infrared

applications.

Contact Name:

John Nelson

Position:

Address:

Marketing Manager Marlow Industries, Inc.

Organization:

Component:

10451 Vista Park Road

Dallas, TX 75238

Notes:

Manufactures thermoelectric cooling devices, thermoelectric cooling

assemblies, and related power supplies and temperature controllers

19 3.50

 $\sim 0.033\Delta$

Contact Name:

Ralph Nelson

Position:

Dr.

Organization:

Univ of Illinois College of Medecine

Component: Address:

Carle Foundation
611 West Park Street

Urbanna, IL 61801

Notes:

active in infrared biomedical thermography

D.A. Nelson

Position:

Organization:

University of Maryland

Component:

Address:

College Park, MD

Notes:

Co-authored 1987 study "Magnetophonon Effect in HgCdTe"

Contact Name:

Position:

Address:

Y. Nemirovsky

Organization:

Component:

Kidron Microelectronics Research Center Department of Electrical Engineering Technion-Israel Institute of Technology

Haifa 32000, ISRAEL

Notes:

"UV Photon Assisted Control of Interface Charge Between CdTe Substrates and Metal Organic Chemical Vapor Deposition CdTe Epilayers" for 1992

ì

MCT Workshop.

For 1991 Workshop, co-authored "Tunneling and 1/f Noise Curernts in

HgCdTe Photodiodes"

Contact Name:

Yael Nemirovsky

Technion University

Position:

IIT Department of Electrical Engineering

Organization:

Component:

Technion City

Haifa, Israel 3200

Notes:

Address:

Attended 1992 MCT Workshop

Contact Name:

Brett Nener

Position:

Organization:

Component:

Department of Electrical Engineering Nedlands, Perth, Western Australia 6009

Address: Notes:

Attended 1992 MCT Workshop

University of Western Australia

N. Neumann

Position:

Organization: Component:

Dresden University of Technology Institut fur Festkorperelektronik

Address:

Dresden, FEDERAL REPUBLIC OF GERMANY

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Pyroelectric

Linear Array IR Detectors with CCD Multiplexer"

Contact Name:

Robert Ngyen

Position:

coo

Organization:

Entec

Component:

Address:

Suite 100, 2817 Garden Hwy

Sacramento, CA 95833

Notes:

Basic research in photovoltaics

Contact Name:

Position:

Yongping Ni

Organization:

Component:

Luoyang Optic-Electronic Institute

Address:

P.O. Box 030-12, 471009, Luoyang, Henan, P.R. CHINA

Notes:

Authored for 1992 SPIE meeting on IRFPAs "Auto-Gain-Control

Characteristics of InSb P+/N Diode with High Sheet Resistance"

Contact Name:

Guy M. Nicoletti

Position:

Organization:

Component:

University of Pittsburgh at Greensburg

Address:

Notes:

Authored 1988 "Optoelectronic Proximity Sensors for Automated Deburring"

JA Noll

Position:

CEO

Organization:

JA Noll Co.,

Component:

Address:

PO Box 312

Monrocville, PA 15146

Notes:

Research in optical metrology, some using IR detectors.

Contact Name:

Position:

P.W. Norton

Organization: Loral Infrared and Imaging

Component:

Address:

2 Forbes Road MS/146

Lexington, MA 02173

Notes:

Their "guru" on IR detectors, senior scientist.

Contact Name:

Position:

Paul Norton

Organization:

SBRC

Component:

Address:

75 Coromar Drive

Golcta, CA 93117

Notes:

A leading figure in MCT arrays, esp. IRFPAs.

Contact Name:

Position:

P.R. Norton

Organization:

Component:

Virginia Polytechnic Institute

Address:

Notes:

On Program Committee of 1992 MCT Workshop.

On Program Committee of 1991 MCT Workshop, as a representative of

SBRC.

Brian O'Donahue

Position:

President

Organization:

Inframetrics, Inc.

Component:

16 Esquire Rd.

Address:

North Billerica, MA 01862

Notes:

Infrared imaging radiometers and night vision devices.

Contact Name:

Tom O'Neill

Position:

CEO

Organization:

Pilkington Optronics

Component:

Address:

Caxton Street

Anniesland, Glasgow GL13 1HZ

Notes:

Thermal imaging and surveillance systems, laser rangefinders, etc. visible and IR optical systems. Producer of HgCdTe-based FPSs for a variety of military

systems, including the IRST on the EFA.

Contact Name:

Jasen Ocho

Position:

Address:

Dr.

Organization:

Good Samaritan Hospital & Medical Center

Component:

Dept of Neurology 1015 NW 22nd Avenue

Portland, OR 97210

Notes:

Cctive in infrared biomedical thermography for neurology.

Contact Name:

Position:

Greg Olsen

Organization:

Sensors Unlimited, Inc.

Component:

Address:

Princeton, NJ

Notes:

Start up company founded by former persident and CEO of EPITAXX, Inc., to advance recent developments in III-V compound device tech fro sensing and imaging applications in the 1000-3000 nm near-infrared spectrym. Ongoing development projects include a monolithic InGaAs detector for NASA Jet Propulsion Labs and 2000-5000 DFB lasers for Kirtland Air Force Base

Phillips Lab.

Dr MW Overhoof PhD

Position:

Pres

Organization:

Overhoff Technologies Corporation

Component: Address:

1160 US RT 56, PO Box 182

Millford, OH 45150

Notes: Design and development and

Design and development and manufacture of electronic instrumentaiton and sensor systems for measurement and control, including infrared, other optical,

ultraviolet and nuclear, gaging.

Contact Name:

Tofie Owen

Position:

V.P. Marketing

Organization:

Magnavox Electronic Systems, Inc.

Component:

Address:

1313 Production Road

Fort Wayne, IN 46808

Notes:

/o systems, infrared systems and equipment, night vision for military markets.

Contact Name:

James Owlswey

Position:

VP

Organization: Component:

Northrop Corporation Rolling Meadows Site

Address:

600 Hicks Rd.

Rolling Meadows, IL 60008

Notes:

Development of electronic and infrared detection systems for military.

Contact Name:

Carol L. Oxicy

Position:

President

Organization:

Target Corp.

Component:

Address:

8400 Lakeview Parkway, Suite 200

Kenosha, WI 53142-7404

Notes:

infrared systems and equipment, passive and active c/o devices

Paul Page

Position:

Mer

Organization:

Sensor Control Corporation

Component:

Gentran

Address:

49050 Milmont Dr.

Fremont, CA 94538

Notes:

Research on infrared temperature measurements.

Contact Name:

G.N. Pain

Position:

Organization:

EPI Crystal Supplies Pty, Ltd.

Component:

Address:

Monbulk, Victoria, 3793 Australia

Notes:

Authored for 1991 MCT Workshop "Effects of mixed-valence Mercury and

Indium on the Electrical Properties of HgCdTe"

Contact Name:

H.D. Palfrey

Position:

Address:

Organization:

University of Southampton

Component:

Engineering Materials Southampton, SO9 5NH

UNITED KINGDOM

Notes:

Authored "Growth Method, Composition, and Defect Structure Dependence of

Mercury Diffusion in CdHgTc" for 1992 MCT Workshop.

Contact Name:

Position:

Yen-Ming Pann

Organization:

Address:

Chung-Shan Institute of Science and Technology

Component:

P.O. Box 90008-8-7, Lung-tan, Tao-Yuan

REPUBLIC OF CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "A Novel CID Emulator for

InSb Array"

. อาปกร

Prauin Parekh

Position:

Director

Organization:

Honeywell, Inc.

Component:

Solid State Electronics Center

Address:

12001 State Hwy 55

Notes:

Plymouth, MN 55441-2080 Research, engineering and manufacturing of microunits, sensors, transducers

and advanced packaging.

Contact Name:

Dr Prauin Parekh

Position:

Dir

Organization:

Honeywell, Inc,

Component:

Solid State Electronics Center

Address:

12001 State Hwy 55

Notes:

Plymouth, MN 55441-2080 Research, engineering and manufacturing of microunits, sensors, transducers

and advanced packaging.

Contact Name:

Joseph A. Parini

Position:

President

Organization:

Elbit Systems, Inc.

Component:

Address:

16 Esquire Road

North Billerica, MA 01862

Notes:

EO systems, infrared systems and equipment, night vision for military markets

Contact Name:

Camillo Pariset

Position:

P.R. Manager

Organization:

Elettronica S.p.A.

Component:

Address:

via Tiburtina KM 13.7

1-00131 Rome, ITALY

Notes:

Infrared systems and equipment for European military market.

Mann J. Park

Position:

Organization: Korea University
Component: Sung-Buk-Ku

Address:

Cong-Am-Dong Seoul, KOREA 136-701

Notes:

Attended 1991 MCT Workshop, materials research.

Contact Name:

Nancy Parker

Position:

Address:

Business Communications
Textron Defense Systems

Organization: Component:

201 Lowell Street

Wilmington, MA 01887

Notes:

Infrared systems and equipment, GaAs arrays, active and passive c/o systems,

ą

detectors and sensors

Contact Name:

Ed Patton

Position:

COO

Organization:

Infrared Industries

Component:

Address:

12151 Research Pkwy

Orlando, FL 32826

Notes:

Lead sulphide, lead selenide, indium antimonide and silicon infrared detectors and thin film optical filters for government and industrial applications; hybrid

preamplifier microcircuits.

Contact Name:

Alfred P. Pavot

Position:

Dr.

Organization:

Greater SE Community Hospital & Georgetown Univ School of Medecine

Component:

Dept of PMR

Address:

1310 Southern Avenue, SE

Washigton, DC 20032

Notes:

Active in infrared biomedical thermography community as both user and

former president of the American Academy of Thermology,

M. Pepper

Position:

Organization: Cambridge University

Component:

Cavendish Lab
Cambridge, UNITED KINGDOM

Address: Notes:

Co-authored October 1988 "MBE of HgCdTe"

Contact Name:

F.S. Perry President

Position:

President

Organization:

Boston Electronics Corp.

Component:

Address:

72 Kent Street

Brookline, MA 02146

Notes:

Manufacture and use of germanium and silicon. Handles laser and optoelectronic detectors and accessories, fiberoptic components and equipment, optics, optoelectronic devices, materials and substrates, etc.

Contact Name:

Ron Perry

Position:

Dir. Sales and Marketing

Organization:

Pulse Instruments

Component:

Address:

1234 Francisco Street

Torrance, CA 90502

Notes:

E/o systems, infrared systems & equipment for military applications.

Contact Name:

Position:

David L. Perry

i ositivii.

Organization: Component:

University of Arizona
Optical Sciences Center
Tucson, AZ 85721

Address: Notes:

Author in 1992 SPIE meeting of "Measured Performance of the Hughes

256X256 Hybrid PtSi Imaging Device"

R.E. Peterson Vice President

Position: Organization:

Honeywell, Inc.

Component:

Systems & Research Center

Address:

3660 Technology Dr.

Minneapolis, MN 55418

Notes:

Development of electro-optical materials and sensors mainly for military;

developing commercial opportunities.

Contact Name:

Thomas Petry

Position:

CEO

Organization:

Eagle-Picher Industries, Inc.

Component:

Eagle-Picher Research Laboratory

Address:

200 Ninth Ave., NE

Miami OK 74354-3305

Notes:

Crystals for IR or UV detectors.

Contact Name:

Fletcher Phillips

Position:

President

Organization:

General Motors, Corporation Santa Barbara Research Center

Component: Address:

75 Coromar Dr.

Goleta, CA 93117

Notes:

Manufacture of infrared photodetectors and associated components, packages and infrared focal plane arrays; electro-optical instrumentation for space; particularly multispectral earth observation sensors and weather sensors;

specialized military equipment such as vehicle fire sensors and missle proximity

fuses.

Contact Name:

F.R. Phillips President

Position: Organization:

Hughes

Component:

Santa Barbara Research Center

Address:

75 Coromar Drive

Golcta, CA 93117

Notes:

Heavily involved in a broad array of US military programs using PtSi, HgCdTc,

1612

and InSb.

Jim Phillips

Position:

Marketing Director

Organization:

SBRC

Component:

Address: 75 Coromar Drive

Goleta, CA 93117

Notes:

Their INFRARED PRODUCTS marketing director.

Contact Name:

J.A. Pickup

Position:

Sales Admin. Manager

Organization:

Oxley Developments Co., Ltd.

Component:

Address:

Priory Park

Ulverston

Cumbria, UK L'A12 9QG

Notes:

Detectors and sensors, infrared systems and equipment for military

applications.

Contact Name:

Lars L. Pierce

Position:

Organization:

Component: School of Forestry Address: Missoula, MT 59812

Notes:

active in infrared remote sensing

Contact Name:

Michele Pimpinenelli

University of Montana

Position:

Marketing

Organization:

Officine Galileo

Component:

Address: V.A. Einstein 35

50013 Campi Bisenzio, Florence

ITALY

Notes:

Night vision, thermal lamging, infrared systems & equipment for military

applications.

Joseph Plonski

Position:

V.P. Sales and Marketing

Chelmsford, MA 01824

Organization:

Imagraph Corp.

Component:

11 Elizabeth Drive

Address:

Thermal imaging, primarily for military market.

Contact Name:

Maksymilian Pluta

Position:

Organization:

Institute of Applied Optics

Component:

Address:

ul. Kamionkowska 18

03-805 Warszawa, POLAND

Notes:

Will be editing the May 1994 edition of Optical Engineering, focusing on

Semiconductor Infrared Detectors.

Contact Name:

Ruben Pochaczevsky

Position:

Dr.

Organization:

Albert Einstein College of Medecine

Component:

Dept of Radiology

Address:

1300 Morris Park Avenue

New York, NY 10461

Notes:

Professor and doctor active in infrared biomedical thermography community

Contact Name:

Position:

Leslie G. Polgar

r osition.

Vice President

Organization: Component:

Bertram Laboratories, Inc.

Address:

72 Readington Road Somerville, NJ 08876

Notes:

Manufactures GaAs single and polycrystalline ingots and wafers. APplications

for diode lasers, LED's, detectors, solar cells, source matkerl for liquid phase

epitaxy, IR blanks and modulators.

Fred H. Pollak

Position:

Dr.

Organization:

Brooklyn College

Component: Address:

Semiconductor Institute Brooklyn, NY

Notes:

Former director of the SPIE

Contact Name:

John Pomeroy

Position:

Pres

Organization:

Dover Corporation

Component:

Universal Instrument Corp.

Address:

PO Box 825

Notes:

Binghamton, NY 13902 Automation of electronics industry production.

Contact Name:

Gary Powell

Position:

Address:

Dreng

Organization:

Brunson Instrument Co, Inc

Component:

800 E 23rd PO Box 7951

Kansas City, MO 64129

Notes:

Research, design, and development in the optical mechanical and electro-

optical field, circular and linear developing.

Contact Name:

Mark Prcis

Position:

Organization:

Litton Electron Devices Division

Component:

Address:

Tempe, AZ 85281

Notes:

Spent 22 years at SBRC, doing Lead Salts, InSb, IrSi, and MCT. At litton,

doing Lead Salts for commercial applications, thinks will corner 3-5 micron

range. Extensive contacts at SBRC, which he left in 1986.

Nelson F. Principio

Position: Organization:

Manager of Business Development

Component:

Eastman Kodak Co. Government Systems Div.

Address:

1447 St. Paul Street Rochester, NY 14653

Notes:

IR Detectors work, mostly PtSi.

Contact Name:

Theodore Prophet

Position:

Gmgr

Organization:

Anacon Corp.

Component:

Address:

117 S St.

Hopkinton, MA 01748

Notes:

Applied research on refractometers; chlorine monitors; stack gas monitors;

ultra-violet and infrared analyzers

Contact Name:

N. Pundak

Position:

Organization:

RICOR Ltd.

Component:

Address:

En Haros (IHUD)

18960

Israel

Notes:

Authored for 1992 SPIE IRFPA workshop "Miniature Closed Cycle Cooler for

FPA Detectors*

Contact Name:

Ernie Pusey

Position:

Mkt. Dir.

Organization:

Plessey Semiconductors Ltd.

Component:

Address:

Unit 1, Crompton Road

Groundwell Ind. Estate, Seindon, Wilts SN2 5AY

UNITED KINGDOM

Notes:

Manufacture of a wide variety of HgCdTe-based infrared systems for military

17165 1

applications.

Roger Putnam

Position:

Director of Marketing Acrodyne Research, Inc.

Organization: Component:

Address:

45 Manning Rd.

Billerica, MA 01821-3976

Notes:

Basic and applied product-oriented research in electro-optical and photooptical systems, combustions, atmospheric, and environmental science;

molecular physics; laser development; spectroscopy; product surface chemistry;

optical signal processing; optical computing.

Contact Name:

Abdelrahman Rabie

Position:

Organization:

SUNY College of Technology

Component:

Address:

Notes:

AUthored 1983 "The Use of Sensors in Part Handling" available from S.M.E.

Contact Name:

Position:

Marketing Director Chemring, Ltd.

Organization: Component:

Address:

Alchem Works

David Radford

Fratton Trading Estate

Portsmouth, Hampshire, ENGLAND PO4 8SX

Infrared Systems & Equipment, passive EO systems for military. Notes:

Contact Name:

D. Rajavel

Position:

Address:

Organization: Component:

Georgia Tech Research Institute Physical Sciences Laboratory 225 North Avenue, NW

Atlanta, GA 30332-0800

Notes:

Co-authored for 1991 MCT Workshop "Gas Source Iodine Doping and

Characterization of MBE Grown CdTc"

L.R. Ram-Mohan

Position:

Organization:

MIT

Component: Address:

Electronics Research Lab 77 Massachusetts Avenue Cambridge, MA 02139

Notes:

Co-authored January 1987 "Infrared Nonlinear Optics"

Contact Name:

L.R. Ram-Mohan

Position:

Organization:

Worcester Polytechnic Institute

Component: Address:

Department of Physics Worcester, MA 01609

Notes:

Co-Authored "States Confined in the Barriers of Type-III HgTe/CdTe

Superlattices" for 1992 MCT Workshop

Contact Name:

A.C. Ramamurthy

Position:

Organization:

BASF Corporation

Component:

Coatings Technical Center 26701 Telegraph Road

Address:

Southfield, MI

Notes:

Designing IR inspection system to nondestructively inspect automotive paint

for delaminations or rust

Contact Name:

Position:

Tom Ramey President

Organization:

Ramcy Aerospace

Component:

Box 39

Address:

in north

Carmel, CA 93924

Notes:

Thermal Imaging, Infrared systems & equipment for military applications.

15,3

Albert Rand

Position:

Pres

Organization:

Dynamics Research Corporation

Component:

60 Concord St.

Address: Wilmington, MA 01887

Notes: Design and fabrication of optical digital shaft angle encoders for aerospace and

industrial applications.

Contact Name:

Roderick R. Randolph

Position:

Sales Manager

Organization:

Exotic Materials, Inc.

Component:

2930 Bristol St.

Address:

Costa Mesa, CA 92626

Notes:

Applied, product-oriented research as related to electro-optical materials,

vacuum deposited coatings and devices for government, industrial and military

systems applications.

Contact Name:

Vithal R. Rao

Position:

Organization:

Rensselaer Polytechnic Institute

Component: Address:

JEC 6012

Troy, NY 12180

Notes:

Attended 1992 MCT meeting

Contact Name:

Position:

D. Rasmussen Sales Manager Honeywell, Inc.

Organization:

Solid State Sensors Group

Component: Address:

830 E. Arapaho Road Richardson, TX 75081

Notes:

Manufactures IR optoelectronic components and assemblies, fiberoptic

components, and modules.

J.P. Rasquin

Position:

Directeur Departement de Defense

Organization:

Alcatel Bell-SDT S.A.

Component:

Address:

101, rue Chapelle Beaussart

Notes:

6032 Mont-Sur-Marchienne BELGIUM Infrared Systems and Equipment for military

Contact Name:

N.M. Ravindra

Position:

Organization:

New Jersey Institute of Technology

Component:

Address:

Newark, NJ 07102

Notes:

Authored for 1992 SPIE meeting on IRFPAs "HgCdTe Photovoltaic Detectors

Ì

and Some Related Aspects"

Contact Name:

Position:

Rikki Razdan

Marketing Manager

Organization:

Iscan, Inc.

Component:

Address:

125 Cambridgepark Drive

Cambridge, MA 02140

Notes:

Infrared systems and equipment, e/o systems for military applications.

Contact Name:

Manijch Razeghi

Position:

Organization:

Northwestern University

Component:

Address:

Notes:

Presented at December 1992 DARPA IRFPA Technology Program Reviews

on "Physics and Performance of GainP/GaAs Quantum Wells and New

Infrared III-V Compound InTiSb

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210.000% 15

CZ Razi Pres Dr CZ

Organization:

Litton Industries, Inc.

Component:

Integrated Automation Division

Address:

Position:

1301 Harbor Bay Pkwy Alameda, CA 94501

Notes:

Systems use advanced sensor techniques including vision, ultraviolet, infrared.

and x-ray.

Contact Name:

JB Reagan

Position: Organization:

General Manager Lockheed Corporation

Component:

Lockheed Palo Alto Research Laboratories

Address:

3251 Hanover St., Orgn 90-01

Notes:

Palo Alto, CA 94304
Research and development of electro-optic systems, including HgCdTe under

DARPA's Electronic Sciences program.

Contact Name:

Herman Reedy

Position:

Chief Engineer

Organization:

II-VI Inc.

Component:

Address:

375 Saxonburg Blvd

Saxonburg, PA 16056

Notes:

Manufacture of CdTe, GaAs, germanium, silicon, ZnS, ZnSe for infrared

applications.

Contact Name:

Dr Leon Reibman

Position:

CEO

Organization:

American Electronic Laboratories, Inc.

Component:

Address: 305 Richardson Rd., PO Box 552

Landsdale, PA 19446

Notes:

Diversivied R&D and manufacturing organization specializing in state-of-theart equipment for military and industrial applications, electronic warfare and electronic warfare support measure systems, radar and fire control, antennas, supplies, technical service, system engineering services and manufacturing

scrvices.

Kevin Reily

Position:

V.P. of IR Detector Group

Organization:

SBRC

Component:

Address:

75 Coromar Drive

Goleta, CA 93117

Notes:

Contact Name:

M.B. Reine

Position:

Organization:

Loral Corporation

Component:

Loral Infrared & Imaging Systems, Inc.

Address:

2 Forbes Rd.

Lexington, MA 02173

Notes:

Leading figure in their producibility efforts, has represented LIIS at IRMP

è

consortium.

Contact Name:

Paul Rcising

Position:

Organization: Geonex Verde Technologies

Component:

Address:

734 E. Lake Avenue

Watsonville, CA 95076

Notes:

Active in infrared remote sensing as a consulting firm.

Contact Name:

Position:

J. Ren

Organization:

North Carolina State University

Component:

Department of Physics

Address:

Raleigh, NC 27695-8202

Notes:

AUthored "Integrated Heterostructure Devices Based on II-VI Compound

Semiconductors"

dietar i

Frank Renda

Position:

Organization:

SBRC

Component:

Address:

75 Coromar Drive

Golcta, CA 93117

Notes:

Contact Name:

Richard A. Reynolds

Position:

Dr.

Organization:

Hughes Research Laboratories

Component:

Address:

3011 Malibu Canyon Road

Malibu, CA 90265

Notes:

Former DARPA program officer who contributed extensively to II-VI

semiconductor development while at the Defense Sciences office.

Contact Name:

Herbert Richardson

Position:

Dir

Organization:

Texas Engineering Experiment Station

Component:

Address:

301 Wisenbaker Engineering Research Center, Texas A&M University, College

Station, TX 77843-3126

Notes:

Research into all areas of engineering, including introduction of emerging

technologies.

Contact Name:

H.J. Richter

Position:

Organization:

Fraunhoser-Institut fur Angewandte Festkorperphysik

Component:

Address:

D-7800 Freiburg, GERMANY

Notes:

Authored "XPD Investigation of Substrate Crystallinity at HgCdTe (111B) and

CdTe(111)B Surfaces Upon Ag and Al Overlayer Formation."

Max Riedl

Position:

CEO

Organization:

Contraves USA

Component:

Boston Electro Optic Division

Marlborough, MA 01752

Address:

170 Locke Dr.

Notes:

Applied researach on electrical-optical systems, instruments and components utilizing infrared, visible and ultraviolet spectrums, including infrared

detectors, optical elements, and optical interference and coatings filters, radiation sources, radiometers, combustion analyzers, navigation instruments for satellites and spacecraft and sensors for meteorological satellites; chemical and drug detection, instrumentation, target and scene simulation, models, gas

detection, measurement insstrumentation.

Contact Name:

George A. Riggs Position:

Organization:

University of Montana School of Forestry Missoula, MT 59812

Component: Address:

active in infrared remote sensing

Notes:

Contact Name:

Edward R.J. Ring

Position:

Organization:

Royal National Hospital for Rheumatic Diseases

Component:

Dept of Clinical Measurement Upper Borough Walls, Bath

Address:

UNITED KINGDOM

Notes:

Active in infrared biomedical thermography, has written extensively on the

widespread applications of IR thermography.

Contact Name:

Sherman Rinkel

Position:

Address:

Pres

Organization:

General Microwave Corp.

Component:

5500 New Horizon Blvd

Amityville, NY, 11701

Notes:

Applied sensor technology for industrial and automative applications.

Dr. Malcom Roberts

Position:

Dirres

Organization: Component: Bethlehem Steel Corporation Homer Research Laboratories

Bethlehem, PA 18016-7699

Address:

701 East Third Street

Notes:

Investigation on new methods of measurement and instrumentation used in the control of steel processes and product quality. Thermal analysis of fatigue

and fracture of steel.

Contact Name:

Elisanda Roca

Position:

Organization:

Universitat de Barcelona

Component:

Address:

Avd. Diagonal 647

Address:

E-08028 Barcelona, SPAIN

Notes:

Co-author at 1992 SPIE IRFPA meeting of "Comparative Study of SWIR and

MWIR Schottky-barrier Imagers"

Contact Name:

Tom Rockwell

Position:

CEO

Organization:

Rockwell Engineering Co., Inc.

Component:

Address:

2121 E. 45th St

Indianapolis, IN, 46205

Notes:

Optical radiation research.

Contact Name:

Bill Rogatto

Position:

VP for FPA Development and Producibility

Organization:

SBRC

.

Component: Address:

75 Coromar Drive

Goleta, CA 93117

Notes:

Michael Roitberg

Position:

Organization:

Atomergic Chemetals Corporation

Component:

Address: 222 Sherwood Avenue

Farmingdale, NY 11735

Notes: Material processing of CdTe, GaAs, Germanium, Silicon, ZnS, and ZnSc.

Contact Name:

Brett Rosner Senior Engineer

Position: Organization:

Santa Barbara Focalplane

Component:

Address: 69 Santa Felicia Drive

Goleta, CA 93117

Notes:

One of first firms marketing cameras based on focal plane arrays, InSb based.

Contact Name:

Richard Ross

Position:

CEO

Organization:

Diagnostic Retrieval Systems, Inc.

Component:

Photronics Corporation

Address:

270 Motor Pkwy. Hauppauge, NY 11788

Notes:

Develop and manufacture optical laser ultraviolet detection components,

missile optical component and specialized coating, mostly for military

applications.

Contact Name:

D.V. Rossi

Position:

Organization:

Columbia University

Component:

Address:

New York, NY

Notes:

Co-authored for 1990 SPIE workshop on IR Detectors "GaAs CCD Readout

for Engineered Bandgap Detectors"

Ralph Rotolante

Position:

Organization:

Vicon Infrared

Component:

Address: Four Seneca Court

Acton, MA 01720

Notes: Former founder and president of the now defunct New England Research

Center. Private consultant

Contact Name:

Cathy Rude

Position:

Marketing Communications

Organization:

Alliant Techsystems

Component:

Address:

5901 Lincoln Drive

Edina, MN 55436

Brian Rushton

Notes:

Thermal Imaging, Night vision, detectors and sensors for military

Contact Name:

Position:

VP R&D

Organization:

Air Products and Chemicals, Inc.

Component:

Gas Group

Address:

7201 Hamilton Blvd

Allentown, PA 18195-1501

Notes:

Applications R&D for infrared spectroscopy.

Contact Name:

R.P. Ruth

Position:

Organization:

SBRC

Component:

Address:

75 Coromar Drive

Goleta, CA 93117

Notes:

Research scientist doing their MCT IRFPA projects

A. Ruzin

Position:

Organization:

Component: Address:

Kidron Microelectronics Research Center

Department of Electrical Engineering

Technion-Israel Institute of Technology Haifa 32000, ISRAEL

Notes:

"UV Photon Assisted Control of Interface Charge Between CdTe Substrates and Metal Organic Chemical Vapor Deposition CdTe Epilayers" for 1992

MCT Workshop.

Contact Name:

Morteza Safai

Organization:

The Boeing Company

Component:

Boeing Defense and Space Group

Address:

Position:

Quality Assurance Research and Development

P.O. Box 399, MS 85-08 Scattle, WA 98124-2499

Notes:

infrared non-destructive evaluation

Contact Name:

MS Sandhu

Position:

Pres

Organization:

SRS Technology

Component:

Address:

Suite 402 3501 Jamboree

Newport Beach, CA 92660

Notes:

Development of smart sensors, conformal-array antennas, image processing,

field measurements, and process control systems.

Contact Name:

Ginette Sarrazin Service Publicite

Position: Organization:

Societe de Frabrication d'Instruments de Mesure

Component:

Address:

13 avenue Ramolfo Garnier

F91344 Massy Dedex FRANCE

Notes:

Thermal imaging, night vision equipment for European military market.

T. Sasaki

Position:

Organization:

NEC Corporation

Component:

Address:

4-1-1 Miyazaki

Miyamae, Kawasaki, 216 JAPAN

Notes: Co-authored for 1991 MCT Workshop "Study of CdTc Epitaxial Growthn on

(211)B GaAs by MBE"

Contact Name:

Thomas Scanlon

Position:

Organization:

Inframetrics, Inc.

Component:

Address:

16 Esquirc Road

North Billerica, MA 01862

Notes:

Active in setting up infrared predictive maintenance regimes for Inframetric's

customers.

Contact Name:

S.E. Schacham

Position:

Address:

Organization:

Component:

Department of Electrical Engineering Technion-Israel Institute of Technology

Kidron Microelectronics Research Center

Haifa 32000, ISRAEL

Notes:

For 1991 MCT Workshop Co-authored "Covered Electrode HgCdTe

Photoconductor Under High Illumination Levels"

and for 1992 SPIE meeting on MCT "P-Channel MIS Double-Metal Process

InSb Monolithic Unit Cell for Infrared Imaging"

Contact Name:

Dr Eugene Scheide

Position:

Pres

Organization:

Environmetrics, Inc.

Component:

Address:

2345 Millpark Dr.

Maryland Heights, MO, 63043

Notes:

Development of "smart sensors," chemical sensors, development of gas sensing

instruments

J.F. Schetzina

Position:

Organization:

North Carolina State University

Component: Address:

Department of Physics Raleigh, NC 27695-8202

Notes:

On Program Committe of 1991 & 1992 MCT Workshop, and Authored for 92 MCT workshop "Growth of HgSe and HgCdSe Thin Films by Molecular Beam Epitaxy," and "Integrated Heterostructure Devices Based on II-Vi Compound

Semiconductors."

For 1991 Workshop, co-authored "Properties of CdZnTe Crystals Grown by a High Pressure Bridgman Method" and "Quantum Hall Effect and Setback

Modulation DOping HgTe-CdTe Heterostructures"

Contact Name:

J.T. Schick

Position:

Organization:

Wayne State University

Component:

Department of Physics and Astronomy

Address:

Detroit, MI

Notes:

Co-authored 1990 article, 6 pages, "Structural Energies of Defects in CdTe and

HgCdTe"

And co-authored April 1990 "Point Defects in Lattice Distortion in CdTe and

HgCdTc"

Contact Name:

Position:

J. Schieferdecker

Organization: Component:

Dresden University of Technology Institut fur Festkorperclektronik

Address:

Dresden, FEDERAL REPUBLIC OF GERMANY

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Pyroclectric

Linear Array IR Detectors with CCD Multiplexer"

Contact Name:

Frederick Schmid

Position:

CEO

Organization:

Crystal Systems Inc.

Component:

Address:

Shetland Industrial Park

27 Congress St. Salem, MA 01970

Notes:

Growth of semiconductors using such materials as GaAs and CdTe, and use

of silicon in infrared applications in both commercial and military markets.

Frederick Schmid

Position:

CEO

Organization:

Crystal Systems Inc.

Component: Address:

Shetland Industrial Park

27 Congress St. Salem, MA 01970

Notes:

Growth of semiconductors using such materials as GaAs and CdTe, and use of silicon in infrared applications. Work for both military and commercial

markets.

Contact Name:

Michael Schneider

Position:

Organization:

Research Devices, Inc.

Component:

Address:

121 Ethel Road West

Piscataway, NJ 08854

Notes:

AUthored for 1992 SPIE Workshop on MCT "Hybridizing Focal Plane

Arrays."

Contact Name:

Marija S. Scholl Position:

Organization:

California Institute of Technology

Component:

Jet Propulsion Laboratory 4800 Oak Grove Drive

Address:

Pasadena, CA 91009-8099

Notes:

Editor of upcoming January 1994 edition of the SPIE's Optical Engineering

journal, focusing on infrared technology.

Contact Name:

James R. Schott

Position:

Address:

Organization:

Worchester Institute of Technology

Component:

Center for Imaging Science One Lomb Memorial Drive

Rochester, NY 14623

Notes:

active in infrared remote sensing

L.J. Schowalter

Position:

Organization: Renssalaer Polytechnic Institute

Component:

Physics Department and Center for Integrated Electronics

Address:

110 Eight Street Troy, NY 12180

Notes:

Co-authored for 1992 meeting of SPIE on IRFPAs "Fundamental Studies of

Schottky Barrier IR Detectors by Ballistic Electron Emission Microscopy"

Contact Name:

Frank Schrontz

Position:

CEO

Organization:

The Boeing Company

Component:

Address: Notes:

7755 E Marginal Way S, PO Box 3707 Scattle, WA 98124 Research in the field of aerospace including sensor systems.

Contact Name:

Mangred Schuck

Position:

Senior Manager

Organization:

Rodenstock Industrial Optics

Component:

Address:

P.O. Box 14 04 40

Jsartalstrasse 43

D-8000 Munich 5, GERMANY

Notes:

Infrared systems & equipment, e/o systems, thermal imaging for military

applications.

Contact Name:

Carl Schueler

Position:

Manager, Advanced Development Programs

Organization:

SBRC

Component:

Address:

75 Coromar Drive

Goleta, CA 93117

Notes:

M.J. Schulz

Position:

Organization:

University of Erlangen

Component: Address:

Erlangen, GERMANY

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Electronic

Ì

and Optical Properties of Silicide/ Silicon IR Detectprs"

Contact Name:

Norman Schumaker

Position:

CEO

Organization:

Emcore Corp.

Component: Address:

35 Elizabeth Avenue Somerset, NJ 08873

Notes:

Material production of GaAs, CdTe, silicon, ZnS, and ZnSe for infrared

applications.

Contact Name:

WC Schwartz

Position:

President

Organization:

Schwartz Electro-Optics

Component:

Address:

3404 N Orange Blossom Trail

Orlando, FL 32804

Notes:

Manufactures near and mid-IR solid-state lasers for research, medical,

industrial, and OEM applications. Knowledgeable in photofluoresence in IR,

using IR detectors.

Contact Name:

Edward Scicchitano

Position:

CEO

Organization:

DTX Corporation

Component:

Dynatherm Corporation

Address:

One Beaver Ct.

Cockeysville, MD 21030

Notes:

Thermal systems research oriented toward industrial process temperature

control.

M Seelmann-Eggebert

Position:

Organization:

Fraunhofer-Institut fur Angewandte Festkorperphysik

Component:

Address:

D-7800 Freiburg, GERMANY

Notes:

Authored "XPD Investigation of Substrate Crystallinity at HgCdTe (111B) and

CdTe(111)B Surfaces Upon Ag and Al Overlayer Formation."

For 1991 Workshop "Photoemission Spectrscopic Techniques to Assess Physical and Chemical Properties of Mercury Cadmium Telluride"

Contact Name:

Milton Seiler

Position:

Organization:

Battelle Memorial Institute

Component:

Address:

505 King Avenuc

Columbus, OH 43201-2693

Notes:

Designs infrared non-destructive evaluation applications.

Contact Name:

Position:

ame: D.G. Sciler

Organization:

National Institute of Standards and Technology

Component:

Semiconductor Electronics Division

Address:

Gaithursburg, MD 20899

Notes:

On Program Committee, and Co-Authored "Heavily Accumulated Surfaces of

MCT Detectors: Theory and Experiment" for 1992 MCT Workshop.

Co-Authored for 1991 Workshop "Investigation of Merury Interstitials in MCT

alloys Using Resonant Impact-Ionization Spectroscopy"

Contact Name:

Sharon A. Semanovich

Position:

Ms.

Organization:

Allen Infrared Associates

Component:

RR #1, Box 239K Coward, SC 29530

Notes:

Assistant to Allen, active in design of infrared predictive maintenance regimes

Martin Sensiper

Position:

Organization:

University of Central Florida

Component:

Electrical Engineering Department and Center for Research in Electro-Optics

and Lasers

Address:

12424 Research Parkway, Suite 400

Orlando, FL 32828

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Use of Narrowband Laser

Speckle for MTF Characterization of CCDs"

Contact Name:

Becky Setzler

Position:

Media Relations Program Manager

Organization:

Texas Instruments

Component:

Address:

P.O. Box 660246 MS 3134

Dallas, TX 75266-0246

Notes:

INfrared systems & equipment, thermal imaging, detectors & sensors

Contact Name:

Keith Seybald

Position:

Melec

Organization:

Angstrom Technologies, Inc.

Component:

Address:

PO Box 607

Florence, KY 41042

Notes:

Basic and applied electro-optical vision for robotics and automated guided

vehicles; applied and product-oriented research in packaging and material

handling vision systems.

Contact Name:

Position:

Y. Shacham-Diamand

Organization:

Cornell University

Component:

School of Electrical Engineering and the National Nanofabrication Facility

Address: Ithaca, NY 14853

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "P-Channel MIS Double-

Metal Process InSb Monolithic Unit Cell for Infrared Imaging"

R.R. Shannon

Position:

Organization:

Arizona University **Optical Sciences Center**

Component: Address:

Tucson, AZ

Notes:

Authored March 1990 "Research in the Optical Sciences" which reviews the progress of their optical sciences center, including growth of semiconductors

through LPE and VPE. Some MCT and CZT research

Contact Name:

Richard Shaps

Position:

Dvmgr

Organization:

Bio-Rad Laboratories Digilab Division

Component: Address:

237 Putnam Avenue Cambridge, MA 02139

Notes:

Manufactures fourier transform IR spectrometers.

Contact Name:

Dick Sharmam

Position:

Address:

General Manager Exotic Materials, Inc.

Organization:

Component:

2930 Bristol St.

Costa Mcsa, CA 92626

Notes:

Applied, product-oriented research as related to electro-optical materials,

vacuum deposited coatings and devices for government, industrial and military

systems applications.

Contact Name:

M.C. Shaw

Position:

Organization:

Arizona State University

Component:

Address:

Tempe, AZ 85287-5506

Notes:

Co-authored 1983 "Application of Infrared Radiation Measurements in

Grinding Studies." MCT-based materials research

Dr Manny Shaw

Position:

Pres

Organization:

Interscan Corporation

Component:

Address: 21700 Nordhoff St. PO Box 2496

Chatworth, CA 91313-2496

Notes:

Gas analyzer and sensor developments.

Contact Name:

Diane R. Sheerar

Position: Organization:

Manager Marketing Services Brunswick Technical Group

Component:

Address: 1 Brunswick Plaza

Skokie, IL 60077

Notes:

Infrared Systems and Equipment predominantly for military markets

Contact Name:

Position:

A. Sher

Organization: Component:

SRI International

Componer

Address:

Menio Park, CA 94025

Notes:

On Progam Committee, and Co-Authored "Native Defect Equilibria in

HgZnTe and HgCdTe Alloys" for 1992 MCT Workshop.

On 1991 MCT Workshop Progam Committee; co-authored "Defect

Equilibrium in HgTe"

Contact Name:

K. Shigenaka

Position:

Toshiba Corporation

Organization: Component:

Research and Development Center

Address:

Komukai Works

Kawasaki, Japan

Notes:

Co-authored for 1992 MCT Workshop "Effects of Growth Rate and Mercury

Partial Pressure on Twin Formation in HgCdTe (111) Layers Grown by

MOCVD"

Lee Shiozawa

Position:

Organization:

Cleveland Crystals, Inc.

Component:

19306 Redwood Avenue, P.O Box 17157 Cleveland, OH 44117

Address: Notes:

Manufacturer and research into CdTe, ZnS, and ZnSe infrared materials,

specialty in II-VI, for both military and commercial markets.

Contact Name:

Michael Shur

Position:

Organization:

Virginia University

Component:

Department of Electrical Engineering

Address:

Charlottesville, VA

Notes:

Co-authored May 1992 report "Monte Carlo Simulation of Electron Transport

in HgCdTc"

Contact Name:

Dr Joseph Siewick

Position:

CEO

Organization:

Science & Engineering Consultants, Inc.

Component:

Address:

Suite 300, 1820 discovery St.

Reston, VA 22090-5610

Notes:

Research in imaging and remote sensing.

Contact Name:

Orman Simpson

Position:

Prcs

Organization:

MDA Scientific, Inc.

Component: Address:

Suite 185, 3000 Northwoods Pkwy Norcross, GA 30071

Notes:

Optical remote sensing techniques.

J. Singh

Position:

Organization:

University of Michigan

Component:

Department of Electrical Engineering and Computer Science

Address:

Ann Arbor, MI 48109

Notes:

Co-Authored "Recent Advances on HgCdTe Mid Infrared Diode Lasers" for

1992 MCT Workshop.

Contact Name:

Nicholas Sink

Position:

Gen. Mgr.

Organization:

Semiconductor Processing Co., Inc.

Component:

Address:

409 East First Street

Boston, MA 02127

Notes:

Manufacturer of GaAs, germanium, and silicon for infrared applications.

Contact Name:

S. Sivananthan

Position:

Organization:

University of Illinois at Chicago

Component:

Microphysics Laboratory, Physics Department

Address:

P.O. Box 4348 Chicago, IL 60680

Notes:

Authored "Structure of CdTe(111)B grown by MBE on Misoriented Si(001)"

and "Influence of CdZnTe(211)B Substrate on Electrical Properties of HgCdTe

Grown by MBE" for 1992 MCT Workshop.

For 1991 Workshop, "Current Status of Directo Growth of CdTc and HgCdTc

on Silicon by MBE"

Contact Name:

R. Sizmann

Position: Organization:

Technische Universtat Phsik-Department E-16

Component:

mUNCHEN, d-8046

GERMANY

Notes:

Address:

Co-authored for 1991 MCT Workshop "Influece of Resonant Defect States on

Subband Structures in HgCdTe"

John Skurla Sales Manager

Organization:

EG&G Reticon Corp.

Component:

Address:

Position:

345 Potrero Avenue

Sunnyvale, CA 94086-4197

Notes:

Manufactures photodiode semiconductor detectors, detector arrays, CCPD image sensors, solid-state and line scan and area scan, and circular cameras

Contact Name:

Joseph Slawek

Position: Organization: Gmgr EG&G, Inc.

Component: Address:

EG&G Judson 221 Commerce Dr.

Notes:

Montgomeryville, PA 18936 Application of infrared materials including germanium and mercury cadmium

telluride.

Contact Name:

Jon Slaybaugh

Position:

Gmgr

Organization: Component:

Acme-Ceveland Corporation Namco Controls Division

Address:

7567 Tyler Blvd.

Mentor, OH 44060

Notes:

Product oriented R&D of electronic measurement and control devices

including photoelectric sensors, laser guidance, identification and tracking

devices.

Contact Name:

Lee Slizewski

Position:

Organization:

American Risk Management Corp.

Component:

Address:

P.O. Box 1042

West Brookfirld, MA 01585-1042

Notes:

Design infrared predictive maintenance regimes for factories, esp. nuclear

412

power plants

Mitchell R. Smigield

Position:

Dr.

Organization:

Scott-White Clinic

Component: Address:

Temple, TX 76501

Notes:

Active in infrared biomedical thermography research.

Contact Name:

Philip Smith

Position:

President

Organization:

Agema Infrared Systems

Component:

550 County Avenue.

Address:

Secaucus, N.J. 07094

Notes:

Manufactures infrared thermal imaging systems for condition monitoring, process monitoring and control, military/ defense research, surveillance and the

nondestructive meeasurement and analysis of materials and components.

Contact Name:

Phillip A. Smith

Position: Organization: National Sales Manager Amber Engineering

Component:

Address:

5756 Stonewood Drive

Golcta, CA 93117

Notes:

Participant in DARPA's IRFPA team and producer of InSb used in medium-

wave infrared systems. Designs systems for both commercial and military

markets. Amber's speciality is emissivity correction.

Contact Name:

L.M. Smith

Position:

Organization:

GEC Hirst Research Centre

Component:

Address:

Wembley, UNITED KINGDOM

Notes:

Co-authored May 1990 report "Integrated Technology in MCT/GaAs and

MCT/Si for Medium and Long Wavelength Infrared"

Carol Smith

Position:

Organization:

Wahl Instruments, Inc.

Component:

Address:

5750 Hunnum Ave.,

Culver City, CA 90231

Notes:

Production of non-contact IR thermometers for industrial processes.

Contact Name:

John R. Snell

Position:

Organization:

John Snell & Associates

Component:

Address:

17 First Avenuc

Montpelier, VT 05602

Notes:

Active in infrared predictive maintenance as inspector of plants and factories.

Widely published author on predictive maintenance.

Contact Name:

Ed Snow

Position: Organization: **GrEx** EG&G, Inc.

EG&G Optoelectronics

Component: Address:

22001 Dumberry

Vaudervil, PQ J7V 8P7

Notes:

R&D of optical emitters and detectors.

Contact Name:

Thomas Soderman

Position:

Prcs

Organization:

Bath Electrical Systems

Component:

Address:

5009 N Hwy 288 B, PO Box 198

Clutc, TX 77531

Notes:

Design and development of systems for infrared scanning for energy losses

problems.

R Sommer

Position:

Pres

Organization:

IR Scientific Inc.

Carlisle, MA 01741

Component:

Address:

PO Box 110

Notes:

Product-oriented near infrared research and development manufacturing and

infrared consulting services.

Contact Name:

J.L. Song

Position:

Organization:

Columbia University

Component:

Address:

New York, NY

Notes:

Co-authored for 1990 SPIE workshop on IR Detectors "GaAs CCD Readout

for Engineered Bandgap Detectors"

Contact Name:

X.N. Song

Position:

Organization: Component:

University of Nort Texas Department of Physics Denton, TX 76203

Address: Notes:

Co-Authored "Heavily Accumulated Surfaces of MCT Detectors: Theory and

Experiment" for 1992 MCT Workshop.

For 1991 Workshop, "Investigation of Mercury Interstititals in MCT alloys

Using Resonant Impact-Ionization Spectroscopy"

Contact Name:

James Sorenson

Position:

General Manager

Organization:

Batelle Memorial Institute

Component: Address:

Electronic Systems 505 King Avc.

Columbus, OH 43201

Notes:

Advanced development and integration of complex electronic and optical

systems; development of large laser materials for interaction studies;

automated inspection systems and optical systems for tracking reentry vehicles.

Robert A. Spangler

Position:

Dr.

Organization: Component:

State University of NY at Buffalo Dept of Biophysiacl Sciences

Address:

120 Cary Hall

Buffalo, NY 14214

Notes:

Active in infrared biomedical thermography, helped develop multi-wavelength

camera which measures temperature independent of emissivity.

Contact Name:

Robert Spangler

Position: Organization:

Professor SUNY Buffalo

Component:

Department of Biological Sciences

Address:

120 Cary Hall

Buffalo, NY 14214

Notes:

An MD, with research interests in the application of classical and

nonequilibrium thermodynamics in biological systems, membrane processes, stability properties, etc. as well as the development of novel medical diagnostic techniques. Advised Hejazi on OE article, Nov. 92, on IR detection of skin

temperatures. Extremely knowledgeable on IR detectors biomedical.

Interviewed 11-20-92.

Contact Name:

John Spelman

Position:

Address:

Pres

Organization:

Environmental Technology Group, Inc.

Component:

1400 Taylor Ave., PO Box 9840

Baltimore, MD 21284-9840

Notes:

Applied research in microsensor systems for chemicals, design and

development of environmental, meteorological, biological and chemical

sensors, detectors for explosives, hazardous drugs and chemical warfare agents.

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Contact Name:

Jane Spicer

Position:

Ms.

Organization:

Johns Hopkins University

Component:

Center for NDE and Applied Physics Laboratory

Address:

Laurel, MD 20723

Notes:

Infrared non-destructive evaluation specialist at leading center.

R. Sporken

Position:

Organization:

University of Illinois at Chicago

Component:

Microphysics Laboratory, Physics Department

Address:

P.O. Box 4348 Chicago, IL 60680

Notes:

For 1991 Workshop, "Current Status of Direct Growth of CdTe and HgCdTe

on Silicon by MBE"

Contact Name:

Robert W. Spring

Position:

Organization:

John Snell & Associates

Component:

Address:

17 First Avenue

K.K. Sreenivasan

Montpelier, VT 05602

Notes:

Active in infrared predictive maintenance as large New England consulting

firm.

Contact Name:

Position:

Southern Methodist University

Organization: Component: Address:

Notes:

Co-authored for 1992 SPIE meeting on Machine Vision "Automated Vision

System for INspection of Wedge Bonds"

Contact Name:

M.D. Srinath

Position:

Organization:

Southern Methodist University

Component:

Address:

Notes:

Co-authored for 1992 SPIE meeting on Machine Vision "Automated Vision

System for INspection of Wedge Bonds"

Charles G Stanich Vice President

Organization:

Daedalus Enterprises, Inc.

Component:

Address:

Position:

300 Parkland Plaza, PO Box 1869

Ann Arbor, MI 48106

Notes:

Infrared and multispectral analysis systems for remote sensing.

Contact Name:

Michael Stanton-Hicks

Position:

Dr.

Organization: Component:

Cleveland Clinic Foundation Pain Management Center, M-60

Address:

9500 Euclid Avenue

Cleveland, OH 44195-5001

Notes:

User and innovator of infrared biomedical thermography

Contact Name:

Charles Staples

Position:

Pres .

Organization:

Thorton Associates Inc

Component:

Address:

1432 Main St.

Waltham, MA 02154

Notes:

Production of electronic control devices.

Contact Name:

Position:

Herman Statz General Manager

Organization: Component:

· (), (1): · ·

Raytheon Comp. Research Division

Address:

131 Spring St.

Notes:

Lexington, MA 02173
Infrared window and detection materials and components, radar window

materials, laser and electro-optics. Growth of CdTe on GAs/Si and Si

.

substrates for HgCdTe.

Bob Stauder

Position:

VP

Organization:

LaBarge Inc.

Component:

LaBarge Electronics 11616 E 51st St.

Address:

Tulsa, OK 74146

Notes:

Intrusion detection systems and components, telemetry systems and

components and other eletromechanical systems and components for airborne and space applications; atmospheric, weather and data measuring systems and

components.

Contact Name:

Donald Sting

Position:

CEO

Organization:

Nicolet Instrument Corporation

Component:

Spectra Tech Inc.

Address:

652 Glenbrook Rd, PO Box 2190-G

Stamford, CT 06906

Notes:

Infrared spectroscopy instruments and applications.

Contact Name:

Charles Stokes

Position:

Dir

Organization: Component:

Arvin Industries, Inc Franklin Research Center

Address:

2600 Monroe Blvd. Norristown, PA 19403

Notes:

Applied research, design, and development in electronic and electrical

engineering, including electro-optics.

Contact Name:

JM Stone

Position:

Pres

Organization: Component:

Dukane Corporation Microbiotics Division

Address:

2900 Dukane Dr.

Notes:

Saint Charles, IL 60174

Precision automated alignment and laser welding systems used to manufacture

optoelectronic devices.

Harry Stonecipher

Position:

Pres

Organization:

Sunstrand Corp.

Component:

Analytical Productions Division

Address:

820 Linden Ave. Rochester, NY 14625

Notes:

Image analysis equipment systems and color spectrometry.

Contact Name:

Arthur Stout

Position:

National Sales Manager

Organization:

Agema IR Systems

Component: Address:

550 County Avenue

Secaucus, NJ 07094

Notes:

Contact Name:

Arthur Stout

Position:

Marketing

Organization:

Inframetrics, Inc.

Component:

Address:

16 Esquire Road

Billerica, MA 01862

Notes:

Active in infrared remote sensing, predictive maintenance, nondestructive

evaluation markets for Inframetrics.

Contact Name:

Terry Stractten

Position:

Vice President

Organization:

General Dynamics Corporation

 ${\color{red}\textbf{Component:}}$

Electronics Division 5011 Kearny Villa Rd.

Address:

San Diego, CA 92123-1447

Notes:

Product oriented research in automatic test equipment and electronics, communications, electronic warfare, signal processing, and displays and

imagery, lasers. For military markets.

Dr Terry Straetten

Position:

VP

Organization:

General Dynamics Corporation

Component:

Electronics Division 5011 Kearny Villa Rd.

Address:

San Dicgo, CA 92123-1447

Notes:

Product oriented research in automatic test equipment and electronics, communications, electronic warfare, signal processing, and displays and

imagery, lasers for military markets.

Contact Name:

Robert Stratton

Position:

VP

Organization:

Texas Instruments Inc

Component:

Central Research Laboratories

Address:

PO Box 655936, MS 136 Dallas, TX 75265

Notes:

Production of HgCdTe-based infrared imagers.

Contact Name:

Joc Straub

Position:

Manager, Signal Processing Systems

Organization:

Pacer Systems, Inc.

Component:

Address:

900 Technology Park Drive

Billerica, MA 01803

Notes:

Infrared systems & equipment for military applications.

Contact Name:

Reggie Stroupe

Position:

Pres

Organization: Component:

Andersen Instruments, Inc. Nutech Corporation

Address: 2806 Check Rd

Durham, NC 27704

Notes:

Applied and product-oriented research in the areas of air pollution sampling,

filter systems, electronic sensors and controls, temperature control,

chromatography, and laboratory research instruments, medical electronics and

mass spectrometry.

Gary Stutte

Position:

Organization:

University of Maryland

Component:

Maryland Agricultural Experiment Station

Address:

College Park, MD 20742

Notes:

active in infrared remote sensing

Contact Name:

Miles Suer

Position: Organization: Director of Marketing Irvine Sensors Corp.

Component:

Address:

3001 Redhill Ave Bldg 3

Costa Mesa, CA 92626

Notes:

Applied research in military detection system (infrared sensing).

Contact Name:

C.J. Summers

Position:

Organization:

Georgia Institute of Technology

Component: Address:

Notes:

On Program Committee of 1991 & 1992 MCT Workshop

For 1991 Workshop, "Selected-area Epitaxy on CdTc," and "Gas Source IOdine

Doping and Characterization of MBE Grown CdTe"

Contact Name:

Tai-Ping Sun

Position:

Organization:

Chung-Shan Institute of Science and Technology

Component:

Address:

P.O. Box 90008-8-7, Lung-tan, Tao-Yuan REPUBLIC OF CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "A Novel CID Emulator for

InSb Array"

John Sun

Position:

VP

Organization:

ITI Electro-Optics Corp.

Component:

11500 W Olympic Blvd

Address:

Los Angeles, CA 90064

Notes:

Manufacture of CdTe, GaAs, germanium, ZnS, and ZnSe for infrared

technologies.

Contact Name:

James Swanson

Position:

President

Organization:

Ramtek Corporation

Component:

Address:

1525 Atteberry Lanc

San Josc, CA

Notes:

Remote sensing systems, multispectral system design, for both military and

commercial markets.

Contact Name:

M.L. Swanson

Position:

O section.

Organization: University of North Carolina at Chapel Hill

Component:

Department of Physics and Astronomy

Address:

Chapel Hill, NC 27599-3255

Notes:

Co-Authored "Observation of Indium-Vacancy and Indium Hydrogen

Interactions in (HgCd)Te Using PAC

Contact Name:

Ron Swarbrick

Position:

Marketing Director

Organization:

EG&G, Inc.

Component:

EG&G Optoelectronics

Address:

22001 Dumberry

Vaudervil, PQ J7V 8P7

CANADA

Notes:

R&D of optical emitters and detectors.

Tony Sweet

Position:

Marketing Director

Organization: Component:

EG&G Reticon Corp.

Address:

345 Potrero Avenue

Sunnyvale, CA 94086-4197

Notes: Manufactures photodiode semiconductor detectors, detector arrays, CCPD

image sensors, solid-state and line scan and area scan and circular cameras

Contact Name:

H. Takigawa

Position:

Organization:

Fujitsu Laboratorics, Ltd.

Component:

Atsugi Infrared Devices Laboratory

Address:

10-1 Morinosato-Wakamiya Atsugi 243-01 JAPAN

Notes:

Authored for 1992 MCT Workshop "Mercury Cadmium Telluride in Japan"

Contact Name:

Position:

E.M. Talund Defece Sales

Organization:

Scandinavian Avionics

Component:

Address:

Billund Airport

P.O. Box 59

7190 Billund, DENMARK

Notes:

Infrared systems and equipment, thermal imaging, night vision for military

applications.

Contact Name:

A. Tanabe

Position:

Organization:

NEC Corporation

Component:

Microelectronics Research Laboratories

Address:

1120, Shimokuzawa, Kanagawa 229, JAPAN

Notes:

Co-authored for 1992 SPIE workshop on IRFPAs "Optimum Barrier Height in

Schottky-Barrier Infrared CCD Image Sensor*

JD Tarbet **VPeng**

Organization:

Crane Co

Component:

Hydro-Aire Division

Address:

Position:

3000 Winona Avc. Burbank, CA 91504

Notes:

Infrared tracking for wind shear detection and high response control synthesis

for extra fast control systems.

Contact Name:

Bor-Yeu Tasur

Position:

MIT

Organization: Component:

Lexington Lincoln Lab

Address:

244 Wood Street

Notes:

Lexington, MA 02173-9108 Co-authored April 1990 study entitled "PtSi Schottky-Barrier Focal Plane

Arrays for Multispectral Imaging in Ultraviolet, Visible, and Infrared Spectral

Bands*

Co-authored August 1989 study entitled "128X128 Element IrSi Schottky-

Barrier Focal Plane Arrays for LWIR Imaging"

Contact Name:

David Taylor

EEV Ltd.

Position:

Sales Manager

Organization:

Component:

Waterhouse Lane

Address: Chelmsford, Essex ENGLAND CM1 2QU

Notes:

Active and passive eo systems, infrared systems and equipment, night vision for

military.

Contact Name:

Gary Tcagarden

Position:

Dir. Marketing Communications

Organization:

Paramax Systems Corp.

Component: Address:

8201 Greensboro Drove, Suite 1000

McLean, VA 22102

Notes:

Passive and active c/o systems, c/o systems, infrared systems and equipment for

military applications.

Peter Teets

Position:

Pres

Organization:

Martin Marietta Corporation

Component:

Martin Marietta Astronautics Group

Address:

Mail No S4400, PO Box 179

Denver, CO 80201

Notes:

Research into optical detection, optical control, electronic systems design, and

thermal control systems.

Contact Name:

Jay Teich

Position:

VP for Commercial Products

Organization:

Inframetrics

Component:

Address:

16 Esquire Road

North Billerica, MA 01862-2598

Notes:

Contact Name:

John Tengelsen

Position:

Pres.

Organization:

Lattice Materials Corp.

Component:

Address:

516 E. Tamrack

Bozeman, MT 59715

Notes:

Manufacturer of silicon for infrared applications.

Contact Name:

William Tennant

Position:

Dr.

Organization:

Rockwell International Science Center

Component:

Address:

1049 Camino Dos Rios

Thousand Oaks, CA 91360

Notes:

Chief scientist on IR producibility efforts, substrate issues.

Dennis Thomas

Position:

Organization:

Eagle-Picher Industries, Inc.

Component:

Electro-Optic Materials Department

Address:

P.O. Box 737

Quapaw, OK 74363

Notes:

Production of germanium and silicon systems for infrared applications.

Contact Name:

Robert L. Thomas

Position:

Organization:

Wayne State University

Component:

Institute for Manufacturing Research

Address:

Detroit, MI 48202

Notes:

infrared non-destructive evaluation

Contact Name:

Position:

Earl Thompson

ition: President

Organization:

Delta International, Inc.

Component:

Address:

2111 Wilson Boulevard, Suite 700

Arlington, VA 22201

Notes:

Thermal imaging, detectors and sensors for military applications.

Contact Name:

W.R. Thurber

Position:

Organization:

National Institute of Standards and Technology

Component:

Semiconductor Electronics Division

Address:

Gaithursburg, MD 20899

Notes:

Co-Authored "Heavily Accumulated Surfaces of MCT Detectors: Theory and

Experiment" for 1992 MCT Workshop.O -

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Roger Titrone

Position:

Pres

 ${\bf Organization:}$

Titronics Inc

Component:

RR 1, Box 53B

Address:

Oxford, IA 52322

Notes:

Infrared terrain scanning.

Contact Name:

Glenn Todd

Position:

EW Requirements Manager

Organization:

Texas Instruments

Component:

Defense Systems and Electronics Group

Address:

2501 W. University McKinney, TX 95070

Notes:

infrared systems and equipment

Contact Name:

Glenn Tom

Position:

VPres Research

Organization:

Advanced Technology Materials

Component:

Address:

520-B Danbury Road

New Milford, CT 06776

Notes:

Recently awarded an SDIO contract to develop a new electronic thin-film material to improve IR detector technology. The company will focus on using barium strontium titanate to develop new sensors capable of operating at

room temperature.

Contact Name:

Fei-Ming Tong

Position:

Shanghai Institute of Technical Physics

Organization: Component:

Chinese Academy of Sciences

Address:

Shanghai, 20092 CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "HgCdTe Photovoltaic

Detectors and Some Related Aspects"

Christopher Toth

Position:

President

Organization:

Superior Evaporants

Component:

Address:

6965 Highway 9 Felton, CA 95018

Notes:

Manufacturer of germanium, silicon, ZnS, and ZnSe for infrared systems.

Contact Name:

John R. Tower

Position:

Manager, Visible and IR Imaging Business

Organization:

David Sarnoff Research Center

Component:

Address:

CN5300 Washington Road

Princeton, NJ 08543-5300

Notes:

Oversees their PtSi Schottky-barrier IR focal plane array technology work

Contact Name:

Position:

Steven Towne Public Relations

Organization:

Loral Infrared and Imaging Systems

Component:

Address:

2 Forbes Road

Lexington, MA 02173

Notes:

Detectors and sensors, night vision, thermal imaging, infrared systems &

equipment, predominantly for military applications.

Contact Name:

Russell L. Travis

Position:

Dr.

Organization:

Component:

Address:

152 W. Zandale Drive

1 35/2 10

Lexington, KY 40503

Notes:

Doctor in private practice, active in infrared biomedical thermography

Roger B. Traycoff

Position:

Dr.

Organization:

Southern Illinois Univ School of Medecine

Component:

Address: P.O. Box 9230

Springfield, IL 62794-9230

Notes:

Active in use of infrared biomedical thermography, on board of directors of

American Academy of Thermology.

Contact Name:

R. Triboulet

Position:

Organization:

CNRS

Component:

Laboratoire de Physique des Solides de Bellevue

Address:

1, Place Aristide Briand

F. 92125 Meudon Cedex FRANCE

Notes:

Co-authored for 1992 MCT Workshop "Substrate Issues for Mercury Cadmium

Telluride"

Contact Name:

Charles T. Troy

Position:

Organization:

Photonics Spectra Magazine

Component:

Address:

Berkshire Common

P.O. Box 4949

Pittsfield, MA 01202-4949

Notes:

Follows infraist remote sensing as journalist

Contact Name:

Martha Tulloch

Position:

Organization:

Photonics Spectra Magazine

Component:

Address:

Berkshire Common

P.O. Box 4949

Pittsfield, MA 01202-4949

Notes:

Follows applications for infrared technologies as magazine's associate editor.

Mike Turley Position:

Organization:

Marketing Director Computing Devices Co.

Component:

Address: Castleham Road

St. Leonards on Sea

East Sussex, UK TN389NJ

Infrared systems and Equipment primarily for military markets. Notes:

Contact Name:

S. Kay Turner Position: VP Marketing

Organization:

Loral Corporation Loral Infrared & Imaging Systems, Inc.

Component: Address:

2 Forbes Rd.

Lexington, MA 02173

Notes:

Contact Name:

B.R. Turner

Position:

Organization:

Renssalaer Polytechnic Institute

Component:

Physics Department and Center for Integrated Electronics

Address:

110 Eight Street

Troy, NY 12180

Notes:

Co-authored for 1992 meeting of SPIE on IRFPAs "Fundamental Studies of Schottky Barrier IR Detectors by Ballistic Electron Emission Microscopy"

Contact Name:

Wilson Twohig

Position:

Address:

Pres

Organization:

Timeco Inc

Component:

1035 26th St.

20 8 E P

Huntington, WV 25705

Notes:

Timing controls, photoelectric controls, and load sensors.

Y.L. Tyan

Position:

Organization:

LTV Acrospace and Defense Company

Component:

Address:

Mail Stop PT-88 Dallas, TX 75265

Notes:

Co-authored for 1991 MCT Workshop "Analysis of Excess Carrier Lifetime in

p-Type HgCdTe Using a Three-Level Shockley-Read Model*

Contact Name:

Position:

M.N. Udrea-Spenea

Organization:

Enterprise for Semiconductor Devices

Component:

Address:

ROMANIA

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Accurate

Method for Neutron Fluence Control Used in Improving Neutron-

Transmutation-Doped Silicon Detectors*

Contact Name:

Sumio Ucmatsu

Position:

Organization:

Johns Hopkins Hospital

Component:

Address:

Meyer 2-147

600 N. Wolfe Street Baltimore, MD 21205

Notes:

Active in infrared biomedical thermography, past President of American

Academy of Thermology.

Contact Name:

A. Unikovsky

Position:

Organization: Component:

Kidron Microelectronics Research Center Department of Electrical Engineering

Address:

Technion-Israel Institute of Technology

Haifa 32000, ISRAEL

Notes:

For 1991 MCT Workshop co-authored "Tunneling and 1/f noise currents in

HgCdTe Photodiodes"

Malcom Unsworth

Position:

Gmgr

Organization: Component:

Schlumberger Limited Statham Transducers

Address:

2230 Statham Rd. Oxnard, CA 93033

Notes:

Micromachined silicone and thin film sensors.

Contact Name:

Position:

Frank J. Vallese General Manager

Electrophysics

Organization:

Component: Address:

373 Route 46 West, Building E

Fairfield, NJ 07004

Notes:

Night Vision, thermal imaging for military applications.

Sells their line of Pyroviewer, phovidicon cameras.

Contact Name:

Hervert Van Denend

Position:

Pres

Organization:

Glenro, Inc.

Component:

Address:

29 McBride Ave.

Paterson, NJ 07501

Notes:

Research into infrared system production, infrared ovens

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Contact Name:

Position:

Will Van Dyke

2 001110111

Manager of Advanced Program Development

Organization:

SBRC

Component:

Address:

75 Coromar Drive

Golcta, CA 93117

Notes:

A.D. Van Rheenen

Position:

Organization:

Minnesota University

Component:

Department of Electrical Engineering

Address:

Minncapolis, MN

Notes:

Co-authored August 1991 "Quantum Noise in Solid-State Devices in Particular

HgCdTe Diodes"

Contact Name:

M. van Schilfgaarde

Position:

Organization:

SRI International

Component:

Address:

Menlo Park, CA 94025

Notes:

Author of "Comparison of InTiSb and HgCdTe as Infrared Material" and "Native Defect Equilibria in HgZnTe and HgCdTe Alloys" at 1992 MCT

Workshop

For 1991 Workshop, co-authored "Defect Equilibrium in HgTe"

Contact Name:

M. van Schlifgaarde

Position:

Organization:

SRI International

Component:

Address: Menlo Park, CA 94025

Notes:

Co-authored for 1992 MCT Workshop "Comparison of InTiSb and HgCdTe as

Infrared Material*

Contact Name:

Victor Vargo

Position:

Gmgr

Organization:

Qualitec-Technologies, Inc.

Component:

Optoelectronics Division

Address:

3400 Hillview Avc. Palo Alto, CA 94304

Notes:

Development of III-V optoelectronic materials and silicon detectors.

V.P. Vavilov

Position:

Organization:

Tomsk Polytechnic Institute

Component:

Address:

Tomsk, RUSSIA

Notes:

Authored for 1991 SPIE meeting on IR Technology "Soviet IR IMagers and

THeir Applications: Short State of the Art"

Contact Name:

Position:

Richard Veith President

Organization:

Crystal Technology, Inc.

Component:

Address:

1040 E Meadow Circle Palo Alto, CA 94303

Notes:

Preparation and characterization of single crystal materials for use in optical, acoustic, magnetic applications; device development using these materials in

acousto-optics and surface acoustic waves (SAW).

Contact Name:

Tom Venable

Position:

Marketing Manager for IR Detectors

Organization:

Component:

Cincinatti Electronics

Address:

7500 Innovation Way Mason, OH 45040-9699

Notes:

Manufactures and designs IR detectors including single-element, linear and two dimensional arrays, discrete channel amplified, multiplexed, in Ge, MCT,

InSb and InAs, 1-12 um. Cincinnatti Electronics is owned by Canadian Marconi Company, which is, in turn, owned by the General Electric COmpany.

Contact Name:

Frank Verbeke President Alturdyne

Organization: Component:

Position:

Address:

8050 Armour

San Diego, CA 92111

Notes:

Infrared systems and equipment for military

Horacio R. Verdun

Position:

Organization:

FIBERTEK, Inc.

Component: Address:

510 Herndon Parkway

Herndon, VA 22070

for evaluation purposes.

Notes:

Co-authored for 1992 MCT Workshop "Tunnelling Current Probe for Contactless Electrical Performance Measurements of Infrared Focal Plane Detector Arrays." Firm manufactures high average power diode array pumped solid-state lasers, CW, Q-switched and frequency doubled, and highly advanced laser receiver for the military market, and laser crystals with new formulations

Contact Name:

Jan Vermeiren

Position:

Ms.

Organization:

IMEC

Component:

Address:

Jaockdreef 75

B-3001 Leuven, BELGIUM

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Comparative study of SWIR

and MWIR Schottky-Barrier Imagers"

Contact Name:

Vincent Vidas

Position:

CEO

Organization:

Semcor Inc

Component:

Address:

815 E Gate Dr.

Mount Laurel, NJ 08054

Notes:

Product-oriented research on the ststems engineering and program

management in support to the government in aeronautics, military science,

missile technology, countermeasures, ordnance and fire control

communications, radar, acoustic, optics, INFRARED and ultraviolet detection

systems.

Contact Name:

Position:

C.R. Viswanathan

Organization:

University of California, Los Angeles Electrical Engineering Department

Component: Address:

Los Angeles, CA 90024

Notes:

For 1991 MCT Workshop, wrote "Compositional Analysis of HgCdTe

Epitaxial Layers Using Secondary Ion Mass Spectrometry"

Jeffrey Voelker

Position:

Organization: General Electric Company Component: Electronics Laboratory

Address:

Syracuse, NY

Notes:

Authored Jan 92 piece evaluating LPE vs. MBE and MOCVD for radiometry.

Source on cost differences between two methods.

Contact Name:

Randall Voight

Position:

CEO

Organization:

International Research and Evaluation

Component:

Address: 21098 IRE Control Ctr.

Eagan, MN 55121

Notes:

Product-oriented with emphasis on photovotaic cells.

Contact Name:

H. Vydyanath

Position:

Organization:

Acrojet Corp.

Component:

Electronic Systems Division

Address:

Azuza, CA

Notes:

Co-authored for 1992 MCT Workshop "Photo-Induced Excess Low Frequency

Noise in HgCdTe Photodiodes"

Contact Name:

Position:

B.K. Wagner

Organization:

Georgia Institute of Technology

Component:

Address:

Notes:

Co-authored for 1991 MCT Workshop "Selected-area Epitaxy on CdTe"

and "Gas Source Iodine Doping and Characterization of MBE Grown CdTe"

Roger Waldock

Position:

Pres.

Organization:

MR Semicon, Inc.

Component:

Address:

276 Route 59

Tall Pines Industrial Park Monsey, NY 10952-3407

Notes:

Manufacture of CdTe and GaAs for infrared applications.

Contact Name:

william Wallace

Position:

Pres

Organization:

Westmark Systems, Inc

Component:

Tracor-GIE

Address:

1652 W 820 North

Provo, UT 84601

Notes:

Development of infared and far-infared systems.

Contact Name:

Position:

L. Walther

Organization: Component:

Dresden University of Technology Institut fur Festkorperclektronik

Address:

Dresden, FEDERAL REPUBLIC OF GERMANY

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Pyroelectric

Linear Array IR Detectors with CCD Multiplexer"

Contact Name:

M.W. Wang

Position:

Dr.

Organization:

California Institute of Technology

Component:

Address:

1201 East California Boulevard

Pasadena, CA 91125

Notes:

Reported at the DARPA Program Review on Infrared Focal Plane Array Technology in December, 1992, on "InAs/GaInSb Superlattices: Growth

Involving Anion Switching*

Peter Wang

Position:

CEO

Organization:

Fermionics

Component: Address:

4555 Runway St.

Simi Valley, CA 93063

Notes:

Produces wholesale CdTe and participant in CECOMs night vision advanced

research. Sells in both military and commercial markets.

Contact Name:

Peter C.C. Wang

Position: Organization: Chief Executive Fermionics Corp.

Component:

Address: 4555 Runway Street

Simi Valley, CA 93063

Notes:

Contact Name:

Wen Sang Wang

Position:

Organization:

Rensselaer Polytechnic Institute

Component:

Address:

110 Eight Street

Troy, NY 12180

Notes:

Co-authored "Improved CdTe Layers on GaAs and Si Substrates, Grown by

Atomic Layer Epitaxy" for 1992 MCT Workshop

Co-authored for 1991 Workshop "Low Temperature Epitaxy of HgCd, CdTe,

and HgCdTe Using Flow Modulation Techniques."

Contact Name:

Y.H. Wang

Position:

Organization: University of Florida

Component:

Department of Electrical Engineering

Address:

Gainesville, FL 32611

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "A Noval Grating Coupled Step-Bound-to-Miniband Transition InGaAs/GaAs/AlGaAs Multiquantum

Well Infrared Photodetector"

Raymond Wary

Position:

SIs Mgr

Organization:

PPM Pure Metals

Component:

Address:

111 Richmond Street, West, Suite 418

Toronto, Ontario, CANADA M5H 2G4

Notes:

Manufacture of germanium for infrared technologies.

Contact Name:

John Wasylyk

Position:

Director of Research AGR International, Inc.

Organization: Component:

Address:

PO Box 149

Butler, PA 16003-0149

Notes:

Development of optical inspection techniques for process control in glass

container manufacturing.

Contact Name:

Tomoji Watanabe

Position:

Organization:

Hitachi Koki Co.

Component:

Mechanical Engineering Laboratory

Address:

502 Kandatsu, Tsuchiura, Ibaraki, 300, JAPAN

Notes:

Proposed designs for IR detectors for radiation thermometry of silicon wafers

in a diffusion furnace for fabrication of LSI.

Contact Name:

Gary J. Weil

Position:

Organization:

EnTech Engineering, Inc.

Component:

Address:

111 Marine Lane

St. Louis, MO 63146-2235

Notes:

Active in infrared predictive maintenance. Using joint IR/GPR technique.

Christopher S. Welch

Position:

Organization: College of William and Mary

Component:

Dept of Physics

Address:

Williamsburg, VA 23185

Notes:

Leader in infrared non-destructive evaluation.

Contact Name:

Gary Well

Position:

Organization:

EnTech Engineering, Inc.

Component:

Address: 111 Marine Lane

St. Louis, MO 63146

Notes:

Active in infrared remote sensing, using joint IR/GPR technique.

Contact Name:

Song Wen-Zhen

Position:

Organization:

Shandong University

Component:

Infrared and Remote Sensing Rc.

Address:

Jinan, Shandong, CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "The Dependence of Fermi

Level of HgCdTe on Impurity Concentration and Temperature"

Contact Name:

N. Wercley

Position:

Organization:

BDM Inc.

Component:

Address:

4001 North Fairfax Drive

Arlington, VA 22203

Notes:

Authored for 1992 SPIE workshop on IRFPAs "Modeling the Cost and

Producibility Impacts of IRFPA Operability"

Greg Whaley Business Manager

Position: Organization:

Amorphous Materials Inc.

Component:

Address:

3130 Benton Street Garland, TX 75042

Notes:

Infrared materials production of CdTe, GaAs, and silicon, mainly for military.

Contact Name:

Position:

Robert White

Organization:

VP for Sales
Galileo Electro-Optics Corp.

Component:

Address:

Galileo Park, PO Box 550

Sturbridge, MA 01566

Notes:

Develops fiber-optic and electro-optic components which transmit, intensify or

sense light images.

Contact Name:

Larry Whited

Position:

Pres

Organization:

Magna Industries, Inc

Component:

Address:

2201 W 110th St., PO Box 734

Cleveland, OH 44107

Notes:

Produce oriented research in infrared products for gas saving devices.

Contact Name:

Warner Whitmer

Position:

Pres

Organization: Component:

CVS Systems & Services, Inc, CVD Systems & Services

Address:

Penn Centre Plaza

Quakertown, PA 18951

Notes:

Production of solar cells and sensor prototyping.

P.S. Wijewarnasuriha

Position:

Organization:

EPIR, Ltd.

Component:

Address:

Oak Brook, IL 60521

Notes:

Co-authored for 1992 MCT Workshop "Influence of CdZnTe (211)B Substrate

on Electrical Properties of HgCdTe Grown by MBE"

Contact Name:

Maria Maria.

Position:

Pres

Organization:

Willey Corporation

Ronald Willey

Component:

Address:

PO Box 670

Melbourne, FL 32902

Notes:

R&D of unique and sophisticated infrared reflectance spectrophotometry.

Contact Name:

Clifford Williams

Position:

Pres

Organization:

International Sensor Systems, Inc.

Component:

Address:

Industrial Park, PO Box 345

Aurora, NE 68818

Notes: Research in hybrid thick film technology and optical relays.

Contact Name:

Clayton Williams

Position:

Pres

Organization:

Litton Industries, Inc.

Component: Address:

Applied Technology Division 4747 Hellyer Ave., PO Box 7012

San Jose, CA 95150-7012

Notes:

Electro-optic and acouto-optic systems, predominantly for military.

Patricia Williamson

Position:

Assistant VP Corp. Comm. DRS Photronics Corp

Organization:

Component:

270 Motor Parkway

Address:

Hauppauge, NY 11788

Notes:

Electro optical systems, night vision, infrared systems and equipment for

Ì

military applications.

Contact Name:

Nick Willick

Position:

Senior Manager

Organization:

McDonnell Douglas Aerospace

Component:

Address:

1801 E. St. Andrew Place

Santa Ana, CA 92705

Notes:

Night Vision, thermal imaging, e/o systems for military markets.

Contact Name:

A.F.W. Willoughby

Position:

Organization:

University of Southampton **Engineering Materials**

Component: Address:

Southampton, SO9 5NH UNITED KINGDOM

Notes:

Authored "Growth Method, Composition, and Defect Structure Dependence of

Mercury Diffusion in CdHgTe" for 1992 MCT Workshop.

Contact Name:

Jeanine Wilson

Position:

Ms.

Organization:

Coors Brewing Company

Component:

Address:

Golden, CO 80401

Notes:

Proposed technique used by Coors to determine the parameters necessary to

improve glass distribution in the bottles used by Coors, and thuse achieve

reductions in glass weight.

Bill Wilson

Position:

Pres

Organization:

Microwave Technology Incorporated

Component:

Address:

4268 Solar Way

Fremont, CA 94538

Notes:

Research on GaAs and silicon for infrared applications.

Contact Name:

Robert Wilson

Position:

VΡ

Organization: Component: Textron Inc Sensor Systems 201 Lowell St

Address:

Wilmington, MA 01887

Notes:

Sensor systems for target discriminations, detections, and tracking.

Contact Name:

Position:

Kirk Winchester Marketing Director

Organization:

Janos Technology, Inc.

Component:

Address:

HCR #33, Box 25

Townshcad, VT 05353-7702

Notes:

Manufacturer of CdTe, GaAs, germanium, silicon, ZnS, and ZnSe for infrared

applications.

Contact Name:

William P. Winfree

Position:

Organization:

NASA, Langley Research Center

Component:

Address:

MS-231

Hampton, VA 23665

Notes:

Infrared non-destructive evaluation, aging aircraft skins.

Debra Withrow

Position:

Advertising Manager

Organization:

Recognition Concepts, Inc.

Component:

Address:

5200 Convair Drive

Carson City, NV 89706

Notes:

Infrared systems & equipment, imaging software for military applications.

Contact Name:

Norman Witriol

Position:

Organization:

Lousiana Tech University

Component:

Address:

Notes:

Co-authored 1990 "A Simplified Vision System With Robotic Assembly and

Manufacturing Applications"

Contact Name:

A.F. Witt

Position:

Organization:

MIT

Component:

Address:

Cambridge, MA 02139

Notes:

Co-authorrd for 1991 MCT Workshop "Nonlinear Optical Effects in

Rotationally Twinned CdTe and CdMnTe Crystals"

Contact Name:

Darold C. Wobschall

Position:

Dr.

Organization:

State Univ of NY at Buffalo

Component:

Dept of Elec & Computer Engineering

Address:

Bell Hall

Buffalo, NY 14214

Notes:

Active in infrared biomedical thermography. Active in designing a multi-

wavelength IR system which overcomes problems of emissivity differences in

imaging the body.

John Wohlgemuth Head of R & D

Organization:

AMOCO Corporation

Component:

Solarex Corp 1335 Piccard Dr.

Address:

Position:

Rockville, MD 20850

Notes:

Applied R&D including photovoltaic devices and power systems.

Contact Name:

T. Wojtowicz

Position:

Organization: Component:

University of Notre Dame Department of Physics Notre Dame, IN 46556

Address: Notes:

Co-authored for 1991 MCT Workshop "Magnetic Generation of electrons and

Holes in Semimetallic HgTe-CdTe Superlattices"

Contact Name:

Peter A. Wolff

Position:

Organization:

MIT

Component: Address:

Electronics Research Lab 77 Massachussets Avenue

Cambridge, MA 02139

Notes:

Co-authored January 1987 "Infrared Nonlinear Optics"

Contact Name:

R. Wollrab

Position:

Address:

Organization:

AEG

Component:

D-7100 Heilbronn

GERMANY

Notes:

Co-authored for 1991 MCT Workshop "Influence of Resonant Defect States

on Subband Structures in HgCdTe"

Edward Wood

Position:

President

Organization:

FJW Optical Systems, Inc.

Component:

Address:

629 S Vermont St. Palatine, IL 60067

Notes:

Electro-optical systems and infrared viewing devices for production industries.

Manufactures IR viewers, IR thermal imagers, and IR non-contact

thermometers.

Contact Name:

Richard Wood

Position:

Pres

Organization:

Optical Radiation Corp.

Component:

Address:

1300 Optical Dr.

Azusa, CA 91702

Notes:

Development of electro-optical systems.

Contact Name:

Thomas W. Woody

Position:

Manager of Product Engineering & Test Development

Organization:

Tektronix, Inc.

Component: Address:

CCD Product Group P.O. Box 500, MS 59-567

Microelectronics Product Line

Notes:

Beaverton, OR 97077
Oversees high performance CCD development at CCD, and has strong

knowledge of entire CCD industry, esp. compared with MCT-based detectors

Contact Name:

Ronald Wright

Position:

President

Organization:

Sequa Corporation

Component:

Kollsman Military Systems

Address:

220 Daniel Webster

Merrimack, NH 03054

Notes:

A variety of infrared research using primarily HgCdTe and InSb. Most

HgCdTe is reportedly supplied by Sofradir.

Harrison Wroton

Position:

Pres

Organization:

Solar Power Engineering Company

Component:

Address:

PO Box 91

Morrison, CO 80465

Notes:

Tracking photovotaic tracking power systems.

Contact Name:

Wen-Jack Wu

Position:

Organization:

National Taiwan University

Component:

Department of Electrical Engineering

Address:

1, Sec. 4, Roosevelt Road

Notes:

Taipci, TAIWAN, 10764, REPUBLIC OF CHINA Co-authored for 1992 SPIE meeting on IRFPAs "A Novel CID Emulator for

InSb Array"

Contact Name:

Chao-Wen Wu

Position: Organization:

National Taiwan University

Component:

Department of Electrical Engineering

Address:

1, Sec. 4, Roosevelt Road

Taipei, TAIWAN, 10764, REPUBLIC OF CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "A Novel CID Emulator for

InSb Array"

Contact Name:

Larry S. Wu

Position:

University of Florida

Organization: Component:

Department of Electrical Engineering

Address:

Gainesville, FL 32611

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "A Noval Grating Coupled

Step-Bound-to-Miniband Transition InGaAs/GaAs/AlGaAs Multiquantum

Well Infrared Photodetector"

Robert N. Wurzbach

Position:

Organization: Philadelphia Electric Company

Component:

Peach Bottom Atomic Power Station

Address:

Rd #1 Box 208 Delat. PA 17314

Notes:

Designed infrared predictive maintenance regime and purchased equipment for

the Peach Bottom Atomic Power plant.

Contact Name:

Hu Xicrong

Position:

Organization:

Shandong University

Component:

Infrared and Remote Sensing Jinan, Shandong, CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "Study of the Recombination

Mechanisms and Carrier Lifetimes in HgCdTe Alloy"

Contact Name:

Hu Xicrong

Position:

Organization:

Shandong University

Component:

Infrared and Remote Sensing

Address:

Shandong University

CHINA 250100

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "The Effect of Schockley-

Read Recombination on Minority-Carrier Lifetime of HgCdTe"

Contact Name:

Yang Xiuzhen

Position:

Organization:

Shanghai Institute of Technical Physics

Component:

Chinese Academy of Sciences Shanghai, 20092 CHINA

Address: Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "HgCdTe Photovoltaic

Detectors and Some Related Aspects"

Hirofumi Yagi

Position:

Organization: Mitsubishi Electric Corporation

Component: Address:

LSI Laboratory

4-1, Mizujara Itami, Hyogo, 664 JAPAN

Notes:

Co-authored for 1992 SPIE Workshop on IRFPAs "Improved 512X512 IRCSD

with Large FIII Factor and High Saturation Level"

Contact Name:

Wenzhong Yang

Position:

Organization: Component:

Chongqing Optoelectronics Research Institute

Address:

P.O. Box 1102, YongChuan, CHongqing

CHINA

Notes:

Authored at 1992 SPIE meeting on IRFPAs "LWIR Monolithic HgCdTc

Infrared Focal Plane Arrays."

Contact Name:

Sheng-Jenn Yang

Position:

Organization:

Chung-Shan Institute of Science and Technology

Component:

P.O. Box 90008-8-7, Lung-tan, Tao-Yuan Address:

REPUBLIC OF CHINA

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "A Novel CID Emulator for

InSb Array"

Contact Name:

G.L. Yang

Organization:

University of Notre Dame Department of Physics

Component:

Position:

Notre Dame, IN 46556

Address: Notes:

Co-Authored "Staes Confined in the Barriers of Type-III HgTe/CdTe

Superlattices" for 1992 MCT Workshop

Li Yanjin

Position:

Organization:

Shanghai Institute of Technical Physics

Component:

Academia Sinica

Address:

Shanghai, China 200083

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "The Effect of Shockley-Read

Recombination on Minority Carrier Lifetime of HgCdTc*

Contact Name:

Bob Yanka

Position:

Organization: Component:

GE Aerospace Electronics Lab

Address:

Building 3, Electronic Park

Syracuse, NY 13211

Notes:

Scientist working on MBE, past work on advanced iRFPA concepts for

WRight Patterson AFB April 1987-December 1990. The electronics lab works on gas (gallium arsenide) monolithic microwave technology, infrared arrays,

high speed digital electronics gas GaAs monolithic

Contact Name:

Wan Yong

Position:

Organization:

Shandong University

Component:

Infrared and Remote Sensing

Address:

Shandong University

CHINA 250100

Notes:

Co-authored for 1992 SPIE meeting on IRFPAs "The Effect of Schockley-

Read Recombination on Minority-Carrier Lifetime of HgCdTe"

Contact Name:

K.M. Yoo

Position:

Dr.

Organization:

Graduate Center for the City Univ of NY

Component:

Dept of Electrical Engineering and Physics

Address:

New York, NY 10031

Notes:

Active in multi-wavelength biomedical thermography system development

Institute for Ultrafast Spectroscopy & Lasers, Photonics Appl Lab

Larry Yost

Position:

SrVP

Organization:

Rockwell International Corporation

Component:

Industrial Control Group

Address:

1201 S Second St. Milwaukee, WI 53204

Notes:

Automation systems and industrial controls, including IR sensors.

Contact Name:

P.M. Young

Position:

Harvard University

Organization: Component:

Division of Applied Sciences

Audress:

20 Oxford Street

Cambridge, MA 92138

Notes:

Co-Authored "Augur Lifetimes in Ideal InGaSb/InAs Superlattices" for 1992

MCT Workshop.

Contact Name:

Michael F. Young

Position: Organization:

President Young Design

Component:

7110 Sca Cliff Road

McLean, VA 22101

Notes:

Address:

Infrared systems & equipment

Contact Name:

z. Yu

Position:

Organization:

North Carolina State University

Component:

Department of Physics

Address:

Raleigh, NC 27695-8202

Notes:

AUthored "Integrated Heterostructure Devices Based on II-VI Compound

Semiconductors*

Z. Yu

Position:

Organization: Component:

University of Nort Texas Department of Physics Denton, TX 76203

Address: Notes:

Co-Authored "Heavily Accumulated Surfaces of MCT Detectors: Theory and

Experiment" for 1992 MCT Workshop.

For 1991 Workshop, "Investigation of Mercury Interstititals in MCT alloys

Using Resonant Impact-Ionization Spectroscopy"

Contact Name:

Sunny Y. Yuen

Position:

Organization:

MIT

Component: Address:

Electronics Research Lab
77 Massachussets Avenue

Cambridge, MA 02139

Notes:

Co-authored January 1987 "Infrared Nonlinear Optics"

Cor _ t Name:

Ken Zanio

Position:

Mr.

Organization:

MOSET Corporation

Component:

Address:

El Toro, CA 92630

Notes:

Authored for 1992 SPIE Workshop on MCT "HgCdTe on Si for Monolithic

Focal Plane Arrays" supported by NRL contract from Dean Scribner

Contact Name:

Thomas Zappetti

Position:

Pres

Organization:

Unitron, Inc

Component:

Address:

170 Wilbur Pl., PO Box 469

Bohemia NY 11716

Notes:

Development of advanced optical systems.

Contact Name:

Cindy Zeidler

Position:

Ms.

Organization:

Xedar Corp

Component:

Address:

2500 Central Avenue

Boulder, CO 80301

Notes:

infrared non-destructive evaluation

Contact Name:

D. Zenatti

Position:

Dr.

Organization:

Sofradir

Component:

Address:

43/47 rue Camille Pelletan

92290 Chatcnay-Malabry

FRANCE

Notes:

Research scientist working on SOFRADIR's process for reduction of IRFPA

costs, presented paper on analysis criteria selection for IRFPA detector

production at 1992 SPIE Orlando meeting.

Contact Name:

Francis Ziemba

Position:

VP

Organization:

Applied Electron Corp.

Component:

2360 Owen Street

Santa Clara, CA 95054

Notes:

Address:

Product-oriented research in the field of radiation detection, both nuclear and

optical, including alpha, gamma, x-ray and radon detection, also near IR to

visible optical radiation detection.

Contact Name:

A. Zigelmann

Position:

Organization:

Soreq Nuclear Research Center

Component:

Address:

Notes:

Co-authored for 1991 SPIE meeting on Growth of IR Materials "Anodic

Oxides on HgZnTe"

Contact Name:

Steve Zimmerman

Position:

Organization:

KRS Electronics Corporation

Component:

Address: Suite 16, 11649 Chairman Dr.

Pres

Dallas TX, 75243

Notes:

Optical electronic sensing of liquids gases and temperatures, interest in

developing IR products.

Contact Name:

P.D. Zingen

Position:

Marketing Coordinator

Organization:

Astronautics Corporation of America

Component:

Address:

4115 N. Teutonia

Milwaukee, WI 53209

Notes:

Night vision, robotics, security systems, ASW equipment, infrared systems &

equipment, for military

Contact Name:

U. Zinnegger

Position:

Marketing Manager

Organization:

Siemens AG

Component: Address:

SI SM MA

Landsluter Strasse 26

8044 Unterschleissheim, GERMANY

Notes:

Infrared systems & equipment, night vision for military applications.

Contact Name:

David Zish

Position:

IR CCD Marketing Director
David Sarnoff Research Center

Organization: Component:

Address:

CN5300 Washington Road

Princeton, NJ 08543-5300

Notes:

Contact Name:

Nello Zuech

Position:

Organization:

Vision Systems, Intl

Component:

Address:

3 Milton Drive

Yardley, PA 19067

Notes:

infrared non-destructive evaluation

Contact Name:

M. Zutterman

Position:

Mr.

Organization:

Sofradir

Component: Address:

43/47 rue Camille Pelletan 92290 Chatenay-Malabry

FRANCE

Notes:

Marketing Director for their MCT commercialization projects

Appendix G

Questionnaire Sent to Industry Individuals

1742 Swann Street, NW Washington, D.C. 20009

August 14, 1992

Mr./Mrs. First Name, Last Name Title Company Address

Dear Mr./Mrs. Last Name:

I am carrying out a study of potential future applications of sensitive infrared materials in industrial processes and commercial products as a consultant to a US Government R&D organization.

Your company is listed in the 1992 edition of the <u>Directory of American Research and Technology</u>, compiled by the Department of Commerce, and is said to be carrying out research on IR technologies. It would be very helpful for our study if you could complete the attached questionnaire and return it to me in the envelope provided. It should require no more than 30 minutes of your time to answer the questions.

I am asking a structured sample of more than 300 companies like yours to respond. Based on these responses, I will prepare an analysis of the view from industry. In return for your time, I will be delighted to make available to you the aggregate results of the survey. Individual responses are considered confidential, however, and will not be distributed further.

If you would like to discuss this study or the questionnaire prior to completing it, please feel free to call me. I can be reached during the day at 202/785-9041.

It would be most helpful to have your response no later than September 8th, 1992. Thanks very much for your cooperation.

Yours truly,

Barry M. Blechman

Future Applications of Sensitive IR Materials in Industrial Processes and Commercial Applications

Which specific research questions related to IR materials or detectors is your organization now pursuing? What benefits will result from the successful solution of these problems?

(Please turn to back of page)

91...

What types of materials/compounds are you working with for infrared applications?

What do you think are the most promising specific applications of the materials with which you work in industrial processes or in commercial end-products? In what time frame -- 1-2 years, 3-7 years, 8-12 years -- do you think that each of these applications will be feasible on a commercial basis?

What specific industrial or commercial applications of sensitive IR materials, like mercury cadmium telluride and cadmium zinc telluride, do you foresee in 1-2, 3-7, or 8-12 years? If you are doing work on other IR materials, like PtSi, GaAs, Si, etc., please answer for those as well.

(Please turn to back of page)

What are the one, two, or three most difficult technologic order to see widespread use of each potential application have to be accomplished to see significant reductions in	listed above? In particular, what will
Name of individual completing questionnaire:	·
Company:	

Questionnaire Sent To University Individuals

1742 Swann Street, NW Washington, D.C. 20009

September 4, 1992

Mr./Mrs. First Name, Last Name Title University Research Center Address

Dear Mr/Mrs. Last Name:

I am carrying out a study of potential future applications of sensitive infrared materials in industrial processes and commercial products as a consultant to a US Government R&D organization.

Your center is listed in the 1993 edition of the <u>Research Centers Directory</u>, compiled by Gale Research, and is said to be carrying out research on photoelectric sensors, IR technologies, or both. It would be very helpful for our study if you could complete the attached questionnaire and return it to me in the envelope provided. It should require no more than 30 minutes of your time to answer the questions.

I am asking a structured sample of more than 60 university- affiliated organizations like yours to respond. Based on these responses, I will prepare an analysis of the view from research institutions. In return for your time, I will be delighted to make available to you the aggregate results of the survey. Individual responses are considered confidential, however, and will not be distributed further.

If you would like to discuss this study or the questionnaire prior to completing it, please feel free to call me. I can be reached during the day at 202/785-9041.

It would be most helpful to have your response no later than September 30th, 1992. Thanks very much for your cooperation.

Yours truly, Barry M. Blechman

QUESTIONNAIRE

Future Applications of Sensitive IR Materials in Industrial Processes and Commercial Applications

Which specific research questions related to IR materials or detectors is your research organization now pursuing? What benefits will result from the successful solution of these problems?

(Please turn to back of page)

What types of materials/compounds are you working with for infrared applications?

What do you think are the most promising specific applications of the materials with which you work in industrial processes or in commercial end-products? In what time frame -- 1-2 years, 3-7 years, 8-12 years -- do you think that each of these applications will be feasible on a commercial basis?

What specific industrial or commercial applications of sensitive IR materials, like mercury cadmium telluride and cadmium zinc telluride, do you foresee in 1-2, 3-7, or 8-12 years? If you are doing work on other IR materials, like PtSi, GaAs, Si, etc., please answer for those as well.

(Please turn to back of page)

:

What are the one, two, or three most difficult technological hurdles that have to be overcome in order to see widespread use of each potential application listed above? In particular, what will have to be accomplished to see significant reductions in cost?		

Name of individual completing questionnaire:

University Center:

Appendix H

Individuals Contacted for Section on Biomedical Thermography

Dr. Margaret Abernaty
Georgetown University Medical Center
Kober-Cogan 320
3800 Reservoir Road
Washington, DC 20007

Dr. R. R. Alfano
Inst for Ultrafast Spectroscopy and Lasers
Photonics Appl. Lab
Dpt of Electrical Engineering and Physics
Graduate Center of the City Univ of NY
New York, NY 10031

Dr. Kurt Ammer Ludwig Boltzmann Forschungsstelle fue Physikalische Diagnostik Heinrick Collinstr. 30 A-1140 Wien AUSTRIA

Dr. Michael Anbar State University of NY at Buffalo Department of Biophysical Sciences 120 Cary Hall Buffalo, NY 14214

Dr. Ray P. Clark
Thermal Biology Research Unit
King's College
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Dr. Bob Deuple Biophysics Department Thayer School of Engineering Hanover, NH 03755

Dr. Mervin Goff
Thermal Biology Unit
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London, W8 7AH, UNITED KINGDOM

Dr. Srini Govindan Professional Center 1, Suite 206 Medical Park Wheeling, WV 26003

Dr. Shahram Hejazi
Eastman Kodak Company
Health Sciences Division
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Rochester, NY 14653-9015

Dr. Jack Hubbard
Minneapolis Clinic of Neurology
Univ of Minnesota School of Medicine
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Ridgeview Medical Bldg, Suite 185
Burnesville, MN 55337

Dr. John Hughes
Division of Rheumatology
Clinical Research Centre
Watford Road, Harrow, UNITED
KINGDOM

Dr. Leonard Klenerman
Department of Orthopaedics
Northwick Park Hospital
Watford Road
Harrow, UNITED KINGDOM

Dr. Ralph Nelson Univ of Illinois College of Medicine Carle Foundation 611 West Park Street Urbanna, IL 61801

Dr. Jasen Ocho Department of Neurology Good Samaritan Hospital & Medical Center 1015 NW 22nd Avenue Portland, OR 97210

Dr. Alfred P. Pavot Greater S.E. Community Hospital And Georgetown Univ School of Medicine Department of PMR 1310 Southern Avenue, SE Washington, DC 20032

Dr. Rubem Pochaczevsky
Department of Radiology
Albert Einstein College of Medicine
1300 Morris Park Avenue
New York, NY 10461

Dr. Edward R.J. Ring
Department of Clinical Measurement
Royal Natl Hospital for Rheumatic Diseases
Upper Borough Walls, Bath, UNITED
KINGDOM

Dr. Mitchell R. Smigield Scott-White Clinic Temple, TX 76501

Dr. Robert A. Spangler State University of NY at Buffalo Department of Biophysical Sciences 120 Cary Hall Buffalo, NY 14214

Dr. Michael Stanton-Hicks Cleveland Clinic Foundation Pain Management Center, M-60 9500 Euclid Avenue Cleveland, OH 44195-5001

Dr. Russell L. Travis 152 W. Zandale Drive Lexington, KY 40503

Dr. Roger B. Traycoff Southern Illinois Univ School of Medicine P.O. Box 9230 Springfield, IL 62794-9230

Dr. Sumio Uematsu Johns Hopkins Hospital Meyer 2-147 600 N. Wolfe Street Baltimore, MD 21205

Dr. Darold C. Wobschall
State University of NY at Buffalo
Elec. and Computer Engineering Dpt
Bell Hall
Buffalo, NY 14214

Dr. K.M. Yoo Institute for Ultrafast Spectroscopy and Lasers Photonics Application Laboratory Department of Electrical Engineering and Physics Graduate Center of the City University of NY New York, NY 10031

Appendix I

Individuals Interviewed for Section on Non-Destructive Evaluation

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Delco Electronics
700 East Firman Avenue
Kokomo, IN 46901

Ravi Bhatla Motorola Corporation 1303 Eat Algonquin Road Schaumberg, IL 60196

Robert Bruno Inframetrics 16 Esquire Road North Billerica, MA 01862

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Hans Bucher Xedar Corp. 2500 Central Avenue Boulder, CO 80301

Doug Burleigh General Dynamics Space Systems Div. 5001 Keasrny Villa Road San Diego, CA 92123-1407

Antonio Colantonio
Technology, Architectural, and Enginereing
Services
Public Works Canada
Riverside Drvie
Ottawa, Ontario, CANADA K1A 0M2

R.P. Cooper PO Box 2053 Scientific Research Laboratory Ford Motor Co. Dearborn, MI 48121

Edward Cox Digital Equipment Corp. Mail Stop MLO5-4/E22 Maynard, MA 01754

Elliott Cramer MS 231 NASA, Langley Research Center Hampton, VA 23665

B. Scott Crews
MS 231
Analytical Services and Materials, Inc.
NASA Langley Research Center
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D.J. Crowther
Department of Physics and Institute for
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Wayne State University
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Hugh Danaher UTI Instruments

William De La Torre Research Opportunities, Inc. 2200 Hamipola Court Suite 101 Torrance, CA 90501 Robert Dixon
Tektronix, Inc.
26600 Southwest Parkway
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Frans Eberth
FLIR Systems, Inc.
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Portland, OR 97224

Lawrence D. Favro
Institute for Manufacturing Research
Wayne State University
Detroit, MI 48202

Mary Fallon Inframetrics 16 Esquire Drive Billerica, MA 01862

Pat Finney FLIR Systems, Inc. 16505 SW 72nd Avenue Portland, OR 97224

Greg Haug Compaq Computer

D.K. Hohnke
Scientific Research Laboratory, Room S2038
Ford Motor Company
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Dearborn, MI 48121-2053

Patricia A. Howell Analytical Services and Materials, Inc. c/o MS 231 NASA, Langley Research Center Hampton, VA 23665 K. Irani Mikron Instruments 445 W. Main Street Wyckoff, NJ 07481

Timo Kaupinnen
Technical Research Center of Finland
Building Laboratory
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Johns Hopkins University
Center for NDE and Applied Physics
Laboratory
Laurel, MD 20723

Pao-Kuang Kuo
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Wayne State University
Detroit, MI 48202

Ronald Lucier American Risk Management Corp. 4807 Rockside Road, Suite 500 Cleveland, OH 44131

Ken Matz
Matrix Scientific Systems

Phillip C. McMullan TSI Thermoscan Energy Management 15658 North Gray Road, Box 705 Carmel, IN 46032

William T. Morgan Infrared Engineering Services 110 Shadow Oaks Drive Easley, SC 29642 James C. Murphy
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The Boeing Company
Boeing Defense and Space Group
Quality Assurance Research and
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Milton Seiler
Battelle Memorial Institute
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George Sieverson Honeywell

Jane Spicer
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Robert L. Thomas
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Wayne State University
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Christopher S. Welch
College of William and Mary

Department of Physics Williamsburg, VA 23185

William P. Winfree MS 231 NASA, Langley Research Center Hampton, VA 23665

Nello Zuech Vision SYstems, International 3 Milton Drive Yardley, PA 19067

Cindy Zeidler Xedar Corp. 2500 Central Avenue Boulder, CO 80301

Appendix J

Individuals Contacted for Section on Predictive Maintenance

Lee Allen Allen Infrared Associates RR #1, Box 239K Coward, SC 29530

Mr. George S. Baird Baird Infrared Technology, Inc. 110 South Poplar Street #310 Wilmington, DE 19801-5046

Mr. Douglas D. Burleigh 2845 Arcola Avenue San Diego, CA 92117-3636

Patrick Finney FLIR Systems, Inc. 16505 SW 72nd Avenue Portland, OR 97224

James Garner
Infrared Research, Inc.
100 Park City Road
Rossville, GA 30741

Paul Grover Infraspection Institute 1971 Shelburne Road, Suite C Shelburne, VT 05482 Mr. Robert G. Hammaker Electric Power Research Institute 3 Industrial Highway Eddystone, PA 19022

Albert E. Hammett Southern Nuclear Operating Company 40 Inverness Center Parkway Birmingham, AL 35242

Donald Heller Agema Infrared Systems 142 Sunset Avenue Verona, NJ 07044

Mr. Paul Hughett Hughett Research 2110 Cedar Street #B Berkeley, CA 94709-1515

Herbert Kaplan Honeyhill Technical Company 193 East Avenue Norwalk, CT 06855

Mr. Donald D. Lucier
American Risk Management Corporation
P.O. Box 1042
West Brookfirld, MA 01585-1042

Phillip C. McMullan
TSI Thermo-Scan Energy Management
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Carmel, IN 46032

Neal A. MacNamara Southern Nuclear Operating Company 40 Inverness Center Parkway Birmingham, AL 35242

Robert P. Madding McDonnell Douglas Technologies, Inc. 16761 Via Del Campo Ct. San Diego, CA 92127

Thomas Scanlon Inframetrics, Inc. 16 Esquire Road North Billerica, MA 01862

Ms. Sharon A. Semanovich Allen Infrared Associates RR #1, Box 239K Coward, SC 29530

Lee Slizewski American Risk Management Corp. P.O. Box 1042 West Brookfirld, MA 01585-1042

Mr. John R. Snell, Jr. John Snell & Associates 17 First Avenue Montpelier, VT 05602-3119

Robert W. Spring John Snell & Assocs. 17 First Avenue Montpelier, VT 05602

Mr. Gary J. Weil EntTech Engineering, Inc. 111 Marine Lane St. Louis, MO 63146-2235 Richard N. Wurzbach Philadelphia Electric Company Peach Bottom Atomic Power Station Rd #1 Box 208 Delta, PA 17314

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Appendix K

Individuals Interviewed for Section on Process Control

Ms. Christine Anderson Cray Research 925 First Avenue Chippewa Falls, WI 54729-1402

Michel Balle HGH Ingenerie Systemes au Parc d"Activities du Moulin de Massy 3, rue du Saule Trapu Massy, 91300 FRANCE

Ed Bangs Infrared Monitoring Systems 10 West 35th Street Chicago, IL 60616

Kim Boyer Ohio State University 469 Dreese Lab 2015 Knil Avenue Columbus, OH 43210-1210

Brian Chin Materials Engineering Department 201 Ross Hall Auburn University Auburn, AL 36849-5351

Diane Cook
University of Texas at Arlington
Department of Computer Science
Engineerinbg
PO Box 19015
Arlington, TX 76019-0015

Craig Davidson Vision Harvest HCR Box 36 Hatch, NM 87937

Eustace Dereniak University of Arizona Optical Sciences Center Tucson, AZ 85721

Michel Engelhardt Grumman Aircraft Systems MS B46-35 Bethpage, NY 11714

James Fritz ISI Group 211 Conchas SE Albuquerque, NM 87123

Bill Gary Vision Harvest HCR Box 36 Hatch, NM 87937

Peter Gaylord
Total Vision Photonics
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Ottowa, CANADA K1M1W9

David Gilblom Sierra Scientific 605 West California Avenue Sunnyvale, CA 94086 Thorsten Graeve Optical Sciences Center University of Arizona Tucson, AZ 85721

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Thomas Hospod ((() +)
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John Lamonica Farmer's Investment Company PO Box 7 Sahuarita, AZ 85629

Christopher LeBeau
 Motorola Semiconductor Product Sector
 Group
 EL605 Mail Drop
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 Tempe, Arizona 85284

Cognex Corp
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Needham, MA 02194

Russell Mack
NDT Development, B-2406
Dow Chemical Company
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Freeport, TX 77541-3257

___ Sam Malizia
Youngstown Systems
Youngstown, OH

__Tom Murphy
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---Richard Phillips ITRAN 10291 E. Grand River Suite Brighton MI 48116

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Thayer School of Engineering
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Ed Schaufler IR Scanning Services 14()7 Third Street Beaver, PA 15009

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Joseph Setzer Kaiser Aluminum MS 50. Inst. Dev. PO Box 877 Pleasanton, CA 94566-0807

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University of the Pacific
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Baun Hall
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Howard Stern Robotic Vision Systems, Inc. 425 Rabro Drive Hauppauge, NY 11788

Michael Travis
Data Translation, Inc.
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Bo Wallin AGEMA Infrared Research and Development Division Rinkebivagen 19, Box 3 Danderyd, SWEDEN S-18211

Jeannie S. Wilson Coors Brewing Co. Rural Route 836 Golden, CO 80401-1295

Nello Zuech Visions Systems International 3 Milton Drive Yardley, PA 19067

Appendix L

Individuals Interviewed for Section on Remote Sensing

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Elizabeth A. Fuchs Sandia National Labs ORG 8246 P.O. Box 969 Levermore, CA 94551

Don Grandstrom SPIE P.O. Box 10 Bellingham, WA 98227-0010

John D. Bossler Center for Mapping Ohio State University 1216 Kinnear Road Columbus, OH 43212

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Nancy C. DelGrande Lawrence Livermore National Laboratories Livermore, CA 94551

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USDA - ARS
Remote Sensing Research Unit
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Richard J. Graf EnTech Engineering, Inc. 111 Marine Lane St. Louis, MO 63146

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Bob Madding McDonnel Douglas Tech Inc. 11955 Bajada Road San Diego, CA 92128-2023

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Lincoln, NE 69588

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Paul Reising Geonex Verde Technologies 734 E. Lake Avenue Watsonville, CA 95076

George A. Riggs School of Forestry University of Montana Missoula, MT 59812

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Gary Stutte
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Charles T. Troy Photonics Spectra Magazine Berkshire Common PO Box 4949 Pittsfield, MA 01202-4949

Martha Tulloch Photonics Spectra Magazine Berkshire Common PO Box 4949 Pittsfield, MA 01202-4949 Gary Weil EnTech Engineering, Inc. 111 Marine Lane St. Louis, MO 63146 XV

Appendix M

Individuals Interviewed for Section on Surveillance

James Abraham
Ball Aerospace Systems Group
P.O. Box 1235
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David Aikens FLIR Systems, Inc. 16505 S.W. 72nd Avenue Portland, OR 97224

Dr. Albert Brandenstein
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Office of National Drug Control Policy
Executive Office of the President
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J.C. Chow Massachussets Institute of Technology Lincoln Laboratories 244 Wood Street Lexington, MA 02173

G.A. Clark Carrier Car

C 40 - 10 - 10

Ron Creel
Maryland State Police, and
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•

Robert Cullen 101 N. George Mason Drive, Suite 2 Arlington, VA 22203-2905

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Nancy K. Del Grande Lawrence Livermore National Labs L-379, P.O. Box 808 Livermore, CA 94500

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George Elerding Santa Barbara Research Cetner 75 Coromar Drive Goleta, CA 93117

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Raymond D. Mintz Office of Enforcement Support U.S. Customs Service 1301 Constitution Avenue, NW, Room 5305 Washington, DC 20229

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Tom Venable Cincinnati Electronics Detector and Microcircuit Devices Lab Div 7500 Innovation Way Mason, OH 45040-9699 Robert Wisner Hamamatsu Corporation 360 Foothill Road P.O. Box 6910 Bridgewater, NJ 08807

Kenneth Wood Inframetrics, Inc. 16 Esquire Road Billerica, MA 01862

William R. Young United States Navy 3170 Manistee Drive Costa Mesa, CA 92626

David Zish David Sarnoff Research Center 201 Washington Road CN5300 Princeton, NJ 08543

Appendix N

Individuals Interviewed for Section of Transportation

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Collins Avionics
Division of Rockwell International Corp.
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Cedar Rapids, IA 52498

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Federal Aviation Administration
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Washington, DC 20591

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